

GEETHANJALI INSTITUTE OF SCIENCE & TECHNOLOGY: NELLORE (AUTONOMOUS)

NELLORE–524317 (A.P) INDIA

B.TECH IN ELECTRONICS & COMMUNICATION ENGINEERING (ACCREDITATED BY NBA) COURSE STRUCTURE AND SYLLABI UNDER RG 22 REGULATIONS



GEETHANJALI INSTITUTE OF SCIENCE & TECHNOLOGY: NELLORE

AUTONOMOUS

DEPARTMENT OF ELECTRONICS & COMMUNICATION ENGINEERING (ACCREDITATED BY NBA)

DEPARTMENT VISION

Achieving academic excellence in Electronics and Communication Engineering by shaping nextgeneration technocrats keeping pace with socio-economic needs.

DEPARTMENT MISSION

M1: Adopting outcome oriented teaching -learning processes to provide comprehensive knowledge in the application of Electronics and Communication Engineering principles.

M2: Striving for implementation of advanced technology to cater to industrial demands and societal concerns.

M3: Producing highly skilled and responsible professionals with robust ethical values.

M4: Integrating technical capabilities, life skills and entrepreneurship abilities to produce dynamic contributors to social advancement.

Program Educational Objectives (PEOs)

PEO-1: Demonstrating a deep passion for continuous learning through technical expertise for a promising career.

PEO-2: Exhibiting a strong commitment to serving the society with adherence to professional ethics.

PEO-3: Managing resources efficiently as competent engineers through effective social interaction.

PEO-4: Engaging in advanced learning and contributing to technological innovations.

Program Outcomes

PO1	Engineering knowledge: Apply the knowledge of mathematics, science, engineering
101	fundamentals, and an engineering specialization to the solution of complex engineering
	problems.
PO2	Problem analysis: Identify, formulate, review research literature, and analyze complex
	engineering problems reaching substantiated conclusions using first principles of
	mathematics, natural sciences, and engineering sciences.
PO3	Design/development of solutions: Design solutions for complex engineering problems and
	design system components or processes that meet the specified needs with appropriate
	consideration for the public health and safety, and the cultural, societal, and environmental
	considerations.
PO4	Conduct investigations of complex problems: Use research-based knowledge and
	research methods including design of experiments, analysis and interpretation of data, and
D O F	synthesis of the information to provide valid conclusions.
PO5	Modern tool usage: Create, select, and apply appropriate techniques, resources, and
	modern engineering and IT tools including prediction and modelling to complex
	engineering activities with an understanding of the limitations.
PO6	The engineer and society : Apply reasoning informed by the contextual knowledge to assess societal, health, safety, legal and cultural issues and the consequent responsibilities
	relevant to the professional engineering practice.
PO7	Environment and sustainability : Understand the impact of the professional engineering
10/	solutions in societal and environmental contexts, and demonstrate the knowledge of, and
	need for sustainable development
PO8	Ethics: Apply ethical principles and commit to professional ethics and responsibilities and
	norms of the engineering practice.
PO9	Individual and team work: Function effectively as an individual, and as a member or
	leader in diverse teams, and in multidisciplinary settings.
PO10	Communication: Communicate effectively on complex engineering activities with the
	engineering community and with society at large, such as, being able to comprehend and
	write effective reports and design documentation, make effective presentations, and give
	and receive clear instructions.
PO11	Project management and finance: Demonstrate knowledge and understanding of the
	engineering and management principles and apply these to one's own work, as a member
	and leader in a team, to manage projects and in multidisciplinary environments.
PO12	Life-long learning: Recognize the need for, and have the preparation and ability to engage
	in independent and life-long learning in the broadest context of technological change.

Program Specific Outcomes

PSO1 Design and develop electronic circuits and communication systems, applying the principlesof signal, image processing, VLSI, Embedded and wireless applications relevant to industry and society.

PSO2 Adopting software tools like Matlab, Xilinx, Microwind, NS-2 to develop intelligent systems to offer customized solutions.

SI. No.	Category	Course Code	CourseTitle	Hoursper week		eek	Credits
1	BSC				T	P	C
I		22A0015T	Methods	3	0	0	3
2	BSC	22A0020T	ProbabilityTheoryandStochasticP rocesses	3	0	0	3
3	PCC	22A0404T	SignalsandSystems	3	0	0	3
4	PCC	22A0405T	DigitalLogicDesign	3	0	0	3
5	HSC	22A0021T	UniversalHumanValues	3	0	0	3
6	PCC	22A0406T	AnalogCircuits	3	0	0	3
7	PCC(Lab)	22A0407P	SimulationLab	0	0	3	1.5
8	PCC(Lab)	22A0408P	DigitalLogic DesignLab	0	Ō	3	1.5
9	PCC(Lab)	22A0409P	AnalogCircuitsLab	0	0	3	1.5
	SC	22A3205	SkillOrientedCourse: PythonProgramming	1	0	2	2
1	MC		MandatoryCourse: ConstitutionofIndia	2	0	0	0
			Totalc	redits			24.5

Category	Credits
BasicScienceCourse(BSC)	6
ProfessionalCoreCourses(PCC)	13.5
HumanitiesandSocialScienceCourse(HSC)	3 =
SkillOrientedCourse (SC)	2
Total	24.5

Head of the Department lest of Electronics & Communication Engine GEETHANJALI INSTITUTE SCIENCE & TECHNOLOGY GANGAVARAM (V), Kovur (M).

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SCIENCE & TECHNOLOGY GANGAVARAM (V), Kovur (Md) SPSR Nellore Dt A.P. Pin 524 .5

SI. No	Category	Course Code	CourseTitle	Hou	rsperw	eek	Credits
				L	Т	P	С
Ι	HSC	22A0022T	ManagerialEconomics &FinancialAnalysis	3	0	0	3
2	ESC	22A0205T	ElectricalEngineering	3	0	0	3
3	PCC	22A0414T	Electromagnetic Wavesand TransmissionLines	3	0	0	3
4	PCC	22A0415T	Analog&DigitalCommunications	3	0	0	3
5	PCC	22A0416T	LinearICApplications	3	0	0	3
6	PCC(Lab)	22A0417T	Linear ICApplicationsLab	0	0	3	1.5
7	ESC(Lab)	22A0206P	ElectricalEngineering Lab	0	0	3	1.5
8	PCC(Lab)	22A0418P	Analog&DigitalCommunicationsLab	0	0	3	1.5
9	SC	22A0419P	SkillOrientedCourse: PCB&CircuitDesigning	I	0	2	2
10	MC	22A0027M	MandatoryCourse: EnvironmentalStudies	2	0	0	0
					Total	redits	21.5

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Category	Credits	
HumanitiesandSocialScienceCourse(HSC)	3	
EngineeringScienceCourse(ESC)	4.5	
ProfessionalCoreCourses(PCC)	12	
SkillorientedCourse(SC)	2	
Total	21.5	

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SI.	Category	Course	CourseTitle Hoursperweek				Credits
No.		Code		L	Τ	P	C
1	PCC	22A0420T	DigitalSystemDesignthroughVerilog	3	0	0	3
2	PCC	22A0213T	ControlSystems	3	0	0	. 3
3	PCC	22A0421T	Antennas&MicrowaveEngineering	3	0	0	- 3
4	PEC		ProfessionalElective-I	3	0	0	3
5	OEC		OpenElective-I	3	0	0	3
6	PCC(Lab)	22A0425P	DigitalSystemDesignthroughVerilogLab	0	0	3	1.5
7	PCC(Lab)	22A0426P	Antennas&MicrowaveEngineering Lab	0	0	3	1.5
8	SC	22A0028P	SkillAdvancedCourse: SoftSkills	I	0	2	2
9	MC	22A0526	MandatoryCourse: DesignThinkingandInnovation	2	0	0	0
10	CSP	22A0459	Evaluation of Community Service Project	0	0	0	1.5
				T	otalcr	edits	21.5

	S.No.	CourseCode	NameoftheProfessionalElective-I	
	SILIO	coursecoue	Nameonner rolessionalElective-I	
	1	22A0422T	DataCommunication&Networks	
l	2	22A0423T	InformationTheoryandCoding	
	3	22A0424T	IndustrialElectronics	

S.No.	CourseCode	NameoftheOpenElective-I
I	22A0512T	DatabaseManagementSystems
2	22A0214Ta	PowerElectronics
3	22A0332Tc	Fundamentalso fDrone Technology
4	22A0149T	BuildingMaterials

ProfessionalCoreCourses(PCC) 12 ProfessionalElectiveCourses(PEC) 3 OpenElectiveCourses (OEC) 3 SkillAdvancedCourse(SC) 2 SummerInternship 1.5 Total 21.5 Mark of the Pcontent of the Pcon	Category	Credits	1
OpenElectiveCourses (OEC) 3 SkillAdvancedCourse(SC) 2 SummerInternship 1.5 Total 21.5	ProfessionalCoreCourses(PCC)	12	
SkillAdvancedCourse(SC) 2 SummerInternship 1.5 Total 21.5 How of the Occanterial Q-W- How of the Occanterial G-W-	ProfessionalElectiveCourses(PEC)	3	
SummerInternship SummerInternship 1.5 Total 1.5 Total 21.5 Comparison	OpenElectiveCourses (OEC)	3	
Total 21.5 Adapt of the Department's Q-With JEETHANJALMINSTITUTE of Electronics & Continunication - Acodumica JEETHANJALMINSTITUTE	SkillAdvancedCourse(SC)	2	
Aran of the Department definition o	SummerInternship	1.5	
of FUCTIONES & COMMANDER THE STATES TO A COLUMN ALL THE STATES TO A COLUMNA ALL THE STATES	Total	21.5	11
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SI. No.	Category	Course Code	CourseTitle	Hou	sperw	eek	Credits
				L	T	P	C
1	PCC	22A0434T	MicroprocessorandMicrocontroller	3	0	0	3
2	PCC	22A0435T	DigitalSignalProcessing	3	0	0	3
3	PCC	22A0436T	VLSIDesign	3	0	0	3
4	PEC		ProfessionalElective-II:	3	0	0	3
5	OEC		OpenElective-II:	3	0	0	3
6	PCC(Lab)	22A0440P	MicroprocessorandMicrocontrollerLab	0	0	3	1.5
7	PCC(Lab)	22A0441P	VLSI DesignLab	0	0	3	1.5
8	PCC(Lab)	22A0442P	DigitalSignalProcessingLab	0	0	3	1.5
9	SC	22A0539	SkillOrientedCourse: JAVAProgramming	Ī	0	2	2
10	MC	22A0032M	MandatoryCourse: ResearchMethodology	2	0	0	0

_	S.No.	CourseCode	NamcoftheProfessionalElective-H
	1	22A0437T	ElectronicMeasurementsandInstrumentation
	2		Sensors&Actuators
Į	3	22A0439T	RadarandSatelliteCommunications

S.No.	CourseCode	Nameofthe OpenElective-II
1	22A0528T	MachineLearning
2	22A0238Ta	ModernControltheory
3	22A0150T	EnvironmentalEconomics
4	22A0027T	Organizational Behaviour

Category	Credits
ProfessionalCoreCourses(PCC)	13.5
ProfessionalElectiveCourses(PEC)	3
OpenElectiveCourses (OEC)	3
SkillOrientedCourse(SC)	2
Industrial/ResearchInternship(Mandatory)2Months	•
Total	21.5.
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SI. No.	Category	ategory Course Cou Code	CourseTitle	Hour	Hoursperweek		
		Coue		L	Τ	P	С
	PEC		ProfessionalElective-III	3	0	0	3
2	PEC		ProfessionalElective-IV	3	0	0	3
3	PEC		ProfessionalElective-V	3	0	0	3
4	OÉC		OpenElectives-III	3	0	0	3
5	OEC		OpenElectives-IV	3	0	0	3
6	HSC		OpenElective-V:	3	0	0	3
7	SC	22A0458P	SkillAdvancedCourse: MobileApplicationDevelopment	1	0	2	2
8	INT	22A0460	Evaluation of Industry Internship	0	0		3

S.No.	CourseCode	NameoftheProfessionalElectives
1	22A0449T	MobileCommunications
2	22A0450T	LowPowerVLSIDesign
3	22A0451T	EmbeddedRealTimeSystems
4	22A0452T	Fuzzysets, logicsystemsand Applications
5	22A0453T	AdvancedDigitalSignalProcessing
6	22A0454T	InternetofThings
7	22A0455T	CPLD&FPGAArchitecturesandApplications
8	22A0456T	DigitalImageProcessing
9	22A0457T	DigitalTVEngineering

S.No.	CourseCode	NameoftheOpenElectives		٦
1	22A0529T	CloudComputing		-
2	22A0241Ta	SmartGrid		-
3	22A0330Ta	MeasurementsandMechatronics		-
4	22A0151T	DisasterManagement		-
5	22A0534b	CyberSecurity		-
6	22A0327Ta	RenewableEnergySources		-
7	22A0152T	ConstructionManagement		-
8	22A0232Ta	ElectricVehicles		-
9	22A0024T	Entrepreneurship&Innovation0		-
10	22A0023T	ManagementScience		1
11	22A0026T	BusinessEnvironment		-
12	22A0033T	HumanResourceManagement	4	• == *



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Category	Credits
ProfessionalElectiveCourses(PEC)	9
HumanitiesandSocialScienceCourse(HSC)	3
OpenElective Courses(OEC)	6
SkillAdvancedCourse(SC)	2
Industrial/ResearchInternship	3
Total	23

Head of the Department Dept. of Electronors & Communication Engineering GEETHANJALLI INSTITUTE OF SCIENCE & TECHNOLOGY GANGAVARAM (V), Kovur (M), S.P.S.R. Ne: Jre Dt. A.P. Pin : 524 137

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SCIENCE & TECHNOLOGY GANGAVARAM (V), Kovur (Md) SPSR Nellore Dt. A.P. Pin 524 - 3

			IVYear(Semester-8)				20
SI.No.	Category	Course Code	CourseTitle	Ηοι	ırsperv	veek	Credits
1	MajorProject	22A0465P	Project work, Seminar and Internship in industry	0	0	24	12
	L		Totalcredits		9		12

TypesofCourses:

Typesof Courses	CourseCategory	Code	Department
	EngineeringSciences	ESC	24
Foundation	BasicSciences	BSC	21
	Humanities&SocialSciencesa nd Management	HSC	13.5
Core	ProfessionalCore	PCC	51
Project	Project&Internship(12)	PROJ	16.5
	Internship(4.5)		
Elective Courses	ProfessionalElective	PEC	15
Courses	OpenElective(includingtwoMOOCs)	OEC	12
Mandatory Courses	Mandatory	MC	-
	SkillOrientedCourses	SC	10
	T	otalCredits	163

Dept. of Electronics & Communication Engineering GEETHANJALI INSTITUTE OF SCIENCE & TEOHNOLOGY GANGAVARAM (V), KOYUH (M). S.P.S.R. Nessie BI, A.P. Pin : 524

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COURSES OFFERED FOR HONOR DEGREE BY ECE

Note: 1. The Honor subjects are having a total of 20 additional credits.

2. 8	Students should acquire 4	credits through MOOCs c	compulsorily to award the Honor	Degree.
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Sl. No.	Course	Name of the Honor Course	Ho	ours per	week	Credits	
	Code		L	Т	Р	С	
1	22A04H01	Low Power VLSI Circuits and Systems	3	1	0	4	
2	22A04H02	Pattern Recognition	3	1	0	4	
3	22A04H03	Software Defined Radio	3	1	0	4	
4	22A04H04	Micro Electro Mechanical Systems	3	1	0	4	
5	22A04H05	Wireless Communications	3	1	0	4	
6	22A04H06	VLSI Testing and Testability	3	1	0	4	
7	22A04H07	ARM based Embedded System Design	3	1	0	4	
8	22A04H08	Semiconductor Device Modelling	3	1	0	4	
9	22A04109	Modern Digital Communication Techniques	3	1	0	4	
10	22A04110	VLSI Interconnects	3	1	0	4	

S. No.	Name of the Honor Subject	Pre-requisite required
1	Low Power VLSI Circuits and Systems	Basics of VLSI
2	Pattern Recognition	Signal Processing, Probability Theory and Graph Theory
3	Software Defined Radio	Background in electrical engineering
4	Micro Electro Mechanical Systems	Basic Electronics
5	Wireless Communications	Principles of Signals and Systems and Principles of Communication Systems
6	VLSI Testing and Testability	Basics of VLSI
7	ARM based Embedded System Design	Embedded Systems
8	Semiconductor Device Modelling	Basic Knowledge on Electronic Devices and Circuits
9	Modern Digital Communication	Principles of Communication Systems and
	Techniques	Digital Communications
10	VLSI Interconnects	Electro-magnetics or Microwave Engineering or EM Waves

COURSES OFFERED FOR MINOR DEGREE BY ECE

Note: 1. The Minor subjects are having a total of 20 additional credits. 2. Students should acquire 4 credits through MOOCs compulsorily to award the Minor Degree.

Sl. No.	Course Code	Name of the Minor Course	Hour	s per	week	Credits	
			L	Τ	P	С	
1	22A0401T	Electronic Devices & Circuits	3	1	0	4	
2	22A0404T	Signals and Systems	3	1	0	4	
3	22A0405T	Digital Logic Design	3	1	0	4	
4	22A0416T	Linear IC Applications	3	1	0	4	
5	22A0430T	Principles of Communication Systems	3	1	0	4	
6	22A0437T	Electronic Measurements and Instrumentation	3	1	0	4	
7	22A0432T	Basic VLSI Design	3	1	0	4	
8	22A04111	Digital Circuits	3	1	0	4	
9	22A04112	Digital Image Processing	3	1	0	4	
10	22A04113	Fundamentals of Wireless Communication	3	1	0	4	
11	22A04114	Introduction to Semi conductor Devices	3	1	0	4	



B.TECH Electronics & Communication Engineering

Course Structure (RG22)

Semester 0

Induction Program: 3weeks (Common for All Branches of Engineering)

S.No	Course No	Course	Category	L-T-P-C
		Name		
1		Physical Activities Sports, Yoga and Meditation, Plantation	MC	0-0-6-0
2		Career Counselling	MC	2-0-2-0
3		Orientation to all branches career options,tools, etc.	MC	3-0-0-0
4		Orientation on admitted Branch corresponding labs, tools and platforms	EC	2-0-3-0
5		Proficiency Modules & Productivity Tools	ES	2-1-2-0
6		Assessment on basic aptitude andmathematical skills	MC	2-0-3-0
7		Remedial Training in Foundation Courses	MC	2-1-2-0
8		Human Values & Professional Ethics	MC	3-0-0-0
9		Communication Skills focus on Listening,Speaking, Reading, Writing skills	BS	2-1-2-0
10		Concepts of Programming	ES	2-0-2-0



B.TECH Electronics & Communication Engineering

Course Structure (RG22)

			Semester - 1 (Theory-5, Lab-3)			
	Category	Course	Course Title	Hour	s per w	eek	Credits
No.		Code		L	Т	Р	С
1	BSC	22A0001T	Linear Algebra and Calculus	3	0	0	3
2	BSC	22A0003T	Applied Physics	3	0	0	3
3	HSC	22A0013T	Communicative English	3	0	0	3
4	ESC	22A0518T	C Programming & Data Structures	3	0	0	3
5	ESC	22A0302T	Engineering Drawing	1	0	4	3
6	HSC (Lab)	22A0014P	Communicative English Lab	0	0	3	1.5
7	BSC (Lab)	22A0008P	Applied Physics Lab	0	0	3	1.5
8	ESC (Lab)	22A0519P	C Programming & Data Structures Lab	0	0	3	1.5
			Te	otal cre	edits		19.5

Category	Credits
Basic Science Course (BSC)	7.5
Engineering Science Course (ESC)	7.5
Humanities and Social Science Course (HSC)	4.5
Total	19.5



B.TECH Electronics & Communication Engineering

Course Structure (RG22)

			Semester - 2 (Theory-4, Lab-5)				
Sl. No.	Category	Course Code	Course Title	Hours	s per w	eek	Credits
100		Couc		L	Т	Р	С
1	BSC	22A0002T	Differential Equations and Vector Calculus	3	0	0	3
2	BSC	22A0006T	Chemistry	3	0	0	3
3	ESC	22A0201T	Fundamentals of Electrical Circuits	3	0	0	3
4	ESC	22A0401T	Electronic Devices & Circuits	3	0	0	3
5	BSC (Lab)	22A0011P	Chemistry Lab	0	0	3	1.5
6	ESC (Lab)	22A0202P	Fundamentals of Electrical Circuits Lab	0	0	3	1.5
7	ESC (Lab)	22A0402P	Electronic Devices & Circuits Lab	0	0	3	1.5
8	ESC (Lab)	22A0403P	Electronics Workshop	0	0	3	1.5
9	ESC (Lab)	22A0502P	IT Workshop	0	0	3	1.5
			Tot	tal cred	its		19.5

Category	Credits
Basic Science Course (BSC)	7.5
Engineering Science Course (ESC)	12
Total	19.5

		-	EBRA & CALCU			
Course Code	L:T:P:C	Credits	Exam Marks	Exam Durat	tion Course	Туре
22A0001T	3: 0:0:0	3	CIE: 30 SEE:70	3Hours	BS)
Course Objectiv	es:					
the students with	standard con- onfidence and	cepts and to ability amo	the concepts of call ols at an intermeding the students to	ate to advance	ed level mathe	-
Syllabus				1	Total Hours:	45
Module - I			Matrices		9 Hrs	10
nomogeneous eq circuits Eigen va	uations linear dues and Eig finding inver	equations.	form. Solving syst Applications: Fin nd their properties wer of a matrix b	ding the curr s, Cayley- Ha	ent in electric amilton theore	cal em
Module - II		Mean	Value Theorems		9 Hrs	
Cauchy's mean wheorems with rea	value theorem nainders (with	(Without P hout proof)	ange's mean valu roof), related prob - related problems, y Taylors and Mac	lems, Taylor' Taylor's and	s and Maclaur Maclaurin seri	in
Module - III		Multiv	variable Calculus		9 Hrs	
			rule, change of var od of Lagrange mu		ans, maxima a	nd
Module - IV		Mul	tiple Integrals		9 Hrs	
integrals, change	e of variable	s between	gration, change of Cartesian, cylindr double and triple i	ical and sph	1	
Module - V		Beta and	l Gamma function	ns	9 Hrs	
			perties, relation be ing beta and gamm		nd gamma	
Course Outcome	es (CO):					
use thisinTranslate analyzetheAcquire the Jacobian of	he system of formation to f the given fund e behavior of the Knowledge of a coordinate	linear equat facilitate the etion as series functions by e maxima an e transformat	be able to tions, find the eige calculation of matries of Taylor's and I using mean value d minima function tion to deal with the es in evaluating are	ix characteris Maclaurin's w theorems. s of several va problems in	tics. ith remainders ariables. Utiliz change of vari	s, æ ables

• Understand beta and gamma functions and its relations, conclude the use of special function in evaluating definite integrals.

Textbooks:

1. Higher Engineering Mathematics, B. S. Grewal, 44/e, Khanna Publishers, 2017.

2. Linear Algebra & Calculus by T.K.V. Iyengar, B.Krishna Gandhi, S.Ranganatham and M.V.S.S.N.Prasad S. Chand publication.

3. Engineering Mathematics III by N.P. Bali, Dr. K.L. Sai Prasad, University Science Press.

Reference Books:

1. "Advanced Engineering Mathematics", Erwin Kreyszig, Wiley India

2. B.V.Ramana, "Higher Engineering Mathematics", Mc Graw Hill publishers.

3. Mathematical Methods by T.K.V. Iyengar, B.Krishna Gandhi, S. Ranganatham and M.V.S.S.N.Prasad, S. Chand Publications.

		Ap	oplied Physics		
		(Comn	non to ECE, EEE))	
Course Code	L:T:P:C	Credits	Exam Marks	Exam Duration	Course Type
22A0003T	3:0:0:0	3	CIE:30 SEE:70	3Н	BS
Prerequisite: S	Student should	know about fu	undamental and bas	sic principles in pl	nysics.
		Co	ourse Objectives:		
 and high en with engine To open ne magneticm Evolution of of chargeca To identify To enlighted 	hergy application eering application wavenues of laterials and its of band theory arriers in semiconthe importance of the importance	ons, study of p ions. knowledge and application in to distinguish conductors. e of semicond s related to sup	propagation of ligh d understanding the n the emerging mic n materials, basic co luctors in the funct	t wave through op e basic concepts of ro devices. oncepts and transpo ioning of electroni ich leads to their fa	f dielectric and ort phenomenon
		Sylla	abus		Total Hours: 48
		Module - I V	Wave Optics		10
difference – P	hase difference ometry) – Col	e – Conditio	ons for sustained	interference- Inte	of Interference – Path rference in thin film ion of wavelength and
			Fraunhofer diffra e) – Grating spectr		fer diffraction due to

refraction - Nicol's Prism - Half wave and Quarter wave plates with applications.	
Module –II Lasers and Fiber optics	10
Lasers- Introduction – Characteristics of laser – Spontaneous and Stimulated emission of Einstein's coefficients – Population inversion – Lasing action – Pumping mechanisms – He-Ne laser – Applications of lasers.	
Fiber optics- Introduction – Principle of optical fiber – Acceptance Angle – Numeric Classification of optical fibers based on refractive index profile and modes – F electromagnetic wave through optical fibers – Propagation Losses (qualitative) – Applica	Propagation o
Module –III Dielectric and Magnetic Materials	10
Dielectric Materials - Introduction – Dielectric polarization – Dielectric polarizability, and Dielectric constant – Types of polarizations: Electronic, Ionic and Orientation (Qualitative) – Lorentz internal field – Clausius-Mossotti equation.	
Magnetic Materials- Introduction –Basic definitions – Origin of permanent magne Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and H materials	
Classification of magnetic materials: Dia, para & Ferro - Hysteresis - Soft and H	
Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and H materials	ard magnetic 10 iconductors - vel- Extrinsio ormation of p
Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and H materials Module –IV Semiconductors and Superconductors Semiconductors- Introduction – Classification of crystalline solids – Intrinsic sem Intrinsic Density of charge carriers- Intrinsic conductivity-Intrinsic Fermi lev semiconductors– p-type and ntype- Drift and diffusion currents – Einstein's equation – F n junction diode – Direct and indirect band gap semiconductors – Hall effect – Hall	10 10 iconductors - vel- Extrinsion ormation of p l coefficient -
Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and H materials Module –IV Semiconductors and Superconductors Semiconductors- Introduction – Classification of crystalline solids – Intrinsic sem Intrinsic Density of charge carriers- Intrinsic conductivity-Intrinsic Fermi lev semiconductors- p-type and ntype- Drift and diffusion currents – Einstein's equation – F n junction diode – Direct and indirect band gap semiconductors – Hall effect – Hall Applications of Hall effect. Superconductors- Introduction – Properties of superconductors – Meissner effect – TypeII superconductors – BCS theory – Josephson effects (AC and DC) – High Tc super	10 10 iconductors vel- Extrinsion ormation of p l coefficient
Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and H materials Module –IV Semiconductors and Superconductors Semiconductors- Introduction – Classification of crystalline solids – Intrinsic sem Intrinsic Density of charge carriers- Intrinsic conductivity-Intrinsic Fermi lev semiconductors- p-type and ntype- Drift and diffusion currents – Einstein's equation – F n junction diode – Direct and indirect band gap semiconductors – Hall effect – Hall Applications of Hall effect. Superconductors- Introduction – Properties of superconductors – Meissner effect – TypeII superconductors – BCS theory – Josephson effects (AC and DC) – High Tc super Applications of superconductors.	Iard magnetic 10 10 iconductors - vel- Extrinsition of p commation of p - coefficient - - Type I and rconductors - 8 - d due to linea -

Course Outcomes:

On completion of this course, the students are able to:

- Describe the importance of Interference, Diffraction and Polarization and the engineering applications as well (L2)
- Demonstrate the properties of lasers and fibre optics to various applications in science and technology (L2)
- Explain the fundamental concepts and theory related to dielectric and magnetic materials (L1)
- Illustrate the functioning of semiconductors in electronic devices (L2)
- Discuss the principles and theory related to superconductors and explore their technological applications(L2)
- Explain the electromagnetic wave propagation and its power in non-conducting medium (L2)

Text Books:

- 1. Engineering Physics Dr. M.N. Avadhanulu & Dr. P.G. Kshirsagar, S. Chand and Company
- 2. Engineering Physics B.K. Pandey and S. Chaturvedi, Cengage Learning.
- 3. Applied Physics for Engineers- K. Venkataramanan, R. Raja, M. Sundararajan(Scitech) [3,5] 2014

Reference Books:

- 1. Engineering Physics Shatendra Sharma, Jyotsna Sharma, Pearson Education, 2018
- 2. Engineering Physics K. Thyagarajan, McGraw Hill Publishers
- 3. Engineering Physics Sanjay D. Jain, D. Sahasrambudhe and Girish, University Press
- 4. David J.Griffiths, "Introduction to Electrodynamics"- 4/e, Pearson Education, 2014
- 5. Semiconductor physics and devices- Basic principle Donald A, Neamen, Mc Graw Hill

E-resources:

- https://www.textbooks.com/Catalog/MG5/Applied-Physics.php
- https://edurev.in/courses/9596_Electromagnetic-Theory-Notes--Videos--MCQs--PPTs
- https://libguides.ntu.edu.sg/c.php?g=867756&p=6226561
- https://bookauthority.org/books/best-applied-physics-books
- https://www.electronicsforu.com/resources/16-free-ebooks-on-material-science/2

			ICATIVE ENGL		
Course Code	L:T: P: S	Credits	Branches of Engir Exam marks	Exam Dura	tion Course Type
22A0013T	3: 0: 0: 0	3	CIE:30 SEE:70		¥1
Course Objectives:		3	CIE.30 SEE.70	5 110018	115
v		ng skills for	better comprehens	zion of academ	nic lectures and
	ken by native	0	better comprehens		inc lectures and
0 1	•	-	ing the learners to	narticinate in	activities such as
			alks/oral presenta		detryffies sdeff ds
1 5			or comprehension of		demic texts and
authentic ma		8	r r		
Impart effec	tive strategies	s for good wi	riting skills in sur	nmarizing, wr	iting well
organized es	says, drafting	formal letter	s and designing we	ell structured r	reports
	-	-	natical structures a	nd vocabulary	and encourage
their approp	riate use in sp	eech and wr	iting		
Syllabus					Total Hours:48
				TT 1 4 4	0.11
Module - I	O	n the Condu	ct of Life: Willia	m Hazlitt	9 Hrs
Listening: Identify	ing the topic	the context	and specific piece	s of informati	ion by listening to short
audio texts and ans				s or morman	on by insteming to short
	•	-		r topics such	as home, family, work,
studies and interest					us 1101110, 1411111j, 110111,
	-			ook for specif	ic pieces of information.
-			_	-	e topic, summarizing the
main idea and/or pi				-	
Grammar and Voca	abulary: Parts	of Speech,			
	Co	ontent words	and function word	s;	
	We	ord order in s	sentences;		
	Ba	sic sentence	structures;		
	Ту	pes of questi	ons - Wh- question	ns.	
Module - II		The Broo	k: Alfred Tennys	on	9Hrs
		<u> </u>	1 . • • 1	1	
_	ing a series o	f questions a	about main idea a	nd supporting	g ideas after listening to
audio texts.		11	······································	11 1 11 -	
1 0	-	0 1		•	ort structured talks.
paragraph together.		r lucas, recog	ginzing verbar teer	inques that no	elp to link the ideas in a
1 0 1 0		cific topics)	using suitable coh	esive devices	; mechanics of writing -
punctuation, capita	• •	ente topies)	using suitable con	estve devices,	meenames of writing -
Grammar and Voca		of Articles an	d zero Article		
	-	epositions			
		ctuation, cap	ital letters		
		esive device			
Module - III		- D41 T	C-1-		11 Hrs
	11	he Death Tra	ар: Sакі		
Listening: Listening	g for global o	omprehensio	n and summarizing	y what is lister	ned to
Speaking: Discussi	0	-	•		
					d interpreting specific
context clues; strate					- morprovide spoonie
Writing: Paragraph	-		L · ·		
Grammar and Voca	-	-			
	•	oject-Verb ag	greement		
	Dir	ect & Indirec	et speech		

Module - IV	Ponnuthayi – Bama	10 Hrs
Listening: Making pr	redictions while listening to conversations/ transactiona	l dialogues without
video; listening with	video.	
Speaking: Role plays	s for practice of conversational English in academic cor	ntexts (formal and
informal) - asking for	r and giving information/directions.	
	nd Interpret graphic Information to reveal tren	nds/patterns/relationships,
communicate process	ses or display complicated data.	
Writing: Letter Writi	ng: Official Letters/Report Writing	
Grammar and Vocab	ulary: Adjectives and Adverbs; Comparing and Contra	sting
	Voice - Active & Passive Voice.	
Module - V	My Beloved Charioteer- Shasi Deshpande	9 Hrs
Listening: Identifying	g key terms, understanding concepts and answering a se	ries of relevant
questions that test co		
•	al presentations on topics from academic contexts- with	nout the use of PPT
slides	1 1	
Reading: Reading for	or Comprehension	
	uctured essays on specific topics using suitable claims a	nd evidences.
0 0	oulary: Identifying and correcting common errors in gran	
	s, tenses, subject verb agreement)	
-	s course, student will be able to	
	nowledge of basic grammatical concepts.	
	e context, topic, and pieces of specific information fro	om social or transactiona
	ten by native speakers of English.	
	atical structures to formulate sentences and correct word	
-	urse markers to speak clearly on a specific topic in infor	
• Evaluate lister these texts.	ning /reading texts and to write summaries based on	global comprehension of
• Create and dev	velop coherent paragraph interpreting graphical description	ion.
Textbooks:		1 ~
1) Language and Lif	fe: English Skills for Engineering Students - Orient Blac	ek Swan
Reference Books:		
1. 1. Balley, Stej 2014.	phen. Academic Writing: A Handbook for International	I Students. Routledge,
•	Tarver. Pathways: Listening, Speaking and Critical Thi	nking. Heinley ELT;
2nd Edition, 2		D 1 1.
•	rphy's English Grammar in Use Fourth Edition (2012)	E-000K
	rtin. Cambridge Academic English (B2). CUP, 2012.	
	ers Dictionary, 12 th Edition, 2011 a Word Power Mada Eagy. The Complete Handback fo	r Duilding o
	s Word Power Made Easy- The Complete Handbook fo	r building a
Superior Voca Web links:	abulary (2014)	
www.englishclub.com		
www.easyworldofeng		
www.languageguide.o	org/english/	
www.bbc.co.uk/learni	ngenglish	
www.eslpod.com/inde	v html	

www.eslpod.com/index.html

C-PROGRAMMING & DATA STRUCTURES

Common to(ECE,EEE,ME,CE)

	C		/LCE,EEE,MIE,	CE)	
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0502T	3: 1:0:0	3	CIE: 30SEE:70	3Hours	ESC

Course Objectives:

This course will enable students to:

- Illustrate the basic concepts of C programming language.
- Choose a suitable C-construct to develop C code for a given problem.
- Illustrate the fundamental concept of data structures and Arrays.
- Emphasize the importance of data structures in developing and implementing efficient. algorithms.
- Illustrate a variety of data structures such as linked structures, stacks, queues, trees, and graphs.

	Syllabus	Total Hours:45
Unit - I	Introduction to C Language	9Hrs

Structure of C program, C Tokens, Data types, Operators, Precedence and Associativity of operators, Expressions and its evaluation, control structures – sequence, selection and Iteration statements, unconditional control structures – break, goto, continue. Arrays: Introduction to arrays, types of arrays, applications of arrays, Programming examples

|--|

String: Declaring and Initializing string, Printing and reading strings, string manipulation functions, String input and output functions, array of strings, Programming examples

Functions: Defining function, user defined functions, standard functions, passing array as argument to function, recursion

Pointers: declaring and initializing pointers, pointers and arrays, pointer to pointer, pointer arithmetic, dynamic memory allocation,

Structures and Unions

Unit - III	Data Structures	9Hrs
Introduction to Data	Structures: Definitions, Concept of Data Structures,	Overview of Data
Structures, Implementat	ion of Data Structures	
	n, Single Linked List, Circular Linked List, Double Li plications of Linked List	nked List, Circular
Unit - IV	Stacks & Queues	9Hrs
Stacks: Introduction, I	Definition, Representation of Stack, Operations on Stac	ks, Applications of
Stacks		
	Definition, Representation of Queues, Operations on Que	ues, Various Queue

Unit - V	Trees ,Graphs ,Searching and Sorting	9Hrs
	bgies, Definition and Concepts, Binary Tree, Represence, Binary Search Tree, Heap Tree	ntation of Binary Tree,
-	Graph Terminologies, Representation of graphs, Ope Techniques: BFS and DFS	rations on Graphs,
Searching and Sorting –	sequential search, binary search, exchange (bubble) sort,	, selection sort,
insertion sort.		
Course Outcomes(CO):		
On completion of this co	ourse, student will be able to	
 language(L2) Select the best set Develop C prog pointers, strings. Implement basic Use linked struct 	Explain the basic computer concepts and programming p election and loop construct for solving given problem(L grams to demonstrate the applications of derived data t .(L2) e operations on stack and queue using array representation tures, trees, and Graphs in writing programs(L2) ferent methods for traversing Graphs and Trees (L2)	.2) types such as arrays,
 Programming wit C Programming : Gilberg Classic Data Stru 	& Data Structures – Behrouz A. Fourazan, Richard F. Gi th C – Byron Gottfried, Third edition, Scham's Outlines A Problem Solving Approach- Behrouz A. Fourazan, I ctures, Second Edition, Debasissamanta, PHI Data Structures in C, 2 nd Edition, E. Horowitz, S.Sahni a es Press	E.V.Prasad, Richard F.
Reference Books:		
 C Programming a C Programming, Programming in C Data Structures: A Cengage Learning "Data Structures 	ntKanetkar, 6th Edition, BPB and Data Structures, P.Padmanabham, Third Edition, BS E.Balagurusamy, 3rd edition, TMHPublishers C, Ashok N. Kamthane, AmitKamthane, Pearson A Pseudo code Approach with C, 2 nd Edition, R.F.Gilber g. and Algorithm Analysis in C" by Weiss Through C" by Yashavant P Kanetkar	
E-resources:		
https://www.geeksforgee	ks.org/c-programming-language/	
http://en.cppreference.co	<u>m/w/c</u>	
https://onlinecourses.npte	<u>el.ac.in/noc19_cs42/</u>	
https://www.linuxtopia.o	rg/online_books/programming_books/gnu_c_programmi	ing_tutorial/index.html
https://codeforwin.org/		

		Engineering Drawing		
Course Co	de	L:T:P/D:C	0	Course Type
22A03027	r I	1: 0: 0/4 :3		ESC
Course Objectives:				
	ess that Engine	ering Drawing is the Language	e of Engineer	Ś.
Familiarize ho	w industry cor	nmunicates technical informat	ion.	
• Teach the prace	ctices for accur	acy and clarity in presenting th	ne technical i	nformation.
• Develop the e	ngineering ima	gination essential for successf	ul design.	
Syllabus		-		Total Hours:50
Unit - I	Introd	luction to Engineering Draw	ing	10 Hrs
ntroduction to Enginee	ering Drawing:	Principles of Engineering Dra	wing and its	significance-
Conventions in drawing			0	0
		ng Ellipse, Parabola, Hyperbo	la, and the R	ectangular hyperbola
using general metho		С г [,] , т.урчоо	, I .	6 JP OR
b) Draw the Cycloid	,	and Hypocycloid		
-	1 0	and hypotyclold large, pentagon, and hexagon		
c) Draw the myolat	es or encie, squ	auro, pontagon, and nonagon		
J nit - II	Projec	ctions of points, lines and pla	nes	10 Hrs
Projections of points, li	nes, and planes	s: Projection of points in any c	uadrant, line	s inclined to one and
	_	ing true inclinations, angle ma	-	
blane surfaces using rot	-	•		j
Unit - III		Projections of Solids		10 Hrs
Projections of solids: using auxiliary views n	·	regular solids inclined to one	and both the	e principle planes
T		Sections of solids		10 Hrs
Unit - IV				
	tion planes and	l sectional view of right regula		
Sections of solids: Sec	-	l sectional view of right regula		
Sections of solids: Sec and cone. True shapes	-	• •	r solids- pris	
Sections of solids: Sec and cone. True shapes of Jnit - V	of the sections.	Development of surfaces	r solids- pris	m, cylinder, pyramic 10 Hrs
Sections of solids: Sec and cone. True shapes Unit - V Development of surface	of the sections.		r solids- pris	m, cylinder, pyramic 10 Hrs
Sections of solids: Sec and cone. True shapes Unit - V Development of surface	of the sections.	Development of surfaces	r solids- pris	m, cylinder, pyramic 10 Hrs
Sections of solids: Sec and cone. True shapes of Unit - V Development of surfac cone and their sectional	of the sections.	Development of surfaces	r solids- pris	m, cylinder, pyramic
Sections of solids: Section of cone. True shapes of Jnit - V Development of surface cone and their sectional Course Outcomes (CC	of the sections.	Development of surfaces ent of surfaces of right regular	r solids- pris	m, cylinder, pyramic 10 Hrs
Sections of solids: Sec and cone. True shapes of Jnit - V Development of surfactional cone and their sectional Course Outcomes (CC Dn completion of this of	of the sections.	Development of surfaces ent of surfaces of right regular t will be able to	r solids- pris	m, cylinder, pyramic 10 Hrs
Sections of solids: Sec and cone. True shapes of Unit - V Development of surface cone and their sectional Course Outcomes (CC Dn completion of this • Draw various cu	of the sections. ces: Development l parts. D): course, studen urves applied ir	Development of surfaces ent of surfaces of right regular t will be able to n engineering. (12)	r solids- pris	m, cylinder, pyramic 10 Hrs
and cone. True shapes Unit - V Development of surface cone and their sectional Course Outcomes (CC On completion of this Draw various cu Show projection	of the sections. ces: Development l parts.)): course, studen urves applied in as of solids and	Development of surfaces ent of surfaces of right regular t will be able to	r solids- pris	m, cylinder, pyramic

Textbooks:

- 1. K.L.Narayana & P.Kannaiah, Engineering Drawing, 3/e, Scitech Publishers, Chennai, 2012.
- 2. N.D.Bhatt, Engineering Drawing, 53/e, Charotar Publishers, 2016.

Reference Books:

- 1. Dhanajay A Jolhe, Engineering Drawing, Tata McGraw-Hill, Copy Right, 2009
- 2. Venugopal, Engineering Drawing and Graphics, 3/e, New Age Publishers, 2000
- 3. Shah and Rana, Engineering Drawing, 2/e, Pearson Education, 2009
- 4. K.C.John, Engineering Graphics, 2/e, PHI, 2013
- 5. Basant Agarwal & C.M.Agarwal, Engineering Drawing, Tata McGraw-Hill, Copy Right, 2008.

			NICATIVE ENGI to all Branches of E		
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duratio	n Course Type
22A0014P	0:0:3:0	1.5	CIE:30 SEE:70	3H	HS
 Students Students public sp Students 	will be exposed will learn between will be trained will be trained beaking	ed to a variety ter pronunciat d to use langu	ion through sounds, age effectively to fa	l, learner friend stress, intonatio ce interviews, g	•
		ist of Experi	ments		Total Hours: 48
 Role Pla JAM Etiquette Group D Debates Oral Pre Interview 	ng objects/plac y or Conversa es of Telephon Discussions sentations vs Skills comprehensio Vriting me Writing	tional Practice			
 Understa Apply co Analyze and Spea Evaluate Create a Improve 	g and repeating and the differe ommunication the English sp aking Comprel and exhibit ac wareness on m e fluency in sp	g the sounds on nt aspects of t skills through beech sounds, nension. cceptable etiq nother tongue oken English.	of English Language he English language n various language le syllable division, st uette essential in soo influence and neutra	e proficiency wite earning activitie ress, rhythm, int cial and professi	onation for better Listening onal settings
Suggested Soft	ware: Walder	n InfoTech / Y	oung India Films		
 Chase, Becl 2018. Skillful Lev Hewings, N 	ohen. Academi ky Tarver. Path rel 2 Reading & Iartin. Cambrid	hways: Listen & Writing Stu dge Academic	nandbook for interna ing, Speaking and C dent's Book Pack (E c English (B2). CUF dian Students by T.	Critical Thinking 31) Macmillan E P, 2012.	. Heinley ELT; 2 nd Edition,
Online Learnin	0	Virtual Labs	:		
www.esl-lab.c www.englishn www.englishi	nedialab.com				

		Ар	plied Physics Lab		
		(Cor	nmon to ECE, EEE)		
Course (Code L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A000	8P 0:0:3:0	1.5	CIE:30 SEE:70	3Н	BS
		(Course Objectives:		
This cou	rse will enable stud	lents to:			
 Unde Reco semi Illus 	erstand the role of egnize the importation conductor. The magnetic the magnetic ended the	optical fiber par nce of energy and materials a	ce, diffraction and the rameters in communic gap in the study of c applications. s in various electronic	cation. conductivity and Ha	ll Effect in a
	J r r r		llabus		Total Hours 48
Note: In mode	the following list,	out of 12 experi	ments, any 2 experim	ents must be perform	ned in a virtual
			List of Experiment	s	
I. Dete	rmine the thickness	s of the wire us	ing wedge shape met	hod	
2. Dete	rmination of the ra	dius of curvatu	re of the lens by New	ton's ring method	
3. Dete	rmination of wave	length by plane	diffraction grating m	ethod	
I. Dete	rmination of disper	rsive power of p	orism.		
5. Dete	rmination of wavel	length of LASE	R light using diffract	ion grating.	
6. Dete	rmination of partic	le size using LA	ASER.		
7. To d	etermine the nume	rical aperture o	f a given optical fibe	r and hence to find	itsacceptance angle
3. Mag	netic field along th	e axis of a circu	alar coil carrying curr	ent –Stewart Gee's	method.
). Stud	y the variation of E	B versus H by m	nagnetizing the magne	etic material (B-H cu	irve)
10. To d	etermine the resist	ivity of semicor	nductor by Four probe	e method	
10. IO u		u con of a comi	conductor		
	etermine the energ	y gap of a semi	conductor		

Course Outcomes:

On completion of this course, the students are able to:

- Determine the radius of a curvature and / or thickness of thin wire using microscope with the help of interference concept (L2)
- Evaluate the wavelength of various colors of grating and also dispersive power of prism by spectrometer using the principle of diffraction (L2)
- Evaluate wavelength of light source and particle size with He-Ne laser using the principle of diffraction Estimate the numerical aperture of a given optical fiber and hence to find its acceptance angle (L2)
- Estimate the dielectric constant of a given material (L2)
- Examine the hysteresis loss of the magnetic material by B- H curve and Estimate the magnetic field of a circular coil carrying current along the axis (L2)
- Measure the type of conductivity ,hall voltage and hall coefficient of a given semiconductor using hall effect and also measure the energy band gap of a given semiconductor material (L2)

Text Books:

1. Engineering Practical Physics B Mallick S Panigrahi, 1st, Edition, Cengage Learning Publishers

2. A Text book of Engineering Physics Practical, Dr. Ruby Das, Dr. Rajesh Kumar, C. S. Robinson, Prashant Kumar Sah, UNIVERSITY SCIENCE PRESS (An Imprint of Laxmi Publications Pvt. Ltd.)

Reference Books:

1. S. Balasubramanian, M.N. Srinivasan "A Text book of Practical Physics"- S ChandPublishers, 2017

E-resources:

http://vlab.amrita.edu/index.php -Virtual Labs, Amrita University https://www.scribd.com/doc/81569075/Physics-Lab-Manual http://www.mlritm.ac.in/assets/img/Lab%20manual%20Physics.pdf https://bmsit.ac.in/public/assets/pdf/physics/studymaterial/Physics%20lab%20manual_cbcs%20%20-%20kavichintu.pdf

	C-1 KOC		& DATA STRUCTUE on to ECE, EEE)	XES LAD	
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0502P	0:0:3:0	1.5	CIE:30 SEE:70	3Hours	ESC
Use withDes	Il enable studer rk with an IDE of conditiona conditions an ign & develop	to create, edi l expressions d repetitions. of C program	t, compile, run and debu and looping statements s using arrays, strings, p	s to solve problem pointers & function	
• Intr	•	of data struct	such as stacks and queue ures such as hash linked g algorithms.		bhs.
		Syllabus		Tot	al Hours: 48
		L	ist of Experiments	1	
a) Write an . width (w=12cm			isplay the volume of a C	CUBE having its he	eight (h=10cm)
b) Write an	algorithm to c	alculate area a	and Circumference of a o	circle.	
c) Write an a	algorithm to ca	lculate simple	e interest for a given P, 7	Γ , and R (SI = P*T	*R/100)
2.a) Write a C J	program to find	l both the larg	est and smallest number	in a list of integer	·S.
b) Write a C p	rogram that us	es functions to	perform the following:		
i) Addition of	Two Matrices	ii) Multiplicat	ion of Two Matrices		
3 a) Write a C	program that u	uses functions	to perform the followin	g operations:	
i) To insert a s	ub-string in to	a given main	string from a given posi	tion.	
ii) To delete n	characters from	m a given posi	tion in a given string.		
4 a) Write a C	program to fi	nd sum and av	verage of three numbers.		
b) Write C pro	gram to evalua	ate each of the	following equations		
5a) Write a pro	ogram in C to j	print individua	l characters of string in	reverse order.	
b) Write a pro	gram in C to c	ompare two st	rings without using strin	ng library functions	5.
c) Write a C p	rogram to dete	ermine if the g	iven string is a palindron	me or not	
6.a) Write C	program to fin	d GCD of two	integers by using recur	sive function.	
b) Write C pro	ogram to find C	GCD of two in	tegers using non-recurs	ive function	
7 .Write C prog	grams that imp	lement stack (its operations) using		
i) Arrays ii) Po	ointers				
8. Write C pro	grams that imp	olement Queu	e (its operations) using		
i) Arrays ii) Po	inters				

9. Write a C program that uses Stack operations to perform the following:

i) Converting infix expression into postfix expression

ii) Evaluating the postfix expression

10. Write a C program that uses functions to perform the following operations on singly linked list.

i) Creation ii) Insertion iii) Deletion iv) Traversal

11. Write a C program that uses functions to perform the following operations on Doubly linkedlist.

i) Creation ii) Insertion iii) Deletion iv) Traversal

12. Write a C program that uses functions to perform the following operations on circular linkedlist.

i) Creation ii) Insertion iii) Deletion iv) Traversal

13 .Write a C program that uses functions to perform the following:

i) Creating a Binary Tree of integers

ii) Traversing the above binary tree in preorder, inorder and postorder.

14. Write C programs that use both recursive and non-recursive functions to perform the following

searching operations for a key value in a given list of integers:

i) Linear search ii) Binary search

15 .Write a C program that implements the following sorting methods to sort a given list of integers in

ascending order i) Bubble sort ii) Selection sort iii) Insertion sort

Course Outcomes:

On completion of this course, the students are able to:

- Use conditional and iterative statements for writing the C programs(L2)
- Make use of different data-structures like arrays, strings, structures for solving problems.(L2)
- Use basic data structures such as arrays, Stacks and Queues
- Programs to demonstrate fundamental algorithmic problems including Tree Traversals, Graph traversals
- Use various searching and sorting algorithms.
- Use linked structures, trees, and Graphs in writing programs

Text Books:

- 1. Byron Gottfried, Schaum's Outline of Programming with C, McGraw-Hill
- 2. B.A. Forouzan and R.F. Gilberg C Programming and Data Structures, Cengage Learning, (3rd Edition)
- 3. Classic Data Structures, Second Edition, Debasissamanta, PHI

Fundamentals of Data Structures in C, 2nd Edition, E. Horowitz, S.Sahni and Susan Anderson Freed, Universities Press

Reference Books:

- 1. C Programming and Data Structures, P.Padmanabham, Third Edition, BS Publications
- 2. C Programming, E.Balagurusamy, 3rd edition, TMHPublishers
- 3. .Programming in C, Ashok N. Kamthane, AmitKamthane, Pearson
- 4. Data Structures: A Pseudo code Approach with C, 2nd Edition, R.F.Gilberg and B. A. Forouzan, Cengage Learning.
- 5. "Data Structures and Algorithm Analysis in C" by Weiss
- "Data Structure Through C" by Yashavant P Kanetkar
 "Problem Solving in Data Structures and Algorithms Using C: The Ultimate Guide to Programming Interviews" by Hemant Jain



B.TECH Electronics & Communication Engineering Course Structure (RG22)

			Semester - 2 (Theory-4, Lab-	5)			
Sl. No.	Category	Course Code	Course Title	Hours	s per w	eek	Credits
				L	Т	Р	С
1	BSC	22A0002T	Differential Equations and Vector Calculus	3	0	0	3
2	BSC	22A0006T	Chemistry	3	0	0	3
3	ESC	22A0201T	Fundamentals of Electrical Circuits	3	0	0	3
4	ESC	22A0401T	Electronic Devices & Circuits	3	0	0	3
5	BSC (Lab)	22A0011P	Chemistry Lab	0	0	3	1.5
6	ESC (Lab)	22A0202P	Fundamentals of Electrical Circuits Lab	0	0	3	1.5
7	ESC (Lab)	22A0402P	Electronic Devices & Circuits Lab	0	0	3	1.5
8	ESC (Lab)	22A0403P	Electronics Workshop	0	0	3	1.5
9	ESC (Lab)	22A0502P	IT Workshop	0	0	3	1.5
			Tot	tal cred	its		19.5

Category	Credits
Basic Science Course (BSC)	7.5
Engineering Science Course (ESC)	12
Total	19.5

		Differentia	ll Equations & Ve Calculus	ctor		
Course Code	L:T:P:S	Credit s	Exam marks	Exam Dura	tion	Course Type
22A0002T	3:0:0:0	3	CIE:30 SEE:70	3 Hours	s	BS
Course Object	ives:	I	1			
To enlighten the	learners in th	e concept o	f differential equation	ions and mult	ivaria	ble calculus,
to furnishthe lea	rners with ba	sic concepts	and techniques at	t plus two lev	vel to	lead them into
advanced level l	oy handling v	arious real w	orld applications.	-		
Syllabus						al Hours:45
Module - I	Line		ial Equations of T r(Constant Coeff		9 Hı	rs
Definitions, hon	ogenous and	non-homoge	enous, compliment	ary function,	gener	al solution,
particular integr	al, Wronskea	an, method	of variation of par	rameters. Sim	nultan	eous linear
equations, Appli	cations to L-0	C-R Circuit p	problems and Mass	spring system	n.	
Module - II		Partial I	Differential Equat	tions	9 Hi	rs
Introduction and	formation of	f Partial Dif	ferential Equations	by elimination	on of	arbitrary
constants and ar	bitrary functi	ons, solution	ns of first order e	quations using	g Lag	grange's
method. Non lir	earequations	of first order	r – Type I, II, III, I	V.		_
Module - III	Applica	tions of Par	tial Differential H	Equations	9 Hı	rs
Classification o	f PDE, metl	hod of sepa	ration of variable	es for second	order	r equations.
Applications of	Partial Differ	rential Equat	ions: One dimensi	ional Wave ed	quatio	on (Without
Derivation), Sol	utions one D	Dimensional	Wave equation by	the method	of se	paration of
variables and rel	ated Problem	s.				-
Module - IV		Vector Di	fferentiation		9 Hi	rs
Scalar and vector	or point func	tions, vector	operator del, del	applies to sc	alar j	point
	ent, del applie	d to vector p	oint functions-Div	ergence and C	Curl, v	vector
identities.		.				
Module - V		Vector In	8		9 Hi	
-			ace integral-flux,			-
· · · · · ·			ut proof), volume	integral, Div	ergen	ce theorem
(without proof) a	11	ons of these t	heorems.			
Course Outcom	· /	-4	1 h h l . 4 .			
On completion		·		a affi ai anta hay		unioto mothed
		-	ons with constant constant constant constant	-		-
	-	-	d solutions of stand	uard partial di	neren	itial equations.
•			ions of PDEs	turata tha mhave		intermentation of
	, Divergence		oint functions, illus	strate the phys	sical I	interpretation of
	0		gence theorem in	avaluation of	douk	ala and tripla
integrals			gence meorem m	evaluation of	uout	ble and triple
Textbooks:						
1. B.S. Grewal.	Higher Engi	neering Math	nematics, 44/e, Kha	anna publishe	rs. 20	17.
	0	e	is by T.K.V. Iyeng			
	-		Chand publication.	ar, D.H.Ibillia	Ound	,
Reference Boo		1.1 1asau D. V				
	n.s.					
1 Erwin Krover		Engineering	Mathematics 10/	A John Wilow	1 87 5	ons 2011
	ig, Advanced	0	g Mathematics, 10/	•		ons, 2011.
2. B.V.Ramana,	ig, Advanced "Higher Engi	neering Mat	hematics", Mc Gra	w Hill publish	ers.	
2. B.V.Ramana,	ig, Advanced "Higher Engi Iathmatic I &	neering Mat		w Hill publish	ers.	

С	HEMISTI	KY (Comm	on to CSE, AI&MIL	,CS,ECE,EEE,DS)
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0006T	3: 0:0:0	3	CIE: 30 SEE:70	3Hours	BS
Course Objective	s. Student	t will he ah	le to		
			istry and its applica	tions	
\succ To train the	ne students	on the pri	nciples and application	tions of electrocher	nistry and
polymers		-			•
To introdu	ce instrum	ental metho			
			Syllabus		Total Hours:
					48 Hrs
Module- I		St	tructure and Bondi	ing	9Hrs
D1			- free att an Calena din ar		: Cincorne AT(
	2		ofmatter,Schrodinge	1 2	
			onding in homo- an		
			f O ₂ and CO, etc. π	-molecular orbitals	of butadiene
and benzene, ca	alculation (
Module-II		Mode	ern Engineering ma	iterials	10Hrs
0 11 11	L		C 11.1		
Coordination	compound	s. Crystal	tiold theory cold	ient teatures _ snl	itting of d-
	-	•	-	ient leatures spi	itting of u
orbitals in octa	-	•	-	ient reatures spr	itting of u
	ahedral and	d tetrahedra	algeometry.	-	-
Basic concept,	ahedral and band diag	d tetrahedra rams for co	-	-	-
Basic concept, doping on band	ahedral and band diag lstructures.	d tetrahedra rams for co	algeometry. onductors, semicond	luctors and insulato	-
Basic concept, doping on banc Supercapacitor	ahedral and band diag lstructures. s: Introduc	l tetrahedra rams for co tion, Basic	algeometry. onductors, semicond concept-Classificati	luctors and insulato	rs, Effect of
Basic concept, doping on band Supercapacitor Nano chemist	ahedral and band diag lstructures. s: Introduc try: Introd	l tetrahedra rams for co tion, Basic duction, c	algeometry. onductors, semicond concept-Classification of r	luctors and insulato	rs, Effect of
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Basic concept, doping on band Supercapacitor Nano chemist applications off Module-III Electrodes – co glass electrode);Elec blems, potention titrations (acid- Primary cells: working of the -oxygen fuel ce Module-IV Introduction to condensation polymerization Plastics - Therr – PTFE, Bakel number average Elastomers–Bu Conducting po applications.	ahedral and band diag lstructures. s: Introduc try: Intro- Fullerenes, oncepts, ref trochemica ontery- pot base titrati Zinc-air b batteries in ells – work polymers, and copol moplastics lite, Calcul e method, I ma-S, Buna olymers:	d tetrahedra rams for co tion, Basic duction, c andcarbon Electroo ference elect alcell,Nerns entiometric ons). attery, Sec ncluding ce ing principl functionality ymerizatio and Therma ation of me Polydispers a-N-prepara polyacetyle polylactic a	algeometry. onductors, semicond concept-Classification classification of re- nanotubes. chemistry and App ctrodes (Calomel elec- stequation, cellpotent c titrations (redox tit condary cells: lead ll reactions, Fuel ce le of the cells. Polymer Chemistry ity of monomers, Ty n with specific e osetting, Preparation olecular weight of p sity Index. ation, properties and	luctors and insulato ion – Applications. aanomaterials, pro blications ectrode, Ag/AgCl e cialcalculationsandn rations), conducton acid and lithium-ic lls: hydrogen-oxyge y /pes of polymerizati xamples and mec n, properties and appolymer by weight l applications. mechanism of con e, starch, cellulose.	ers, Effect of perties and 10Hrs lectrode and umericalpronetric on batteries- en, methanol 10Hrs ion-addition, chanisms of plications of average and

EMR spectra, Beer-Lambert's law, Basic Principle, Instrumentation and applications of UVvisible spectrophotometer and FTIR, Chromatography-Introduction, Principle and instrumentation of Gas Chromatography (GC), retention time, TLC, R_f factor.

Course Outcomes (CO): After completion of the course, students will be able to

- Describe Planck's quantum theory, dual nature of matter, Schrodinger equation, molecular orbital Theory and molecular orbital energy level diagram of different molecules
- Explain Crystal field theory, splitting in octahedral and tetrahedral geometry and the magnetic behaviour, Oxidation state, coordination and colour of complexes.
- Explain the principle of Band diagrams of conductors, superconductor, semiconductors and insulator and nonmaterial
- Discuss the principles of electrochemistry in potentiometry, conductometry, battery and electrochemical sensors
- Explain polymerization and the preparation, properties, and applications of thermoplastics & thermosetting, elastomers, & conducting polymers
- > Discuss the different applications of analytical instruments

Textbooks:

1. P. C. Jain & Monika Jain, Engineering Chemistry, Dhanpat Rai Publishing Company

(P) Ltd, New Delhi, 16th edition, 2013.

- 2. K. N. Jayaveera, G. V. Subba Reddy and C. Ramachandriah, Engineering Chemistry, Mc.Graw Hill Publishers, New Delhi.
- 3. Energy scenario beyond2100,by S.Muthu Krishna Iyer.

ReferenceBooks:

- J. D. Lee, Concise Inorganic Chemistry, Oxford University Press, 5th edition 2010.
- 2. Skoog and West, Principles of Instrumental Analysis, Thomson, 6th edition, 2007.
- 3. Peter Atkins, Julio de Paula and James Keelar, Atkins' Physical Chemistry, Oxford University Press, 10th edition, 2010.

	FUNE		TALS OF ELECTI		ITS
Course Code	L:T:P:S		(common to EEE& itsExam Marks	ECE) Exam Duratio	on Course Type
Course Coue	3: 0:0:0	3	CIE: 30 SEE:70	3Hours	BS
Course Objecti		-		SHOUIS	D 0
Various of 2. Basics of 3. Network 4. The Sing	combinations f Magnetic cir Topology and	of these cuits d concep circuits a	ots like Tree, Cut-set and concepts of real	, Tie-set, Loop,	
5. Network	theorems and	l their ap	oplications		
Unit - I	I	ntroduc	tion to Electrical Ci	rcuits	10 Hrs
Electrical Circu	iits: Circuit C	Concept -	- Types of elements	- Source Transf	ormation-Voltage – Curr
Relationship for	r Passive Ele	ements.	Kirchhoff's Laws -	- Network Red	uction Techniques- Seri
Parallel, Series	Parallel, St	ar-to-De	lta or Delta-to-Star	Transformatio	n, Nodal Analysis, Me
Analysis, Exam	oles.				
Learning Outcon					
At the end of thi		dent wil	l be able		
	,			llel. non-series-1	parallel configurations in
DC networks		2000		,	
	it voltage sou	rce to cu	irrent source and vice	-versa transform	nation in their
representation	it voltage sou		intent source and view		
1	l analyzaia of N	Jodalan	d Mach analysis for	different circuits	
Unit - II	-		d Mesh analysis for		. 8 Hrs
			tion to Magnetic Ci		
-	•		Electromagnetic Ind	-	
			in of Coupling-Com	posite Magnetic	Circuit-Analysis of Serie
and Parallel Mag		5.			
Learning Outcom		1 / 11			
At the end of thi	<i>,</i>		i be able to		
1.To understand	•				
-	•••		tric and magnetic cir		
3. To understand	l analysis of s	eries and	d parallel magnetic c	ircuits.	
					0.11
Unit - III			Graph theory		9 Hrs
Definitions – Gr	aph – Tree B	asic Cut	set and Basic Tieset	Matrices for Pla	nar Networks – Loop and
	-				ent Sources, Network
equilibrium equa	•		-	C	
Learning Outcon	mes:				
At the end of thi					
		-		required for solv	ving electrical circuits
2.To understand	-				
3. To understand				ulso	
			ality and dual netwo		on the topology
Unit - IV			gy in solving electric le Phase A.C Circui		11 Hrs
$\frac{\text{Omt} - 1}{\text{D} \text{MS}}$					

R.M.S, Average Values and Form Factor for Different Periodic Wave Forms – Sinusoidal Alternating Quantities – Phase and Phase Difference – Complex and Polar Forms of Representations, Steady State Analysis of R, L and C (In Series, Parallel and Series Parallel Combinations) with Sinusoidal

Excitation - Phasor diagrams - Concept of Power Factor- Concept of Reactance, Impedance, Susceptance and Admittance-Apparent Power, Active and Reactive Power, Examples. Resonance.

Learning Outcomes:

At the end of this unit, the student will be able

1. To understand fundamental definitions of $1-\phi$ AC circuits

2. To distinguish between scalar, vector and phasor quantities

3. To understand voltage, current and power relationships in 1- ϕ AC circuits with basic elements R, L, and C.

4. To understand the basic definitions of complex immittances and complex power

5. To solve $1-\phi$ AC circuits with series and parallel combinations of electrical circuit elements R, L and C.

10 Hrs

Unit - V Network Theorems

Superposition, Reciprocity, Thevenin's, Norton's, Maximum Power Transfer, Millmann's, Tellegen's, and Compensation Theorems for D.C and Sinusoidal Excitations.

Learning Outcomes:

At the end of this unit, the student will be able

1. To know that electrical circuits are 'heart' of electrical engineering subjects and network theorems are main part of it.

2. To distinguish between various theorems and inter-relationship between various theorems

3. To know about applications of certain theorems to DC circuit analysis

4. To know about applications of certain theorems to AC network analysis

5. To know about applications of certain theorems to both DC and AC network analysis

Course Outcomes (CO): After completion of the course, students will be able to

- Explain types of networks and Network Reduction Techniques
- > Analyze Magnetic Circuits and Coupled circuits.
- > Analysis of electrical networks using graph theory and duality and dual networks
- > Analyze RLC circuits with AC Excitation
- > Analyze the power, voltage and current for different network configurations.
- > Apply theorems for finding the solutions of network problems

Textbooks:

1. Fundamentals of Electric Circuits Charles K. Alexander and Matthew. N. O. Sadiku, Mc Graw Hill, 5th Edition, 2013.

2. Engineering circuit analysis William Hayt and Jack E. Kemmerly, Mc Graw Hill Company, 7th Edition, 2006.

3. Circuit Theory Analysis & Synthesis A. Chakrabarti, Dhanpat Rai & Sons, 7th Revised Edition, 2018.

Reference Books:

1. Network Analysis M.E Van Valkenberg, Prentice Hall (India), 3rd Edition, 1999.

2. Electrical Engineering Fundamentals V. Del Toro, Prentice Hall International, 2nd Edition, 2019.

3. Electric Circuits- Schaum's Series, Mc Graw Hill, 5th Edition, 2010.

4. Electrical Circuit Theory and Technology John Bird, Routledge, Taylor & Francis, 5th Edition, 2014.

Electronic Devices and Circuits							
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type		
22A0401T	3:0:0	3	CIE:30 SEE:70	3 Hours	РС		
 To be able To analy amplifier To be able 	stand the basic e to solve prob ze diode circu s. e to compare t	blems relate he performation	of all semiconductor d to diode circuits, a biasing and small ance of BJTs and M ous amplifier circuit	nd amplifier circuits signal equivalent ci OSFETs.	rcuits of		
			Syllabus Unit –I				
Terminal Charac Applications: R Capacitor, L-sec regulator, Diode	eteristics of Junectifiers – Halletion and π -Fias switch, Clip Special Diode	nction Diod If wave, Fu Iters, Zene oping and C Types– U.	current voltage chara les– forward bias, re ll wave rectifier and r Diodes– Zener di Clamping Circuits– li JT, Schottky barrier	everse bias, and brea Bridge rectifier. Fi ode Characteristics, miter circuit, the cla	kdown regions lters - Inductor Voltage shun mped capacitor		
ingite entiteting at	de(LLD), 110		Unit –II				
dependence of Configurations -	collector curre Common-Em	ent on colleitter (CE) a	s - graphical represe ector voltage, the l implifier without and CC) amplifier or Em Unit –III	Early Effect, Basic l with emitter resista	BJT Amplifie ance, Common		
MOS Field-Eff	ect Transisto	ors (MOS	FETs): Introduction	Device Structure	and Physica		
Operation – devi operation for characteristics– saturation, chara MOSFET in An	ce structure, o different drai i _D - v _{DS} char acteristics of the plifier Design	peration wi n to sour cacteristics, he p-Chann n – voltage	th zero gate voltage, rce voltages, the $i_D - v_{GS}$ character nel MOSFET, MOS transfer characterist ge gain, graphical an	creating a channel f P-channel MOSFE ristics, finite output FET Circuits at DC ics, biasing the MO	or current flow T,CMOS, V- t resistance i C, Applying th SFET to obtain		
	- 9 MOSEE		Unit –IV		C ircle 1 1 1 1 1 1 1 1 1 1		
bias, voltage div	vider bias circu	uits, Bias c	g of BJT's – load li ompensation, Therm bias, Self bias, Vol	al runaway, conditi	on for Therma		
U			Unit –V				
signal analysis, circuit model, characterizing an	Small signal o Basic MOS nplifiers, comi	equivalent FET Amp mon source	dels – the dc bias, s circuit models, the plifier Configuratio (CS) amplifier witho wer, the amplifier fre	transconductance, th ons– three basic out and with source i	ne T equivalen configurations resistance,		
			30		-		

Text Books:

- Adel S. Sedra and Kenneth C. Smith, "Microelectronic Circuits Theory and Applications", 6th Edition, Oxford Press, 2013.
- Donald A Neamen, "Electronic Circuits analysis and design", 3rd Edition, McGraw Hill (India), 2019.

References:

- 1. J. Milliman and C Halkias, "Integrated electronics", 2nd Edition, Tata McGraw Hill, 1991.
- 2. R.L. Boylestad and Louis Nashelsky, "Electronic Devices and Circuits," 9th Edition, Pearson, 2006.

Course Outcomes:

After the completion of the course students will able to

- 1. Understand principle of operation, characteristics and applications of Semiconductor diodes.
- 2. Design the diode applications such as rectifiers, clippers and clampers.
- 3. Understand principle of operation, characteristics and applications of Bipolar Junction Transistor and MOSFETs.
- 4. Design amplifiers using BJTs, and MOSFETs.
- 5. Solve the problems related to Semiconductor diodes, BJTs, and MOSFETs.
- 6. Analyze performance of diode applications, biasing circuits of BJTs, MOSFETs and their applications.

		Chen	nistry Lab		
	(Commo	on to CSE,A	I&ML,CS,ECE,EI	EE,DS)	
Course Cod	le L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0011	P 0:0:1.5:0	1.5	CIE:30 SEE:70	3Н	BS
This course v	will enable students		ourse Objectives:	1	
onexp	0	ples discusse	stoenablethelearners d in theory sessions	U U	the applications o
		Syllabus	5		Total Hours: 48
		Lis	t of Experiments		
 Deter Poten Poten pH m Deter Prepa Verif Prepa Separ Ident: Estim 	tiometry - determin netric titration of strengt ration of a polymer ication of Lambert- ration of Nanomate ration of organic mi ification of simple on nation of Ferrous Iro rmination of Coppen	nstant and co ation of redo rong acid vs. h of an acid i Beer's law erials xtures by Thio rganic comp on by Dichron by EDTA m	nductance of solution ox potentials and em strong base in Pb-Acid battery in Layer chromatog ounds by IR. metry.	fs raphy	
Course Outco	mes:				
> Deter	ion of this course, the rmine the cell construction of the cell construction of the co		re able to: ductance of solutio	ons and the strengtl	n of an acid by
> Synth	nesize of advanced p	olymer mate	erials		
	ure the strength of netric analysis	an acid prese	ent in secondary bat	tery and Ferrous io	on using
> Deter	mine the potentials	and EMFs of	f solutions byPotent	iometry	
> Ident	ify some organic an	d inorganic c	compounds by instru	imental methods	
> Synth	nesize of nanomater	ials by simple	e methods		
Text Book(s):				
2. 3.	Jain & Jain. Engin S.S.Dara, Experir Publications, Rev	neering Chen nents and Ca	nalysis, Arthur J. Vo nistry: Dhanapathra lculations in Engine 2008.	i Publications., 201	
Reference B	ook(s):				
	Rai Publishing Co	ompany, Nev Experiments	'Laboratory Manual v Delhi, 2 nd edition. in Applied Chemist		
			32		

Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0011P	0:0:3:0	1.5	CIE:30 SEE:70	ЗН	ESC
Course Obj	ectives:	I		1	
This course v	will enable stu	udents to:			
1. Remember	r, understand	and apply va	rious theorems a	nd verify practica	ally.
				• -	phase balanced & un
balanced cir	•		Ĩ		1
		Sy	yllabus		Total Hours: 48
			List of Experi	ments	
1. Verificatio	on of Kirchho	ff's current la	aw and voltage la		re
			hard ware and dig	U	
	on of nodal an	• •			
		ge value, rms	value, form fact	or, peak factor of	f sinusoidal wave, square
wave using h			: 4 -		
•	eries and Para				
			on's Theorems		
	on of Superpo				
	Power Trans	ter Theorem	for DC and AC	circuits	
			for DC and AC or for DC circles		
 10. Verificat 11. Verificat 	ion of Compe ion of Recipro	ensation Theo ocity, Millma	orem for DC circu ann's Theorems f	uits for DC circuits	
 10. Verificat 11. Verificat 	ion of Compe ion of Recipro	ensation Theo ocity, Millma	orem for DC circu	uits for DC circuits	ing
 10. Verificat 11. Verificat 	ion of Compe ion of Recipro	ensation Theo ocity, Millma Mutual Indu	orem for DC circu ann's Theorems f actances and Coe	uits for DC circuits fficient of Coupli	-
 Verificat Verificat Determin 	ion of Compe ion of Recipro ation of Self,	ensation Theo ocity, Millma Mutual Indu	orem for DC circu ann's Theorems f	uits for DC circuits fficient of Coupli	-
 Verificat Verificat Determin 	ion of Compe ion of Recipro ation of Self, mes:	ensation Theo ocity, Millma Mutual Indu (Any 10 e	orem for DC circu ann's Theorems f actances and Coe	uits for DC circuits fficient of Coupli	-
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 Verificat Verificat Verificat Determin Determin Course Outco On complet Analy Analy Analy Analy Apply Ext Book(s Fundament Hill, 5th Edit Engineerin Edition, 2000 Circuit Th 2018 	ion of Compe- ion of Recipro- nation of Self, mes: ion of this con- yze network p yze RLC circu yze Resonanc y theorems for y Maximum yze coupled c): itals of Electri- tion, 2013. ng circuit anal 5. eory Analysis	ensation Theo ocity, Millma Mutual Indu (Any 10 e urse, the stud parameters an uits and coup e for differen r finding the power transfe ircuits.	erem for DC circu ann's Theorems for actances and Coerce experiments from lents are able to: nd types of network oled circuits. nt circuits. solutions of network er theorems for for harles K. Alexand a Hayt and Jack E	uits For DC circuits fficient of Coupli n the above list) Forks Forks work problems inding the solution der and Matthew E. Kemmerly, Mc	ons of DC & AC Networks . N. O. Sadiku, Mc Graw : Graw Hill Company, 7th
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ELECTRONIC DEVICES AND CIRCUITS LAB

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0402P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PC

Course Objectives:

- To verify the theoretical concepts practically from all the experiments.
- To analyse the characteristics of Diodes, BJT, MOSFET.
- To design the amplifier circuits from the given specifications.
- To Model the electronic circuits using tools such as PSPICE/Multisim.

Syllabus

LIST OF EXPERIMENTS: (Conduct all experiments).

Note: All the experiments shall be implemented using both Hardware and Software.

- 1. Design a half wave rectifier with and without filters for the given specifications, and verify the results experimentally for different load conditions, also Calculate ripple factor with relevant graphs.
- 2. Design a full wave rectifier with and without filters for the given specifications, and verify the results experimentally for different load conditions, also Calculate ripple factor with relevant graphs
- 3. Verify the operation of various clipping and clamper circuits using PN junction diode experimentally.
- 4. Design a voltage regulator using Zener diode and verify load regulation characteristics.
- 5. Analyze the input and output characteristics of BJT in Common Emitter configuration experimentally.
- 6. Analyze the input and output characteristics of BJT in Common Base configuration experimentally.
- 7. Design voltage- divider bias/self-bias circuit using BJT and verify experimentally.
- 8. Design a small signal amplifier using BJT (common emitter) for the given specifications also calculate Bandwidth.
- 9. Analyze the output and transfer characteristics of MOSFET in Common Source Configuration experimentally.
- 10. Design self-bias circuit using MOSFET and verify experimentally.
- 11. Verify the operation of a switch using CMOSFET/JFET/BJT experimentally.
- 12. Design a small signal amplifier using MOSFET (common source) for the given specifications also calculate Bandwidth.

Tools / Equipment Required: Software Tool like Multisim/ Pspice or Equivalent,

DC Power supplies, Multi meters, DC Ammeters, DC Voltmeters, AC Voltmeters, CROs, all the required active devices.

Course Outcomes:

After the completion of the course students will able to

- 1. Understand the operation and characteristics of basic electronic devices.
- **2.** Design the Diode applications like Rectifiers, Clippers and Clampers for the given specifications.
- 3. Analyze the Characteristics of Diodes, BJTs, MOSFETs.
- 4. Design BJT based amplifiers for the given specifications.
- 5. Design MOSFET based amplifiers for the given specifications
- 6. Simulate Diode, BJT and MOSFET applications in PSPICE /Multisim.

ELECTRONICS WORKSHOP

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0403P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PC

Course Objectives:

- To introduce electronic components, measuring instruments and tools used in electronic workshop.
- To equip with the knowledge of understanding data sheets of electronic components.
- To give practical experience on soldering the electronic components on a PCB.
- To introduce EDA tools.
- To know about the internal parts of a computer, assembling a computer from the parts, preparing a computer for use by installing the operating system
- To provide training on Productivity tools like word processors, spreadsheets, presentations.

Syllabus

List of Exercises / Experiments:

1. Familiarization of commonly used Electronic Workshop Tools: Bread board, Solder, cables, relays, switches, connectors, fuses, Cutter, plier, screwdriver set, wire stripper, flux, knife/blade, soldering iron, de-soldering pump etc.

• Provide some exercises so that electronics hardware tools and instruments are learned to be used by the students

2. Familiarization of Electronic Measuring Instruments like Voltmeters, Ammeters, multimeter, LCR-Q meter, Power Supplies, CRO, DSO, Function Generator, Frequency counter.

• Provide some exercises so that electronic measuring instruments are learned to be used by the students

3. Electronic Components: Familiarization/Identification of electronic components (Resistors, Capacitors, Inductors, Diodes, transistors, IC's etc.) – Functionality, type, size, color coding, package, symbol, cost etc.

4. Testing of electronic components like Resistor, Capacitor, Diode, Transistor, ICs etc.

• Compare values of components like resistors, inductors, capacitors etc with the measured values by using electronic instruments

5. Study of Cathode Ray Oscilloscope (CRO)

- Find the Amplitude and Frequency of a signal
- Measure the Unknown Frequency & Phase difference of signals using Lissajous figures 6. Interpret data sheets of discrete components and IC's.
 - Write important specifications/ratings of components & ICs and submit it in the form of a report

7. Introduction to EDA Tools: MULTISIM/PSPICE/TINA schematic capture tool, learning of basic functions of creating a new project, getting and placing parts, connecting placed parts, simulating the schematic, plotting and analyzing the results.

Provide some exercise so that students are familiarized in using EDA tools

8. Assembling and Testing of simple electronic circuits on breadboards; identifying the components and its location on the PCB, soldering of the components, testing the assembled circuit for correct functionality.

Course Outcomes:

- Identify discrete components and ICs.
- Assemble simple electronic circuits over a PCB.
- Test various components.
- Interpret specifications (ratings) of the component.

IT WORKSHOP							
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type		
22A0502P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	ESC		
Course Objecti	ves•		*	·			

Course Objectives:

- To make the students know about the internal parts of a computer, assembling and dissembling a computer from the parts, preparing a computer for use by installing the operating system
- To provide Technical training to the students on Productivity tools like Word processors Spreadsheets, Presentations and LAteX
- To learn about Networking of computers and use Internet facility for Browsing and Searching

Syllabus

Task 1: Learn about Computer: Identify the internal parts of a computer, and its peripherals. Represent the same in the form of diagrams including Block diagram of a computer. Write specifications for each part of a computer including peripherals and specification of Desktop computer. Submit it in the form of a report.

Task 2: Assembling a Computer: Disassemble and assemble the PC back to working condition. Students should be able to trouble shoot the computer and identify working and non-working parts. Student should identify the problem correctly by various methods

Task 3: Install Operating system: Student should install Linux on the computer. Student may install another operating system (including proprietary software) and make the system dual boot or multi boot. Students should record the entire installation process.

Task 4: Operating system features: Students should record the various features that are supported by the operating system(s) installed. They have to submit a report on it. Students should be able to access CD/DVD drives, write CD/DVDs, access pen drives, print files, etc. Students should install new application software and record the installation process. Networking and Internet

Task 5: Networking: Students should connect two computers directly using a cable or wireless connectivity and share information. Students should connect two or more computers using switch/hub and share information. Crimpling activity, logical configuration etc. should be done by the student. The entire process has to be documented.

Task 6: Browsing Internet: Student should access the Internet for Browsing. Students should search the Internet for required information. Students should be able to create e-mail account and send email. They should get acquaintance with applications like Facebook, skype etc. If Intranet mailing facility is available in the organization, then students should share the information using

it. If the operating system supports sending messages to multiple users (LINUX supports it) in the same network, then it should be done by the student. Students are expected to submit the information about different browsers available, their features, and search process using different natural languages, and creating email account.

Task 7: Antivirus: Students should download freely available Antivirus software, install it and use it to check for threats to the computer being used. Students should submit information about the features of the antivirus used, installation process, about virus definitions, virus engine etc. Productivity tools

Task 8: Word Processor: Students should be able to create documents using the word processor tool. Some of the tasks that are to be performed are inserting and deleting the characters, words and lines, Alignment of the lines, Inserting header and Footer, changing the font, changing the colour, including images and tables in the word file, making page setup, copy and paste block of text, images, tables, linking the images which are present in other directory, formatting paragraphs, spell checking, etc. Students should be able to prepare project cover pages, content sheet and chapter pages at the end of the task using the features studied. Students should submit a user manual of the word processor considered, Image Manipulation tools.

Task 9: Presentations: creating, opening, saving and running the presentations, selecting the style for slides, formatting the slides with different fonts, colours, creating charts and tables, inserting and deleting text, graphics and animations, bulleting and numbering, hyperlinking, running the slide show, setting the timing for slide show.

Task 10: Spreadsheet: Students should be able to create, open, save the application documents and format them as per the requirement. Some of the tasks that may be practiced are Managing the worksheet environment, creating cell data, inserting and deleting cell data, format cells, adjust the cell size, applying formulas and functions, preparing charts, sorting cells. Students should submit a user manual of the Spreadsheet

Task 11: LateX: Introduction to Latex and its installation and different IDEs. Creating first document using Latex, using content into sections using article and book class of LaTeX. Styling Pages: reviewing and customizing different paper sizes and formats. Formatting text (styles, size, alignment, colors and adding bullets and numbered items, inserting mathematical symbols, and images, etc.). Creating basic tables, adding simple and dashed borders, merging rows and columns. Referencing and Indexing: cross-referencing (refer to sections, table, images), bibliography (references).

References:

1. Introduction to Computers, Peter Norton, McGraw Hill

2. MOS study guide for word, Excel, Powerpoint& Outlook Exams, Joan Lambert, Joyce Cox, PHI.

Introduction to Information Technology, ITL Education Solutions limited, Pearson Education.
 Networking your computers and devices, Rusen, PHI

5. Trouble shooting, Maintaining & Repairing PCs, Bigelows, TMH

6. Lamport L. LATEX: a document preparation system: user's guide and reference manual. Addison-wesley; 1994.

References:

1. Introduction to Computers, Peter Norton, McGraw Hill

2. MOS study guide for word, Excel, Powerpoint & Outlook Exams, Joan Lambert, Joyce Cox, PHI.

Introduction to Information Technology, ITL Education Solutions limited, Pearson Education.
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5. Trouble shooting, Maintaining & Repairing PCs, Bigelows, TMH

6. Lamport L. LATEX: a document preparation system: user's guide and reference manual. Addison-wesley; 1994.

		ectrical and		0 0				
(Common for all branches excluding EEE & ECE) Course Code L:T:P Credits Exam. Marks Exam Duration Course Type								
course	0:0:3	1.5	CIE:30	3 Hours	PC			
22A02			SEE:70					
Course (Objectives:							
	actical knowledge abo				iodes, BJT, JFE			
and also	analyze the performan	ce of DC Motors	s, AC Motors and	l Transformers.				
		S	yllabus					
LIST OI	EXPERIMENTS: (Conduct all exp	eriments).					
Note: Al	l the experiments sha	ll be implement	ted using both H	lardware and Soft	tware.			
Equipm	ent Required:							
1. V	erification of Kirchho	ff's Laws.						
	Verification of Superpo							
	Aagnetization characte							
	Brake Test on DC-Shu			rmance curves.				
	OC & SC Tests on Sing		ormer.					
	/-I Characteristics of S							
	-I Characteristics of P	5	e					
	-I Characteristics of Z							
	Half Wave Rectifier an			<i>.</i> •				
	nput and Output chara		-					
	nput and Output chara		-	Iration				
	nput and Output Chara		41.					
	dditional Experimen							
	peed control of DC Sh Brake Test on Three Ph		lotor					
14. 1			10101.					
	Dutcomes:							
After the	completion of the cou	rse students will	able to,					
1. E	xperimentally verify th	ne basic circuit tl	heorems, KCL an	nd KVL				
	raw the Open circuit c				•			
	cquire hands on exper							
	ansformers obtaining t	heir performanc	e indices using st	andard analytical a	as well as			
-	raphical methods							
	xperimentally verify th							
	raw the characteristics				n Diode, Zener			
	iode, BJT and JFET b		-					
6. E	Experimentally verify t	he working of ha	alf and full wave	rectifier by using l	PN Junction			
	iodes							

Sl.	Category	Course		Hour	Credits		
No.		Code		L	Т	Р	C
1	BSC	22A0015T	Complex Variables & Numerical Methods	3	0	0	3
2	BSC	22A0020T	Probability Theory and Stochastic Processes	3	0	0	3
3	PCC	22A0404T	Signals and Systems	3	0	0	3
4	PCC	22A0405T	Digital Logic Design	3	0	0	3
5	HSC	22A0021T	Universal Human Values	3	0	0	3
6	PCC	22A0406T	Analog Circuits	3	0	0	3
7	PCC (Lab)	22A0407P	Simulation Lab	0	0	3	1.5
8	PCC (Lab)	22A0408P	Digital Logic Design Lab	0	0	3	1.5
9	PCC (Lab)	22A0409P	Analog Circuits Lab	0	0	3	1.5
10	SC	22A3205	Skill Oriented Course: Python Programming	1	0	2	2
11	MC	22A0029M	Mandatory Course: Constitution of India	2	0	0	0
	ı		Total	credits	1		24.5

Category	Credits
Basic Science Course (BSC)	6
Professional Core Courses (PCC)	13.5
Humanities and Social Science Course (HSC)	3
Skill Oriented Course (SC)	2
Total	24.5

Come C 1	I. T. D. C		mon to EEE, ECH		C T
Course Code	L: T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0015T	3: 0:0:0	3	CIE: 30 SEE:70	3Hours	BSC
Course Objec					
	1	0	-	he knowledge on the c	
			cal methods for interest central equations.	erpolating the polynor	nials, evaluation of
			Syllabus		Total Hours:45
Unit - I	A	analytic Fu	nctions And Confo	ormal Mapping	9 Hrs
Differentiation				equations (both Car	rtesian and polar
	tions, and Ha	rmonic con	jugate, Potential fur		0.11
Unit - II	<u>Carralia (1</u>	(:'41	Complex Integ		9 Hrs
				's integral formula (w. omplex Power Series:	
				ions, Singularities: Ty	
pole of order.	s (minour pi	001), 20105	or an analytic ranet		pes of singularities
Unit - III			Residue Th	eorem	9 Hrs
Residues and e of $\frac{1}{2}$	valuation of g residue the	residues at j orem, Evalu	ation of improper a	sidue theorem (without and real integrals of the	proof), Evaluation type:
(i) c f(c	c o ș sin)	d	(ii) $f(x) dx$		
Unit - IV	Interpolat	ion-Numer	ical Differentiation	n & Integration	9 Hrs
				olation formulae – Lagi	
				- Simpson's 1/3 Rule -	
Unit - V			,	erential Equations	9 Hrs
Method ofsucc				ution by Taylor's serie ethod-Runge-Kutta Me	
Textbooks:					
1. Higher Eng	ineering Mat	hematics, B	S.S.Grewal, Khanna	publishers.	
2. Engineering	g Mathematic	s Volume I	II by T.K.V. Iyenga	r, B.Krishna Gandhi,S.	Ranganatham and
M.V.S.S.N	. Prasad, S. C	hand Publi	cations.		
3. Introductory	Methods of	Numerical A	Analysis by S. S. Sa	stry, PHI Learning Pvt	. Ltd., New
References:					
1. Higher Eng	ineering Mat	hematics, b	y B.V.Ramana, Mc	Graw Hill publishers.	
2. Advanced I	Engineering I	Mathematic	s, by Alan Jeffrey, I	Elsevier.	
Course Outco	mes (CO):				
On completion	of this course	, student wi	ll be able to:		
CO-1: Underst	and function	s of Comple	ex variable and its p	roperties,	
		-	mal mappings of co	-	
	•	•	11 0	ply Cauchy's integral t	heorem and
	-		ularities of complex		
•	U U	e e	1	sing Residue theorem.	
		-	-	-	.1 1.00
		•	s using interpolation	formulae and evaluate	the differentiation
•	gration nume	•			
	00	· · . 1	uations numerically		

	PROBABILITY THEORY AND STOCHASTIC PROCESSES							
Course Code	Course Code L: T:P Credits Exam Marks Exam Duration Course Type							
22A0020T	3:0:0	3	CIE:30 SEE:70	3 Hours	BSC			

Course Objectives:

- This gives basic understanding of random signals and processes signal
- To understand the principles of random signals and systems in Communications and Signal Processing areas.
- To know the Spectral and temporal characteristics of Random Processes.
- To Learn the Basic concepts of Noise sources.

Syllabus	Total Hours:48
Unit –I	10 Hrs

Probability: Probability Introduced through Sets and Relative Frequency: Experiments and Sample Spaces, Discrete and Continuous Sample Spaces, Events, Probability Definitions and Axioms, Mathematical Model of Experiments, Probability as a Relative Frequency, Joint Probability, Conditional Probability, Total Probability, Bayes' Theorem, Independent Events, Problem Solving. Random Variable: Definition of a Random Variable, Conditions for a Function to be a Random Variable, Discrete, Continuous, Mixed Random Variable, Distribution and Density functions, Properties, Binomial, Poisson, Uniform, Gaussian, Exponential, Rayleigh, Conditional Distribution, Methods of defining Conditioning Event, Conditional Density, Properties, Problem Solving.

Unit –II	10 Hrs
Operations on Single Random Variable: Introduction, Expectation of	a random variable,
moments-moments about the origin, Central moments, Variance and Skew, Ch	ebyshev's inequality,
moment generating function, characteristic function, transformations of rando	om variable, Problem
Solving.	
	· · · · ·

Multiple Random Variables: Vector Random Variables, Joint Distribution Function, Properties of Joint Distribution, Marginal Distribution Functions, Conditional Distribution and Density - Point Conditioning, Interval conditioning, Statistical Independence, Sum of Two Random Variables, Sum of Several Random Variables, Central Limit Theorem, (Proof not expected), Unequal Distribution, Equal Distributions, Problem Solving.

Operations on Multiple Random Variables: Expected Value of a Function of Random Variables. Joint Moments about the Origin, Joint Central Moments, Joint Characteristic Functions, Jointly Gaussian Random Variables: Two Random Variables case, N Random Variable case,

Properties of Gaussian random variables, Transformations of Multiple Random Variables, Linear Transformations of Gaussian Random Variables, Problem Solving. 10 TL

Unit –III	10 Hrs
Random Processes-Temporal Characteristics: The Random Process Conc	ept, Classification of
Processes, Deterministic and Nondeterministic Processes, Distribution and	l Density Functions,
concept of Stationarity and Statistical Independence, First-Order Stationary	Processes, Second-
Order and Wide-Sense Stationarity, N-Order and Strict-Sense Stationarity.	Time Averages and
Ergodicity, Mean-Ergodic Processes, Correlation-Ergodic Processes, Auto	correlation Function
and Its Properties, Cross-Correlation Function and its Properties, Covariance	Functions, Gaussian
Random Processes, Poisson Random Process, Problem Solving.	
Unit –IV	9 Hrs

Random Processes-Spectral Characteristics: The Power Density Spectrum and its Properties, Relationship between Power Spectrum and Autocorrelation Function, The Cross-Power Density Spectrum and its Properties, Relationship between Cross-Power Spectrum and Cross-Correlation Function, Problem Solving.

Unit –V	9 Hrs
Random Signal Response of Linear Systems: System Response - Convolut	tion, Mean and Mean
squared Value of System Response, autocorrelation Function of Response	se, Cross-Correlation
Functions of Input and Output, Spectral Characteristics of System Respo	onse: Power Density
Spectrum of Response, Cross-Power Density Spectrums of Input and Outp	ut, Band pass, Band
Limited and Narrowband Processes, Properties, Problem Solving.	
Text Books:	
 Probability, Random Variables & Random Signal Principles - Peyton Z. P Edition, 2001. 	eebles, TMH, 4th
2. Principles of Communication systems by Taub and Schilling (TMH), 2008	3.
References:	
1. Athanasios Papoulis and S. Unnikrishna Pillai, "Probability, Random Vari Stochastic Processes", 4th Edition, PHI, 2002.	ables and
2. Simon Haykin, "Communication Systems", 3rd Edition, Wiley, 2010.	
3. Henry Stark and John W.Woods, "Probability and Random Processes with Signal Processing," 3rd Edition, Pearson Education, 2002.	Application to
 George R. Cooper, Clave D. MC Gillem, "Probability Methods of Signal a 	and System
Analysis," 3rd Edition, Oxford, 1999.	ind bystem
Course Outcomes:	
After the completion of the course students will able to:	
CO-1: Understanding the concepts of Probability, Random Variables, Random characteristics learn how to deal with multiple random variables, co joint distribution and statistical independence.	
CO-2: Formulate and solve the engineering problems involving random v processes.	variables and random
CO-3: Analyze various probability density functions of random variables.	
CO-4: Derive the response of linear system for Gaussian noise and random sig	gnals as inputs.
CO-5: Understand and analyze continuous and discrete-time random processes	8.
CO-6: Evaluate the single and multiple random variable concepts to expect and moments.	ation, variance

		SIGNALS	S AND SYSTEMS			
Course Code	L: T:P	Credits	Exam Marks	Exam Durat	ion	Course Type
22A0404T	3:0:0	3	CIE:30	3 Hour	s	PCC
			SEE:70			
Pre-requi	isite		Mathema	tics - I		
Course Objecti	ves:					
• To introduce	students to t	he basic idea of	f signal and system a	nalysis and its c	charac	cterization in
	uency domai		c ·	•		
• To present F	ourier tools t	hrough the anal	ogy between vectors	and signals.		
-		-	truction of signals.	C		
		-	ms in time and frequ	ency domains.		
-			as mathematical too	-	tinuo	us and discrete-
	and systems.			, , , , , , , , , , , , , , , , , , ,		
UNIT			Systems and Fouri	er Series		10 Hrs
		0,	classification of Sigr			
			Important sets & sy	-		
	-	-	mean square error.	, moons, onghan	7 Milai	ysis malogy
	e	•	xponential, Properti	es of Fourier s	series	concept of
discrete spectru	-		ipononiui, iroponi		, ,	concept of
UNIT -		• • • • • • • • • • • • • • • • • • • •	CTFT and DTFT			10 Hrs
		Transform (C'	TFT): Definition, Co	omputation and	nron	
			systems, Inverse For			
			trative Problems.		State	filent and proof o
1 0	-	0	T): Definition, Com	putation and p	roper	ties of Discrete
			of signals and system		- per	
UNIT -			Laplace Transform			10 Hrs
			C, Properties, Inverse	e Laplace transf	forms	
			Response to standard			
equations with		-		a 51811113, 201011	011 01	
UNIT -			smission through L	TI systems		9 Hrs
			stems: Linear syste	ç	nonse	
-			linear time-invariar	-	-	-
-			system. Filter charac	· · ·		
•			bandwidth, System		•	
	e	•	r criterion for physic			
	•	-	spectral densities, I			1
UNIT -		8,	Z-Transform			9 Hrs
		nition, ROC. P	roperties, Poles and	d Zeros in Z-n	lane.	
	, ,		ion, BIBO stability,	-		
-	-		l conditions. Illustrat			<i>U</i> ,
	1					
Text Books:	onhoine A C	Willolm and C	II Nowoh "Change	a and Creaters?	and .	Edition
1. A.V. Opp PHI,2009		. whisky and S	S.H. Nawab, "Signal	s and Systems"	, 2 ^{na}	Ealuon,
2. Simon Ha	ykin and Van	Veen, "Signals	s & Systems", 2 nd Ed	lition, Wiley, 20	005	

Reference Books:

1. BP Lathi, "Principles of Linear Systems and Signals", 2nd Edition, Oxford University Press,015.

Matthew Sadiku and Warsame H. Ali, "Signals and Systems A primer with MATLAB", CRCPress, 2016.

2. Hwei Hsu, "Schaum's Outline of Signals and Systems", 4thEdition, TMH, 2019.

Matthew Sadiku and Warsame H. Ali, "Signals and Systems A primer with MATLAB", CRCPress, 2016.

2. Hwei Hsu, "Schaum's Outline of Signals and Systems", 4thEdition, TMH, 2019.

Course Outcomes (CO):

After the completion of the course students will able to:

- **CO-1:** Understand the mathematical description and representation of continuous-time and discrete-timesignals and systems.
- CO-2: Also understand the concepts of various transform techniques.
- **CO-3:** Apply sampling theorem to convert continuous-time signals to discrete-time signals.
- CO-4: Reconstruct back, different transform techniques to solve signals and system related problems
- **CO-5:** Analyze the frequency spectra of various continuous-time and discrete-time signals using different transform methods.

CO-6: Classify the systems based on their properties and determine the response of them.

		DIGI	TAL LOGIC DES	IGN	
Course Code	L: T:P	Credits	Exam.Marks	Exam Duratio	n Course Type
22A0405T	3:0:0	3	CIE:30 SEE:70	3 Hours	РСС
 To study reminimization To study the To study the To be able to 	and the Arithmeter presentation on techniques e combination e sequential to understand	of switching s. nal logic des logic circuits	codes and theory of functions using Bo sign of various logi s design both in syn switching devices, t	olean algebra expr c circuits. chronous and Asyr	
 realizations To study so functions. 		ogrammable	logic devices and th	eir use in realizatio	on of switching
			Syllabus		
		Unit –			10 Hrs
Boolean functio Three, Four Var	ons – Canonic	cal and Stand	an Algebra – Axior lard Forms. Gate –	Level Minimizatio	n: Introduction – Two
Boolean functio	ons – Canonic	ion to Boole cal and Stand 's – Don't Ca	an Algebra – Axior lard Forms. Gate – are Conditions – NA	Level Minimizatio	olean Algebra – n: Introduction – Two
Boolean functio Three, Four Var Solving. Combinational adder, Binary	ons – Canonic riable K-map circuits: H Adder/Sub	ion to Boole cal and Stand 's – Don't Ca Unit –I lalf/Full Add tractor, BC	an Algebra – Axior lard Forms. Gate – are Conditions – NA II der and Subtractor CD adder, Binary s, Encoders. Problem	Level Minimizatio AND and NOR imp , Ripple carry add / Multiplier, Ma	olean Algebra – n: Introduction – Two olementation, Problen 10 Hrs ler, Carry look ahea agnitude comparato
Boolean functio Three, Four Var Solving. Combinational adder, Binary Multiplexers, D	ons – Canonic riable K-map l circuits: H Adder/Sub e-Multiplexe	ion to Boole cal and Stand 's – Don't C Unit –I lalf/Full Add tractor, BC ers, Decoders Unit –I	an Algebra – Axior lard Forms. Gate – are Conditions – NA II der and Subtractor 2D adder, Binary 5, Encoders. Probler V	Level Minimizatio AND and NOR imp , Ripple carry add / Multiplier, Ma n solving.	olean Algebra – n: Introduction – Two olementation, Problem 10 Hrs ler, Carry look ahea agnitude comparato 9 Hrs
Boolean functio Three, Four Var Solving. Combinational adder, Binary Multiplexers, D Sequential circu sequential circu	ns – Canonic riable K-map l circuits: H Adder/Sub e-Multiplexe ruits: Flip Flo	ion to Boole cal and Stand 's – Don't C Unit –I lalf/Full Add tractor, BC ers, Decoders Unit –I op-SR, JK, T foore/Mealy	an Algebra – Axior lard Forms. Gate – are Conditions – NA II der and Subtractor 2D adder, Binary 5, Encoders. Probler V	Level Minimizatio AND and NOR imp , Ripple carry add / Multiplier, Ma n solving. Flip Flop, Analysis imization, State as	olean Algebra – n: Introduction – Two olementation, Problem 10 Hrs ler, Carry look ahea agnitude comparato 9 Hrs and design of clocke
Boolean functio Three, Four Var Solving. Combinational adder, Binary Multiplexers, D Sequential circu sequential circu	ns – Canonic riable K-map l circuits: H Adder/Sub e-Multiplexe ruits: Flip Flo	ion to Boole cal and Stand 's – Don't C Unit –I lalf/Full Add tractor, BC ers, Decoders Unit –I op-SR, JK, T foore/Mealy	an Algebra – Axior lard Forms. Gate – are Conditions – NA II der and Subtractor CD adder, Binary s, Encoders. Problem V C, D, Master/Slave H models, State min rs, Shift Registers, I	Level Minimizatio AND and NOR imp , Ripple carry add / Multiplier, Ma n solving. Flip Flop, Analysis imization, State as	olean Algebra – n: Introduction – Two olementation, Problem 10 Hrs ler, Carry look ahead agnitude comparator 9 Hrs and design of clocke

References:

- 1. William I. Fletcher, "An Engineering Approach to Digital Design", Prentice- Hall of India, 1980.
- 2. Floyd T.L., "Digital Fundamentals", Charles E. Merril publishing company, 1982.
- 3. John. F. Wakerly, "Digital Design Principles and Practices", Pearson Education, 4th Edition, 2007.
- 4. E-learning resources: http://nptel.ac.in/courses.php

Course Outcomes:

After the completion of the course students will able to:

CO-1: Understand various types of Code conversions.

CO-2: Apply the Boolean theorems to Simplify Complex Boolean Function through logical gates.

CO-3: Design and implement various logical devices using combinational circuits.

CO-4: Design and implement various logical devices using sequential circuits.

CO-5: Analyze sequential circuits like Registers and Counters using flip-flops.

CO-6: Demonstrate and compare the construction of programmable logic devices and different types of ROM.

UNIVERSAL HUMAN VALUES (Common to all branches of Engineering)

			o un prunches or Eng	<u>-</u>	
Course Cod	e L:T:P:S	Credits	Exam marks	Exam Duration	Course Type
22A0021T	3:0:0:0	3	CIE:30 SEE:70	3 Hours	HSC
Course Obj	ectives:	•			·
 being), Underst nature/e 	family, society anding (or deve xistence	and nature/exited oping clarity	ve based on self-exp istence.) of the harmony in th		
	hening of self- oment of comm		ourage to act		
• Develop			labus		Total Hours:48
Unit -I	Course Int		eed, Basic Guideline or Value Education	s, Content and	10 Hrs
Self-Explo Validation Continuou Right unde ofaspiratio Understand scenario. Method to various lev Include pr for living	ration–what is - as the process s Happiness an erstanding, Rel ns of every hur ling Happiness fulfill the abov vels. actice sessions	it? - Its conta for self-explo- id Prosperity- ationship and nan being wit and Prosperi ve human aspir to discuss na pility (living	A look at basic Hun Physical Facility- th h their correct priorit ty correctly- A critic rations: understanding atural acceptance in in relationship, harm	ural Acceptance' an nan Aspirations e basic requirements y cal appraisal of the g and living in harm human being as the	nd Experiential s for fulfillment current nony at e innate acceptance
Unit -II	Understan	iding Harmon	ny in the Human Bei Myself!	ng - Harmony in	9 Hrs
Understand Understand Understand Physical n Programs Include pr available	ling the needs of ling the Body a ling the charact ling the harmo eeds, meaning of to ensure Sanya actice sessions to me. Identif	of Self ('I') an as an instrument teristics and action of Prosperity is am and Health to discuss the Sying from o		and physical facility oer, seer and enjoye rmony in 'I' nd Health; correct a played in making erentiate between	r) appraisal of material goods
Unit -III	Understandin		ı the Family and Soc Iuman Relationship	iety- Harmony in	10 Hrs
Understand relationshi	ling values in l ps) and program	human-human n for its fulfill	relationship; meanir ment to ensure mutua	g of Justice (nine unine the happiness; Trust a	iniversal values in and Respect as the

foundational values of relationship Understanding the meaning of Trust; Difference between intention and competence Understanding the meaning of Respect, Difference between respect and differentiation; the other salient values in relationship
Understanding the meaning of Trust; Difference between intention and competence Understanding the meaning of Respect, Difference between respect and
differentiation: the other salient values in relationship
Understanding the harmony in the society (society being an extension of family): Resolution,
Prosperity, fearlessness (trust) and co-existence as comprehensive Human Goals
Visualizing a universal harmonious order in society- Undivided Society, Universal Order- from
family to world family. Include practice sessions to reflect on relationships in family, hostel and institute as
extended family, real life examples, teacher-student relationship, goal of education etc.
Gratitude as a universal value in relationships. Discuss with scenarios. Elicit examples
from students' lives
Unit -IVUnderstand the Nature and Existence hole existence as Coexis9 Hrs
Understanding the harmony in the Nature
Interconnectedness and mutual fulfillment among the four orders of nature- recyclability and
self-regulation in nature
Understanding Existence as Co-existence of mutually interacting units in all- pervasive
space
Holistic perception of harmony at all levels of existence.
Include practice sessions to discuss human being as cause of imbalance in nature (film
"Home" can beused), pollution, depletion of resources and role of technology etc.
Unit -V Implications of the above Holistic Understanding of Harmony on 10 Hrs
Professional Ethics
Natural acceptance of human values Definitiveness of Ethical Human Conduct
Basis for Humanistic Education, Humanistic Constitution and Humanistic Universal Order
Competence in professional ethics: a. Ability to utilize the professional competence for
augmenting universal human order b. Ability to identify the scope and characteristics of people
friendly and eco- friendly production systems, c. Ability to identify and develop appropriate
technologies and management patterns for above production systems.
Case studies of typical holistic technologies, management models and production
systemsStrategy for transition from the present state to Universal Human Order:
a. At the level of individual: as socially and ecologically responsible engineers, technologists
andmanagers
b. At the level of society: as mutually enriching institutions and
organizationsSum up. Include practice Exercises and Case Studies will be taken up in Practice (tutorial)
Sessions eg. Todiscuss the conduct as an engineer or scientist etc.
Textbooks:
1. R R Gaur, R Asthana, G P Bagaria, "A Foundation Course in Human Values and Professional Ethics", 2 nd Revised Edition, Excel Books, New Delhi, 2019. ISBN 978-93-87034-47-1
 3. R R Gaur, R Asthana, G P Bagaria, "Teachers' Manual for A Foundation Course in Human Values andProfessional Ethics", 2nd Revised Edition, Excel Books, New Delhi, 2019. ISBN 978- 93-87034-53-2
50 0100 I 00 E
Reference Books:

- Jeevan Vidya: EkParichaya, A Nagaraj, Jeevan Vidya Prakashan, Amar kantak, 1999.
 N. Tripathi, "Human Values", New Age Intl. Publishers, New Delhi, 2004. The Story of Stuff (Book).
- 3. Mohandas Karamchand Gandhi "The Story of My Experiments with Truth"
- 4. E. FSchumacher. "Small is Beautiful"Slow is Beautiful -Cecile Andrews
- 5. J C Kumarappa "Economy of Permanence" Pandit Sunderlal "Bharat Mein Angreji Raj" Dharampal, "Rediscovering India"

6. Mohandas K. Gandhi, "Hind Swaraj or Indian Home Rule"India Wins Freedom - Maulana Abdul Kalam Azad Vivekananda - Romain Rolland(English)

Course Outcomes(CO):

On completion of this course, student will be able to:

- **CO-1:** Students are expected to become more aware of themselves, and their surroundings (family, society, nature)
- **CO-2:** They would become more responsible in life, and in handling problems with sustainable solutions, while keeping human relationships and human nature in mind.
- **CO-3:** They would have better critical ability.
- **CO-4:** They would also become sensitive to their commitment towards what they have understood(human values, human relationship and human society).
- **CO-5:** It is hoped that they would be able to apply what they have learnt to their own self in differentday-to-day settings in real life, at least a beginning would be made in this direction.

CO-6: Understand the harmony in the human being, family, society and nature/existence

ANALOG CIRCUITS

Course Code	L: T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0406T	3:0:0	3	CIE:30 SEE:70	3 Hours	PCC

Course Objectives:

- To design amplifiers using BJT & MOSFETs at low and high frequencies.
- To understand the characteristics of Multistage amplifiers
- To understand the characteristics of Differential amplifiers, feedback and power amplifiers.
- To examine the response of tuned amplifiers and multivibrators
- To categorize different oscillator circuits based on the application
- To design the electronic circuits for the given specifications and for a given application.

	Syllabus	Total Hours:48
Unit –I	Multistage and Differential Amplifiers	10 Hrs
Introduction	to Multistage Amplifiers, different Coupling Schemes, Cascode am	plifier, Darlington
L '	OS Differential Pair, Small-Signal Operation of the MOS Differential	·
Differentiall	Pair, and other Non-ideal Characteristics of the Differential Amplifier	
Unit –II	Frequency Response	10 Hrs
Low-Freque	ency Response of the CS and CE Amplifiers, Internal Capacitive E	ffects and the High-
Frequency	Model of the MOSFET and the BJT, High-Frequency Response	of the CS and CH
Amplifiers,	High-Frequency Response of the CG and Cascode Amplifiers, H	igh-Frequency
Response of	f the Source and Emitter Followers.	
Unit –III	Feedback Amplifiers and Oscillators	10 Hrs
Feedback A	Amplifiers : Introduction, The General Feedback Structure, Some Pro	perties of Negative
	The Four Basic Feedback Topologies, The Feedback Voltage Amplific	· · · ·
	k Trans-conductance Amplifier (Series—Series), The Feedback Trans-	
Amplifier (S	Shunt—Shunt), The Feedback Current Amplifier (Shunt—Series), St	ummary.
Oscillators	General Considerations, Phase Shift Oscillator, Wien-Bridge Oscilla	tor, LC Oscillators,
Relaxation (Oscillator, Crystal Oscillators, Illustrative Problems.	
Unit –IV	Power Amplifiers	9 Hrs
Introduction	n, Classification of Output Stages, Class A Output Stage, Class B	Output Stage, Class
ABOutput S	Stage, Biasing the Class AB Circuit, CMOS Class AB Output Stages,	Class C power
amplifier an	d Class S power amplifier, Power BJTs, Variations on the Class AB	Configuration,
MOS Powe	r Transistors, Distortions in Amplifiers	-
Unit –V	Tuned Amplifiers and Multi vibrators	9 Hrs
Tuned Am	plifiers: Basic Principle, Use of Transformers, Single Tuned Amplific	ers, and Amplifiers
•.• •.•	le Tuned Circuits, Stagger Tuned Amplifiers.	
with multip	ie runea cheans, stagger runea rinpinters.	

Text Books:

- 1. Adel. S. Sedra and Kenneth C. Smith, "Micro Electronic Circuits," 6th Edition, Oxford University Press, 2011.
- 2. J. Millman, C Chalkias, "Integrated Electronics", 4thEdition, McGraw Hill Education (India) Private Ltd., 2015.
- 3. Millman and Taub, "Pulse, Digital and Switching Waveforms", 3rd Edition, Tata McGraw-Hill Education, 2011.

References:

- 1. Behzad Razavi, "Fundamentals of Micro Electronics", Wiley, 2010.
- 2. Donald A Neamen, "Electronic Circuits Analysis and Design," 3rdEdition, McGraw Hill (India), 2019.
- 3. Robert L. Boylestad and Louis Nashelsky, "Electronic Devices and Circuits Theory", 9th Edition, Pearson/Prentice Hall, 2006.
- 4. K.Lal Kishore, "Electronic Circuit Analysis", 2ndEdition, B S Publications, 2008

Course Outcomes:

After the completion of the course students will able to:

- **CO-1:** Describe the characteristics of Multistage and Differential amplifiers
- **CO-2:** Analyze the frequency response of single stage amplifiers using BJT & FET at high and low frequencies
- CO-3: Understand different feedback topologies and Oscillator circuits
- CO-4: Analyze different types of large signal amplifiers
- **CO-5:** Compare the performance of different tuned amplifiers and multivibrators
- **CO-6:** Design of Tuned and Multivibrator for the given specifications

SIMULATION LAB

Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0407P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PCC

Course Objectives:

- To realize the concepts studied in theory
- To simulate various Signals and Systems through MATLAB
- To apply the concepts of signals to determine their energy, power, psd etc.
- To analyze the output of a system when it is excited by different types of deterministic and random signals.
- To generate random signals for the given specifications

Syllabus

LIST OF EXPERIMENTS: (Conduct all experiments).

Note: All the experiments are to be simulated using MATLAB or equivalent software.

- 1. Write a program to generate various Signals and Sequences: Periodic and Aperiodic, Unit Impulse, Unit Step, Square, Saw tooth, Triangular, Sinusoidal, Ramp, Sinc function.
- 2. Perform operations on Signals and Sequences: Addition, Multiplication, Scaling, Shifting, Folding, Computation of Energy and Average Power.
- 3. Write a program to find the trigonometric & exponential Fourier series coefficients of a rectangular periodic signal. Reconstruct the signal by combining the Fourier series coefficients with appropriate weightings- Plot the discrete spectrum of the signal.
- 4. Write a program to find Fourier transform of a given signal. Plot its amplitude and phase spectrum.
- 5. Write a program to convolve two discrete time sequences. Plot all the sequences.
- 6. Write a program to find autocorrelation and cross correlation of given sequences.
- 7. Write a program to verify Linearity and Time Invariance properties of a givenContinuous/Discrete System.
- 8. Write a program to generate discrete time sequence by sampling a continuous time signal. Show that with sampling rates less than Nyquist rate, aliasing occurs while reconstructing the signal.
- 9. Write a program to find magnitude and phase response of first order low pass and high pass filter.Plot the responses in logarithmic scale.
- 10. Write a program to find response of a low pass filter and high pass filter, when a speech signal ispassed through these filters.
- 11. Write a program to generate Complex Gaussian noise and find its mean, variance, ProbabilityDensityFunction (PDF) and Power Spectral Density (PSD).
- 12. Generate a Random data (with bipolar) for a given data rate (say 10kbps).Plot the same for a timeperiod of 0.2 sec.

13. To plot pole-zero diagram in S-plane of given signal/sequence and verify its stability

References:

1. Stephen J. Chapman, "MATLAB Programming for Engineers", Cengage, November 2012.

Online Learning Resources/Virtual Labs: https://www.vlab.co.in/

Course Outcomes (CO):

After the completion of the course students will able to:

CO1: Learn how to use the MATLAB software and know syntax of MATLAB programming.

CO2: Understand how to simulate different types of signals and system response.

- **CO3:** Find the Fourier Transform of a given signal and plot amplitude and phase characteristics.
- **CO4:** Analyze the response of different systems when they are excited by different signals and plot power spectral density of signals.

CO5: Generate different random signals for the given specifications

CO6: Simulate different random signals for the given specifications

		DIGITAL I	LOGIC DESIGN	LAB	
Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0408P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	РСС
gates. • To design properties.	et digital circe various comb	inational and	sequential circuits	, truth table of differe s after analyzing their	-
	0	U	Verilog and VHD sing tools such as	L sonware. PSPICE/Multisim.	
			Syllabus		
	et, Concept of			Digital Ics, Specificat of the Truth Tables of	•
2. Implementation	on of the Give	en Boolean Fu	nction using Logi	c Gates in Both Sop	and PosForms.
3. Verification of	of State Tables	s of Rs, J-k, T	and D Flip-Flops	using NAND & NO	R Gates
4. Implementation	on and Verific	cation of Deco	oder and Encoder	using Logic Gates.	
5. Implementation	on of 8x1 mul	tiplexer using	g Logic Gates.		
6. Implementation	on of 4-Bit Pa	rallel Adder	Using 7483 IC.		
7. Design, and V	/erify the 4- B	it Synchrono	ous Counter/ Asyn	chronous Counter.	
Software:					
1. Simulation	of MOS Inver	ter with diffe	rent loads using P	SPICE software	
circuit simu	of CMOS Inv Ilator softward 4-bit Multiple	e.	-	n, Kp as a design var	iable in suitable
4. Design of a	decade count	er using VHI	DL\Verilog.		
5. Design of a	3-input NAN	D gate and its	s simulation using	suitable logic simula	tor.
Fools / Equipmer	nt Required:				
• Power Supply	/ (030V, +)20M ohm,	12 –012v. 0-1000 DC V	. +5volt).	lable in the Laborato olt, 20micro 10 Amp	-

Course Outcomes:

After the completion of the course students will able to:

CO1: Learn the basics operation of gates.

CO2: Construct basic combinational circuits and verify their functionalities.

CO3: Apply the design procedures to design basic sequential circuits.

CO4: Learn about counters.

CO5: Learn about Shift registers

CO6: Simulate basic digital circuits and to verify their operation in PSPICE /VHDL.

		ANALOG CII	RCUITS LAB		
Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0409P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	РСС
Course Objective	es:				
•		ristics of Differe	ntial amplifiers, fe	edback and power	r
amplifiers			I /	Ĩ	
-		funed amplifier	s and multivibrate	ors	
	-	-	used on the applica		
-				and for a given app	lication
• To design			-	and for a given app	
I IST OF EVDEI	DIMENTS. (Co.	Sylla			
LIST OF EXPER		•	- ,		
Note: All the exp	eriments shall b	e implemented	using both Hard	ware and Softwar	re.
1. Design and	d Analysis of Dar	lington pair			
-	d Analysis of Cas	•			
-	Response of Diff	-			
	-	-		d find the frequence	W
response o		les beries leeu	ouek ampimer an	a find the frequence	, y
-		nt Shunt feedb	ack amplifier and	l find the frequenc	X 7
response o	•	in – Shun leeu	Jack amplifier and	i find the frequence	y
-			lifion		
-	d Analysis of Cla				
-	d Analysis of RC	-	llator		
-	d Analysis of LC		fina		
	Response of Sing				
	d Analysis of Bist				
-	d Analysis of Mo				
12. Design and	d Analysis of Ast	able Multivibrat	or		
Equipment Requ	ired: DC Power	supplies, Multi 1	meters, DC Amme	eters, DC Voltmete	ers, AC
Voltmeters, CROS	s, all the required	active devices.			
References:		1 1			
Online learning re		abs: https://www	w.vlab.co.1n/		
Course Outcome					
After the complet					
		and frequency rea	sponse of various	Multi stage amplif	iers for Low,
	gh frequencies.				
CO2: Analyze Fee	-		in.		
CO3: Design vari					
CO4: Determine t		-	er amplifiers usin	lg BJT.	
CO5: Analyze of	-	s.			
CO6: Analyze of					

PYTHON PROGRAMMING (Common to CS, DS, EEE,ME and ECE)					
Course Code	L:T:P	Credits	Exam Marks	Exam Duration	Course Type
22A3205	1:0:2	2	CIE: 30	3 Hours	SC
			SEE:70		
Course Objectives:					
This course will	enable studer	nts to:			
• Acquire progr	amming skil	ls in core Pyt	hon		
• To understand	the importa	nce of Object	-oriented Program	ming	

- Develop the skill of designing graphical-user interfaces (GUI) in Python.
- Develop the ability to write database applications in Python.

Syllabus	Total Hours:48

Introduction to Python: Features of Python, Data types, Operators, Input and output, Control Statements, Looping statements

Python Data Structures: Lists, Dictionaries, Tuples.

Strings: Creating strings and basic operations on strings, string testing methods.

Functions: Defining a function- Calling a function- Types of functions-Function Arguments-Anonymous functions- Global and local variables

OOPS Concepts; Classes and objects- Attributes- Inheritance- Overloading- Overriding- Data hiding

Modules and Packages: Standard modules-Importing own module as well as external modules Understanding Packages Powerful Lamda function in python Programming using functions, modules and external packages

Working with Data in Python: Printing on screen- Reading data from keyboard- Opening and closing file- Reading and writing files- Functions-Loading Data with Pandas-Numpy

Tasks:

1:OPERATORS

- a. Read a list of numbers and write a program to check whether a particular element is present or not using membership operators.
- b. Read your name and age and write a program to display the year in which you will turn 100 years old.
- c. Read radius and height of a cone and write a program to find the volume of a cone.
- d. Write a program to compute distance between two points taking input from the user (Hint: use Pythagorean theorem)

2:CONTROL STRUCTURES

- a. Read your email id and write a program to display the no of vowels, consonants, digits and white spaces in it using if...elif...else statement.
- b. Write a program to create and display a dictionary by storing the antonyms of words. Find the antonym of a particular word given by the user from the dictionary using while

loop.

- c. Write a Program to find the sum of a Series 1/1! + 2/2! + 3/3! + 4/4! +.....+ n/n!. (Input : n = 5, Output : 2.70833)
- d. In number theory, an abundant number or excessive number is a number for which the sum of its proper divisors is greater than the number itself. Write a program to find out, if the given number is abundant. (Input: 12, Sum of divisors of 12 = 1 + 2 + 3 + 4 + 6 = 16, sum of divisors 16 > original number 12)

3: LIST

- a. Read a list of numbers and print the numbers divisible by x but not by y (Assume x = 4 and y = 5).
- b. Read a list of numbers and print the sum of odd integers and even integers from the list.(Ex: [23, 10, 15, 14, 63], odd numbers sum = 101, even numbers sum = 24)
- c. Read a list of numbers and print numbers present in odd index position. (Ex: [10, 25, 30, 47, 56, 84, 96], The numbers in odd index position: 25 47 84).
- d. Read a list of numbers and remove the duplicate numbers from it. (Ex: Enter a list with duplicate elements: 10 20 40 10 50 30 20 10 80, The unique list is: [10, 20, 30, 40, 50, 80])

4: TUPLE

- a. Given a list of tuples. Write a program to find tuples which have all elements divisible by K from a list of tuples. test list = [(6, 24, 12), (60, 12, 6), (12, 18, 21)], K = 6, Output : [(6, 24, 12), (60, 12, 6)]
- b. Given a list of tuples. Write a program to filter all uppercase characters tuples from given list of tuples. (Input: test list = [("GFG", "IS", "BEST"), ("GFg", "AVERAGE"), ("GfG",), ("Gfg", "CS")], Output : [(,,GFG", ,,IS", ,,BEST")]).
- c. Given a tuple and a list as input, write a program to count the occurrences of all items of the list in the tuple. (Input : tuple = ('a', 'a', 'c', 'b', 'd'), list = ['a', 'b'], Output : 3)

5: SET

- a. Write a program to generate and print a dictionary that contains a number (between 1 and n) in the form (x, x*x).
- b. Write a program to perform union, intersection and difference using Set A and Set B.
- c. Write a program to count number of vowels using sets in given string (Input : "Hello World", Output: No. of vowels : 3)
- d. Write a program to form concatenated string by taking uncommon characters from two strings using set concept (Input: S1 = "aacdb", S2 = "gafd", Output : "cbgf").

6: DICTIONARY

- a. Write a program to do the following operations:
 - i. Create a empty dictionary with dict() method
 - ii. Add elements one at a time
 - iii. Update existing key"s value
 - iv. Access an element using a key and also get() method
 - v. Deleting a key value using del() method
- b. Write a program to create a dictionary and apply the following methods:
 - i. pop() method

- ii. pop item() method
- iii. clear() method
- c. Given a dictionary, write a program to find the sum of all items in the dictionary.
- d. Write a program to merge two dictionaries using update() method.

7: STRINGS

- a. Given a string, write a program to check if the string is symmetrical and palindrome or not. A string is said to be symmetrical if both the halves of the string are the same and a string is said to be a palindrome string if one half of the string is the reverse of the other half or if a string appears same when read forward or backward.
- b. Write a program to read a string and count the number of vowel letters and print all letters except 'e' and 's'.
- c. Write a program to read a line of text and remove the initial word from given text. (Hint: Use split () method, Input: India is my country. Output : is my country)
- d. Write a program to read a string and count how many times each letter appears. (Histogram).

8: USER DEFINED FUNCTIONS

- a. A generator is a function that produces a sequence of results instead of a single value. Write a generator function for Fibonacci numbers up to n.
- b. Write a function merge_dict (dict1, dict2) to merge two Python dictionaries.
- c. Write a fact () function to compute the factorial of a given positive number.
- d. Given a list of n elements, write a linear_search () function to search a given element x in a list.

9: BUILT-IN FUNCTIONS

- a. Write a program to demonstrate the working of built-in statistical functions mean (), mode(), median() by importing statistics library.
- b. Write a program to demonstrate the working of built-in trigonometric functions sin (), cos(), tan(), hypot(), degrees(), radians() by importing math module.
- c. Write a program to demonstrate the working of built-in Logarithmic and Power functions exp(), log(), log2(), log10(), pow() by importing math module.
- d. Write a program to demonstrate the working of built-in numeric functions ceil(), floor(), fabs(), factorial(), gcd() by importing math module.

10. CLASS AND OBJECTS

- a. Write a program to create a Bank Account class. Your class should support the following methods for
 - i) Deposit
 - ii) Withdraw
 - iii) Get Balance
 - iv) Pin Change
- b. Create a Savings Account class that behaves just like a Bank Account, but also has an interest rate and a method that increases the balance by the appropriate amount of interest (Hint:use Inheritance).
- c. Write a program to create an employee class and store the employee name, id, age, and salary using the constructor. Display the employee details by invoking employee_info()

method and also using dictionary (_dict_).

d. Access modifiers in Python are used to modify the default scope of variables. Write a program to demonstrate the 3 types of access modifiers: public, private and protected.

11. FILE HANDLING

- a. Write a program to read a filename from the user, open the file (say firstFile.txt) and then perform the following operations:
 - i. Count the sentences in the file.
 - ii. Count the words in the file.
 - iii. Count the characters in the file.
- b. Create a new file (Hello.txt) and copy the text to another file called target.txt. The target.txt file should store only lower-case alphabets and display the number of lines copied.
- c. Write a Python program to store N student's records containing name, roll number and branch. Print the given branch student's details only.

Text Book:

1. Allen B. Downey, "Think Python", 2nd edition, SPD/O'Reilly, 2016.

Reference Books:

- 1. Reema Thareja, "Python Programming Using Problem Solving Approach", Oxford Press, 1st Edition, 2017.
- 2. Michael H Goldwasser, David Letscher, "Object Oriented Programming in Python", Prentice Hall, 1st Edition, 2007.
- 3. Yashavant Kanetkar, Aditya Kanetkar, "Let us Python", BPB publication, 1st Edition, 2019.
- 4. Ashok Kamthane, Amit Kamthane, "Programming and Problem Solving with Python", McGraw Hill Education (India) Private Limited, 2018.
- 5. Taneja Sheetal, Kumar Naveen, "Python Programming A modular approach", Pearson, 2017

Web References:

- 1. https://realpython.com/python3-object-oriented-programming/
- 2. https://python.swaroopch.com/oop.html
- 3. https://python-textbok.readthedocs.io/en/1.0/Object_Oriented_Programming.html
- 4. https://www.programiz.com/python-programming/
- 5. https://www.geeksforgeeks.org/python-programming-language/

Course Outcomes (CO):

On completion of this course, student will be able to:

CO1: Understand various data types like lists, tuples, strings etc.

CO2: Able to create practical and contemporary applications using Functions

CO3: Explore the use of Object oriented concepts to solve Real-life problems

CO4: Explore the use of Object-oriented concepts to solve Real-life problems

CO5: Utilize Python packages in developing software applications

CO6: Solve mathematical problems using Python programming language

CONSTITUTION OF INDIA

(Common to all branches of Engineering)					
Course Code	L: T:P:S	Credits	Exam marks	Exam Duration	Course Type
22A0029M	3:0:0:0	-			

Course Objectives:

- To Enable the student to understand the importance of constitution
- To understand the structure of executive, legislature and judiciary
- To understand philosophy of fundamental rights and duties
- To understand the autonomous nature of constitutional bodies like Supreme Court and high court controller and auditor general of India and Election Commission of India.
- To understand the central-state relation in financial and administrative control

• To understand	• To understand the central-state relation in financial and administrative control					
SyllabusTotal Hours:48						
Unit I	Introduction to Indian Constitution	10 Hrs				
Introduction to India	Introduction to Indian Constitution – Constitution - Meaning of the term - Indian Constitution					
Sourcesand constitut	ional history - Features– Citizenship – Preamble - Funda	mental Rights and				
Duties - Directive Pr	Duties - Directive Principles of State Policy.					
Unit -II	Union Government and its Administration	9 Hrs				
	Structure of the Indian Union					
Union Government	and its Administration Structure of the Indian Union -	Federalism – Centre				
State relationship –	President's Role, power and position - PM and Cou	ncil of ministers -				
Cabinet and Central	Secretariat -Lok Sabha - Rajya Sabha - The Supreme C	ourt and High Court				
- Powers and Function	ons					
Unit -III	State Government and its Administration	10 Hrs				
State Government a	nd its Administration - Governor - Role and Position -Cl	M and Council				
of ministers - State Secretariat-Organization Structure and Functions.						
Unit -IV	Local Administration	10 Hrs				
Local Administration - District's Administration Head - Role and Importance - Municipalities -						
Mayor and role of Elected Representatives -CEO of Municipal Corporation Pachayati Raj -						
Functions- PRI -Zilla Parishath - Elected officials and their roles - CEO, Zilla Parishath - Block						
level Organizational Hierarchy - (Different departments) - Village level - Role of Elected and						
Appointed officials - Importance of grass root democracy						
Unit -V	Election Commission	9 Hrs				
Election Commission - Election Commission- Role of Chief Election Commissioner and Election						
Commissionerate - State Election Commission -Functions of Commissions for the welfare of						
SC/ST/OBC and Women						

Textbooks:

- 1. Durga Das Basu, "Introduction to the Constitution of India", Prentice Hall of India Pvt. Ltd.. NewDelhi
- 2. Subash Kashyap, "Indian Constitution", National Book Trust 3. R R Gaur, R Asthana,

Reference Books:

- 1. H.M.Sreevai, "Constitutional Law of India", 4th edition in 3 volumes
- 2. J.A. Siwach, "Dynamics of Indian Government & Politics"
- 3. M.V. Pylee, "Indian Constitution", Durga Das Basu, Human Rights in Constitutional Law, Prentice - Hall of India Pvt. Ltd. New Delhi
- 4. J.C. Johri, Indian Government and Politics Hans
- 5. M.V. Pylee, "Indian Constitution)

E-Resources:

- 1. nptel.ac.in/courses/109104074/8
- 2. nptel.ac.in/courses/10910404
- 3. nptel.ac.in/courses/101104065/
- 4. www.hss.iitb.ac.in/en/lecture- details
- 5. www.iitb.ac.in/en/event/2nd-lecture-institute-lecture-series-indian-constitution

Course Outcomes (CO):

On completion of this course, student will be able to:

- **CO1:** Understand historical background of the constitution making and its importance for building a democratic India.
- **CO2:** Understand the functioning of three wings of the government i.e., executive, legislative and judiciary.
- CO3: Understand the value of the fundamental rights for becoming good citizen of India.
- **CO4:** Understand the value of the fundamental duties for becoming good citizen of India.
- CO5: Analyze the decentralization of power between central, state and local self-government
- **CO6:** Apply the knowledge in strengthening of the constitutional institutions like CAG,Election Commission and UPSC for sustaining democracy

Sl. No	Category	Course Code	Course Title	Hours per week			Credits
				L	Τ	Р	С
1	HSC	22A0022T	Managerial Economics & Financial Analysis	3	0	0	3
2	ESC	22A0205T	Electrical Engineering	3	0	0	3
3	PCC	22A0414T	Electromagnetic Waves and Transmission Lines	3	0	0	3
4	PCC	22A0415T	Analog & Digital Communications	3	0	0	3
5	PCC	22A0416T	Linear IC Applications	3	0	0	3
6	PCC (Lab)	22A0417T	Linear IC Applications Lab	0	0	3	1.5
7	ESC (Lab)	22A0206P	Electrical Engineering Lab	0	0	3	1.5
8	PCC (Lab)	22A0418P	Analog & Digital Communications Lab	0	0	3	1.5
9	SC	22A0419P	Skill Oriented Course: PCB & Circuit Designing	1	0	2	2
10	MC	22A0027M	Mandatory Course: Environmental Studies	2	0	0	0
					Total	credits	21.5

Category	Credits
Humanities and Social Science Course (HSC)	3
Engineering Science Course (ESC)	4.5
Professional Core Courses (PCC)	12
Skill oriented Course (SC)	2
Total	21.5

Course Code	L: T:P:S	Credits	Exam marks	Exam Duration	1	Course Type
22A0022T	3:1:0:0	3	CIE:30 SEE:70	3 Hor		HSC
Course Objectiv	ves:					
0		pts of manage	erial economics and	financial a	nalys	sis this
			siness environmer		2	
• To have a	thorough kno	wledge on the	e production theor	ries and cos	t whi	ile dealing
with thepr	oduction and	factors of prod	luction.			C
• To have a	thorough kno	wledge regard	ling market struct	ure and form	ns of	
businessor	ganizations ir	the market.				
• To underst	and the conce	pt of capital ar	nd capital budgetin	g in selectin	g the	proposals.
• To have a	thorough kno	wledge on reco	ording, classifying	and summa	rizing	g of
transaction	ns inpreparing	of final accou	ints.			
		S	Syllabus]	Fotal Hours:48
Unit -I In	troduction to	Managerial 1	Economics & Den	nand		9 Hrs
of Demand - E Elasticityof De Methods of De	Elasticity of D mand - Dem emand Foreca	Demand - Sigr nand Forecast	s - Concept of Den nificance - Types ing - Factors go onship of Manag	nand - Den of Elasticity verning De	nand y - N mand	Function - Lav Measurement o I Forecasting
of Demand - E Elasticityof De Methods of De Accounting and Management.	Elasticity of E mand - Dem emand Foreca	Demand - Sign hand Forecast sting - Relati	nificance - Types ing - Factors go onship of Manag	nand - Dem of Elasticit verning De erial Econo	nand y - N mand	Function - Law Measurement o Forecasting with Financia
of Demand - E Elasticityof De Methods of De Accounting and Management. Unit -II	Elasticity of E mand - Dem emand Foreca	Demand - Sign nand Forecast sting - Relati of Production	nificance - Types ing - Factors go onship of Manag n and Cost Analy	nand - Dem of Elasticit verning De erial Econo sis	nand x y - N mand mics	Function - Law Measurement o I Forecasting with Financia 9 Hrs
of Demand - E Elasticityof De Methods of De Accounting and Management. Unit -II Production Fund - Isoquants and Internal and Ex Analysis (BEA	Elasticity of E mand - Dem emand Foreca I Theory ction – Least- Iso costs, M cternal Econor) - Determir	Demand - Sign nand Forecast sting - Relati of Production cost combinat RTS - Cobb-I mies of scale nation of Bre	nificance - Types ing - Factors go onship of Manage n and Cost Analy ion - Short-run and Douglas Productio - Cost concepts a ak-Even Point (S	nand - Dem of Elasticit verning De erial Econo sis d Long-run n Function and Cost be	nand y - N mand mics Produ - Lav	Function - Law Measurement o I Forecasting with Financia 9 Hrs uction Function ws of Returns or - Break-Even
of Demand - E Elasticityof De Methods of De Accounting and Management. Unit -II Production Fund - Isoquants and Internal and Ex Analysis (BEA significance and	Clasticity of E mand - Dem emand Foreca I Theory ction – Least- Iso costs, M cternal Econor) - Determin I limitations o	Demand - Sign nand Forecast sting - Relati of Production cost combinat RTS - Cobb-I mies of scale nation of Bre f Break-Even	nificance - Types ing - Factors go onship of Manage n and Cost Analy ion - Short-run and Douglas Productio - Cost concepts a ak-Even Point (S	nand - Dem of Elasticit verning De erial Econo sis d Long-run n Function and Cost be simple Prob	nand y - N mand mics Produ - Lav	Measurement o I Forecasting with Financia 9 Hrs uction Function ws of Returns or - Break-Even

Unit -V	Introduction To FinancialAccounting And Analysis	10 Hrs
and Trial Ba with simple	Concepts and Conventions - Introduction Double-Entry Book Keepi lance - Final Accounts (Trading Account, Profit and Loss Account a adjustments). Financial Analysis - Analysis and Interpretation of Lic- ios, and Capital structure Ratios and Profitability.	nd Balance Sheet
Textbooks:		
1. Manage	rial Economics, PL Mehata, Sulthan Chand Publications	
•	"Business Economics and Financial Analysis", 4th edition, MGH, 2	2019
Reference B		
1. Ahuja H	Il "Managerial economics" 3 rd edition, Schand, ,2013	
	ldiqui and A.S. Siddiqui: "Managerial Economics and Financial Ana ional, 2013.	llysis", New Age
3. Joseph New De	G. Nellis and David Parker: "Principles of Business Economics", elhi.	2nd edition, Pearson,
4. Domnic	k Salvatore: "Managerial Economics in a Global Economy", Cengag	e, 2013.
5. Manage	rial Economics, Varshney & Maheswari, Sultan Chand, 2013.	
6. Manage	rial Economics and Financial Analysis, Aryasri, 4th edition, MGH, 2	2019
Course Outc	omes (CO):	
On completio	n of this course, student will be able to:	
CO1: Outli	ne the Managerial Economic concepts for decision making and for	rward planning. Also
kno	w law of demand and its exceptions, to use different forecasting m	ethods for predicting
dem	and for various products and services.	
vari	ss the functional relationship between Production and factors of pr ous costs associated with production and able to compute breakeven ous uses of breakeven analysis.	
	ne the different types of business organizations and provide a fram bey in its functions as a medium of exchange.	nework for analyzing
CO4: Inter	pret various techniques for assessing the proposals of project for fin ness.	ancial position of the
	ate the capital budgeting techniques	
	ify the principles of accounting to record, classify and summarize v	arious transactions in
CO6: Ident	ks of accounts for preparation of final accounts.	

ELECTRICAL ENGINEERING

Course Code	L: T:P:C	Credits	ExamMarks	Exam Duration	Course Type
					5 T
	2		CTE 20		FRG
22A0205T	3: 0:0:0	3	CIE: 30	3Hours	ESC
			SEE:70		
			SEE.70		

Course Objectives:

Student will be able to:

- Distinguish between classical method and Laplace transform approach in analyzing transient phenomenon in DC excitations
- Understand and design the different types of filters.
- To know about various characteristics of DC Generators and motors.
- To know about principle of operation of a DC machine working as a generator and motor.
- To understand computation and predetermination of regulation of a $1-\phi$ transformer
- To know about principle of operation of three phase induction motor.

UNIT- I	Transient Analysis	10Hrs
Source free R-L-O Ccircuits with DO factor in R-L-C c	rce free R-L, R-C circuits, R-L, R-C circuits with DC, ste C circuits – under damped, over damped and critical dam C and Sinusoidal forcing functions, Relationship between ircuits – Response of R-L-C circuits using Integral-differ thes for dc And – Problem Solving.	ped cases, Response of RL- bandwidth and Quality
UNIT-II	Frequency Response	9Hrs
bandwidth and Q	ries and Parallel Resonant circuits, Resonant freque uality factor, Variation of resonant frequency with circu ass, band pass, band elimination filter, – Problem Solving	it elements, Passive Filters -
UNIT-III	Two-port Networks	10Hrs
	es of two port networks, Various parameters of two port smission, Hybrid parameters and their relations – Finding	· · ·
Admittance, Tran various circuits, C Problem solving.	smission, Hybrid parameters and their relations – Finding Concept of transformed network, conversion from one par	g the two port parameters for rameter to other parameters—
Admittance, Tran various circuits, C Problem solving. UNIT-IV	smission, Hybrid parameters and their relations – Finding Concept of transformed network, conversion from one par DC Machines	g the two port parameters for rameter to other parameters– 10Hrs
Admittance, Tran various circuits, C Problem solving. UNIT-IV DC Generators: applications of dc DC Motors: Prin	smission, Hybrid parameters and their relations – Finding Concept of transformed network, conversion from one par	the two port parameters for rameter to other parameters– 10Hrs - types of generators – C generators EMF Equation,
Admittance, Tran various circuits, C Problem solving. UNIT-IV DC Generators: applications of dc DC Motors: Prin Characteristics of	smission, Hybrid parameters and their relations – Finding Concept of transformed network, conversion from one par DC Machines Principle of operation of DC machines – EMF equation - generators Magnetization and Load characteristics of DC ciple of operation of DC Motor, Types of Motors, Back I	the two port parameters for rameter to other parameters– 10Hrs - types of generators – C generators EMF Equation,

Textbooks:

- 1. William Hayt, Jack E. Kemmerly and Jamie Phillips, "Engineering Circuit Analysis", Mc Graw Hill, 9th edition, 2019.
- 2. Charles Alexander & Mathew Sadiku, "Fundamentals of Electric Circuits", 6th edition,McGraw HillPublications, 2016.
- 3. I. J. Nagrath&D.P.Kothari, "Electric Machines", 7th Edition, Tata Mc Graw Hill, 2005.

Reference Books:

- 1. M.E. Van Valkenberg, "Network Analysis", 3rd Edition, Prentice Hall (India), 1980.
- 2. B. R. Gupta, "Fundamentals of Electric Machines", Vandana Singhal, 3rd Edition, New ageInternational Publishers, 2005.
- T.K. Nagsarkar and M.S. Sukhija, "Basic Electrical Engineering", 3rd Edition, Oxford University Press2017.
- 4. S. Kamakashiah, "Electromachanics III", overseas publishers Pvt. Ltd.
- 5. V.K. Mehta an2. A. E. Clayton and N. N. Hancock, "Performance and design of DC machines", CBSPublishers, 2004.
- 6. M. G. Say, "Performance and design of AC machines", CBS Publishers, 2002.

Online Learning Resources:

https://onlinecourses.nptel.ac.in/noc21_ee71/preview

https://onlinecourses.nptel.ac.in/noc21_ee24/preview

Course Outcomes (CO):

After the completion of the course students will be:

CO1: Able to acquire knowledge about how to determine the transient response of R-L, R-C, R-L-C series circuits for D.C and A.C excitations.

CO2: Able to solve the problems on R L C circuits for different excitations using different approaches.

CO3: Analyze the complex circuits of R L C circuits

CO4: Able to solve the problems the e.m.f. generated on DC Generator.

CO5: Design winding diagrams of AC machines and equivalent circuit of transformer.

CO6: Able to acquire knowledge about how to determine the efficiency and regulation of single phase transformer and synchronous machine.

ELECTROMAGNETIC WAVES AND TRANSMISSION LINES

Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0414T	3:0:0	3	CIE:30	3 Hours	PCC
			SEE:70		

Course Objectives:

- To introduce fundamentals of static and dynamic electromagnetic fields.
- To teach the application of vector calculus for problem solving in Electromagnetic fields.
- To introduce Maxwell's equations in wave concept.
- To introduce the propagation of electromagnetic waves intransmission lines and their practical applications.
- To analyze the behaviour of electromagnetic waves propagated in normal andoblique incidences.

	Syllabus	
Unit –I	Static Electric Fields	10 Hrs
Recap of Vector Analysis	: Coordinate systems and transformation-Cartesian,	Cylindrical and
Spherical coordinate		
Recap of Vector Calculus:	Differential length area and volume, line surface and	volume integrals,

Del operator, gradient, divergent and curl operations.

Coulomb's Law, Electric Field Intensity – Fields due to Different Charge Distributions, Electric Flux Density, Gauss Law and Applications, Divergence Theorem, Electric Potential, Relations Between E and V, Maxwell's Two Equations for Electrostatic Fields, Energy Density, Convection and Conduction Currents, Dielectric Constant, Isotropic and Homogeneous Dielectrics, Continuity Equation, Relaxation Time, Poisson's and Laplace's Equations, Capacitance – Parallel Plate, Coaxial, Spherical Capacitors, Illustrative Problems.

-	-		
Unit –II		Static Magnetic Fields & Time varying Fields	10 Hrs

Magnetic Fields: Biot-Savart Law, Ampere's Circuital Law and Applications, Magnetic Flux Density, Maxwell's Two Equations for Magneto static Fields, Magnetic Scalar and Vector Potentials, Forces due to Magnetic Fields, Magnetic dipole, Ampere's Force Law, Inductances and Magnetic Energy, Illustrative Problems.

Faraday's Law and Transformer e.m.f, Inconsistency of Ampere's Law and Displacement Current Density, Maxwell's equations for time varying fields, Maxwell's Equations in Different Final Forms and Word Statements, Illustrative Problems

Unit –IIIBoundary Conditions and Uniform Plane Wave10 Hrs	
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Boundary Conditions of Electromagnetic fields: Dielectric-Dielectric and Dielectric-Conductor Interfaces, Wave Equations for Conducting and Perfect Dielectric Media.

Uniform Plane Waves – Definition, All Relations between E & H, Sinusoidal Variations, Wave Propagation in Lossless and Conducting Media, Conductors & Dielectrics – Characterization, Wave Propagation in Good Conductors and Good Dielectrics, Polarization, Illustrative Problems

Unit –IV	Reflection and Refraction of Plane Waves	9 Hrs
Reflection and	Refraction of Plane Wayes – Normal and Oblique Incidences	for both Perfect

Reflection and Refraction of Plane Waves – Normal and Oblique Incidences, for both Perfect Conductor and Perfect Dielectrics, Brewster Angle, Critical Angle and Total Internal Reflection, Poynting Vector, and Poynting Theorem, Illustrative Problems.

Unit	–V
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Transmission Lines

Transmission Lines: Introduction, Transmission line parameters, Transmission line equivalent circuit, Transmission line equations and their solutions in their phasor form, input impedance, standing wave ratio, Transmission of finite length- half wave, quarter wave transmission line, Smith chart, graphical analysis of transmission lines using Smith chart, stub matching- single and double stub matching, Illustrative Problems

Text Books:

- 1. Matthew N.O. Sadiku, "Elements of Electromagnetics", 4th edition. Oxford Univ. Press, 2008.
- 2. William H. Hayt Jr. and John A. Buck, "Engineering Electromagnetics", 7thedition., TMH, 2006.

References:

- 1. E.C. Jordan and K.G. Balmain, "Electromagnetic Waves and Radiating Systems", 2ndEdition, PHI, 2000.
- 2. John D. Krauss, "Electromagnetics", 4th Edition, McGraw-Hill publication, 1999.
- 3. Electromagnetics, Schaum's outline series, 2nd Edition, Tata McGraw-Hill publications, 2006.

Course Outcomes:

After the completion of the course students will able to:

CO1: Describe vector algebra, coordinate systems, vector calculus and fundamentals of electrostatic

fields' duo to point, line, sheet, and volume charges using Coulomb's law and Gauss's law.

- **CO2:** Calculate magnetic field intensity using Biot-Savart's law and Ampere's law
- CO3: Analyze Maxwell's equations for Time-varying EM fields.
- **CO4:** Analyze boundary conditions of EM fields for dielectric-dielectric, dielectric-conductor media.
- **CO5:** Describe the propagation of UPW in good conductor, good dielectric, Dielectric-Dielectric, Dielectric-Conductor media.

CO6: Analyze the concept of transmission lines and their applications.

Course Code	L: T:P	Credits	Exam. Marks	Exam Du	ration	Course Type
22A0415T	3:0:0	3	CIE:30 SEE:70	3 Hou	irs	PCC
Course Objectiv	es:	- I		•		
	1		transmission power	• • •	g time	and frequency
-	-	-	various modulation			
	•		nes various applicat		1.	To introduce
	• •		hniques by using signiques such as PC	· 1	0	
	U		erent source coding		various	s shift keynig
-		•	and error correction	-	e block	codes, cyclic
	convolution cod	U		0		
			Syllabus			
		Unit –I			-	10 Hrs
-			tion, Amplitude M			·
			ower relations in Al			
			ves - Envelope detec			
	-		of DSBSC Waves as Loop, SSB modu			
			Phase discrimination		-	
			tigial side band mod		101 80	
	-	Unit –II			-	10 Hrs
Angle Modulati	on: Basic con					
	on Duble com	cepts of File	ase Modulation, Fr	equency Mo	dulatior	n: Single tone
8		1		1 1		U U
frequency modula	ation, Spectrum	Analysis of	Sinusoidal FM Wa	ve using Bes	sel func	ctions, Narrow
frequency modula band FM, Wide	ation, Spectrum band FM, Co	Analysis of nstant Avera	Sinusoidal FM Wa nge Power, Transm	ve using Bes ission bandw	sel func vidth of	ctions, Narrow f FM Wave -
frequency modula band FM, Wide Generation of FM	ation, Spectrum band FM, Co A Signal- Arms	Analysis of nstant Avera strong Metho	Sinusoidal FM Wa age Power, Transm od, Detection of FM	ve using Bes ission bandw I Signal: Bal	sel fund vidth of lanced s	ctions, Narrow f FM Wave slope detector
frequency modula band FM, Wide Generation of FM	ation, Spectrum band FM, Co A Signal- Arms p, Comparison	Analysis of nstant Avera strong Metho	Sinusoidal FM Wa nge Power, Transm	ve using Bes ission bandw I Signal: Bal	sel fund vidth of lanced s	ctions, Narrow f FM Wave slope detector
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun	ation, Spectrum band FM, Co A Signal- Arms p, Comparison o ication Tool.	Analysis of nstant Avera strong Metho of FM and A	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr	ve using Bes ission bandw I Signal: Bal he receiver.Ap	sel func vidth of lanced s pplicatio	ctions, Narrow f FM Wave - slope detector, on of SIMTEL
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun	ation, Spectrum band FM, Co A Signal- Arms p, Comparison ication Tool. Noise: Types	Analysis of nstant Avera strong Metho of FM and A of Noise, Re	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, No	ve using Bes ission bandw I Signal: Bal he receiver.Ap	sel func vidth of lanced s pplicatio	ctions, Narrow f FM Wave - slope detector, on of SIMTEL
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to	ation, Spectrum band FM, Co A Signal- Arms p, Comparison ication Tool. Noise: Types	Analysis of nstant Avera strong Metho of FM and A of Noise, Re	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, No	ve using Bes ission bandw I Signal: Bal he receiver.Ap	sel func vidth of lanced s pplicatio DSB, S	ctions, Narrow f FM Wave - slope detector, on of SIMTEL
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types mphasis and De- m: Types of Pu	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro -emphasis in <u>Unit –III</u> Ilse modulati	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM.	ve using Bes ission bandw I Signal: Bal the receiver.Ap ise in AM, I d PPM. Con	sel func vidth of lanced s pplicatio DSB, S	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types mphasis and De- m: Types of Pu	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro -emphasis in <u>Unit –III</u> Ilse modulati	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM.	ve using Bes ission bandw I Signal: Bal the receiver.Ap ise in AM, I d PPM. Con	sel func vidth of lanced s pplicatio DSB, S	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza	ation, Spectrum band FM, Co A Signal- Arms p, Comparison ication Tool. Noise: Types mphasis and De- m: Types of Pu le Modulation:	Analysis of nstant Avera strong Metho of FM and A of Noise, Re -emphasis in Unit –III Ilse modulati PCM Gener	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM.	ve using Bes ission bandw I Signal: Bal the receiver.Ap ise in AM, I d PPM. Con- ruction, Quar	sel func vidth of lanced s pplication DSB, S	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non-
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coc Uniform Quantiza PCM and DM.	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types mphasis and De- m: Types of Pu le Modulation: ation and Comp	Analysis of nstant Avera strong Metho of FM and A of Noise, Re <u>-emphasis in</u> <u>Unit –III</u> Ilse modulati PCM Gener panding, DPC	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM	ve using Bes ission bandw I Signal: Bal the receiver. Ap ise in AM, I d PPM. Con ruction, Quar I, DM and A	sel func vidth of lanced s pplication DSB, S DSB, S nparisor ntization daptive	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse	ation, Spectrum band FM, Co A Signal- Arms p, Comparison o ication Tool. Noise: Types mphasis and De- n: Types of Pu le Modulation: ation and Comp Transmission:	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro <u>-emphasis in</u> Unit –III Ilse modulati PCM Gener panding, DPC	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM h, Matched Filter, F	ve using Bes ission bandw I Signal: Bal he receiver. Ap ise in AM, I de PPM. Con- ruction, Quar I, DM and A Properties of	sel func vidth of lanced s pplication DSB, S nparison ntization daptive	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Communi Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol	Analysis of nstant Avera strong Metho of FM and A of Noise, Re -emphasis in Unit –III Ilse modulati PCM Gener panding, DPC	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Not FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM n, Matched Filter, F e (ISI), Nyquist crit	ve using Bes ission bandw I Signal: Bal ie receiver. Ap ise in AM, I ise in AM, I d PPM. Con- ruction, Quar I, DM and A properties of erion for dis	sel func vidth of lanced s pplication DSB, S DSB, S DSB, S Application daptive Matcheo tortion	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission	ation, Spectrum band FM, Co A Signal- Arms p, Comparison o ication Tool. Noise: Types mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative	Analysis of nstant Avera strong Metho of FM and A of Noise, Re -emphasis in Unit –III Ilse modulati PCM Gener panding, DPC	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM h, Matched Filter, F	ve using Bes ission bandw I Signal: Bal ie receiver. Ap ise in AM, I ise in AM, I d PPM. Con- ruction, Quar I, DM and A properties of erion for dis	sel func vidth of lanced s pplication DSB, S DSB, S DSB, S Application daptive Matcheo tortion	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Communi Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise	ation, Spectrum band FM, Co A Signal- Arms p, Comparison o ication Tool. Noise: Types mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro -emphasis in Unit –III Ilse modulati PCM Gener panding, DPC Introduction Interference level coding	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Not FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM n, Matched Filter, F e (ISI), Nyquist crit	ve using Bes ission bandw I Signal: Bal ie receiver. Ap ise in AM, I ise in AM, I d PPM. Con- ruction, Quar I, DM and A properties of erion for dis	sel func vidth of lanced s pplication DSB, S DSB, S DSB, S DSB, S Matcheo tortion ission, f	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband QAM,
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission	ation, Spectrum band FM, Co A Signal- Arms p, Comparison o ication Tool. Noise: Types mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative	Analysis of nstant Avera strong Metho of FM and A of Noise, Re -emphasis in Unit –III Ilse modulati PCM Gener panding, DPC	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Not FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM n, Matched Filter, F e (ISI), Nyquist crit	ve using Bes ission bandw I Signal: Bal ie receiver. Ap ise in AM, I ise in AM, I d PPM. Con- ruction, Quar I, DM and A properties of erion for dis	sel func vidth of lanced s pplication DSB, S DSB, S DSB, S DSB, S Matcheo tortion ission, f	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Communi Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission Equalization, Eye	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative pattern.	Analysis of nstant Avera strong Metho of FM and A of Noise, Re -emphasis in Unit –III Ilse modulati PCM Gener banding, DPC Introduction Interference level coding Unit –IV	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Not FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM n, Matched Filter, F e (ISI), Nyquist crit	ve using Bes ission bandw I Signal: Ball the receiver. Ap ise in AM, I ise in AM, I d PPM. Con- ruction, Quar I, DM and A properties of erion for dis PAM transm	sel func vidth of lanced s pplication DSB, S DSB, S nparison ntization daptive Matcheo tortion ission,	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband QAM, 9 Hrs
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission Equalization, Eye	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- n: Types of Pu de Modulation: ation and Comp Transmission: c, Inter Symbol on, Correlative pattern.	Analysis of nstant Avera strong Metho of FM and A of Noise, Re- emphasis in Unit –III Ilse modulati PCM Gener banding, DPC Introduction Interference level coding Unit –IV on: Introduct	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Not FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM n, Matched Filter, F e (ISI), Nyquist crit g, Baseband M-ary	ve using Bes ission bandw I Signal: Bal he receiver. Ap ise in AM, I de PPM. Con- ruction, Quar I, DM and A Properties of erion for dis PAM transm	sel func vidth of lanced s pplication DSB, S DSB, S nparison ntization daptive Matcheo tortion ission, of Aodel, Q	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband QAM, 9 Hrs Gram-Schmidt
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Community Introduction to Receivers, Pre-En Pulse Modulation TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission Equalization, Eye Digital Pass ban Orthogonalization	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative pattern. Id Transmission	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro -emphasis in Unit –III Ilse modulati PCM Gener anding, DPC Introduction Interference level coding Unit –IV on: Introduc	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM h, Matched Filter, F e (ISI), Nyquist crit g, Baseband M-ary	ve using Bes ission bandw I Signal: Ball ie receiver. Ap ise in AM, I ise in AM, I ind PPM. Con- ruction, Quar I, DM and A Properties of erion for dis PAM transm	sel func vidth of lanced s pplication DSB, S DSB, S nparison ntization daptive Matcheo tortion ission, of Model, O f bank o	ctions, Narrow f FM Wave - slope detector, on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband QAM, 9 Hrs Gram-Schmidt f correlators in
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Commun Introduction to Receivers, Pre-En Pulse Modulatio TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission Equalization, Eye Digital Pass ban Orthogonalization noise, Correlation	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- n: Types of Pu de Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative e pattern. Inter Symbol on, Correlative e pattern.	Analysis of nstant Avera strong Metho of FM and A of Noise, Re- emphasis in Unit –III Ilse modulati PCM Gener banding, DPC Introduction Interference level coding Unit –IV on: Introduc ometric Inter	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM h, Matched Filter, F e (ISI), Nyquist crit g, Baseband M-ary	ve using Bes ission bandw I Signal: Bal he receiver. Ap ise in AM, I d PPM. Con- ruction, Quar I, DM and A Properties of erion for dis PAM transm ansmission M Response of als with unkn	sel fund vidth of lanced s pplication DSB, S DSB, S nparison ntization daptive Matched tortion ission, of Model, Q f bank o own pha	ctions, Narrow f FM Wave slope detector on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Error less baseband QAM, 9 Hrs Gram-Schmidt f correlators in ase.
frequency modula band FM, Wide Generation of FM Phase locked loo Analog Community Introduction to Receivers, Pre-En Pulse Modulation TDM. Pulse Coo Uniform Quantiza PCM and DM. Baseband Pulse rate due to noise binary transmission Equalization, Eye Digital Pass ban Orthogonalization Coherent Digital	ation, Spectrum band FM, Co A Signal- Arms p, Comparison of ication Tool. Noise: Types of mphasis and De- m: Types of Pu le Modulation: ation and Comp Transmission: b, Inter Symbol on, Correlative pattern. d Transmission procedure, Geo a receiver, Proba Modulation Scl	Analysis of nstant Avera strong Metho of FM and A of Noise, Ro -emphasis in Unit –III Ilse modulati PCM Gener anding, DPC Introduction Interference level coding Unit –IV on: Introduc ometric Inter ability of Erro hemes – ASF	Sinusoidal FM Wa age Power, Transm od, Detection of FM M, Super heterodyr eceiver Model, Nor FM. on- PAM, PWM ar ration and Reconstr CM, Adaptive DPCM h, Matched Filter, F e (ISI), Nyquist crit g, Baseband M-ary tion, Pass band Tra pretation of Signals or, Detection of Signals	ve using Bes ission bandw I Signal: Ball the receiver. Ap ise in AM, I and PPM. Con- ruction, Quar I, DM and A Properties of erion for dis PAM transm ansmission M Response of als with unkn PSK, Non-co	sel fund vidth of lanced s pplication DSB, S DSB, S DSB, S DSB, S Matcheo tortion ission, C Matcheo tortion ission, C Model, C f bank o own pha herent 1	ctions, Narrow f FM Wave slope detector on of SIMTEL SB, and FM 10 Hrs n of FDM and n Noise, Non- DM, Noise in d Filter, Erron less baseband QAM, 9 Hrs Gram-Schmidt f correlators in ase. BFSK, and

Unit –V	9 Hrs
Channel Coding: Error Detection & Correction - Repetition & Parity Cha	eck Codes, Interleaving
Code Vectors and Hamming Distance, Forward Error Correction (FEC) Sy	stems, Automatic
Retransmission Query (ARQ) Systems, Linear Block Codes - Matrix Repre	sentation of Block
Codes, Convolutional Codes – Convolutional Encoding, Decoding Methods.	
Text Books:	
1. Simon Haykin, "Communication Systems", John Wiley& Sons, 4th Editio	n. 2004.
 B. P. Lathi, Zhi Ding "Modern Digital and Analog Communication System 	
References:	
1. Sam Shanmugam, "Digital and Analog Communication Systems", John W	•
2. Bernard Sklar, F. J. Harris, "Digital Communications: Fundamentals and A	Applications",
Pearson Publications, 2020.	
3. Taub and Schilling, "Principles of Communication Systems", Tata McGra	w Hill, 2007.
Course Outcomes:	
After the completion of the course students will able to:	
CO1: Recognize the basic terminology used in analog and digital communic transmission of information/data.	cation techniques for
CO2: Explain the basic operation of different analog and digital communicat	ion systems at baseband
and pass band level.	
CO3: Compute various parameters of baseband and pass band transmission basic engineering knowledge.	schemes by applying
CO4: Analyze the performance of different modulation & demodulation tech problems in the presence of noise.	niques to solve complex
CO5: Evaluate the performance of all analog and digital modulation tech merits and demerits of each one of them in terms of bandwidth and pow	-
CO6: Understand the basics of information theory and error correcting codes.	

		LIN	EAR IC APPLIC	CATIONS	
Course Code	L: T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0416T	3:0:0	3	CIE:30 SEE:70	3 Hours	РСС
To teachTo teachTo introd	uce the basic the linear an the theory of tuce the conc	d non-linear f ADC and D cepts of wave	AC.	erational amplifiers.	cial function ICs.
			Syllabus		
		Unit	-I		10 Hrs
Inverting, Non-I and Integrators,	nverting, and Comparate	d Differentia or and its	l, Instrumentation	am of Op-Amp, Moo Amplifier, AC Ampli hmitt Trigger, Introc tage Regulators.	fier, Differentiators
	Unit –II				10 Hrs
	Astable Op	erations, App	-	Vave, IC555 Timer - F PLL - Block Schematic	-
	Unit –III				10 Hrs
DAC, R-2R lade	ler DAC, Inv Ype ADC, S	verted R-2R	DAC, Different T	Fifferent types of DAC Types of ADCs - Parall C and Dual Slope AD	lel ComparatorType
	Unit –IV				9 Hrs
Specifications a	nd Applicat der, Priority	ions of TTI y Encoder,	2-74XX & CMO	ed Circuits, Combina S 40XX Series ICs e-multiplexer, Paralle	- Code Converters,
	Unit –V				9 Hrs
Sequential Logi			-	ommonly available 74. lip-flops, Synchronou	

Text Books:

- 1. Linear Integrated Circuits D. Roy Chowdhury, New Age International (p) Ltd, 2ndEdition,2003.
- 2. Op-Amps & Linear ICs Ramakanth A. Gayakwad, PHI, 2003.
- 3. Digital fundamentals Floyd and Jain, Pearson Education,8th Edition ,2005.

References:

- 1. Op Amps & Linear Integrated circuits-Concepts and Applications James M.Fiore, Cengage Learning/Jaico, 2009.
- 2. Operational Amplifiers with linear integrated circuits by K.Lal kishore-Pearson, 2009.
- 3. Linear integrated circuits and applications-Salivahana,TMH.
- 4. Modern digital electronics-RP Jain-4/e-TMH,2010.
- 5. Digital design principles and practices-John.F.Wakerly 3/e,2005.

Course Outcomes:

After the completion of the course students will able to:

CO1: List out the characteristics of Linear and Digital ICs.

CO2: Discuss the various applications of linear & Digital ICs.

CO3: Solve the application-based problems related to linear and digital ICs.

CO4: Analyze various applications-based circuits of linear and digital ICs.

CO5: Design the circuits using either linear ICs or Digital ICs from the given specifications.

CO6: Understand the various type of Memory Architectures using the Digital ICs.

LINEAR IC APPLICATIONS LAB

Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0417T	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PCC

Course Objectives:

• To verify the theoretical concepts practically from all the experiments.

- To analyze the characteristics of Diodes, BJT, MOSFET.
- To design the amplifier circuits from the given specifications.
- To Model the electronic circuits using tools such as PSPICE/Multisim.

Syllabus

MINIMUM TWELVE EXPERIMENTS MUST CONDUCT: (Six from each part A & B)

PART -A:

TO VERIFY THE FOLLOWING FUNCTIONS

- 1. Adder, Subtractor, Comparator Circuits using IC 741 OP AMP.
- 2. Integrator and Differentiator Circuits using IC 741 OP AMP.
- 3. Active Low pass, High pass Butterworth (Second Order).
- 4. RC Phase Shift and Wien Bridge Oscillators using IC 741 Op-Amp.
- 5. IC 555 Timers Monostable Operation Circuits.
- 6. Schmitt Trigger Circuits using IC 741 and IC 555.
- 7. IC 565 –PLL applications
- 8. Voltage Regulator using IC 723, Three terminal voltage regulators 7805,7809, 7912
- 9. Sample and Hold LF398 IC

PART –B:

TO VERIFY THE FOLLOWING FUNCTIONALITY OF THE FOLLOWING 74 SERIES TTL ICS

- 1. D-Flip Flop (74LS74) and JK Master Slave Flip-flop(74LS73)
- 2. Decade counter (74LS90) and Up-down Counter (74LS192)
- 3. Universal shift Register(74LS194/195)
- 4. 3-8 Decoder using (74LS138).
- 5. 4 bit comparator (74LS85)
- 6. 8x1 Multiplexer 74LS151 and 2x4 DeMultiplexer-74155.
- 7. RAM 16X4 -74189(read and write operation)
- 8. Stack and queue implementation using RAM, 74189

Equipment required for Laboratories:

- 1. RPS
- 2. CRO
- 3. Function Generator
- 4. Multi Meters
- 5. Bread Boards

6. Components: - IC741, IC555, IC566, IC1496, IC723, 7805, 7809, 7912 and other Essential components.

7. Analog IC Tester

Course Outcomes:

After the completion of the course students will able to:

CO1: Understand the characteristics of Linear and Digital ICs.

CO2: Design circuits using operational amplifiers for various applications

CO3: Analyze various applications-based circuits of linear and digital ICs

CO4: Design various combinational circuits using various Digital Integrated IC's.

CO5: Design various Sequential Logic circuits and Memories circuits using various DigitalIntegrated IC's.

CO6: Understand differences between Linear and Digital Integrated IC's.

Course Code	L: T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0206P	0: 0:3:0	1.5	CIE: 30 SEE:70	3Hours	ESC
Course Objectiv				<u> </u>	
	•	• •	ort network parame	eters	
• To do experime					
• To do experime	ents on AC Ma				
1. Response of	PL and PC ci		COF EXPERIM	ENTS	
-		-	r the given two po	rt natwork	
	-			of a given two port net	works
		•	ond Farameters o	a given two port ner	tworks
4. OCC of DC	-				
5. Load charac		•			
6. Load charac		•			
7. Load charac		shunt moto	or		
8. Swinburne's					
9. Speed contro					
10. OC & SC te					
11. Load test on	1 0				
	0		nator by Synchron at least 10 experin	-	
Reference Book			at least 10 experim	nents.	
		nre, "Laborat	tory Manual for El	lectrical Machines" I.	K International
Publishing H	House Pvt. Ltd	l, 2017.			
		"A Laborato	ory Course in Elect	rical Machines" NEM	I Chand & Bros
Web References		lectronics by	u Drof D.C. Forma	ndea Department of	CDD
	itg.vlabs.ac.in		y PIOI. D.G. Ferna	ndes, Department of	LEL
-	-		20experiments.ht	ml?domain=Electrica	l Engineering
3. http://vlabs.	iitb.ac.in/vlabs	s-dev/vlab_t	pootcamp/bootcam	np/Sadhya/experiment	list.html
Course Outcon					
After completio	n of the cours	e, students w	vill be able to:		
CO1: Determin	e the various p	parameters e	xperimentally		
CO2: Understa	nd various cha	aracteristics	of DC generators.		
CO3: Understa	nd various cha	aracteristics	of DC motors.		
CO4: Predetern	nine the effici	ency and reg	gulation of a 1-φ tr	ansformer.	
CO5: Predetern	nine the effici	ency and reg	gulation of an Alte	rnator.	
CO6: Determin					

Course Code	L: T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0418P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PCC
Course Objecti	ves:				
• To design an applications	nd implemen	•		techniques. dulation techniques an	d their
5			Syllabus		
			OF EXPERIMEN	TS:	
Note: Conduct	any six expe	eriments from	n each section.		
Section-A					
1. AM Modulati	on and Demo	odulation			
2. DSB-SC Mod	lulation and I	Demodulatior	1		
3. FM Modulation	on and Demo	dulation			
4. Radio receive	r measureme	ents			
5. PAM Modula	tion and Den	nodulation			
6. PWM Modula	ation and Der	nodulation			
7. PPM Modulat	ion and Dem	odulation			
Section-B					
1. Sampling The	orem.				
2. Time Division	n Multiplexin	g			
3. Delta Modula	tion and Den	nodulation			
4. PCM Modula	tion and Den	nodulation			
5. BFSK Modula	ation and De	modulation			
6. QPSK Modul	ation and De	modulation			
7. DPSK Modul	ation and De	modulation			
Tools / Equipm	ent Require	d:			
1. CROs: 20MH	Z				
2. Function Gen	erators: 2MH	Iz			
3. Spectrum Ana	lyzer				
4. Regulated Por	wer Supplies	: 0-30V			
7 A 1 1D	····	ation and Day	nodulation Trainer l	Kito	

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Know about the usage of equipment/components/software tools used to conduct the experiments analog and digital modulation techniques.
- **CO2:** Conduct the experiment based on the knowledge acquired in the theory about modulation and demodulation schemes to find the important metrics of the communication system experimentally.
- **CO3:** Analyze the performance of a given modulation scheme to find the important metrics of thesystem theoretically.
- **CO4:** Draw the relevant graphs between important metrics of the system from the observed measurements.

CO5: Compare the experimental results with that of theoretical ones and infer the conclusions.

CO6: Design and implement different modulation and demodulation techniques.

PCB & CIRCUIT DESIGNING

Course Code	L: T:P	Credits	Exam.Marks	Exam Duration	Course Type
22A0419P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	SC

Course Objectives:

- This course will teach how to design and fabricate PCB for prototyping as well as in Industrial Production environment.
- This will help students to innovate faster with electronics technology.

Syllabus	Total Hours: 48
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UNIT I

Fundamental of basic electronics: Component identification, Component symbols & their footprints, understand schematic, creating new PCB, browsing footprints libraries, Setting up the PCB layers, Design rule checking, Track width selection, Component selection, Routing and completion of the design

UNIT II

Introduction to PCB: Definition and Need/Relevance of PCB, Background and History of PCB, Types of PCB, Classes of PCB Design, Terminology in PCB Design, Different Electronic design automation(EDA)tools and comparison.

UNIT III

PCB Design Process: PCB Design Flow, Placement and routing, Steps involved in layout design, Artwork generation Methods - manual and CAD, General design factors for digital and analogue circuits, Layout and Artwork making for Single-side, double-side and Multilayer Boards, Design for manufacturability, Design-specification standards.

Practice Exercises: Any twelve experiments are to be done

- 1. Practice following PCB Design steps
 - Schematic Design: Familiarization of the Schematic Editor, Schematic creation, Annotation, Net list generation.
 - Layout Design: Familiarization of Foot print Editor, Mapping of components, Creation of PCB layout Schematic.
 - Create new schematic components.
 - Create new component footprints.
- 2. Regulator circuit using 7805
- 3. Inverting Amplifier or Summing Amplifier using op-amp
- 4. Full-wave Rectifier
- 5. Astable multivibrator and Monostable multivibrator using IC555
- 6. Calling bell circuit and Temperature measuring circuit.
- 7. Automatic street light using LDR sensor.
- 8. LED Chaser using 4017B decoded counter and IC555.
- 9. Water level indicator using IC555.
- 10. Sequenced display of traffic lights using IC555 and IC74LS190.
- 11. Design an 8051 Development board having Power section consisting of IC7805, capacitor, resistor, headers, LED.

- 12. Design an 8051 Development board having Serial communication section consisting of MAX 232, Capacitors, DB9connector, Jumper, LEDs
- Design an 8051 Development board having Reset & Input/output sections consisting of 89C51 Microcontroller, Electrolytic Capacitor, Resistor, Jumper, Crystal Oscillator, Capacitors.
- 14. Fabricate a single-sided PCB, mount the components, and assemble them in a cabinet for any one of the circuits mentioned in the above exercises.

Text Book:

1. Printed circuit board design ,fabrication assembly and testing By R. S. Khandpur, Tata McGraw Hill 2006

References:

- 1. Printed circuit Board Design and technology, Walter C. Bosshart
- 2. Printed Circuits Handbook, Sixth Edition, by Clyde F. Coombs, Jr, Happy T. Holden, Publisher: McGraw-Hill Education Year: 2016

Course Outcomes:

After the completion of the course students will able to:

CO1: Understand a single layer PCB

CO2: Understand a multilayer PCB

CO3: Apply PCB for various applications.

CO4: Design PCB for 8051

CO5: Create and fabricate a PCB

CO6: Evaluate and test a PCB

			IENTAL STUDI E, AI&ML, ECE	. –	2)	
Course Code	L: T:P:S	Credits	Exam Marks	Exam Di	-	Course Type
22A0027M	3: 0:0:0	0		3 Hours		MC
Course Objectives	:					
0	udents to get aw	vareness on er	vironment.			
• To understand	the importance of	of protecting	natural resources,	ecosystem	s for futur	e generations
andpollution ca	uses due to the	day to day ac	tivities of human	life.		
• To save earth f	rom the invention	ons by the eng	gineers.			
		Syl	labus		Total	Hours: 48 Hrs
Unit- I	Multidis	cinlinary Na	ture of Environ	nental		10Hrs
	Withdie	- •	l Natural Resour			
Definitions commo	nonta of Enviro				Dublic Arr	
Definitions, compo	onents of Enviro	innent, scope	and importance -	-need for f	Public Aw	areness
Renewable and not	n-renewable res	ources –Fore	st resources – Use	and over -	– exploita	tion,
deforestation,					Ĩ	
- Food resources:	World food pr	roblems, char	nges caused by a	griculture	and over	grazing, effects
ofmodern agricultu	ire, fertilizer-pe	sticide proble	ms, water logging	g, salinity,	case studi	ies.
Unit-II Concept of an eco decomposers– Eco	osystem. – Stru plogical success	Ecos acture and fu sion – Food	ystems unction of an eco chains, food we	osystem – bs and eco	Producers	9Hrs s, consumers an oyramids –
Unit-II Concept of an eco decomposers– Eco Introduction, types a. Grassland	osystem. – Stru plogical success , characteristic f ecosystem.	Ecos acture and fu sion – Food	ystems unction of an eco chains, food we	osystem – bs and eco	Producers	9Hrs s, consumers an oyramids –
Unit-II Concept of an eco decomposers– Eco Introduction, types	osystem. – Stru plogical success , characteristic f ecosystem.	Ecos acture and fu sion – Food	ystems unction of an eco chains, food we	osystem – bs and eco	Producers	9Hrs s, consumers an oyramids –
Unit-II Concept of an eco decomposers– Eco Introduction, types a. Grassland	osystem. – Stru ological success , characteristic f ecosystem. osystem	Ecos acture and fu sion – Food ceatures, struc	ystems unction of an eco chains, food we	osystem – bs and eco of the follo	Producers	9Hrs s, consumers an oyramids –
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Concept of an eco decomposers– Eco Introduction, types a. Grassland b. Desert eco Unit-III Introduction De consumptive use, diversity nation	osystem. – Stru plogical success , characteristic f ecosystem osystem efinition: gene Productive use – Hot spots o	Ecos icture and fu sion – Food features, struc Biodiversity tic, species e, social, eth of biodiversit	ystems inction of an eco chains, food we cture and function And Its Conserv and ecosystem ical, aesthetic an ty – Threats to	esystem – bs and eco of the follo ration diversity d option v biodiversi	Producers ological p owing eco – Value values – ty: habita	9Hrs s, consumers an oyramids – system 10Hrs e of biodivers India as a me at loss, poachi
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From Unsustainable to Sustainable development – Urban problems related to energy Environment Protection Act. – Air (Prevention and Control of Pollution) act

Definition, Cause, effects and control measures of:

- a. Global warming
- b. Acid rain
- c. Ozone layer depletion

Field Work: Visit to a local area to document environmental assets River/forest grassland/hill/mountain –Visit to a local polluted site-Urban/Rural/Industrial/Agricultural Study of common plants, insects, and birds – river, hill slopes, etc.

Textbooks:

- 1. Text book of Environmental Studies for Undergraduate Courses- Erach Bharucha forUniversity Grants Commission, Universities Press.
- 2. Environmental Studies- Kaushik & kaushik, New Age Pubilishers.

Reference Books:

- 1. Environmental studies- R.Rajagopalan, Oxford University Press.
- 2. Comprehensive Environmental studies- J.P.Sharma, Laxmi publications.

Course Outcomes (CO):

After completion of the course, students will be able to:

CO1: Recognize the knowledge about environment, natural resources and different techniques involved in its conservation.

CO2: Describe the information about different eco-systems and its functions.

CO3: Understand flow and bio-geo- chemical cycles and ecological pyramids.

CO4: Explain the different types of bio-diversity along with values and conservation methods.

CO5: Predict various environmental pollutions and able to design the environmentally friendly process inengineering.

CO6: Apply the sustainable development concepts in life, society and industry.

Sl. Category		Course	Course Title		Hours per week			
No.		Code		L	Т	P	С	
1	PCC	22A0420T	Digital System Design through Verilog	3	0	0	3	
2	PCC	22A0213T	Control Systems	3	0	0	3	
3	PCC	22A0421T	Antennas & MicrowaveEngineering	3	0	0	3	
4	PEC		Professional Elective-I	3	0	0	3	
5	OEC		Open Elective-I	3	0	0	3	
6	PCC (Lab)	22A0425P	Digital System Design throughVerilog Lab	0	0	3	1.5	
7	PCC (Lab)	22A0426P	Antennas & MicrowaveEngineering Lab	0	0	3	1.5	
8	SC	22A0028P	Skill Advanced Course: Soft Skills	1	0	2	2	
9	MC	22A0526	Mandatory Course: Design Thinking and Innovation	2	0	0	0	
		22A0459	Evaluation of Community Service Project	0	0	0	1.5	
		Total credits					21.5	

S. No.	Course Code	Name of the Professional Elective-I
1	22A0422T	Data Communication &Networks
2	22A0423T	Information Theory and Coding
3	22A0424T	Industrial Electronics

S. No.	Course Code	Name of the Open Elective-I
1	22A0512T	Data base Management Systems
2	22A0214Ta	Power Electronics
3	22A0332Tc	Fundamentals of Drone Technology
4	22A0149T	Building Materials

Category	Credits
Professional Core Courses (PCC)	12
Professional Elective Courses (PEC)	3
Open Elective Courses (OEC)	3
Skill Advanced Course (SC)	2
Summer Internship	1.5
Total	21.5

	DIGIT	AL SYSTEM	DESIGN THRO	UGH VERILOG	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0420T	3:0:0	3	CIE:30 SEE:70	3 Hours	PCC
Course Object	ives:				
HDL				eling of digital circ	
	its aims to pr ital circuits.	actical experier	nce by designing,	modelling, implemer	nting and verifyin
-			tanding of the dift HDL programs us	fferent technologies sing provided	related to HDLs
		Syllabu	15		Total Hours: 48
			Basics of Verilog		10 Hrs
Introduction to) Verilog HI	DL: Verilog as	HDL, Levels of D	esign Description,Be	ehavioural
Module. Language Cor	nstructs and	Conventions	Introduction, Ke	s, Programming Lang ywords, Identifiers, ata Types, Scalars a	White Space,
Operators.					10 11
~			leling and Data f		10 Hrs
mustrative Exa	mples, Trista			odule Structure, Oth Primitives, Design	
Gate Primitives Modeling at 1	, Gate Delay, Dataflow Le ignments, As	te Gates, Arra Strengths and evel: Introduct ssignment to Ve	y of Instances of Contention Resolu- tion, Continuous ector, Operators.	Primitives, Design	of Flip-Flops wit
Gate Primitives Modeling at I Continuous Ass	, Gate Delay, Dataflow Le ignments, As Unit	te Gates, Arra Strengths and evel: Introduct ssignment to Vo –III:: Behavio	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Tral Modeling	Primitives, Design o ation, Net Types. Assignment Struct	of Flip-Flops wit ture, Delays and 10 Hrs
Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking	, Gate Delay, Dataflow Le ignments, As Unit odeling: Int gnments with Assignments, peat' Constru Parallel Block	te Gates, Arra Strengths and evel: Introduct ssignment to Vo –III:: Behavio roduction, Ope n Delays, 'Wait The 'Case' Sta act, for loop, 'T	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Tral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'if 'he Disable' Const	Primitives, Design of the other states of the	of Flip-Flops wit ture, Delays and 10 Hrs Construct, Alway evel, Blocking an Assign- De-Assign Forever Loop,
Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking A Constructs, 'Rep sequential and H	, Gate Delay, Dataflow La ignments, As Unit odeling: Int gnments with Assignments, peat' Constru Parallel Block Unit -	te Gates, Arra Strengths and evel: Introduct ssignment to Vo –III:: Behavio roduction, Open Delays, 'Wait The 'Case' Sta act, for loop, 'T as. -IV:: Switch L	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Tral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'iff The Disable' Const evel Modeling	Primitives, Design on ation, Net Types. Assignment Struct ignments, 'Initial' (gn at Behavioral Le f-Else' Constructs, 'A cruct, 'While Loop', H	of Flip-Flops wit ture, Delays and 10 Hrs Construct, Alway evel, Blocking an Assign- De-Assign Forever Loop, 9 Hrs
Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking A Constructs, 'Rep sequential and I Switch Level I	, Gate Delay, Dataflow La ignments, As Unit odeling: Int gnments with Assignments, peat' Constru Parallel Block Unit - Modeling: B	te Gates, Arra Strengths and evel: Introduct ssignment to Vo -III:: Behavio roduction, Opo n Delays, 'Wait The 'Case' Sta ict, for loop, 'T cs. -IV:: Switch L asic Transistor	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Dral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'if 'he Disable' Const evel Modeling : Switches, CMOS	Primitives, Design on ation, Net Types. Assignment Struct ignments, 'Initial' O gn at Behavioral Le f-Else' Constructs, 'A	of Flip-Flops wit sure, Delays and 10 Hrs Construct, Alway evel, Blocking an Assign- De-Assig Forever Loop, 9 Hrs ional Gates, Tim
Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking A Constructs, 'Rep sequential and I Switch Level I Delays with Sw NAND, NOR a	, Gate Delay, Dataflow Lo ignments, As Unit odeling: Int gnments with Assignments, peat' Constru Parallel Block Unit - Modeling: B vitch Primitiv nd XOR.	te Gates, Arra Strengths and evel: Introduct ssignment to Vo -III:: Behavio roduction, Ope n Delays, 'Wait The 'Case' Sta ict, for loop, 'T cs. -IV:: Switch L asic Transistor yes, instantiatio	y of Instances of Contention Resolu- tion, Continuous ector, Operators. oral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'if 'he Disable' Const evel Modeling : Switches, CMOS on with strengths a	Primitives, Design on ation, Net Types. Assignment Struct ignments, 'Initial' Ogn at Behavioral Le f-Else' Constructs, 'A cruct, 'While Loop', H S Switches, Bidirect and delays, Switch I	of Flip-Flops wit sure, Delays and 10 Hrs Construct, Alway evel, Blocking an Assign- De-Assig Forever Loop, 9 Hrs ional Gates, Tim
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Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking A Constructs, 'Rep sequential and H Switch Level I Delays with Sw NAND, NOR a Unit –V:: Sy System Tasks, System Tasks a	, Gate Delay, Dataflow La ignments, As Unit odeling: Int gnments with Assignments, peat' Constru- Parallel Block Unit - Modeling: B witch Primitiv nd XOR. ystem Tasks,	tte Gates, Arra Strengths and evel: Introduct ssignment to Vo -III:: Behavio roduction, Ope n Delays, 'Wait The 'Case' Sta act, for loop, 'T as. -IV:: Switch L asic Transistor ves, instantiation Functions & Circuit Deso nd Compiler I , User Defined	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Dral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'if The Disable' Const evel Modeling : Switches, CMOS on with strengths : Compiler Directives: Parama Primitives, Compiler	Primitives, Design ation, Net Types. Assignment Struct ignments, 'Initial' Ogn at Behavioral Le f-Else' Constructs, 'A cruct, 'While Loop', H S Switches, Bidirect and delays, Switch I ves & Sequential eters, Path Delays, M	of Flip-Flops with sure, Delays and 10 Hrs Construct, Alway evel, Blocking and Assign- De-Assig Forever Loop, 9 Hrs ional Gates, Tim level modeling for 9 Hrs lodule Parameters
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Gate Primitives Modeling at I Continuous Ass Behavioral M construct, Assig Non Blocking A Constructs, 'Rej sequential and H Delays with Sw NAND, NOR a Unit –V:: Sy System Tasks a Sequential Cir Model. Text Books:	, Gate Delay, Dataflow La ignments, As Unit odeling: Int gnments with Assignments, peat' Constru- Parallel Block Unit - Modeling: B vitch Primitiv nd XOR. ystem Tasks, Functions a nd Functions	tte Gates, Arra Strengths and evel: Introduct ssignment to Vo -III:: Behavio roduction, Ope n Delays, 'Wait The 'Case' Sta act, for loop, 'T cs. -IV:: Switch L asic Transistor ves, instantiatio Functions & Circuit Deso nd Compiler I , User Defined tion: Sequentia	y of Instances of Contention Resolu- tion, Continuous ector, Operators. Dral Modeling erations and Ass t 'Construct, Desi- atement, 'If' and 'if 'he Disable' Const evel Modeling : Switches, CMOS on with strengths : Switches: Parama Primitives, Comp- al Models - Feedba	Primitives, Design on ition, Net Types. Assignment Struct ignments, 'Initial' Ogn at Behavioral Lee f-Else' Constructs, 'A cruct, 'While Loop', H S Switches, Bidirect and delays, Switch H ves & Sequential eters, Path Delays, Mailer directives.	of Flip-Flops wi sure, Delays an 10 Hrs Construct, Alway evel, Blocking an Assign- De-Assig Forever Loop, 9 Hrs ional Gates, Tim level modeling for 9 Hrs lodule Parameter ve Model, Implic

References:

- Fundamentals of Digital Logic with Verilog Design Stephen Brown, Zvonkoc Vranesic, TMH, 2nd Edition.
- 2. Zainalabdien Navabi, Verliog Digital System Design, TMH, 2nd Edition.
- Advanced Digital Logic Design using Verilog, State Machines & Synthesis for FPGA -Sunggu Lee, Cengage Learning, 2012.
- 4. Advanced Digital Design with Verilog HDL Michel D. Ciletti, PHI, 2009.

Course Outcomes:

After the completion of the course students will able to:

CO1: Describe Verilog HDL Design Digital circuits

CO2: Write behavior model of digital circuits

CO3: Write RTL models of digital circuits

CO4: Describe standard Cell Libraries and FPGAs

CO5: Synthesize RTL models to standard cell libraries and FPGAs

CO6: Implement RTL models on FPGAs and testing and verification

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Course Code 22A0213T	L:T:P 3:0:0	Credits 3	Exam. Marks CIE:30	Exam Duration 3 Hours	Course Type PCC
22A02131	5:0:0	5	SEE:70	5 nours	FCC
Course Objectives	•		SEE.70		
•		loop and clos	sed loop systems; th	ne effect of feedbac	ck
	-	-	son's gain formula		
	0	0	domain specification		
			iagrams and Nyqui		
 State space mo 	1		ugrunns und rygur		
Unit-I		-	ept of Control Sys	tem	10 Hrs
	control syst		loop and closed l		
			back, Feedback Ch		
Principle of opera	tion of DC	and AC Serve	o motor, Transfer	function of DC set	rvo motor - AC
servo motor, Sync					
	-		diagram algebra, I	e	
Ũ		ow graphs(SF	G) - Reduction usi	ng Mason's gain fo	ormula Transfer
function of SFG's.					_
Unit –II		Tim	e Response Analy	sis	10 Hrs
('ontrollers		1	ay state errors and	error constants, P,	FI, FID
Unit –III		Stability .	Analysis in Time l	Domain	10 Hrs
A) Stability Anal	-	Stability A	Analysis in Time I ncept of stability –	Domain Routh-Hurwitz's s	10 Hrs stability criterior
Unit –III A) Stability Anal	-	Stability A	Analysis in Time l	Domain Routh-Hurwitz's s	10 Hrs stability criterior
Unit –III A) Stability Anal – qualitative stabil	ity and condi	Stability 2 main: The control of the stability	Analysis in Time I ncept of stability – v – Limitations of F	Domain Routh-Hurwitz's s Routh-Hurwitz's sta	10 Hrs stability criterior ability
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T	ity and conditive the condition of the c	Stability A main: The control of the	Analysis in Time I ncept of stability –	Domain Routh-Hurwitz's s Routh-Hurwitz's sta	10 Hrs stability criterior ability
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I	ity and conditive the condition of the c	Stability A main: The control of the	Analysis in Time I ncept of stability – v – Limitations of F	Domain Routh-Hurwitz's s Routh-Hurwitz's sta	10 Hrs stability criterior ability Effects of addin
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV	ity and conditient of the condition of t	Stability A main: The contribution of the contributication of the contribution of the	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus,	10 Hrs stability criterion ability Effects of addin 9 Hrs
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV Introduction, Freq	ity and condition 'echnique: C H(s) on the round uency domain	Stability A main: The continual stability oncept of roo ot loci. Freque	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana as-Bode diagrams-I	Domain Routh-Hurwitz's statement Routh-Hurwitz's statement tion of root locus, alysis Determination of Figure 1	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV Introduction, Freq specifications and	ity and condition cechnique: C H(s) on the round uency domain transfer function	Stability A main: The control of roo ot loci. Freque of specification ction from the	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana is-Bode diagrams-I e Bode Diagram-S	Domain Routh-Hurwitz's statement Routh-Hurwitz's statement tion of root locus, alysis Determination of Fit tability Analysis f	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis	echnique: C H(s) on the ro uency domain transfer functions st Plots- Phase	Stability A main: The continual stability oncept of roo ot loci. Freque a specification ction from the e margin and o	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct ncy Response Ana s-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil	Domain Routh-Hurwitz's statement Routh-Hurwitz's statement tion of root locus, alysis Determination of Fitability Analysis fity Analysis.	10 Hrs stability criterior ability Effects of addir 9 Hrs requency domain from Bode Plots
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis	ity and condit echnique: C H(s) on the ro uency domain transfer func- st Plots- Phase hniques – Lag	Stability A main: The continual stability oncept of roo ot loci. Freque a specification ction from the e margin and of g, Lead, Lag-L	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct mcy Response Ana is-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil cead Compensator	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fitability Analysis fity type and the sign in frequency	10 Hrs stability criterior ability Effects of addir 9 Hrs requency domain from Bode Plots
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect <u>Unit-V</u>	ity and condition iechnique: C H(s) on the rouse uency domain transfer functions st Plots- Phase hniques – Lag Sta	Stability A main: The continual stability oncept of roo ot loci. Freque a specification ction from the e margin and of g, Lead, Lag-L te Space Ana	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct ncy Response Ana s-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fraction of Fractionality Analysis for the sign in frequency is Systems	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain from Bode Plots y Domain. 9 Hrs
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect Unit-V Concepts of state, function models -	iity and condit iechnique: C H(s) on the ro uency domain transfer function st Plots- Phase hniques – Lag State state variable Block diagram	Stability A main: The contional stability oncept of roo ot loci. Freque a specification ction from the e margin and of g, Lead, Lag-L te Space Ana es and state m ums. Diagonal	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct mcy Response Ana s-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Ilysis of Continuou odel, state models lization, Transfer f	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fit tability Analysis f ity Analysis. design in frequency is Systems - differential equate unction from state	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain From Bode Plots y Domain. 9 Hrs ions & Transfer model, Solving
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect <u>Unit-V</u> Concepts of state, function models - the Time invarian	ity and condit echnique: C H(s) on the ro uency domain transfer func- st Plots- Phase hniques – Lag State variable Block diagra t state Equati	Stability A main: The continual stability oncept of roo ot loci. Freque a specification ction from the e margin and of g, Lead, Lag-L te Space Ana es and state mains. Diagonal ions- State Tr	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana is-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Ilysis of Continuou odel, state models lization, Transfer f ansition Matrix an	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fratability Analysis. design in frequency is Systems - differential equate unction from state d it's Properties.	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain from Bode Plots y Domain. 9 Hrs ions & Transfer model, Solving System response
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect Unit-V Concepts of state, function models - the Time invarian through State Spa	iity and condit iechnique: C iechnique: C H(s) on the ro C uency domain c transfer fund c st Plots- Phase hniques – Lag State State Block diagrat t state Equati ce models. T	Stability A main: The continuation of the concept of root of the concept of root of the concept	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct mcy Response Ana s-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Ilysis of Continuou odel, state models lization, Transfer f	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fratability Analysis. design in frequency is Systems - differential equate unction from state d it's Properties.	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain from Bode Plots y Domain. 9 Hrs ions & Transfer model, Solving System response
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect <u>Unit-V</u> Concepts of state, function models - the Time invarian through State Spa controllability and	iity and condit iechnique: C iechnique: C H(s) on the ro C uency domain c transfer fund c st Plots- Phase hniques – Lag State State Block diagrat t state Equati ce models. T	Stability A main: The continuation of the concept of root of the concept of root of the concept	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana is-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Ilysis of Continuou odel, state models lization, Transfer f ansition Matrix an	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fratability Analysis. design in frequency is Systems - differential equate unction from state d it's Properties.	10 Hrs stability criterior ability Effects of addin 9 Hrs requency domain from Bode Plots y Domain. 9 Hrs ions & Transfer model, Solving System response
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I <u>Unit –IV</u> Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect <u>Unit-V</u> Concepts of state, function models - the Time invarian through State Spa controllability and Fext Books: 1. Modern Control	iity and condit iechnique: C iechnique: C H(s) on the ro C uency domain c transfer fund c st Plots- Phase hniques - State State Block diagrat t state Equation C ice models. observability	Stability A main: The continual stability oncept of roo ot loci. Freque a specification ction from the e margin and c g, Lead, Lag-L te Space Ana es and state mas. Diagonal ions- State Tr The concepts of 7.	Analysis in Time I ncept of stability – 7 – Limitations of F t locus - Construct ency Response Ana is-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Ilysis of Continuou odel, state models lization, Transfer f ansition Matrix an	Domain Routh-Hurwitz's state Routh-Hurwitz's state tion of root locus, alysis Determination of Fitability Analysis fity Determination of Fitability Analysis fity Analysis - differential equate unction from state d it's Properties. S nd observability, I	10 Hrs stability criterior ability Effects of addir 9 Hrs requency domain from Bode Plots y Domain. 9 Hrs ions & Transfer model, Solving System response Duality between
Unit –III A) Stability Anal – qualitative stabil B) Root Locus T and zeros to G(s) I Unit –IV Introduction, Freq specifications and Polar Plots-Nyquis Compensation tect Unit-V Concepts of state, function models - the Time invarian through State Spa controllability and Fext Books: 1. Modern Contro 2010.	ity and condit echnique: C H(s) on the ro uency domain transfer func- st Plots- Phase hniques – Lag State variable Block diagra t state Equation ce models. T observability ol Engineerin	Stability A main: The contional stability oncept of roo ot loci. Freque a specification ction from the e margin and c g, Lead, Lag-L te Space Ana es and state mass. Diagonal ions- State Tr The concepts of A	Analysis in Time I ncept of stability – / – Limitations of F t locus - Construct ency Response Ana Is-Bode diagrams-I e Bode Diagram-S Gain margin-Stabil Lead Compensator Iysis of Continuou odel, state models lization, Transfer f ansition Matrix an of controllability a	Domain Routh-Hurwitz's state Routh-Hurwitz's state alysis Determination of Frability Analysis Determination of Frability Analysis design in frequency Is Systems - differential equat unction from state d it's Properties. S nd observability, I Hall of India Pvt.	10 Hrs stability criterior ability Effects of addir 9 Hrs requency domain Y Domain. 9 Hrs ions & Transfer model, Solving System response Duality between Ltd., 5th edition

References:

- 1. Control Systems Principles & Design by M.Gopal, 4th Edition, Mc Graw Hill Education, 2012.
- 2. Automatic Control Systems by B. C. Kuo and Farid Golnaraghi, John wiley and sons, 8th edition, 2003.
- 3. Feedback and Control Systems, Joseph J Distefano III, Allen R Stubberud& Ivan J Williams, 2nd Edition, Schaum's outlines, Mc Graw Hill Education, 2013.
- 4. Control System Design by Graham C. Goodwin, Stefan F. Graebe and Mario E. Salgado, Pearson, 2000.
- 5. Feedback Control of Dynamic Systems by Gene F. Franklin, J.D. Powell and Abbas Emami-Naeini, 6th Edition, Pearson, 2010.

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Understand the concepts of control systems feedback effect, mathematical modelling, and time response.
- **CO2:** Apply the concepts of Block diagram reduction, Signal flow graph method for obtaining mathematical and Root locus, Bode, Nyquist, Polar plots for stability calculations.
- **CO3:** Apply the concept of controllability and observability and demonstrate the use of these techniques.
- **CO4:** Analyze time response analysis, error constants, and stability characteristics of a given mathematical model using different methods.
- **CO5:** Design and develop different compensators, controllers and their performance evaluation for various conditions.
- **CO6:** Implement different compensators and controllers in solving various engineering applications.

a a .	AN	TENNAS &	MICROWAVE	ENGINEEKING	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0421T	3:0:0	3	CIE:30 SEE:70	3 Hours	PCC
Course Objecti	ves:		1		
To allow	the studen	t to understar	nd the basic princi	ples in antenna and	micro wave system
design.			-	•	·
-	the studen	t to gain know	wledge in various	antenna designs	
		•	•	-	to and automas for
		-	e in the area of mi	crowave componen	ts and antenna for
practical	applicatior	18.			
		Syllab			Total Hours: 48
		Unit -			10 Hrs
				e	frequency independen
antennas, Radia	tion Mecha	ınism – singl	e wire, two wire,	dipoles, Antenna l	Parameters - Radiation
Patterns, Main	Lobe and	Side Lobes	, Beam widths,	Beam Area, Radi	ation Intensity, Bean
Efficiency, Dire	ectivity, Ga	in and Reso	lution, Aperture	Efficiency, Effecti	ve Height and length
Radiation from	Small Elec	ctric Dipole,	Quarter wave M	onopole and Half	wave Dipole- Curren
Distributions, I	Field Com	ponents, Ra	diated power, I	Radiation Resistanc	e, Loop Antennas
Introduction, Sr	nall Loop, (Comparison of	of far fields of sm	all loop and	
	-	-		-	Qualitative Treatment)
• '		Unit –			10 Hrs
VHF, UHF and	d Micro wa	ave Antenna	s: Helical Antenr	as-Helical Geomet	ry, Helix modes, Hori
Antennas- Type	s, Fermat's	Principle, O	ptimum Horns, D	esign consideration	ns of Pyramidal Horns
Micro strip Ai	ntennas- Ir	troduction,	features, advanta	ges and limitation	ns, Rectangular patel
antennas-Geom	etry and pa	arameters, ch	aracteristics of N	Aicro strip antenna	s, parabola reflectors
geometry, patter	rn character	istics, Feed N	Methods, Reflecto	r Types - Related F	anturas
				i Types - Related I	Eatures.
		Unit –	III	r rypes - Related r	10 Hrs
Antenna Array	vs and pro				10 Hrs
•	-	pagation: A	rrays of 2 Isotro	pic sources- Differ	10 Hrs ent cases, Principle o
Pattern Multipli	ication, Un	pagation: A iform Linear	rrays of 2 Isotro Arrays – Broad	pic sources- Differ side Arrays, End f	10 Hrs ent cases, Principle o fire Arrays, EFA with
Pattern Multipli Increased Direc	ication, Un ctivity, Der	pagation: A iform Linear ivation of th	rrays of 2 Isotro Arrays – Broad eir characteristics	pic sources- Differ side Arrays, End f s and comparison,	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasitie
Pattern Multipli Increased Direc Elements-Yagi-	ication, Un ctivity, Der Uda Array	pagation: A iform Linear ivation of th ys, Folded I	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their c	pic sources- Differ side Arrays, End f and comparison, characteristics Grou	10 Hrs ent cases, Principle o fire Arrays, EFA with
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro	ication, Un ctivity, Der Uda Array pagation-Sk	pagation: A iform Linear ivation of th ys, Folded I ky wave prop	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitativ	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment).	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro Waveguides: In	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction,	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their c agation(Qualitativ theory, Rectangu	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro Waveguides: In and TM modes,	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction,	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their c agation(Qualitativ theory, Rectangu	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction,	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their c agation(Qualitativ theory, Rectangu	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction,	pagation: A iform Linear ivation of th ys, Folded I ky wave prop Wave Guide pagation in t	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitativ theory, Rectangu he guide, Phase a	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH s, Wave guide curren
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation.	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave proj	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t Unit –	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitative theory, Rectangue he guide, Phase a	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou ve treatment). lar wave guides, Fi and group velocitie	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasitio and wave propagation eld expressions for TH s, Wave guide curren 9 Hrs
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation.	ication, Un ctivity, Der Uda Arra pagation-Sk ntroduction, Wave prop mponents:	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t Unit – Introduction	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitativ theory, Rectangu he guide, Phase a IV to scattering para	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi and group velocitie	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH s, Wave guide curren 9 Hrs roperties, Hybrid Tee
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation. Microwave Co (H-plane, E-pla	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave prop mponents: ne, Magic	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t <u>Unit –</u> Introduction Tees), Hybri	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitative theory, Rectangue he guide, Phase a IV to scattering par- id ring, Direction	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou ze treatment). lar wave guides, Fi and group velocitie	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TH s, Wave guide curren 9 Hrs
Pattern Multipli Increased Direc Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation. Microwave Co (H-plane, E-pla Couplers, Deriv	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave prop mponents: ne, Magic ing Scatteri	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t <u>Unit –</u> Introduction Tees), Hybri ng matrix for	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitativ theory, Rectangu he guide, Phase a IV to scattering par- id ring, Direction r H-plane, E-plane	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi and group velocitie ameters and their p al Couplers – Beth e, Magic Tees.	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TI s, Wave guide current 9 Hrs roperties, Hybrid Tee he hole and Two-hole
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation. Microwave Co (H-plane, E-pla Couplers, Deriv Micro wave A	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave prop mponents: ne, Magic ing Scatteri mplifiers a	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t <u>Unit –</u> Introduction Tees), Hybri ng matrix for and Oscillate	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitative theory, Rectangue he guide, Phase a IV to scattering para id ring, Direction r H-plane, E-plane ors: Micro wave	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou ze treatment). lar wave guides, Fi and group velocitie ameters and their p al Couplers – Bet e, Magic Tees. Tubes: Linear Bea	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasition and wave propagation eld expressions for TI s, Wave guide current 9 Hrs roperties, Hybrid Tee he hole and Two-hole am Tubes–Two cavity
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation. Microwave Co (H-plane, E-pla Couplers, Deriv Micro wave A Klystron amplif	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave prop mponents: ne, Magic ing Scatteri mplifiers a ier -velocit	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t Unit – Introduction Tees), Hybri ng matrix for and Oscillate y modulation	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitative theory, Rectangue he guide, Phase a IV to scattering para id ring, Direction or H-plane, E-plane ors: Micro wave h, bunching proce	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi and group velocitie ameters and their p al Couplers – Bet e, Magic Tees. Tubes: Linear Bea	10 Hrs ent cases, Principle o fire Arrays, EFA with Arrays with Parasiti and wave propagation eld expressions for TI s, Wave guide curren 9 Hrs roperties, Hybrid Tee he hole and Two-hol am Tubes–Two cavit n oscillator, Travelling
Pattern Multipli Increased Direct Elements-Yagi- Space wave pro Waveguides: In and TM modes, and mode excitation. Microwave Co (H-plane, E-pla Couplers, Deriv Micro wave A Klystron amplif Wave Tube (T	ication, Un ctivity, Der Uda Array pagation-Sk ntroduction, Wave prop mponents: ne, Magic ing Scatteri mplifiers a ier -velocit WT) – Bur	pagation: A iform Linear ivation of th ys, Folded I cy wave prop Wave Guide pagation in t Unit – Introduction Tees), Hybri ng matrix for and Oscillate y modulation aching proces	rrays of 2 Isotrop Arrays – Broad eir characteristics Dipoles & their of agation(Qualitative theory, Rectangue he guide, Phase a IV to scattering para id ring, Direction r H-plane, E-plane ors: Micro wave h, bunching process ss and amplificat	pic sources- Differ side Arrays, End f s and comparison, characteristics Grou re treatment). lar wave guides, Fi and group velocitie ameters and their p al Couplers – Bet e, Magic Tees. Tubes: Linear Bea	10 Hrs ent cases, Principle of fire Arrays, EFA with Arrays with Parasiti and wave propagation eld expressions for The s, Wave guide current 9 Hrs roperties, Hybrid Tee he hole and Two-hol am Tubes–Two cavit h oscillator, Travelling cative treatment only)

Unit –V 9 Hrs
Micro wave Semi conductor Devices: Gunn Oscillator – Principle of operation, Characteristics Two valley model. Antennas and Microwave Measurements: Sources of errors, Patterns to b
Measured, Pattern Measurement Arrangement, Directivity Measurement, Gain Measurements (by comparison, Absolute and 3-Antenna Methods). Description of Microwave bench-different block and their features, errors and precautions, Measurement of attenuation, frequency, VSWR (low medium, high), Impedance measurements.
Textbooks:
1. JohnD.Kraus, Ronald J. Marhefkaand Ahmad S. Khan, "Antennas and Wave propagation", TM
New Delhi, 4thEd, 2010.
2. SamuelY. Liao, "Micro wave devices and circuits", 3rdEdition, Pearson Publishing, 2003.
References:
1. R .E. Collin, "Foundations for micro wave engineering", 2ndEdition, JohnWiley,2002.
2. C.A. Balanis, "Antenna Theory-Analysis and Design", John Wiley & Sons, 2 nd Edn. 2001.
3. M. Kulkarni, "Micro wave and Radar Engineering", Umesh Publications, 4 th edition 2009.
4. G.S.NRaju, "AntennaandWavePropagation",PearsonEducationIndia,3 rd Edition2009.
Course Outcomes:
After the completion of the course students will able to:
CO1: Understand the generation of radiation and basic concepts of dipole and loop Antennas
CO2: Analyze the Practical antenna design characteristics to meet the requirements of modern
wireless communications.
CO3: Understand the uses of antenna arrays and waveguides for propagation of EM wave.
CO4: Analyze various microwave components and the principles of different microwave sources.
CO5: Gain knowledge on Micro wave Amplifiers and Oscillators.
CO6: Measure the different Parameters of antennas and propagation of microwaves through
waveguides.

	DATA	COMMUNI	ICATION AND N	ETWORKS	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0422T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objectiv	ves:				
The student shou	ld be made to	:			
• Understan	nd the divisior	n of network fu	unctionalities into I	layers.	
				rent types of networ	ks
	-		ity at each layer		
• Learn the	e flow control a	e	n control algorithm		
		Syllabus			Fotal Hours: 48
		Unit –I			10 Hrs
				, Network and Prot	
				ansmission mode,	
-		-	-	ng: Circuit switchi	• •
	1	division), pack	tet switching (virtu	ual circuit and Data	a gram approach)
message switchin	ng.				
		Unit –II			10 Hrs
·	e			ocols: Flow and Er	· •
-	-	-	-	lective Repeat ARC	, HDLC, Point-to
	PP Point _to_	Doint Drotocol	DDD Stool		
-Point Access: P			I, FFF Stack.		
		Unit –III	·		10 Hrs
Medium Acces	s Sub layer:	Unit –III Channel alle	ocation problem,	Controlled Access	, Channelization
Medium Access multiple access p	s Sub layer: protocols, IEE	Unit –III Channel allo E standard 802	ocation problem, 2.3 & 802.11 for L	ANS and WLAN,	s, Channelization high-speed LANs
Medium Access multiple access p Bluetooth IEEE	s Sub layer: protocols, IEE 802.16.Token	Unit –III Channel allo E standard 802	ocation problem, 2.3 & 802.11 for L		s, Channelization high-speed LANs
Medium Access multiple access p	s Sub layer: protocols, IEE 802.16.Token	Unit –III Channel alle E standard 802 ring, Token Bu	ocation problem, 2.3 & 802.11 for L	ANS and WLAN,	s, Channelization high-speed LANs ces-repeaters,
Medium Access multiple access p Bluetooth IEEE hubs, switches b	s Sub layer: protocols, IEE 802.16.Tokenn ridges.	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV	ocation problem, 2.3 & 802.11 for L us, FDDI based L	ANS and WLAN, EAN, Network Devic	s, Channelization high-speed LANs ces-repeaters, 9 Hrs
Medium Access multiple access p Bluetooth IEEE hubs, switches bu	s Sub layer: protocols, IEE 802.16.Token ridges. : Design issue	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest	ANS and WLAN, 2 AN, Network Devic	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ms, Host to Hos
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest routing, IP address	ANS and WLAN, EAN, Network Devic	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ms, Host to Hos
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest	ANS and WLAN, EAN, Network Devic	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ms, Host to Hos
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF	Unit –III Channel allo E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP	ANS and WLAN, EAN, Network Device	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Host Classless), Subnet, 9 Hrs
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Layer	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF	Unit –III Channel allo E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V O Process Del	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP ivery: UDP; TCP	ANS and WLAN, AN, Network Device	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality of
Medium Access multiple access p Bluetooth IEEE hubs, switches bu Network Layer Delivery: Interne Network Layer F Transport Layer service. Applicat	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl	Unit –III Channel allo E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V O Process Del lient Server M	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP ivery: UDP; TCP	ANS and WLAN, AN, Network Device ion control algorithing (class full & C V6.	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality or
Medium Access multiple access p Bluetooth IEEE hubs, switches bu Network Layer Delivery: Interne Network Layer F Transport Layer service. Applicat	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl	Unit –III Channel allo E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V O Process Del lient Server M	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP ivery: UDP; TCP lodel, Socket Inter	ANS and WLAN, AN, Network Device ion control algorithing (class full & C V6.	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality o
Medium Access multiple access p Bluetooth IEEE hubs, switches bu Network Layer Delivery: Interne Network Layer F Transport Layer service. Applicat Electronic Mail (Text Books:	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file th	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V O Process Del lient Server M ransfer (FTP),	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP ivery: UDP; TCP lodel, Socket Inter HTTP and WWW	ANS and WLAN, AN, Network Device ion control algorithing (class full & C V6.	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ms, Host to Hos Classless), Subnet 9 Hrs ol and Quality of the System (DNS)
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Laye service. Applicat Electronic Mail (Text Books: 1. S. Tannenbur	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file tu n, D. Wethera	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V D Process Del lient Server M ransfer (FTP),	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest routing, IP address P, IPV6 and ICMP ivery: UDP; TCP Iodel, Socket Inter HTTP and WWW	ANS and WLAN, AN, Network Devic ion control algorith sing (class full & C V6.	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality of the System (DNS)
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Laye service. Applicat Electronic Mail (Text Books: 1. S. Tannenbur	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file tu n, D. Wethera	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V D Process Del lient Server M ransfer (FTP),	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest routing, IP address P, IPV6 and ICMP ivery: UDP; TCP Iodel, Socket Inter HTTP and WWW	ANS and WLAN, EAN, Network Device ion control algorithesing (class full & CV6. c, congestion contro face, Domain Name tice Hall, Pearson, 5	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality of the System (DNS)
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Laye service. Applicat Electronic Mail (Text Books: 1. S. Tannenbur 2. Behrouz A. F References:	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file tr m, D. Wethera Forouzan, —D	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V D Process Del lient Server M ransfer (FTP), Ill, —Compute ata Communic	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest routing, IP address P, IPV6 and ICMP ivery: UDP; TCP Iodel, Socket Inter HTTP and WWW	ANS and WLAN, EAN, Network Device ion control algorithing (class full & CV6. c, congestion contro face, Domain Name tice Hall, Pearson, 5 rking , Tata McGrav	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos Classless), Subnet 9 Hrs ol and Quality of the System (DNS)
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Laye service. Applicat Electronic Mail (Text Books: 1. S. Tannenbur 2. Behrouz A. F References: 1. Fred Halsall	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file tr m, D. Wethera Forouzan, —D , —Computer	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V o Process Del lient Server M ransfer (FTP), Ill, —Compute ata Communic	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest outing, IP address P, IPV6 and ICMP ivery: UDP; TCP Iodel, Socket Inter HTTP and WWW er Networks , Prent cations and Networ ddison – Wesley P	ANS and WLAN, EAN, Network Device ion control algorithing (class full & CV6. c, congestion contro face, Domain Name tice Hall, Pearson, 5 rking , Tata McGrav	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ums, Host to Hos classless), Subnet 9 Hrs ol and Quality o e System (DNS) othEd. w-Hill, 4th Ed
Medium Access multiple access p Bluetooth IEEE hubs, switches br Network Layer Delivery: Interne Network Layer F Transport Laye service. Applicat Electronic Mail (Text Books: 1. S. Tannenbur 2. Behrouz A. F References: 1. Fred Halsall 2. Larry L, Pet 4thEd	s Sub layer: protocols, IEE 802.16.Tokenn ridges. : Design issue etworking, add Protocols: ARF er: Process to tion Layer: Cl (SMTP), file tr n, D. Wethera Forouzan, —D , —Computer erson and Brue	Unit –III Channel alle E standard 802 ring, Token Bu Unit –IV es, Routing alg dressing and r P, IPV4, ICMF Unit –V D Process Del lient Server M ransfer (FTP), Ill, —Compute ata Communic NetworksI, Ac ce S. Davie, –	ocation problem, 2.3 & 802.11 for L us, FDDI based L gorithms, Congest routing, IP address P, IPV6 and ICMP ivery: UDP; TCP Iodel, Socket Inter HTTP and WWW er Networks , Prent cations and Networ ddison – Wesley P –Computer Netwo	ANS and WLAN, EAN, Network Device AN, Network Device ion control algorithesing (class full & CV6. congestion control face, Domain Name tice Hall, Pearson, 5 rkingl, Tata McGrav	s, Channelization high-speed LANs ces-repeaters, 9 Hrs ms, Host to Hos Classless), Subnet 9 Hrs ol and Quality o e System (DNS) 6 thEd. w-Hill, 4th Ed oachl, Elsevier,

Course Outcomes:

After the completion of the course students will able to:

CO1: Understand the basics of data communication, networking, internet and their importance.

CO2: Analyze the services and features of various protocol layers in data networks.

CO3: Differentiate wired and wireless computer networks

CO4: Analyze TCP/IP and their protocols.

CO5: Understand the flow control and congestion control algorithms

CO6: Understand different internet devices and their functions.

	IN	FORMATIO	ON THEORY ANI		
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0423T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objectiv	ves:				
•		ameters of I	nformation, the con	cepts of source codi	ing techniques and
	trol coding te			1	0 1
	0	-	ation theory and er	ror control coding to	echniques to solve
problems	-		5	U	1
-		source codin	g and channel cod	ing techniques for e	error detection and
			bearing signals.	0 1	
				convolutional code	s.
		Syllab			Total Hours: 48
		Unit -			10 Hrs
Information Th	eory: Introdu			Conditional Entropy,	
				n Inequalities, Probl	
1	1		· · · · · · · · · · · · · · · · · · ·	e Random Variable,	U
	-			Single Random Var	
		-	• •	oding an information	
Coding, Example		and coung	The fix code, et	ang an mormation	i bource, munnai
		Coding: Pro	ner message set Δ	ssigning probabiliti	es to K-ary roote
				ing of a proper me	
message set, Tun	• • •	er message s		ing of a proper me	ssuge set, Tunstan
message set, 1 un	istan coung.	Unit -	_TT		10 Hrs
Acumptotic Fau	i nortition I			y, Weak law of large	
• • •	-	Toperty – C	neuysnev mequant	y, weak law of large	z numbers, i ypica
Sequences Bloc	k to Block ('oding of DN	AS: Consequences	of Asymptotic Faui	nartition Property
-		Coding of DN	AS: Consequences	of Asymptotic Equi	partition Property
Problem solving.		-	-		
Problem solving. Universal Sour	ce Coding:]	Lempel –Ziv	Algorithm, LZ – 7	77 Encoding and De	
Problem solving. Universal Sour Ziv Welch (LZW	ce Coding:] /) Algorithm,	Lempel –Ziv LZW Encoc	Algorithm, LZ – ² ling, and Decoding.	77 Encoding and De	ecoding, Lempel -
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc	ce Coding: 1 () Algorithm, es with mem	Lempel –Ziv LZW Encoc ory, Channe	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy (77 Encoding and De	ecoding, Lempel - corem, Differentia
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc	ce Coding: 1 () Algorithm, es with mem	Lempel –Ziv LZW Encoci ory, Channe Cate Distortio	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C n Theory, Blahut –	77 Encoding and De	ecoding, Lempel - corem, Differentia - problem solving
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia	ce Coding: 1 7) Algorithm, es with mem in Channel, R	Lempel –Ziv LZW Encoc ory, Channe Late Distortio Unit –	Algorithm, LZ – ling, and Decoding. l Capacity, Noisy (n Theory, Blahut – III	77 Encoding and De Channel Coding The Arimoto Algorithm	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (ce Coding: 1 7) Algorithm, es with mem in Channel, R C oding: Intro	Lempel –Ziv LZW Encoci lory, Channe <u>ate Distortio</u> Unit – oduction to H	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy (on Theory, Blahut – III Error Control Codes	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Sym	ce Coding: 1 7) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr	Lempel –Ziv LZW Encod ory, Channe <u>ate Distortio</u> <u>Unit –</u> oduction to F nel, Parity C	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy Con Theory, Blahut – III Error Control Codes heck Bit Coding for	77 Encoding and Do Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection,	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symmetry Detection	ce Coding: 1) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to F nel, Parity Cl on, The Har	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy Con Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symmetry Detection	ce Coding: 1) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti	Lempel –Ziv LZW Encoci ory, Channe ate Distortio Unit – oduction to Hatel, Parity Cl on, The Har ion Decoding	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision Decision Decision Decision	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for the Probability of
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Sym Error Detection Error with Codin	ce Coding: 1 7) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to H nel, Parity Cl on, The Har ion Decoding Unit –	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy Con Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision De IV	77 Encoding and Do Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding.	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for the Probability of 9 Hrs
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symmetry Symmetry Detection Error Detection Error with Codin	ce Coding: 1) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro-	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to H nel, Parity Ch on, The Har ion Decoding Unit – roduction to	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy Con Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision De IV Linear Block Co	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for the Probability of 9 Hrs I Error Detection
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symi Error Detection Error with Codin Linear Block (Encoding Block	ce Coding: 1 7) Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro- Codes, Deco	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to H nel, Parity Cl on, The Har ion Decoding Unit – roduction to ding of Bloc	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for mming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition in Block Coding for the Probability of 9 Hrs Error Detection c, Repeated Codes
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Sym Error Detection Error with Codin Linear Block (Encoding Block Hadamard Code	ce Coding: 1 () Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro Codes, Deco , Hamming ()	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to F nel, Parity Cl on, The Har ion Decoding <u>Unit –</u> roduction to ding of Bloc Code, Cyclic	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa	77 Encoding and Do Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code and Parity-Check I	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition in Block Coding for the Probability of 9 Hrs Error Detection c, Repeated Codes Matrices of Cyclic
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Sym Error Detection Error with Codin Linear Block (Encoding Block Hadamard Code	ce Coding: 1 () Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro Codes, Deco , Hamming ()	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to Har ion Decoding Unit – roduction to ding of Bloc Code, Cyclic ng of Cyclic (Algorithm, LZ – ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa codes, Generator Codes, BCH codes,	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition in Block Coding for the Probability of 9 Hrs Error Detection c, Repeated Codes Matrices of Cyclic e.
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symi Error Detection Error with Codin Linear Block (Encoding Block Hadamard Code, Codes, Encoding	ce Coding: 1 () Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro- Codes, Deco , Hamming C and Decodir	Lempel –Ziv LZW Encoci ory, Channe ate Distortio Unit – oduction to Har ion Decoding Unit – roduction to ding of Bloc Code, Cyclic ng of Cyclic (Unit –	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for nming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa codes, Generator Codes, BCH codes, - V	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code and Parity-Check I Reed-Solomon Cod	ecoding, Lempel - eorem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for the Probability of 9 Hrs Error Detection e, Repeated Codes Matrices of Cyclic e. 9 Hrs
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symi Error Detection Error with Codin Linear Block (Encoding Block Hadamard Code, Codes, Encoding	ce Coding: 1 () Algorithm, es with mem in Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intro- Codes, Deco , Hamming (and Decodir Coding – C	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to Har ion Decoding Unit – roduction to ding of Bloc Code, Cyclic on Cyclic O Unit –	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for mming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa codes, Generator Codes, BCH codes, -V tion, Decoding Co	77 Encoding and De Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code and Parity-Check I Reed-Solomon Cod	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition ir Block Coding for the Probability of 9 Hrs Error Detection c, Repeated Codes Matrices of Cyclic e. 9 Hrs - the Code Tree
Problem solving. Universal Sour Ziv Welch (LZW Coding of Sourc Entropy, Gaussia Error Control (the Binary Symi Error Detection Error with Codin Linear Block (Encoding Block Hadamard Code, Codes, Encoding Decoding in the	ce Coding: 1 () Algorithm, es with mem () Channel, R Coding: Intro- netric Chanr and Correcti g, Soft Decis Codes – Intr Codes, Deco , Hamming () and Decodir Coding – C presence of N	Lempel –Ziv LZW Encod ory, Channe ate Distortio Unit – oduction to F nel, Parity Cl on, The Har ion Decoding Unit – roduction to ding of Bloc Code, Cyclic of Cyclic (Unit – code General Noise, State a	Algorithm, LZ – 7 ling, and Decoding. l Capacity, Noisy C on Theory, Blahut – III Error Control Codes heck Bit Coding for mming Distance, T g, Hard Decision De IV Linear Block Co ek Codes, Single Pa codes, Generator Codes, BCH codes, -V tion, Decoding Co and Trellis Diagram	77 Encoding and Do Channel Coding The Arimoto Algorithm s, Error Probability or Error Detection, he upper bound of ecoding. des, Syndrome and rity Check bit Code and Parity-Check I Reed-Solomon Cod onvolutional Code s, The Viterbi Algor	ecoding, Lempel - corem, Differentia - problem solving 10 Hrs with Repetition in Block Coding fo the Probability of 9 Hrs Error Detection e, Repeated Codes Matrices of Cyclic e. 9 Hrs - the Code Tree rithm, Comparison
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References:

- 1. Shu Lin, Daniel J. Costello Jr., Error Control Coding, Pearson, Second Edition, 2013.
- 2. Simon Haykin, Communication Systems, John Wiley, 4th Edition, 2010.

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Describe the basic parameters of Information, the concepts of source coding techniques, and Error Control coding techniques.
- **CO2:** Apply the knowledge of Information theory and error control coding techniques to solve problems.
- **CO3:** Analyze various source coding and channel coding techniques for error detection and error correction in the information bearing signals.
- **CO4:** Compare various block to variable length coding and variable to block length coding techniques for merits and demerits. Also compare the performance of linear block codes and convolutional codes.
- **CO5:** Design various systems for linear block codes and convolutional codes.
- **CO6:** Implement the various source coding methods to improve the efficiency of information theory.

INDUSTRIAL ELECTRONICS						
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type	
22A0424T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC	
characteristicsUnderstand the	-conductor d s. e characterist pout the pract	ics of AC to ical applicati its application	DC converters. ons Electronics in on.	ode & Transistor) an		
		Syllabu			Total Hours: 48	
		Unit –			10 Hrs	
Intrinsic semicond	uctors, Extrinute resistance,	nsic semicon Zener diod	ductors, current f	semiconductors, cry low in semi conduct ors and junction ph	or, Open circuited	
		Unit –I	Ι		10 Hrs	
resistance, Transis Devices, Characte curves of PNP ju collector Configur AC to DC conve	stor as an an ristic curves inction transi ation. rters- Introdu	nplifier, Tran of junction t stor in com <u>Unit –I</u> uction, Class	nsistor construction ransistor in comm mon emitter conf II ification of Rectifi	or and transistor-α, on, Letter symbols non configuration, s figuration, The trans fiers, Half wave Rea rs, Bridge Rectifiers	for semiconductor tatic characteristic sistor in common 10 Hrs ctifiers, Full wave	
meter, Voltage mu Power Supplies, O period .Accuracy	ltiplying Rec Classification of Voltage using Zener c	tifier circuits of Voltage I Regulator, P liode, D.C. V	s, Capacitor filter, Regulators, Short Principle of auton Voltage Regulators	LC Filter, Metal Re period Accuracy of natic voltage Regula , Series Voltage Reg	ctifiers, Regulated Regulators, Long ator, Simple D.C	
series voltage rege		Unit –I		•	9 Hrs	
resistance welding welding, Energy Induction heating power source of dielectric heating,	g, Types of I storage weld merits of in- induction hea dielectric pr	Resistance w ing. Induction duction heat ating. Dielect operties of t	velding, Electronic on heating: Princ ing, Application etric heating: Princ typical materials,	ding process, Basic c welding control u iple of induction h of induction heating iciple of dielectric l electrodes used in Thermal losses in I	sed in Resistance eating, Theory of g, High frequency neating, theory of dielectric heating,	
_ 		Unit –	V		9 Hrs	
Ultrasonic strobos image on non-hon matter, Dispersive mixtures by ultras	cope, ultraso ogeneities, u and colloida sonic waves, ds by ultraso	nic as mean ltrasonic stud l effect of Ul cutting and nic waves, Pl	s of communicati dy of structure of n trasonic, Coagular machining of ha nysio-chemical eff	s, Application of on, ultrasonic flaw matter, Dispersive st ting action of Ultrasor rd materials by ultr fects of ultrasonics, o	detection, Optical udy of structure of onic, separation of asonic vibrations, chemical effects of	

Textbooks:

- 1. Fundamentals of Industrial Electronics, Bogdan M Wilamowski, J David irwin, 2nd Edition, 2011.
- 2. Industrial and Power Electronics G. K. Mithal and Maneesha Gupta, Khanna Publishers, 19th Ed., 2003.
- 3. Integrated Electronics J. Millman and C.C Halkias, McGraw Hill, 1972.

References:

- 1. Electronic Devices and circuits Theodore. H. Bogart, Pearson Education, 6th Edn., 2003.
- 2. Integrated Circuits and Semiconductor Devices Deboo and Burroughs, ISE

Course Outcomes:

After the completion of the course students will able to:

CO1: Understand the semi-conductor devices and their switching characteristics.

CO2: Apply the Ultrasonic waves with different applications.

CO3: Understand the working of Transistor and its different configurations.

CO4: Analyze the thermal effects of ultrasonic, soldering and welding by ultrasonic, ultrasonic

Drying in the industry; interpret the characteristics of AC to DC converters.

CO5: Develop the practical applications Electronics in industries.

CO6: Apply the process of Resistance welding, Induction heating and Dielectric heating in the industry.

	D		MANAGEMENT to CE,EEE,ME a		
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duratio	n Course Type
22A0512T	3:0:0:0	3	CIE: 30 SEE:70	3 Hours	OEC
Course Objecti	ves:				
This course will o	enable studen	ts to:			
• To teach the	e role of datal	base manage	ment system in an o	organization.	
• To design d	atabases usin	g data mode	ling and Logical da	tabase design tech	iniques.
• To construct	t database qu	eries using r	elational algebra an	d calculus and SQ	QL.
• To explore	implementati	on issues in o	database transaction	1.	
• To familiar	ize database s	5			
		Syllabu			Total Hours:48
Unit -I	Introd	uction to Da	tabase concepts a	nd Modeling	10Hrs
View of Data, Da The Entity-Rela	ata Models, D ationship Mo	atabase Lang D del: Overvi	guages, Database U lew of Database D	sers, Database Sy besign, Beyond E	Database Systems, stems architecture. R Design, Entities, Design with the ER
Unit -II	ŀ	Relational M	lodel, Relational A	lgebra	9Hrs
	bra: Introduc		elational data, Logio tional algebra, sele		gn, Views. ion, set operations,
Unit -III			SQL		10Hrs
•			ML queries, Views		ested & Correlated
PL/SQL: Introdu	ction, Functi	ons & Proce	dures, Triggers, Cu	rsors.	
Unit -IV		Ň	ormalization		9Hrs
	e		· •		Normalization for lued Dependencies,
4NF and 5NF.	1	action Mana	gement &Concur	rency Control	10Hrs
4NF and 5NF. Unit -V	Transa		and Recovery		
Unit -V Transaction Ma	nagement: 7	Transaction p	and Recovery processing, Transact ty, Concurrent Exec	1 ·	nsaction States,
Unit -V Transaction Ma Implementation of	nagement: 7 of Atomicity a ontrol: Lock	Transaction p and Durabilit -Based Prot	processing, Transact ty, Concurrent Exec	cutions.	nsaction States,

Text Books:

- 1. Abraham Silberschatz, Henry F. Korth, S. Sudarshan, Database System Concepts, 6th Edition, Tata McGraw-Hill Publishing Company,2017.
- 2. Raghu Ramakrishnan, Database Management System, 3rd Edition, Tata McGraw-Hill Publishing Company, 2014.

Reference Books:

- 1. Peter Rob, A.Ananda Rao, Corlos Coronel, Database Management Systems (for JNTU), Cengage Learning, 2011.
- 2. Hector Garcia Molina, Jeffrey D. Ullman, Jennifer Widom, Database System Implementation, 1st Edition, Pearson Education, United States, 2000.
- 3. E. Ramez and Navathe, Fundamental of Database Systems, 7th Edition, Pearson Education
- 4. R.P. Mahapatra & Govind Verma, Database Management Systems, Khanna Publishing House, 2016.
- 5. Carlos Coronel and Steven Morris, Database Systems: Design, Implementation, and Management, 12th edition, Cengage Learning, 2016.
- 6. John V. , Absolute beginner's guide to databases, Petersen, QUE

Web Resources:

- 1. https://www.coursera.org/learn/database-management
- 2. https://www.coursera.org/learn/sql-data-science
- 3. https://www.w3schools.com/sql/
- 4. https://www.youtube.com/watch?v=fHAfc7Hjq28&list=PLWPirh4EWFpGrpcMfZ6UcdI786 QdtSxV8
- 5. https://www.youtube.com/watch?v=HwmEcudlv44&list=PL4OCRJojkV1jN-Ed6RkQpWfBvqe0utRd6
- 6. http://www.w3schools.in/dbms/
- 7. https://www.geeksforgeeks.org/dbms/
- 8. https://www.javatpoint.com/dbms-tutorial
- 9. https://www.edureka.co/blog/dbms-tutorial/

Course Outcomes (CO):

On completion of this course, student will be able to:

CO1: Understand the Basic Concepts of Database languages, Relational model, SQL.

CO2: Choose the specific Data models for large enterprise database design.

CO3: Analyze the data efficiently through SQL instructions.

CO4: Apply Normal forms on database for eliminating the redundancy.

CO5: Demonstrate the Basic Concepts of transaction management techniques.

CO6: Apply concurrency control techniques for Database recovery.

		POWE	CR ELECTRONIC	CS		
		1	on to all Except EI			
Course Code	L:T:P	Credits	Exam marks	Exam Dura		Course Type
22A0214Ta	3:0:0	3	CIE:30 SEE:70	3 Hours		OEC
Course Objective						
5			idents learn about:	. 1. 1 0	T	•
		onductor devic	es (such as PN ju	nction diode &	Iran	sistor) and their
switching charaUnderstand the		es of AC to DC	converters			
			Electronics in indus	stries		
		Syllabus			Tota	l Hours: 49 Hr
		•			1000	
Unit-I		Power Semi	i Conductor Devic	es -I		10 Hrs
			E			
	-		Frequency and Potence ACs, GTOs - Charac	-	-	
and other Thyristo		SCR S = TRIA	ics, 010s - Chara	ciensiics and Fi	meipi	es of Operation
Unit-II	ль. 	Power Semi	Conductor Device	es-II		10 Hrs
0 1110 11	Power Semi Conductor Devices-II 10 Hrs					
Turn Off Method Circuits- Series an	ls SCR- Dyn	amic Character	– Power IGBT – S ristics of SCR - T CR's – Specificatio	wo Transistor A	Analog	gy – Triggering R's, BJT, IGBT
Turn Off Method	ls SCR- Dyn	amic Character	ristics of SCR - T	wo Transistor A	Analog	gy – Triggering
Turn Off Method Circuits- Series an Unit -III	ls SCR- Dyn nd Parallel Co	amic Character onnections of S Phase Co	ristics of SCR - T CR's – Specificatio ntrolled Converte	wo Transistor A ons and Ratings rs	Analog of SC	gy – Triggering R's, BJT, IGBT 9 Hrs
Turn Off Method Circuits- Series an Unit -III Phase Control Te	ls SCR- Dyn nd Parallel Co echnique – S	amic Character onnections of So Phase Co Single Phase L	ristics of SCR - T CR's – Specificatio	wo Transistor A ons and Ratings rs Converters – N	Analog of SCI	gy – Triggering R's, BJT, IGBT 9 Hrs iint and Bridge
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha	ls SCR- Dyn nd Parallel Co echnique – S ilf Controlled	amic Character onnections of S Phase Co Single Phase L Converters, Fu	ristics of SCR - T CR's – Specificatio ntrolled Converter ine Commutated (wo Transistor A ons and Ratings rs Converters – M overters with Re	Analog of SCI Iid Po sistive	gy – Triggering R's, BJT, IGBT 9 Hrs pint and Bridge , RL Loads and
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Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic S e Forced Comm e Width Modu	ristics of SCR - T CR's – Specificatio ntrolled Converte ine Commutated C illy Controlled Con Voltage and Curren Inverters eries Inverter – Ba nutation Circuits fo ilation Control-Har	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte	Analog of SCI Iid Po sistive Source paciton ers – S	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte	amic Character onnections of So Phase Co Single Phase L Converters, Fu verage Load V erter – Basic So e Forced Comm e Width Modu ors – Numerical	ristics of SCR - T CR's – Specificatio ntrolled Converte ine Commutated C illy Controlled Con Voltage and Curren Inverters eries Inverter – Ba nutation Circuits fo ilation Control-Har	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte monic Reduction	Analog of SCI Iid Po sistive Source paciton ers – S	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I Control Techniqu Unit -V	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic So e Forced Comm e Width Modu ors – Numerical	ristics of SCR - T CR's – Specificatio ntrolled Converter ine Commutated C illy Controlled Con /oltage and Curren Inverters eries Inverter – Ba nutation Circuits fo ilation Control-Har Problems,	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte monic Reduction	Analog of SCI Iid Po sistive Source pacitor ers – S on Tec	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha hniques-Voltag
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I Control Techniqu Unit -V AC Voltage Con	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte Ac trollers – Sir	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic S e Forced Comm e Width Modu ors – Numerical e Voltage Cont	ristics of SCR - T CR's – Specificatio ntrolled Converter ine Commutated C illy Controlled Con /oltage and Curren Inverters eries Inverter – Ba nutation Circuits fo ilation Control-Har Problems, rollers & Cyclo Co	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte monic Reduction onverters vallel – With R a	Analog of SCI Iid Po sistive Source pacitor ers – S on Tec	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha hniques-Voltag
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I Control Techniqu Unit -V AC Voltage Con	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled avation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte Ac trollers – Sir RIAC – TRIA	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic Se e Forced Comm e Width Modu ors – Numerical e Voltage Cont ngle Phase Two AC with R– De	ristics of SCR - Tr CR's – Specificatio ntrolled Converter ine Commutated Converter ine Commutated Converter ing Controlled Converter /oltage and Curren Inverters eries Inverter – Banutation Circuits for alation Control-Har Problems, rollers & Cyclo Co o SCR's in Anti Par privation of RMS Lo	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte monic Reduction onverters vallel – With R a	Analog of SCI fid Po sistive Source pacitor ers – S on Tec	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha hniques-Voltag
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I Control Techniqu Unit -V AC Voltage Con of Operation of T Wave Forms – Fin	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte Ac trollers – Sir RIAC – TRIA	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic S e Forced Comm e Width Modu ors – Numerical e Voltage Cont ngle Phase Two AC with R– De -Numerical Pro	ristics of SCR - Tr CR's – Specificatio ntrolled Converter ine Commutated Converter ine Commutated Converter ing Controlled Converter /oltage and Curren Inverters eries Inverter – Banutation Circuits for alation Control-Har Problems, rollers & Cyclo Co o SCR's in Anti Par privation of RMS Lo	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverter monic Reduction onverters rallel – With R a bad Voltage, Cu	Analog of SCI fid Po sistive Source pacitor ers – S on Tec and RI urrent a	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha hniques-Voltag 10 Hrs L Loads – Mod and Power Fact
Turn Off Method Circuits- Series an Unit -III Phase Control To Connections – Ha RLE Load– Deri Numerical Proble Unit -IV Inverters – Sing Inverter – Wavefo and Full Bridge I Control Techniqu Unit -V AC Voltage Con of Operation of T Wave Forms – Fin	ls SCR- Dyn nd Parallel Co echnique – S alf Controlled ivation of Av ms. le Phase Inve orms – Simple inverters-Puls es for Inverte Ac trollers – Sir RIAC – TRIA ring Circuits – rs – Single P	amic Character onnections of S Phase Co Single Phase L Converters, Fu verage Load V erter – Basic S e Forced Comm e Width Modu ors – Numerical e Voltage Cont agle Phase Two AC with R– De -Numerical Pro Phase Mid Poir	ristics of SCR - Tr CR's – Specificatio ntrolled Converter ine Commutated Converter ine Commutated Converter ing Controlled Converter //oltage and Curren Inverters eries Inverter – Banutation Circuits for alation Control-Har Problems, rollers & Cyclo Co o SCR's in Anti Par privation of RMS Lobblems	wo Transistor A ons and Ratings rs Converters – M overters with Re t – Effect of S sic Parallel Cap r Bridge Inverte monic Reduction onverters rallel – With R a bad Voltage, Cu	Analog of SCI Iid Po sistive Source pacitor ers – S on Tec and RI urrent a	gy – Triggering R's, BJT, IGBT 9 Hrs oint and Bridge , RL Loads and Inductance – 10 Hrs Inverter Bridg ingle Phase Ha hniques-Voltag 10 Hrs L Loads – Mod and Power Fact Inductive Load

Textbooks:

- 1. Power Electronics, M. D. Singh and K. B. Khanchandani, Mc Graw Hill Education (India) Pvt. Ltd., 2nd Edition, 2007, 23rd Reprint 2015.
- 2. Power Electronics: Circuits, Devices and Applications, Muhammad H. Rashid, Pearson, 3rdEdition, 2014, 2nd Impression 2015

Course Outcomes(CO):

At the end of studying the course, the student should be able to:

CO1: Understand basic concepts of diode and transistor and its operation.

- CO2: Understand the characteristics and usage of basic Power Semiconductor Devices.
- **CO3:** Understand basic operating principles of power semiconductor switching devices.
- **CO4:** Understand the Construction of power electronic converters, inverters, AC voltage controllers, and cyclo converters.
- **CO5:** Understand the operation of power electronic converters, inverters, AC voltage controllers, and cyclo converters.
- **CO6:** How to apply the learnt principles and methods to practical applications.

	FUN	DAMENTAL	S OF DRONE TE	CHNOLOGY		
Course Code	L:T:P	Credits	Exam marks	Exam Durat	ion	Course Type
22A0332Tc	2: 1:0	3	CIE:30 SEE:70	3 Hours		OEC
Course Objective	es:				l	
The course should	enable the st	udents to				
• To make the	students to un	derstand the b	asic concepts of UA	V drone system	ns.	
• To introduce	the stability a	and control of	an aircraft			
		Syllabus	5		Tota	l Hours: 50
UNIT-I		Introdu	ction to Drones		10 H	rs
Introduction to U	Inmanned Air	craft Systems,	History of UAV dr	ones, classificat	ion of	drones, System
Composition, app	olications					
UNIT-II		Design of U	AV Drone System	s	10Hr	S
Introduction to I	Design and Se	election of the	System, Aerodyna	amics and Airfr	ame C	Configurations,
	f Aircraft Typ	bes, Design St	andards and Regula	atory Aspects-In	idia Sp	becific, Design
for Stealth.						
UNIT-III		Avionics H	ardware of Drones	S	10Hr	S
Autopilot, AGL-	pressure sense	ors servos-acce	elerometer –gyros-a	ctuators- power	suppl	y-processor,
integration, insta						
UNIT-IV	Co	mmunication	, Payloads and Co	ntrols	10Hr	S
	-	-	loads, Telemetry, T	-		
	luency range,	modems, men	nory system, simula	tion, ground tes	t-analy	ysis-trouble
shooting UNIT-V		Novicot	ion and Tasting		10H	
	Casting, Wayn		ion and Testing	oftware Swater		
System In-flight				onware, System	I GIOU	nu resting,
• •	resting, r dtu		la chanenges			
Textbooks:						
1. Reg Austin "U	Jnmanned Air	craft Systems	UAV design, devel	lopment and dep	oloyme	ent", Wiley,
2010.						
2. Robert C. Nel	son, Flight St	ability and Au	tomatic Control, Mo	cGraw-Hill, Inc,	, 1998	
3. Kimon P. Val	avanis, "Adva	nces in Unma	nned Aerial Vehicle	es: State of the A	Art and	l the Road to
	Springer, 2007					
A DOMONIA S	ringer, 2007					
	_					
Reference Books	:					
Reference Books		J Gleason, "In	troduction to UAV	Systems", UAV	' Syste	ems, Inc, 1998
Reference Books 1. Paul G Fahlst	rom, Thomas			•	•	
Reference Books 1. Paul G Fahlst	rom, Thomas		troduction to UAV anned Air Vehicle	•	•	

Course Outcomes(CO):

At the end of studying the course, the student should be able to:

CO1: Understand the Concept of UAV, its components and its known applications.

CO2: Identify the type of drone and design a drone for a given application/specification.

CO3: Ability to design UAV drone system

CO4: To understand working of different types of engines and its area of applications.

CO5: To understand static and dynamic stability dynamic instability and control concepts

CO6: To know the loads taken by aircraft and type of construction and also construction materials.

		BUILDI	ING MATERIALS				
		(ME, CSE, Al	I&ML, CS, DS, EC	CE, EEE)			
Course Code	L:T:P	Credits	Exam marks	Exam Durat	xam Duration Course		
22A0149T	3:1:0:0	3	CIE:30 SEE:70	3 Hours		OEC	
Course Objective	es:						
• To identify the	e traditional m	aterials that are	e used for building c	onstructions.			
• To explain ba	sic concepts of	f building comp	oonents such as stain	case and maso	nry		
• To know the	causes of dam	pness in structu	res and its preventi	ve measures			
• To understar	nd the building	rules, building	bye laws and acous	tics of building			
		Syllabus			Total	Hours: 48	
Unit-I		MA	ATERIALS			9 Hrs	
		• -	masonry -Brick-typ	bes of brick ma	sonry- lii	me Cement –	
Timber – Season Unit-II			Inding works	\$		9 Hrs	
				0			
Lintels, Arches a	and Vaults – S	Staircases, Lifts	– Types. Differen	t types of floor	ing-Conc	crete, Mosaic,	
Terrazo floors; D	oifferent types of	of roofs- Pitche	ed, Flat and Curved	Roofs. Lean-to-	-Roof, Co	oupled Roofs,	
Trussed roofs - k	Ling and Queer	n Post Trusses.	Doors & Windows-	Types and Spec	cification	S	
Trussed roofs - k	Ling and Queer		Doors & Windows-	Types and Spec		s 10 Hrs	
Unit -III		D				10 Hrs	
Unit -III Dampness and it	s prevention:	D Causes of dam	AMPNESS	f dampness-req	uirement	10 Hrs	
Unit -III Dampness and in	s prevention:	D Causes of dam erials for damp	AMPNESS pness- ill effects o	f dampness-req	uirement ng.	10 Hrs	
Unit -III Dampness and it material for dam Unit -IV Elements of buil	s prevention: p proofing-mat ding planning-	D Causes of dam erials for damp BUILD - basic requirer	DAMPNESS pness- ill effects o proofing –methods	f dampness-req of damp proofi	uirement ng.	10 Hrs s of an ideal 10 Hrs	
Unit -III Dampness and ir material for dam Unit -IV Elements of buil based on utility-o	ts prevention: p proofing-mat ding planning- other requireme	D Causes of dam erials for damp BUILD • basic requirer ents	DAMPNESS apness- ill effects o proofing –methods ING PLANNING ments-orientation-pl	f dampness-req of damp proofi anning for ener	uirement ng. rgy effici	10 Hrs s of an ideal 10 Hrs ency-plannin	
Unit -III Dampness and it material for dam Unit -IV Elements of buil	ts prevention: p proofing-mat ding planning- other requireme	D Causes of dam erials for damp BUILD • basic requirer ents	DAMPNESS apness- ill effects o proofing –methods ING PLANNING	f dampness-req of damp proofi anning for ener	uirement ng. rgy effici	10 Hrs s of an ideal 10 Hrs	
Unit -III Dampness and in material for dam Unit -IV Elements of buil based on utility-o Unit -V Zoning regulation	ding planning- other requirement	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la	DAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivis	f dampness-req of damp proofi anning for ener LAWS ions; Building	uirement ng. rgy effici regulatic	10 Hrs 10 of an ideal 10 Hrs ency-planning 10 Hrs ons; Rules for	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulation special type of	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la	DAMPNESS pness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I	f dampness-req of damp proofi anning for ener LAWS ions; Building	uirement ng. rgy effici regulatic	10 Hrs 10 of an ideal 10 Hrs ency-planning 10 Hrs ons; Rules for	
Unit -III Dampness and in material for dam Unit -IV Elements of buil based on utility-o Unit -V Zoning regulation special type of Information Syst	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la	DAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivis	f dampness-req of damp proofi anning for ener LAWS ions; Building	uirement ng. rgy effici regulatic	10 Hrs s of an ideal 10 Hrs ency-planning 10 Hrs ons; Rules for	
Unit -III Dampness and in material for dam Unit -IV Elements of buil based on utility-o Unit -V Zoning regulation special type of Information System Textbooks:	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli	DAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivis	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor	uirement ng. rgy effici regulatic space in	10 Hrs s of an ideal 10 Hrs ency-plannin 10 Hrs ons; Rules for	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulations special type of Information System Textbooks: 1. Building Dra	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli Shah, C.M. Kal	PAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivise nth, floor and carp e and S.Y. Patki, Ta	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor	uirement ng. rgy effici regulatic space in Il, New	10 Hrs s of an ideal 10 Hrs ency-planning 10 Hrs ons; Rules for dex. Building	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulations special type of Information System Textbooks: 1. Building Dra 2. B.C. Punmia	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em wing by M.G. 3 , Ashok Kuma	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli Shah, C.M. Kal ar Jain and Ar	DAMPNESS appness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivisanth, floor and carp	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor	uirement ng. rgy effici regulatic space in Il, New	10 Hrs s of an ideal 10 Hrs ency-plannin 10 Hrs ons; Rules fo dex. Building	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulations special type of Information System Textbooks: 1. Building Dra 2. B.C. Punmia Publications	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em wing by M.G. 5 , Ashok Kuma (P) Ltd., New I	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli Shah, C.M. Kal ar Jain and Ar	PAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivise nth, floor and carp e and S.Y. Patki, Ta	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor	uirement ng. rgy effici regulatic space in Il, New	10 Hrs s of an ideal 10 Hrs ency-plannin 10 Hrs ons; Rules fo dex. Building	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulations special type of Information System Textbooks: 1. Building Dra 2. B.C. Punmia Publications	ts prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em wing by M.G. 5 , Ashok Kuma (P) Ltd., New I	D Causes of dam erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli Shah, C.M. Kal ar Jain and Ar	PAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivise nth, floor and carp e and S.Y. Patki, Ta	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor	uirement ng. rgy effici regulatic space in Il, New	10 Hrs s of an ideal 10 Hrs ency-plannin 10 Hrs ons; Rules fo dex. Building	
Unit -III Dampness and in material for damy Unit -IV Elements of buil based on utility-o Unit -V Zoning regulations special type of Information System Textbooks: 1. Building Dra 2. B.C. Punmia Publications Reference Books	is prevention: p proofing-mat ding planning- other requirement ons; Regulation buildings; Cal- em wing by M.G. 5 , Ashok Kuma (P) Ltd., New I	D Causes of dame erials for damp BUILD - basic requirer ents BUILDING R ns regarding la culation of pli Shah, C.M. Kal ar Jain and Ar Delhi	PAMPNESS ppness- ill effects o proofing –methods ING PLANNING nents-orientation-pl ULES AND BYE-I ayouts or subdivise nth, floor and carp e and S.Y. Patki, Ta	f dampness-req of damp proofi anning for ener LAWS ions; Building et area; Floor ata McGraw-Hi suilding Constru	uirement ng. rgy effici regulatic space in Il, New	10 Hrs s of an ideal 10 Hrs ency-plannin 10 Hrs ons; Rules fo dex. Building	

E-resources:

- 1 http://nptel.ac.in/courses/105104103/
- 2. http://www.academicpub.org/jwrhe/
- 3. http://www.peo.on.ca/index.php/ci_id/21843/la_id/1

Course Outcomes(CO):

On completion of this course, student will be able to:

- **CO1:** To understand the characteristics of different building materials.
- **CO2:** Differentiate brick masonry, stone masonry construction and bonds used in construction of walls of buildings.
- **CO3:** To know about the causes of dampness in buildings and its ill effects.

CO4: To understand the principles of planning in buildings.

CO5: Describe capable of understanding building rules.

CO6: Acquire the knowledge about bye-laws and building elements.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0425P	0:0:3	1.5	CIE:30	3 Hours	PCC
			SEE:70		
Course Objecti	ves:				
• To underst	and and deve	elop HDL(Ver	ilog) source code fo	or the given problem/	experiment
• To analyz	e the obtaine	d results of the	e given experiment/	problem	
• To simula	te the given	circuit with su	itable simulator and	l verify the results	
• To unders	tand how to	use FPGA/CP	LD hardware tools	in the lab	
• To design	and impleme	ent the experim	nents using FPGA/C	CPLD hardware tools	
			Syllabus		
LIST OF EXPI	ERIMENTS	: (Conduct A	ny 10 experiments).	
1. Realizatio	n of Logic g	ates			
2. Design and	d Implementa	ation of an Inv	erter		
3. Design and	d Implementa	ation of Full ad	lder.		
4. Design and	d Implementa	ation of Full S	ubtractor		
5. Design and	d Implementa	ation of 4-bitco	omparator.		
6. Design and	d Implementa	ation of 4-bit r	ipple carry and carr	y look ahead adder	
7. Design and	d Implementa	ation of 16:1 n	nux through 4:1 mu	X	
8. Design and	d Implementa	ation of 3:8 de	coder realization th	rough 2:4 decoder	
9. Design and	d Implementa	ation of 8:3 en	coder		
10. Design and	d Implementa	ation of 8-bit p	parity generator and	checker	
11. Design and	d Implementa	ation of differe	ent Flip-Flops		
12. Design and	d Implementa	ation of 8 bit u	p-down counter		
13. Design	and Implem	entation of 4b	it sequence detector	r through Mealy and	Moore state
machines.					
Software Requ					
-	-	vare like Xilin	x Vivado / Altera (l	Intel) / Cypress / E	quivalent Industr
Standard Softwa					
ii)Personal com	nputer system	n with necessar	ry software to run th	he programs and to in	nplement
Course Outco	mes(CO):				
On completion	of this cours	e, student will	be able to:		
CO1: Underst	and HDL(Ve	erilog) source	code for the given p	problem/experiment	
CO2: Develop	HDL(Verile	og) source cod	le for the given prob	blem/experiment	
CO3: Analyze	e the obtained	l results of the	given experiment/j	problem	

CO4: Simulate the given circuit with suitable simulator and verify the results

CO5: Understand how to use FPGA/CPLD hardware tools in the lab

CO6: Design and implement the experiments using FPGA/CPLD hardware tools

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0426P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PCC
Course Object	ives:	L			
• To make st	udents to un	derstand var	ious antennas		
• To understa	and the wor	king of diffe	rent micro wave o	components and verify	characteristics using
micro wave	e bench setu	ıp.			
		-	Syllabus		
Part-A: Anten	nas Lab				
• To ana	alyze the ch	aracteristics	of Simple Dipole	$\lambda/2$ and $\lambda/4$ Antenna	
• To and	alyze the va	riation in the	e Radiation Streng	th at given distance fr	om Antenna
	•		neorem for Antenr	as	
	•	Dipole $\lambda/2A_1$			
-	-		-	ement folded dipole.	
	•		of micro strip ant	ennas ern of broad side and	and fine amous
• 10 and	aryze the ch		and radiation pat		end me arrays.
 Direct VSWI Measu Measu Attenu Micr NOTE: At least 	R Measurer arement of S arement of S ation Meas owave Free 5 Experime	ler Character nent. Wave Guide Scattering Pa surement. Juency Meas	Parameters. trameters of a Mag urement	gic Tee. e done in the semester	
Course Outcor					
-			ents will able to:		
•			tics of Antennas		
CO2: Understa	nd the work	king, differen	t microwave com	ponents and sources in	n a microwave bench
CO3: Verify the	e characteri	stics of vario	ous microwave co	mponents using micro	wave bench setup.
CO4: Verify Th	neorems app	plicable for a	intennas		
CO5: Measure	scattering p	parameters of	f microwave comp	oonents.	

		S	OFT SKILLS				
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type		
22A0428P	1:0:2	2	CIE:30	SC SC			
			SEE:70				
Course Objectiv	ves:						
• To encourag	e all round	development of	the students by focu	using on soft skills.			
• To make the	students av	vare of critical t	hinking and problen	n-solving skills.			
• To develop l	eadership s	kills and organiz	zational skills throug	gh group activities.			
• To function	effectively	with heterogene	eous teams.				
Syllabus				Total Ho	urs:45		
Unit -I		Soft	Skills & Communi	cation Skills	9Hrs		
Introduction me	aning signi	ficance of soft s	kills Vital Compo	nents of communicati	on skills -		
			al Communication.	inclus of communicati	on skins -		
1				ity of thought - Inter	personal Skills-		
		-		nd film Reviews by			
-			-	temporary issues or o			
				addresses and speech	• •		
			-	ng – Mock interview	0		
Skills.			1	8	U		
Unit -II			Critical Think	ing	9Hrs		
Active Listening	– Observa	tion – Curiosity	– Introspection –	Analytical Thinking	– Open-		
mindedness – Cr	eative Thinl	king.	-		-		
Activities: Gathe	ering inforn	nation and stati	stics on a topic - se	equencing – assorting	, – reasoning –		
critiquing issues	- placing th	ne problem – fi	nding the root cause	e - seeking viable sol	ution – judging		
with rationale – e	evaluating th	ne views of othe	ers - Case Study, Sto	ory Analysis.			
Unit -III		Probl	em Solving & Deci	sion Making	9Hrs		
Meaning & features of Problem Solving – Managing Conflict – Conflict resolution – Methods of							
-		-	g in teams – Method				
Activities: Placin	ng a proble	m which involv	es conflict of intere	ests, choice and views	s – formulating		
the problem - e	xploring so	lutions by prop	per reasoning – Dis	scussion on importan	t professional,		
career and organ	izational de	cisions and init	iate debate on the a	ppropriateness of the	decision. Case		
Study & Group Discussion.							
Unit -IVEmotional Intelligence & Stress Management9Hrs							
Managing Emoti	ons – Think	ting before Read	cting – Empathy for	Others - Self-awarer	ess – Self-		
Regulation – Stress factors – Controlling Stress – Tips.							
Activities: Provi	Activities: Providing situations for the participants to express emotions such as happiness,						
enthusiasm, grati	itude, and s	ympathy, and co	onfidence, compassi	on in the form of writ	ten or oral		
presentations. Pr	oviding opp	ortunities for th	e participants to nar	rate certain crisis and	stressridden		
situations caused	l by failure,	anger, jealousy,	, resentment and fru	stration in the form of	f written and		
oral presentation	, Organizing	g Debates.					

Unit -V	Leadership Skills	9Hrs					
Team-Building – Decision-Making – Accountability – Planning – Public Speaking – Motivation –							
Risk Taking - Team Building - Time Management.							
	p with a consensus among the participants- choosing a leader						
	press views on leadership- democratic attitude- sense of sacri ommodating nature- eliciting views on successes and failures						
	e and experience of the participants, Public Speaking, Activ						
	, Decision Making, Group discussion etc.						
Text Books:							
1. Personality Developm	nent and Soft Skills (English, Paperback, MitraBarunK.)Publ	isher: Oxford					
University Press; Pap	/Cdr edition (July 22, 2012)						
2. Personality Developm	nent and Soft Skills: Preparing for Tomorrow, Dr Shikha Kap	oor Publisher					
: I K International Pul	blishing House; 0 edition (February 28, 2018)						
References:		1					
1. Soft skills: personality 2018.	y development for life success by Prashant Sharma, BPB pub	lications,					
	. Published by S.Chand						
•	ated Approach to Maximise Personality Gajendra Singh Chau	ıhan.					
Sangeetha Sharma Pu		,					
4. Communication Skills	s and Soft Skills (Hardcover, A. Sharma) Publisher: Yking bo	ooks					
	BIG IMPACT (English, Paperback, RenuShorey) Publisher: N						
_	English Dr. Rajiv Kumar Jain, Dr. Usha Jain Publisher: Vaya	u Education					
of India.							
Online Learning Resour 1. https://youtu.be/DUIsl	rces: NJtg2L8?list=PLLy_2iUCG87CQhELCytvXh0E_y-bOO1_q						
	gJZ0t6A?list=PLzf4HHlsQFwJZel_j2PUy0pwjVUgj7KlJ	l					
3. https://youtu.be/-Y-R9							
4. https://youtu.be/gkLsr							
5. https://youtu.be/2bf9k	K2rRWwo						
6. https://youtu.be/Fchfl	E3c2jzc						
Course Outcomes:							
After the completion of the course students will able to :							
CO1: Memorize various elements of effective communicative skills.							
CO2: Interpret people at the emotional level through emotional intelligence.							
CO3: Apply critical think	king skills in problem solving.						
CO4: Analyze the needs	of an organization for team building.						
CO5: Judge the situation	and take necessary decisions as a leader.						
CO6: Develop social and	d work-life skills as well as personal and emotional well-beir	ıg.					

	т	NESICN TH			NT		
DESIGN THINKING AND INNOVATION (Common to CSE, AIML, CS, DS, CE, EEE, ME and ECE)							
Course Code	L:T:P	Credits	Exam Marks	Exam D		Course Type	
22A0526	2:0:0	0	CIE:30		•	MC	
Course Objectives:							
The objective of	f this course	is to familiar	ize students with de	sign thinkin	g process a	as a tool for	
breakthrough in	novation. It	aims to equip	students with desig	n thinking s	skills and i	gnite the minds	
to create innova	tive ideas, de	evelop soluti	ons for real-time pro	oblems.			
		Syllabus			Tota	l Hours:48	
Unit -I	In	troduction t	o Design Thinking			9Hrs	
	sign compon	ents. Princip	of Design, basics les of design. Intro- try.	-		-	
Unit -II		Design Th	inking Process			9Hrs	
Unit -III Art of innovations in organizations	on, Differences. Creativity	Inn e between in to Innovation	xplain about product ovation novation and creati n. Teams for innova vation and creativit	vity, role of tion, Measu	creativity ring the in	npact and value	
innovation, Deb	-			5 /	1 .		
Unit -IV		Produ	ıct Design]	10Hrs	
planning, prod	uct specifica	ations. Innov	duct design, Product vation towards pro rifications, Explaining	duct design	Case stu	idies. Activity:	
Unit -V	Desig	n Thinking	in Business Proces	ses]	10Hrs	
redefine busines Extreme compe Design thinkin	ss – Business tition, Standa g for Startu esting protot	s challenges: ardization. D 1ps. Definin 1ypes. Activit	z Strategic Innovati Growth, Predictabi esign thinking to ma g and testing Bus ry: How to market o	lity, Change eet corporate iness Mode	e, Maintair e needs. els and B	usiness Cases.	
	-		per Bollins (2009) vation, Idris Mootee	, 2013, Johr	n Wiley &	Sons	

- 1. Design Thinking in the Classroom by David Lee, Ulysses press
- 2. Design the Future, by Shrrutin N Shetty, Norton Press
- 3. Universal principles of design- William lidwell, kritinaholden, Jill butter.
- $4. \ \ \, The \ era \ of \ open \ innovation-chesbrough.H$

Course Outcomes (CO):

On completion of this course, student will be able to:

CO1: Define the concepts related to design thinking.

CO2: Explain the fundamentals of Design Thinking and innovation

CO3: Apply the design thinking techniques for solving problems in various sectors.

CO4: Analyze to work in a multidisciplinary environment

CO5: Evaluate the value of creativity

CO6: Formulate specific problem statements of real time issues

Category	Course	Course Title		Hours per week			
	Code		L	Т	Р	С	
PCC	22A0434T	Microprocessor and Microcontroller	3	0	0	3	
PCC	22A0435T	Digital Signal Processing	3	0	0	3	
PCC	22A0436T	VLSI Design	3	0	0	3	
PEC		Professional Elective-II:	3	0	0	3	
OEC		Open Elective-II:	3	0	0	3	
PCC (Lab)	22A0440P	Microprocessor and Microcontroller Lab	0	0	3	1.5	
PCC (Lab)	22A0441P	VLSI Design Lab	0	0	3	1.5	
PCC (Lab)	22A0442P	Digital Signal Processing Lab	0	0	3	1.5	
SC	22A0539	Skill Oriented Course: JAVA Programming	1	0	2	2	
MC	22A0032M	Mandatory Course: Research Methodology	2	0	0	0	
				To	otal cre	edits 21.	

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S. No.	Course Code	Name of the Professional Elective-II
1	22A0437T	Electronic Measurements and Instrumentation
2	22A0438T	Sensors & Actuators
3	22A0439T	Radar and Satellite Communications

S. No.	Course Code	Name of the Open Elective-II
1	22A0528T	Machine Learning
2	22A0238Ta	Modern Control theory
3	22A0150T	Environmental Economics
4	22A0027T	Organizational Behaviour

Category	Credits
Professional Core Courses (PCC)	13.5
Professional Elective Courses (PEC)	3
Open Elective Courses (OEC)	3
Skill Oriented Course (SC)	2
Industrial/Research Internship (Mandatory) 2 Months	-
Total	21.5

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0434T	3:0:0	3	CIE:30	3 Hours	PCC
			SEE:70		
Course Objecti	ves:			· · · ·	
• To introdu	ce fundament	tal architectu	ral concepts of mic	roprocessors and mici	cocontrollers.
• To impart	knowledge of	n addressing	modes and instruct	ion set of 8086 and 80)51
• To introdu	ce assembly]	language pro	gramming concepts	5	
• To explain	memory and	I/O interfaci	ing with 8086 and 8	3051	
• To introdu	ce16 bit and	32 bit microc	controllers.		
		Syllal	bus		Total Hours: 48
		Unit	-I		10 Hrs
8086 Architec	ture: Main f	eatures, pin	diagram/description	n, 8086 microprocess	or family, interna
architecture, bu	s interfacing	unit, execut	tion unit, interrupt	s and interrupt resp	onse, 8086 system
timing, minimu	m mode and 1		ode configuration.		
		Unit ·			10 Hrs
-		_	-	actions, addressing	
directives, writi	ng simple pi	ograms with	n an assembler as	sembly language pro	oram develonmen
		0	i un ubbennonen, ub	semely language pro	Sium developmen
tools.					
		Unit -	-III		10 Hrs
8086 Interfacii		Unit - ductor memo	-III pries interfacing (R	RAM, ROM), Intel 8	10 Hrs 255 programmable
8086 Interfacion peripheral interf	face, Interfac	Unit - ductor memoring switches	-III pries interfacing (R and LEDS, Interf	RAM, ROM), Intel 8 facing seven segment	10 Hrs 255 programmable displays, software
peripheral inter and hardware i	face, Interfac nterrupt appl	Unit - ductor memo ing switches ications, Inte	- III pries interfacing (R and LEDS, Interf el 8251 USART a	RAM, ROM), Intel 8 facing seven segment rchitecture and interf	10 Hrs 255 programmable displays, software Facing, Intel 8237a
8086 Interfacin peripheral interf and hardware in DMA controller	face, Interfac nterrupt appl	Unit - ductor memo ing switches ications, Inte	- III pries interfacing (R and LEDS, Interf el 8251 USART a	RAM, ROM), Intel 8 facing seven segment	10 Hrs 255 programmable displays, software Facing, Intel 8237a
8086 Interfacion peripheral interfacion and hardware i	face, Interfac nterrupt appl	Unit - ductor memo ing switches ications, Inte otor, A/D and	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters,	RAM, ROM), Intel 8 facing seven segment rchitecture and interf	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup
8086 Interfacin peripheral interf and hardware i DMA controller controllers.	face, Interfac nterrupt appl r, stepper mo	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit -	-III ories interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle	face, Interfac nterrupt appl r, stepper mo r - Architect	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits -
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set -	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic &	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits -
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set -	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic &	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo uctions And Progra	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits -
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C.	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051 z Logic Instru Unit -	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo uctions And Progra -V	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por	10 Hrs 255 programmable displays, software Cacing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C.	Unit - ductor memo- ing switches ications, Inte- otor, A/D and Unit - ture of 8051 c Logic Instru- ture function unit - er-Timers/	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo uctions And Progra -V Counters , Progr	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag	10 Hrs 255 programmable displays, softward facing, Intel 8237 rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming -	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051 c Logic Instru- Unit - er-Timers/ rogramming	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV I –Addressing mo uctions And Progra -V Counters , Progr – LCD & Keyboa	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag	10 Hrs 255 programmable displays, softward facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por C, DAC & Senso
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming - Interfacing - Ex	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P ternal Memo	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru-	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV I –Addressing mo uctions And Progra -V Counters , Progr – LCD & Keyboa	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag amming 8051 Time ard Interfacing - AD I Waveform generation	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por C, DAC & Senso
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming - Interfacing - Ex Microprocessor,	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P ternal Memo	Unit - ductor memo ing switches ications, Inte otor, A/D and Unit - ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru- ture of 8051 z Logic Instru-	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo actions And Progra -V Counters , Progr – LCD & Keyboa Stepper Motor and	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag amming 8051 Time ard Interfacing - AD I Waveform generation	10 Hrs 255 programmable displays, software facing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por C, DAC & Senso
8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming - Interfacing - Ex Microprocessor, Textbooks:	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P ternal Memo , Microcontro handi, A K R	Unit - ductor memori ing switches ications, Inte- otor, A/D and Unit - ture of 8051 c Logic Instru- ture of 8051 c Logic Instru- c Logic Ins	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo actions And Progra -V Counters , Progr – LCD & Keyboa Stepper Motor and ction to RISC proce	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag amming 8051 Time ard Interfacing - AD I Waveform generation	10 Hrs 255 programmable displays, softward Gacing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por C, DAC & Senso on - Comparison o
 8086 Interfacin peripheral interfacin and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming - Interfacing - Ex Microprocessor, Textbooks: 1. K M Bhurc Hill Educat 	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P ternal Memo , Microcontro handi, A K R ion, 2017. Microcontro	Unit - ductor memori ing switches ications, Inte- otor, A/D and Unit - ture of 8051 c Logic Instru- ture of 8051 c Logic Instru- con- con- con- con- con- con- con- con	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo uctions And Progra -V Counters , Progr – LCD & Keyboa Stepper Motor and ction to RISC proce d Microprocessors	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag ramming 8051 Time ard Interfacing - AD I Waveform generation	10 Hrs 255 programmable displays, software Gacing, Intel 8237a rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Por C, DAC & Senso on - Comparison or edition, McGraw
 8086 Interfacin peripheral interf and hardware i DMA controller controllers. Microcontrolle Instruction set - 8051 Programm Interfacing M Programming - Interfacing - Ex Microprocessor, Textbooks: 1. K M Bhurc Hill Educat 2. Raj Kamal, 	face, Interfac nterrupt appl r, stepper mo r - Architect Arithmetic & ing in C. icrocontrolle Interrupts P ternal Memo , Microcontro handi, A K R ion, 2017. Microcontro	Unit - ductor memori ing switches ications, Inte- otor, A/D and Unit - ture of 8051 c Logic Instru- ture of 8051 c Logic Instru- con- con- con- con- con- con- con- con	-III pries interfacing (R and LEDS, Interf el 8251 USART a d D/A converters, -IV 1 –Addressing mo uctions And Progra -V Counters , Progr – LCD & Keyboa Stepper Motor and ction to RISC proce d Microprocessors	RAM, ROM), Intel 8 facing seven segment rchitecture and interf Need for 8259 progr odes - I/O Pins Por ms-Assembly languag ramming 8051 Time ard Interfacing - AD I Waveform generatic essors and Peripherals, 3rd e	10 Hrs 255 programmable 255 programmable displays, softward Gacing, Intel 8237 rammable interrup 9 Hrs ts and Circuits - ge programming- 9 Hrs ers - Serial Poin C, DAC & Senso on - Comparison o edition, McGraw

Course Outcomes:

After the completion of the course students will able to:

CO1: Distinguish between microprocessors & microcontrollers

CO2: Develop assembly language programming

CO3: Describe interfacing of 8086 with peripheral devices

CO4: Understand the concept of Microcontrollers

CO5: Design applications using microcontrollers

CO6: Design external Memory Interface using microcontroller.

		DIGITAL	SIGNAL PROC	CESSING	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0435T	3:0:0	3	CIE:30 SEE:70	3 Hours	PCC
Course Objectiv	es:				
To descr	ibe discrete tin	ne signals an	d systems.		
• To teach	importance of	FFT algorith	nm for computation	on of Discrete Fourie	er Transform.
 To expos 	se various impl	ementations	of digital filter st	ructures.	
To prese	nt FIR and IIR	Filter design	n procedures.		
To outlin	ne need of Mul	ti-rate Proces	ssing.		
		Syllaby	~		Total Hours: 48
Unit –I	Introdu	Syllabus		and systems	10tal Hours: 48
			rete time signals	-time signals and s	
				representation of d	
		•	1 2	-domain, pole-zero s	U
-	-		-	-	-
Unit-II			form & Fast Fou		10 Hrs
				ier Series, propertie	
	n, Inverse DF	T, properties	s of DFT, Linear	and Circular convo	olution, convolution
using DFT.	e t				,• • ,•
				form, Radix-2 Deci	mation in time and
Decimation in fre	quency FF1, I		· · ·		
Unit-III			IR Filters		10 Hrs
				approximations –	
Chebyshey, Desi				ers by Impulse inv	
		ency transto	rmations Basic s	tructures of HR Filt	are Direct torm I
transformation m					ers - Direct Iorni-I
transformation m Direct form-II, Ca		d Parallel fo	rm realizations		1
transformation m Direct form-II, Ca Unit-IV	ascade form an	d Parallel fo F	rm realizations IR Filters		9 Hrs
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro	ascade form an oduction, Char	d Parallel for F acteristics o	rm realizations IR Filters f FIR filters with	h linear phase, Free	9 Hrs Juency response o
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro linear phase FIR	ascade form an oduction, Char R filters, Desi	d Parallel fo F acteristics o gn of FIR	rm realizations IR Filters f FIR filters with filters using Fo	h linear phase, Frequerier series and w	9 Hrs Juency response o indowing method
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro linear phase FIF (Rectangular, Tria	ascade form an oduction, Char R filters, Desi angular, Raiseo	d Parallel fo F acteristics o gn of FIR d Cosine, Ha	rm realizations IR Filters f FIR filters with filters using Fo unging, Hamming	h linear phase, Frec ourier series and w , Blackman), Compa	9 Hrs Juency response of indowing method arison of IIR & FII
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro linear phase FIF (Rectangular, Tria filters, Basic struc	ascade form an oduction, Char R filters, Desi angular, Raised ctures of FIR F	d Parallel fo F acteristics o gn of FIR d Cosine, Ha ilters – Direc	rm realizations IR Filters f FIR filters with filters using Fo anging, Hamming ct form, Cascade	h linear phase, Frecourier series and w , Blackman), Compa form, Linear phase re	9 Hrs Juency response o indowing method arison of IIR & FIF ealizations
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro linear phase FIF (Rectangular, Tria filters, Basic struc Unit-V	ascade form an oduction, Char R filters, Desi angular, Raised ctures of FIR F M	d Parallel fo F acteristics o gn of FIR d Cosine, Ha ilters – Direc fulti rate Dig	rm realizations IR Filters f FIR filters with filters using Fo anging, Hamming ct form, Cascade = gital Signal Proce	h linear phase, Frec ourier series and w , Blackman), Compa form, Linear phase re essing	9 Hrs quency response o indowing method arison of IIR & FIF ealizations 9 Hrs
transformation m Direct form-II, Ca Unit-IV FIR Filters-Intro linear phase FIF (Rectangular, Tria filters, Basic struc Unit-V Multi rate Digit	ascade form an oduction, Char R filters, Desi angular, Raised ctures of FIR F M al Signal Pro	d Parallel fo F acteristics o gn of FIR d Cosine, Ha ilters – Direc fulti rate Dig cessing: De	rm realizations IR Filters f FIR filters with filters using Founging, Hamming ct form, Cascade a gital Signal Proce ccimation, Interpo	h linear phase, Frec ourier series and w , Blackman), Compa form, Linear phase re essing plation, Sampling ra	9 Hrs quency response o indowing method urison of IIR & FIF ealizations 9 Hrs te conversion by a
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Course Outcomes (CO):

After the completion of the course students will able to:

CO1: Understand the basic concepts of discrete time signals and systems.

CO2: Formulate difference equations for the given discrete time systems

CO3: Apply FFT algorithms for determining the DFT of a given signal

CO4: Compare FIR and IIR filter structures

CO5: Design digital filter (FIR & IIR) from the given specifications

CO6: Understand the concept of multi rate DSP and applications of DSP

VLSI DESIGN							
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type		
22A0436T	3:0:0	3	CIE:30	3 Hours	PCC		
			SEE:70				
Course Objectiv	ves•			•			

e Objectives:

- To give exposure to different steps involved in fabrication Process of PMOS & NMOS • transistors, CMOS & BICOM Inverters.
- To provide knowledge on electrical properties of MOS & BICMOS devices to analyze the • behaviour of inverters designed with various loads.
- To apply the design Rules and draw layout of a given logic circuit and basic circuit concepts to • MOS circuits.
- To provide concepts to design building blocks of data path of any system using gates. •
- To Apply the design for testability methods for combinational & sequential CMOS circuits •

Syllabus	Total hours: 48
Unit –I::Introduction to Fabrication Process	10 Hrs
Introduction: Brief Introduction to IC technology, Moore's Law, Different n	nodes MOSFET
operation, Fabrication Process of PMOS, NMOS, CMOS & Bi-CMOS devices, Com	parison between
CMOS and Bi-polar Technologies.	
Fabrication Steps: Wafer Preparation, Oxidation, Photolithography, Etching, Io	n Implantations,
Metallization, Testing.	-
Unit –II::Basic Electrical Properties of MOS/BiCMOS & Circuits Concepts	10 Hrs
Basic Electrical Properties: Ids Vs Vds relationships, MOS transistor Thresho	old Voltage-VT,
figure of merit-ω0, Transconductance - gm, Output conductance-gds, Pass transist	
Inverter, Pull-up to Pull-down Ratio for NMOS inverter driven by another NMO	•
through one or more pass transistors Various pull ups, CMOS Inverter analysis	
CMOS Inverters.	
Basic Circuit Concepts: Sheet Resistance Rs and its concepts to MOS, Area Cap	acitances
calculations, Inverter Delays, Driving large Capacitive Loads, Wiring Capacitances,	
out	
Unit –III:: VLSI Circuit Design Processes	10 Hrs
VLSI Design Flow, MOS Layers, Stick Diagrams, Design Rules and Layout, I	Lambda(λ)-based
design rules for wires, contacts and Transistors, Layout Diagrams for NMOS and	
	CMOS Inverters
Logic Gates and Various MOS Circuits. Scaling of MOS circuits, Limitations of Sca	ling.
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS	
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design	ling. 9 Hrs
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single	9 Hrs stage amplifier
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S	9 Hrs 9 stage amplifier
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S Common Drain amplifier, Common Gate amplifier, current sources and sinks.	9 Hrs 9 stage amplifier ource amplifier,
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S Common Drain amplifier, Common Gate amplifier, current sources and sinks. Static CMOS Design: Complementary CMOS, Rationed Logic, Pass-Transistor Log	9 Hrs 9 Hrs e stage amplifier ource amplifier, ic
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Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S Common Drain amplifier, Common Gate amplifier, current sources and sinks. Static CMOS Design: Complementary CMOS, Rationed Logic, Pass-Transistor Log	9 Hrs 9 Hrs e stage amplifier ource amplifier, ic c Dissipation of
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Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S Common Drain amplifier, Common Gate amplifier, current sources and sinks. Static CMOS Design: Complementary CMOS, Rationed Logic, Pass-Transistor Log Dynamic CMOS Design: Dynamic Logic-Basic Principles, Speed and Power Dynamic Logic, Issues in Dynamic Design, Cascading Dynamic Gates, Choosing a L Unit –V::CMOS Testing CAD Tools for Design and Simulation, Aspects of Design Tools, Test and Te	ling. 9 Hrs e stage amplifier ource amplifier, ic Dissipation of ogic Style. 10 Hrs estability-System ability ,Testing
Unit –IV:: Basic building blocks of Analog IC design & Static/Dynamic CMOS Design Analog IC design: Modelling of transistor, body bias effect, biasing styles, single with resistive load, single stage amplifier with diode connected load, Common S Common Drain amplifier, Common Gate amplifier, current sources and sinks. Static CMOS Design: Complementary CMOS, Rationed Logic, Pass-Transistor Log Dynamic CMOS Design: Dynamic Logic-Basic Principles, Speed and Power Dynamic Logic, Issues in Dynamic Design, Cascading Dynamic Gates, Choosing a L Unit –V::CMOS Testing CAD Tools for Design and Simulation, Aspects of Design Tools, Test and Te Partitioning, Layout and Testability, Reset/Initialization, Design for Test	ling. 9 Hrs e stage amplifier ource amplifier, ic Dissipation of ogic Style. 10 Hrs estability-System ability ,Testing

Text Books:

- 1. Kamran Eshraghian, "Essentials of VLSI Circuits and Systems", Douglas and A. Pucknell and SholehEshraghian, Prentice-Hall of India Private Limited, 2005 Edition.
- 2. Behzad Razavi, "Design of Analog CMOS Integrated Circuits", McGraw Hill, 2003
- 3. Modern VLSI Design Wayne Wolf, 3 Ed., 1997, Pearson Education.

References:

- 1. Jan M. Rabaey, "Digital Integrated Circuits", AnanthaChandrakasan and Borivoje Nikolic, Prentice-Hall of India Pvt.Ltd, 2nd edition, 2009.
- 2. John P. Uyemura, "Introduction to VLSI Circuits and Systems", John Wiley & Sons, reprint 2009
- 3. CMOS VLSI Design-A Circuits and Systems Perspective, Neil H.E Weste, David Harris, Ayan Banerjee, 3rd Edn, Pearson, 2009.

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Acquire qualitative knowledge about the fabrication process of integrated circuit using MOS transistors.
- CO2: Understand the concept of Basic Electrical Properties of MOS/Bi-CMOS Devices
- CO3: Apply the basic circuit concepts to MOS circuits.
- CO4: Apply the design Rules to draw the Stick diagram &layout of a given logic circuit.
- **CO5:** Design MOSFET based Analog IC Design and MOSFET based logic circuits using various logic styles like static and dynamic CMOS

CO6: Understand the concept of testing and adding extra hardware to improve testability of system.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0437T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objectiv	es:				
• It provides a	an understandi	ng of various	measuring system	functioning and m	etrics for
performance	analysis.				
• Provides und	derstanding of	principle of o	peration, working	of different electro	onic instruments
viz. signal ge	enerators, signa	ıl analyzers, re	corders and measu	ring equipment.	
	0 1		0 0	nd their balancing co	
	-		-	iques for measuren	nent of different
physical para	ameters using d	lifferent classe	es of transducers.		
		Syllabus			Total Hours: 48
		Unit –I			10 Hrs
				aracteristics, Static	
-		• •		Error, Root Sum S	-
•	· 1	• •	•	y, Lag; Measuring	
				C Voltmeters and	
			xtension of Range	, True RMS Respor	nding
Voltmeters, Spec	ifications of In			T	
<u></u>		Unit –II			10 Hrs
Signal Analyzer	'S: AF. HF Wa		TT ' D'		4 1
		-		rtion, Heterodyne v	-
Spectrum Analyz	ers, Power Ana	alyzers, Capac	itance-Voltage Me	eters, Oscillators. Si	gnal Generators
Spectrum Analyz AF, RF Signal G	ers, Power Ana enerators, Swe	alyzers, Capac ep Frequency	itance-Voltage Me Generators, Pulse	eters, Oscillators. Si and Square wave G	gnal Generators enerators,
Spectrum Analyz AF, RF Signal G	ers, Power Ana enerators, Swe	alyzers, Capac ep Frequency Waveform Ger	itance-Voltage Me Generators, Pulse	eters, Oscillators. Si	gnal Generators enerators, Specifications
Spectrum Analyz AF, RF Signal Ge Function Generat	ers, Power Ana enerators, Swe ors, Arbitrary	alyzers, Capac ep Frequency Waveform Ger Unit –III	itance-Voltage Me Generators, Pulse nerator, Video Sign	eters, Oscillators. Si and Square wave G nal Generators, and	gnal Generators enerators, Specifications 9 Hrs
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References:

- Electrical and Electronic Measurement and Measuring Instruments A K Sawhney, Dhanpat Rai & Sons, 2013.
- 2. Electronic Instrumentation and Measurements David A. Bell, Oxford Univ. Press, 1997.
- 3. Industrial Instrumentation: T.R. Padmanabham Springer 2009.
- 4. Electronic Measurements and Instrumentation K. Lal Kishore, Pearson Education 2010.

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Measure electrical parameters with different meters and understand the basic definition of measuring parameters.
- **CO2:** Use various types of signal generators, signal analyzers for generating and analyzing various real-time signals.
- CO3: Operate an Oscilloscope to measure various signals.
- CO4: Measure various physical parameters by appropriately selecting the transducers.
- **CO5:** Understand the design of oscilloscopes for different applications.

CO6: Design different transducers for measurement of different parameters.

		SENSORS A	AND ACTUATOR	RS	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0438T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objectiv	es:	I			
• To understar	nd modelling c	oncept;			
• To get expos	sed with basics	s of Sensors, Ac	ctuators and Mecha	tronics;	
• To learn diff	erent types of	Sensors;			
	EMS and smart				
-			river assistance sve	tem and self driving	a care as
-					
			echatronics concept		
1	problem solvi	ng skills and e	xperience in real (time applications the	rough few case
studies					
		Syllabus			Total Hours: 4
		Unit –I:: Sen	sors		10 Hrs
Difference betwe	en sensor, tra			measuring element	s - selection and
			-	tability, linearity	
impedance, back	lash, Response	e time, Dead ba	and. Signal transm	ission - Types of si	gnal: Pneumatio
signal Hydraul	ia signali E		0	v 1	0
Signal, Hydraul	ic signal; E	lectronic Sign	nal Principle of	operation, constr	0
	-	-	-	• 1	ruction details
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characteristics ar thermometer, The	nd applications ermistor, Hot-v U	s of potention wire anemomet nit –II:: Trans	eter, Proving Ring er, Resistance Hyg ducers	operation, constr s, Strain Gauges, rometer, Photo-resi	ruction details Resistance stive sensor. 9 Hrs
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characteristics ar thermometer, The Inductive transo applications of L Capacitive transo transducers – diff pressure sensor, p Definition, types Pneumatic actua system: Hydraul criteria. Electrical Actua operation and its Synchronous Mo L Micro Sensors: speed micro sens sensors and flow Micro Actuators	and selection tor- Electro-Prince and selection tor- Electro-Prince application: I tor; Stepper m Unit –IV:: Mice Principles and sors, accelerat micro sensor s: Actuation p	s of potentiom wire anemomet nit –II:: Trans ciple of operation on potentiomete ciple of operation signal condition or Unit –III:: Actuators neumatic actual Control valves s: Solid-state D.C motors - A otors - Piezoele cro Sensors an nd examples, ion micro sens rs principle, shap	eter, Proving Ring er, Resistance Hyg ducers on, construction de r, variable reluctan on, construction de ning- Applications nators ; linear; rotary; I ttor; cylinder, rota ; Construction, Cl switches, Solenoi C motors - Single ectric Actuator. Id Micro Actuato Force and press ors, chemical sens e memory effects	operation, constr ss, Strain Gauges, rometer, Photo-resi tails, characteristics ce transducer, sync etails, characteristic :- capacitor microp Logical and Contin ry actuators, Mech haracteristics and T ds, Electric Motor phase & 3 Phase In rs ure micro sensors	ruction details Resistance stive sensor. 9 Hrs s and hros, microsyn. cs of Capacitive hone, capacitive hone, capacitive 10 Hrs nous Actuators anical actuating Types, Selection rs- Principle o nduction Motor 10 Hrs s, position and mperature micro ay and pseudo

Unit -V:: Sensor Materials and Processing Techniques

Materials for sensors: Silicon, Plastics, metals, ceramics, glasses, nano materials Processing techniques: Vacuum deposition, sputtering, chemical vapour deposition, electro plating, photolithography, silicon micro machining, Bulk silicon micro machining, Surface silicon micro machining, LIGA process.

Text Books:

- 1. Patranabis.D, "Sensors and Transducers", Wheeler publisher, 1994.
- 2. Sergej Fatikow and Ulrich Rembold, "Microsystem Technology and Microbotics", First edition, Springer –Verlag NEwyork, Inc, 1997.
- 3. Jacob Fraden, "Hand Book of Modern Sensors: Physics, Designs and Application" Fourth edition, Springer, 2010.

References:

- 1. Robert H Bishop, "The Mechatronics Hand Book", CRCPress, 2002.
- 2. Thomas. G. Bekwith and Lewis Buck.N, Mechanical Measurements, Oxford and IBH publishing Co. Pvt. Ltd.,
- 3. Massood Tabib and Azar, "Microactuators Electrical, Magnetic, thermal, optical, mechanical, chemical and smart structures", First edition, Kluwer academic publishers, Springer, 1997.
- 4. Manfred Kohl, "Shape Memory Actuators", first edition, Springer.

Course Outcomes:

After the completion of the course students will able to:

CO1: Explain fundamental physical and technical base of sensors andactuators,

CO2: Describe basic laws and phenomena that define behaviour ofsensors and actuators.

CO3: Analyze various premises, approaches, procedures and resultsrelated to sensors and actuators.

CO4: Create analytical design and development solutions for sensorsand actuators.

CO5: Describe development and application of sensors and actuators

CO6: Understanding basic laws and phenomena on which operation ofsensors and actuators-transformation of energy.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0439T	3:0:0	3	CIE:30	3 Hours	PEC
			SEE:70		
Course Objective	es:	-			
• To explore th	e concepts of r	adar and its fr	equency bands.		
• To understan	d Doppler Effe	ect and get acq	uainted with the w	vorking principles of	f CW radar, FM
CW radar.					
• To impart the	e knowledge of	functioning o	f MTI and Trackin	ng Radars, design of	a Matched Filter
in radar recei	vers.				
• To acquire for	oundation in orl	bital mechanic	s and launch vehic	eles for the satellites.	
• To understan	d the concepts	of satellite nav	vigation and GPS.		
		Syllabus			Total Hours: 4
		Unit –I			10 Hrs
Basics of Radar :	Introduction, N	Maximum Una	ambiguous Range,	simple Radar range	Equation, Rada
Block Diagram	and Operatio	on, Radar Fr	equencies and A	Applications. Predic	ction of Rang
Performance, Min	imum Detectal	ble Signal, Red	ceiver Noise, Illust	trative Problems.	
Radar Equation	: Modified Ra	adar Range E	quation, SNR, pro	bability of detectio	n, probability o
False Alarm, Inte	gration of Rad	lar Pulses, Ra	dar Cross Section	of Targets (simple	targets - sphere
cone-sphere), Cre	eeping Wave,	Transmitter F	Power, PRF and R	Range Ambiguities,	System Losses
(qualitative treatm	nent), Illustrativ	ve Problems.			
		Unit –II			10 Hrs
CW and Freque	ency Modulate	ed Radar: Do	oppler Effect, CW	⁷ Radar – Block Di	agram, Isolation
between Transmi	itter and Rece	eiver, Non-zei	ro IF Receiver, 1	Receiver Bandwidt	h Requirements
Applications of C	W radar. Illust	trative Probler	ns, FM-CW Rada	r: Range and Doppl	er Measurement
Block Diagram ar	nd Characteristi	ics, FM-CW a	ltimeter, Multiple	Frequency CW Rada	ar
MTI and Pulse	Doppler Rad	lar: Introduct	tion, Principle, M	TI Radar with - I	Power Amplifie
Transmitter and H	Power Oscillato	or Transmitter	, Delay Line Canc	ellers – Filter Char	acteristics, Blin
Speeds, Double C	Cancellation, N	th Cancellatio	n Staggered PRFs	. Range Gated Dop	pler Filters. MT
Radar Parameters	, Limitations to	MTI Perform	ance, MTI versus	Pulse Doppler Rada	r.
		Unit –III			9 Hrs
Tracking Radar	: Tracking wit	th Radar, Seq	uential Lobing, C	Conical Scan, Mono	pulse Trackin
Radar – Amplitud	le Comparison	Mono pulse	(one- and two- co	ordinates), Phase Co	omparison Mon
pulse, Tracking in	Range, Acqui	sition and Sca	nning Patterns, Co	mparison of Tracker	rs.
Detection of Ra	dar Signals	in Noise : 1	Introduction, Mat	ched Filter Receiv	er – Response
Characteristics an	d Derivation,	Correlation de	etection and Cross	s-correlation Receiv	er, Efficiency o
Non-matched Filt	ers, Matched F	ilter with Non	-white Noise, Nois	se Figure and Noise	Temperature.
		Unit –IV			10 Hrs
Introduction: O	rigin of Satell	lite Communi	cations, Historica	l Back-ground, Ba	sic Concepts o
Satellite Commun	nications, Frequ	uency allocation	ons for Satellite Se	ervices, Application	s, Future Trend
of Satellite Comm	nunications.				
of Satellite Comm		nchers: Orbit	tal Mechanics, L	ook Angle determ	ination, Orbital
of Satellite Comm Orbital Mechani	ics And Lau			ook Angle determ es, Orbital effects in	

Unit –V	9 Hrs
Satellite Sub Systems: Attitude and orbit control system, telemetry, tracking,	Command and
monitoring, power systems, communication subsystems, Satellite antenna Equipment	nt reliability and
Space qualification.	
Satellite Navigation & Global Positioning System: Radio and Satellite Navigatio	
Location principles, GPS Receivers and codes, Satellite signal acquisition, GPS Navi	0 0
GPS signal levels, GPS receiver operation, GPS C/A code accuracy, Differential GPS	
Text Books:	
1. Introduction to Radar Systems – Merrill I. Skolnik, TMH Special Indian Edition,	
 Satellite Communications – Timothy Pratt, Charles Bostian and Jeremy Allnu Publications, 2ndEdition, 2003. 	itt, WSE, Wiley
References:	
1. Radar: Principles, Technology, Applications – Byron Edde, Pearson Education, 2	2004.
2. Radar Principles – Peebles, Jr., P.Z., Wiley, New York, 1998.	
3. Satellite Communications – Dennis Roddy, McGraw Hill, 2nd Edition, 1996	
4. Satellite Communications Engineering – Wilbur L. Pritchard, Robert A Nelso	on and Henri G
Suyderhoud, 2 nd Edition, Pearson Publications, 2003.	
Course Outcomes:	
After the completion of the course students will able to:	
CO1: Derive the radar range equation and to solve some analytical problems.	
CO2: Understand the different types of radars and its applications.	
CO3: Describe the need and functioning of CW, FM-CW and MTI radars.	
CO4: Apply the concept of tracking and different tracking techniques, various com	ponents of rada
receiver and its performance.	
CO5: Understand basic concepts and frequency allocations for satellite communic	ation, orbital
mechanics and launch vehicles.	
CO6: Analyze the concepts of GEO Stationary Satellite Systems and satellite navigat	ion.

			CHINE LEARNIN		
			to CE,EEE,ME an	,	1
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0528T	3:0:0:0	3	CIE: 30 SEE:70	3 Hours	OEC
Course Object	tives:				
• Study differ	Ill enable stude basic concept rent learning a valuation of lea	s of Machine lgorithms	C		
		Syllab	ous		Total Hours:48
Unit -I	Introducti	on – Human	h Learning & Mach	ine Learning	10Hrs
Applications of	Machine Lear Data in Machir	ning, Issues i	ing, Machine Learn in Machine Learning Data Preprocessing :		
Unit -II		Modelin	g and Evaluation		9Hrs
	-	-	Model, Model Reproving Performance of		pretability,
Unit -III	S	upervised L	earning :Classificat	tion	10Hrs
Classification by	y Decision tre	e Induction,	n : Classification m Classification by Ba Naïve Baye's Classif	ck propagation, K-N	
Unit -IV		Supervised l	Learning : Regressi	on	10Hrs
-	-	-	Analysis, Types of Re egression, Logistic F	• •	-
Unit -V	ι	Insupervised	Learning : Cluster	ring	9Hrs
U	rithm, Hierar	chical Clust	chniques, Partitionir ering Methods, D	0	0
Text Books: 1. Machine Lea	urning, SaikatI	Dutt, Subrama	anian Chandramouli,	, Amit Kumar Das, I	Pearson, 2019.
2. Stephen Mai and Hall/CR	din, "Introduc rsland, "Mach C Machine Le Müller and Sar	ine Learning earning and P	ine Learning", MIT -An Algorithmic Per attern Recognition S atroduction to Machi	rspective", Second E Series,2014.	-

Web Resources:

- 1. Andrew Ng, "Machine Learning Yearning"
- 2. https://www.deeplearning.ai/machine-learning-
- 3. https://www.cse.huji.ac.il/~shais/Understanding MachineLearning/index.html

Course Outcomes (CO):

On completion of this course, student will be able to:

CO1: Identify machine learning techniques suitable for a given problem

CO2: Characterize the machine learning algorithms as supervised learning and unsupervised learning

CO3: Solve the problems using various machine learning techniques

CO4: Design application using machine learning techniques

CO5: Analyze and Apply the suitable supervised learning methods for real-world problems

CO6: Understand the features of machine learning to apply on real world problems

			CONTROL THE	ORY	
Course Code	L:T:P	Credits	(Only ECE) Exam marks	Exam Durat	tion Course Type
22A0238Ta	3:0:0	3	CIE:30 SEE:70	3 Hours	OEC
Course Objectiv	ves:		I		I
The objectives o	f the course are	e to make the s	tudents learn about		
 Concepts of 	state vector, S	tate transition	matrix and solution	of state equatio	ns.
Importance	of controllabili	ty and observa	bility concepts.	-	
-	ent, state estim	•	• •		
1	riterion for stal	C C			
v 1		5 5	atom nonformanaa		
• Types of no	mmearities, the	•	stem performance		T () V
		Syllabus	8		Total Hours:49
Unit-I	State Varial	ole Description	n and Solution of S	State Equation	10 Hrs
Unit-II		Controllabil	f continuous time sy ity and Observabi	ity	10 Hrs
Tests for cont minimum energ of state models	y control, time in Jordan car	Controllability observability e invariant cas nonical form a	ity and Observabil for continuous ti e, Principle of Dua	ity me systems – lity, Controllabi	10 Hrs Time varying cas ility and observabilit of state feedback o
Tests for containimum energ	gy control, time in Jordan can nd observabilit	Controllability observability e invariant cas nonical form a ty.	ity and Observabil for continuous ti e, Principle of Dua	ity me systems – lity, Controllabi l forms. Effect	Time varying cas ility and observabilit
Tests for conta minimum energ of state models controllability a Unit -III	y control, time in Jordan can nd observabilit State Feedback Con	Controllability observability e invariant cas nonical form a ty. e Feedback Controllers throug	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs	ity me systems – lity, Controllabi l forms. Effect ervers	Time varying cas ility and observabilit of state feedback o
Tests for contain minimum energ of state models controllability a Unit -III Design of State	y control, time in Jordan can nd observabilit State Feedback Con	Controllability observability e invariant cas nonical form a ty. e Feedback Co trollers throug ugh Kalman F	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observ	Time varying cas ility and observabilit of state feedback o 9 Hrs
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV	y control, time in Jordan can nd observabilit State Feedback Con estimation thro	Controllability observability e invariant cas nonical form a ty. e Feedback Co trollers throug ugh Kalman F Analysis o	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observ ns	Time varying cas ility and observabilit of state feedback o 9 Hrs ver and reduced-orde
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV Introduction to	y control, time in Jordan can nd observabilit State Feedback Con estimation thro nonlinear sy	Controllability observability e invariant cas nonical form a ty. e Feedback Co trollers throug ugh Kalman F Analysis o ystems, Types	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System of nonlinearities	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observ ns , Concept of	Time varying cas ility and observabilit of state feedback o 9 Hrs ver and reduced-orde 10 Hrs describing function
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV Introduction to Derivation of c	y control, time in Jordan can nd observabilit State Feedback Con estimation thro nonlinear sy lescribing func	Controllability observability e invariant cas nonical form a ty. e Feedback Controllers throug ugh Kalman F Analysis of ystems, Types ctions for Dead	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System of nonlinearities d zone, Saturation,	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observ ns , Concept of backlash, relay	Time varying cas ility and observabilit of state feedback of 9 Hrs ver and reduced-orde 10 Hrs describing function y with dead zone an
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV Introduction to Derivation of co Hysteresis - Ju	y control, time in Jordan can nd observabilit State Feedback Con estimation thro nonlinear sy lescribing func	Controllability observability e invariant cas nonical form a ty. Feedback Controllers throug ugh Kalman F Analysis of ystems, Types etions for Dead ce. Introduction	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System of nonlinearities d zone, Saturation,	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observing , Concept of backlash, relay analysis, Meth	Time varying cas ility and observabilit of state feedback o 9 Hrs ver and reduced-orde 10 Hrs describing function v with dead zone an hod of Isoclines for
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV Introduction to Derivation of co Hysteresis - Ju	y control, time in Jordan can nd observabilit State Feedback Con estimation thro nonlinear sy lescribing func	Controllability observability e invariant cas nonical form a ty. e Feedback Controllers throug ugh Kalman F Analysis of ystems, Types etions for Dead ce. Introduction gular points, Pl	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System of nonlinearities d zone, Saturation, on to phase-plane	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observing , Concept of backlash, relay analysis, Meth	Time varying cas ility and observabilit of state feedback o 9 Hrs ver and reduced-orde 10 Hrs describing function v with dead zone an hod of Isoclines for
Tests for contr minimum energ of state models controllability a Unit -III Design of State observer. State Unit -IV Introduction to Derivation of c Hysteresis - Ji Constructing Tr	y control, time in Jordan can nd observabilit State Feedback Con estimation thro o nonlinear sy lescribing func ump Resonand rajectories, Sing	Controllability observability e invariant cas nonical form a ty. e Feedback Controllers throug ough Kalman F Analysis of ystems, Types etions for Dead ce. Introduction gular points, Pl Sta	ity and Observabil for continuous ti e, Principle of Dua and other canonica ontrollers and Obs h Pole placement. I ilters of Nonlinear System of nonlinearities d zone, Saturation, on to phase-plane hase plane analysis bility Analysis	ity me systems – lity, Controllabi l forms. Effect ervers Full-order observ ns , Concept of backlash, relay analysis, Meth of nonlinear cor	Time varying cas ility and observabilit of state feedback o 9 Hrs ver and reduced-orde 10 Hrs describing function v with dead zone an hod of Isoclines for htrol systems.

Textbooks:

- 1. Modern Control Engineering, Katsuhiko Ogata, Prentice Hall, 5th Edition, 2010.
- 2. Modern Control System Theory, M. Gopal, New Age International Publishers, Revised 2nd edition, 2005.

Course Outcomes(CO):

At the end of studying the course, the student should be able to:

CO1: Model a given dynamic system in state space and obtain the solution for the state equation

CO2: Test whether a given system is controllable and/or observable

CO3: Design a state feedback controller for pole placement

CO4: Design an observer for state estimation

CO5: Apply Lyapunov criterion and determine stability of a given system.

CO6: Analyze nonlinear systems

			ENTAL ECONO		
Course Code	(Comr L:T:P	non to ME, CS Credits	SE,AI&ML, CS, D Exam marks	S, ECE,EEE) Exam Durat	
22A0150T	3:1:0:0	Credits 3	CIE:30	Exam Dura 3 Hours	tion Course Type OEC
22A01301	3.1.0.0	5	SEE:70	5 110015	OLC
Course Objectiv	es:				
To teach regTo inculcateTo demonstr	arding enviror the knowledg rate the unders	nmental degrad e of economics tanding of cost	lopment and econo ation and economic of pollution and th benefit analysis of ciples of economics	e analysis of deg eir managemen environmental	t
Syllabus					Total Hours:48
Unit-I		Sustain	able Development		9 Hrs
Introduction to	sustainable d	evelopment -	Economy-Environ	ment inter link	ages - Meaning of
	-	-	n and the environr		curve – The
sustainability de	bate - Issues c	of energy and th	e economics of ene	ergy	
Unit-II		Environr	nental Degradatio	n	9 Hrs
principle.		e - Economic a	narysis of environi	nentai degradai	ion – Equi –margina
Unit -III		Econo	mics of Pollution		10 Hrs
	s: Bargaining	-	-		naging pollution using t intervention: Taxes,
		Cost –	Benefit Analysis		
Unit -IV					10 Hrs
Unit -IV	Analysis: Eco	nomic value o	f environmental re	sources and en	
Unit -IV Cost – Benefit	•				vironmental damage
Unit -IV Cost – Benefit Concept of Tota	•	Value - Alterna		valuation – Cos	vironmental damage
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V	l Economic V	Value - Alterna Econom	tive approaches to ics Of Biodiversity	valuation – Cos	vironmental damage st-benefit analysis and 10 Hrs
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of b	l Economic V	Value - Alterna Econom conomics of bio	tive approaches to ics Of Biodiversity	valuation – Cos 7 tion - Valuing i	vironmental damage st-benefit analysis and
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of b	l Economic V odiversity: Eccies -Policy 1	Value - Alterna Econom conomics of bio	tive approaches to ics Of Biodiversity	valuation – Cos 7 tion - Valuing i	vironmental damage st-benefit analysis and 10 Hrs individual species and
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of bi diversity of spe Change – stern I	l Economic V odiversity: Eccies -Policy 1	Value - Alterna Econom conomics of bio	tive approaches to ics Of Biodiversity	valuation – Cos 7 tion - Valuing i	vironmental damage st-benefit analysis and 10 Hrs individual species and
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of ba diversity of spe Change – stern I Textbooks:	I Economic V odiversity: Ec cies -Policy 1 Report	Value - Alterna Econom conomics of bio responses at na	tive approaches to ics Of Biodiversity odiversity conserva ational and interna	valuation – Cos 7 tion - Valuing i tional levels. E	vironmental damage st-benefit analysis and 10 Hrs individual species and
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of bi diversity of spe Change – stern I Textbooks: 1. An Introdu	I Economic V odiversity: Ec cies -Policy 1 Report	Value - Alterna Economics of bio responses at na	tive approaches to ics Of Biodiversity odiversity conserva ational and interna	valuation – Cos 7 tion - Valuing i tional levels. E	vironmental damage st-benefit analysis and 10 Hrs individual species and conomics of Climate
Unit -IV Cost – Benefit Concept of Tota discounting. Unit -V Economics of bi diversity of spe Change – stern I Textbooks: 1. An Introdu University	I Economic V iodiversity: Ed cies -Policy r Report uction to Envi Press.(2001 for a Green F	Value - Alterna Economics of bio responses at na ironmental Eco)	tive approaches to ics Of Biodiversity odiversity conserva ational and interna	valuation – Cos tion - Valuing i tional levels. E iley, J. Shogren	vironmental damage st-benefit analysis and 10 Hrs individual species and conomics of Climate

- 1. Environmental Economics: An Elementary Introduction by R.K. Turner, D.W. Pearce and I. Bateman Harvester Wheatsheaft, London. (1994),
- 2. Economics of Natural Resources and the Environment by D.W. Pearce and R.K. Turner Harvester Wheat sheaf, London. (1990),

E-resources:

1. https://nptel.ac.in/courses/109107171

Course Outcomes(CO):

On completion of this course, student will be able to

CO1: Understand the information on sustainable development and economics of energy

CO2: Understand the information regarding environmental degradation

CO3: Understand the information regarding economic analysis of degradation

CO4: The identification of economics of pollution and their management

CO5: The cost benefit analysis of environmental resources.

CO6: The principles of economics of biodiversity

		ORGANI	ZATIONAL BE	HAVIOUR			
Course Code	L:T:P:S	Credits	Exam marks	Exam Dura	tion	Course Type	
22A0027T	3:1:0:0	3	CIE:30	3 Hours		OEC	
			SEE:70				
Course Object							
			the functions and		ē		
_			izance of the imp	-	anization	behaviour.	
			leading and moti				
			ated with organization of the second states and second strain str				
Develop ti	ne group dyna	Syllabu		iiiig.	To	tal Hours:48	
Unit -I		Introduct	ion to Managem	ent		10Hrs	
-						nagement though	
	-	•			•	ehavioural, Huma	
	-		Quantitative App		s and Cor		
Unit -II	Int	roduction to	Organizational	Behavior		9Hrs	
Meaning, defi	nition, natur	e, scope and	d functions - Or	ganizing Proc	ess – M	aking organizing	
effective-Unde	erstanding Inc	lividual Beha	viour–Attitude -P	erception –Lea	rning – Pe	ersonality.	
Unit -III		Percept	tion &Motivatio	n		10Hrs	
Theories of M	lotivation- M	aslow's Hiera	archy of Needs - H	Hertzberg's Tw	vo Factor	Theory - Vroom's	
theory of expe	ectancy – Mc	Cleland's the	eory of needs-Mc	Gregor's theor	ry X and t	heory Y– Adam's	
equity theory	– Locke's go	al setting theo	ory– Alderfer's El	RG theory			
Unit -IV		Organi	izational Culture	2		9Hrs	
Introduction	– Meaning, s	scope, definit	ion, Nature - Org	ganizational Cl	imate - L	eadership - Traits	
	-	-	_	-		Qualities of good	
Leader.		Tunsaetto		national Load	ersnip	Qualities of good	
		0	D			1011	
Unit -V		Gro	oup Dynamics			10Hrs	
Introduction	– Meaning,	scope, defir	nition, Nature- T	ypes of group	os - Dete	rminants of grou	
behavior - C	Froup process	s – Group D	evelopment - Gr	oup norms - (Group co	hesiveness - Sma	
		-	-	-	-		
			am building –Con	inici managen	ient - Coi	linet in the	
organization-	- Conflict res	olution					
Fextbooks:							
1. Luthans, F	Fred, Organisa	ational Behav	viour, McGraw-H	ill, 12th edition	2011		
A DO11 -			TT' 1 5 '	1' 1 ' ' ' ' '	017		
2. P Subba R	ao, Organisa	tional Behavi	our, Himalya Pub	lishing House ²	2017		

- 1. McShane, Organizational Behaviour, TMH 2009
- 2. Nelson, OrganisationalBehaviour, Thomson, 2009.
- 3. Robbins, P. Stephen, Timothy A. Judge, Organisational Behaviour, Pearson2009.
- 4. Aswathappa, Organisational Behaviour, Himalaya, 2009

Course Outcomes(CO):

On completion of this course, student will be able to:

- **CO1:** Understand the managerial functions and have some basic knowledge on various aspect of management.
- CO2: Develop cognizance of the importance of organization behaviour
- **CO3:** Demonstrate the applicability of the concept of organizational behavior to understand the behavior of people in the organization

CO4: Demonstrate the ability to leading and motivation in organization

CO5: Develop the importance of Organizational leadership & culture

CO6: Build team building, group dynamics, group process, group norms to resolve conflicts in organization.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0440P	0:0:3	1.5	CIE:3 SEE:70	3 Hours	PCC
Course Objectiv	ves:				
• Formulate p	roblems and imp	olement algori	thms using Assem	bly language.	
Develop pro	ograms for differ	ent applicatio	ons.		
• Interface per	ipheral devices	with 8086 and	1 8051.		
• Use Assemb	ly/Embedded C	programming	approach for solv	ving real world probl	ems
			Syllabus		
MINIMUM TW	O EXPERIMEN		•		
List of Experim					
-		ARITHMETIC	COPERATIONS	(Using various addre	essing modes)
				ulti precision numbe	•
b) Write an	ALP to Perform	n Multiplicati	on and division o	f signed and unsigned	ed Hexadecima
numbers					
,	1		factorial of a give		
			JLATION INSTR		
		-	positive or negati	ve.	
	ALP to find the	-	l zeros in a given	data	
3. PROGRAM		-		uata.	
	ALP to find Ad		tion of N no 's.		
/	ALP for finding				
	-	-	scending/descending	ng order.	
			TIONS FOR 8086		
	ALP to find Str		~ .		
	ALP for Display		-		
	ALP for Compa	-	-		
,		0	ecking for palindi SIGN USING 808		
			ng INT 21H Interr		
	-	-	ng DOS Interrupt	-	
,	0	0	reading system tin		
6. INTERFAC	ING STEPPER	MÖTOR WIT	TH 8086		
a) Write an	ALP to 8086 pr	ocessors to Ir	nterface a stepper	motor and operate it	in clockwise b
	variable step-si				
		-		er motor and operat	te it in An
	e by choosing va	1	ze.		
	ING ADC/DAC ALP to 8086 pr		tarfaca ADC		
	-			d generate Square V	Wave/Triangula
	ep signal.			a generate square v	, a, c, i mungula
	1 0	VEEN TWO N	AICROPROCESS	ORS	
				wo microprocessors	using 8255
				o microprocessor ki	
				TRUCTIONS FOR	
	ALP to 8051 ALP to 8051		-	Arithmetic operation	s like additior

- b) Write an ALP to 8051 Microcontroller to perform Logical operations like AND, OR and XOR.
- c) Programs related to Register Banks.
- 10. PROGRAM TO VERIFY TIMERS/COUNTERS OF 8051
 - a) Write a program to create a delay of 25msec using Timer0 in mode 1 and blink all the Pins of P0.
 - b) Write a program to create a delay of 50 µsec using Timer1 in mode 0 and blink all the Pins of P2.
 - c) Write a program to create a delay of 75msec using counter0 in mode 2 and blink all the Pins of P1.
 - d) Write a program to create a delay of 80 µsec using counter1 in mode 1 and blink all the Pins of P3.
- 11. UART OPERATION IN 8051
 - a) Write a program to transfer a character serially with a baud rate of 9600 using UART.
 - b) Write a program to transfer a character serially with a baud rate of 4800 using UART.
 - c) Write a program to transfer a character serially with a baud rate of 2400 using UART.
- 12. INTERFACING LCD WITH 8051
 - a) Develop and execute the program to interface16*2 LCD to 8051.
 - b) Develop and execute the program to interface LCD to 8051 in 4-bit or 8-bit mode.

- 1. Kenneth.J.Ayala. The 8051 microcontroller, 3rd edition, Cengage learning, 2010.
- 2. Advanced microprocessors and peripherals-A.K ray and K.M.Bhurchandani, TMH, 2nd
- 3. edition2006.
- 4. The 8051 Microcontroller and Embedded Systems: Using Assembly and C by Muhammad AliMazidi, Janice GillispieMazidi, Second Edition.

Course Outcomes:

After the completion of the course students will able to:

CO1: Interface the peripheral devices with 8086 microprocessors.

CO2: Interface the peripheral devices with 8051microcontrollers.

CO3: Develop the algorithms using Assembly language.

CO4: Develop programs using embedded C language for different applications.

CO5: Develop the Assembly language programming approach for solving real world problems.

CO6: Develop the Embedded C programming approach for solving real world problems.

VLSI DESIGN LAB								
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type			
22A0441P	0:0:3	1.5	CIE:30	3 Hours	PCC			
			SEE:70					
Course Objective	5:							
• Design any log	gic circuit usir	ng CMOS tran	sistor.					
• Use different s	software tools	for analysis of	f circuits.					
• Design layout		•						
• Use different s	software tools	for analog lay	out					
			Syllabus					
LIST OF EXPER	IMENTS: (C	onduct Any 1	0 experiments)					
1. Design and an	•							
, 1			e	nology and design it	s symbol.			
, 1			rter and check its	output response.				
		alysis for CMC	erter using parame	tric sween				
2. Design and a	-			the sweep.				
-	-			ogy and design its s	vmbol			
-			and check its out		ymoon.			
-		lysis for NAN		put response.				
		•	R using parametri	c sween				
3. Design and a	-			e sweep.				
-	-			ogy and design its sy	vmbol.			
-			and check its out	•••••••••••••••••••••••••••••••••••••••	,			
· 1		lysis for XOR		P Teshonser				
		•	R using parametrie	c sweep.				
4. Design of AC	-		8 F	F -				
U	U	B+C'D and ch	eck its output resp	oonse.				
_			heck its output res					
c) Design Scl	nematic for (A	+B')(C+D) ar	nd check its outpu	t response.				
			and check its output					
5. Design and an	nalysis of Full	adder						
a) Design ful	l adder using I	Full custom IC	C design.					
b) Design ful	l adder using S	Semi custom I	C design.					
6. Analysis of N	MOS and PM	IOS characteri	istics					
a) Implement	test bench for	r NMOS/PMC	S transistor.					
b) Perform D	C and AC ana	lysis for NMC	OS/PMOS transist	or				
c) Check the	performance of	of NMOS/PM	OS transistor using	g parametric sweep.				
7. Design and and	nalysis of Con	nmon source a	mplifier					
a) Implement	CS amplifier	schematic usi	ng 90 nm technolo	ogy and design its sy	/mbol.			
b) Implement	test bench for	r CS amplifier	and check its out	put response.				

- d) Check the performance of CS amplifier using parametric sweep.
- 8. Design and analysis of Common drain amplifier
 - a) Implement CD amplifier schematic using 90 nm technology and design its symbol.
 - b) Implement test bench for CD amplifier and check its output response.
 - c) Perform DC and AC analysis for CD amplifier.
 - d) Check the performance of CD amplifier using parametric sweep.
- 9. Design of MOS differential amplifier
 - a) Design differential amplifier schematic using 90 nm technology and its symbol.
 - b) Implement test bench for differential amplifier and check its output response.
 - c) Perform DC and AC analysis for differential amplifier.
 - d) Check the performance of differential amplifier using parametric sweep.
- 10. Design of two stage differential amplifier
 - a) Design two stage differential amplifier schematic using 90 nm technology and its symbol.
 - b) Implement test bench for two stage differential amplifier and check its output response.
 - c) Perform DC and AC analysis for two stage differential amplifier.
 - d) Check the performance of two stage differential amplifier using parametric sweep.
- 11. Design of Inverter Layout
 - a) Design and implement inverter schematic.
 - b) Design the layout for inverter using 90 nm tech file.
 - c) Perform LVS for schematic and layout
 - d) Check and remove all DRC violations.
 - e) Extract parasitic R and C in layout.
- 12. Design of NAND/NOR Layout
 - a) Design and implement NAND/NOR schematic.
 - b) Design the layout for inverter using 90 nm tech file.
 - c) Perform LVS for schematic and layout
 - d) Check and remove all DRC violations.
 - e) Extract parasitic R and C in layout

Software Required:

- i. Mentor Graphics Software / Equivalent Industry Standard Software.
- ii. Personal computer system with necessary software to run the programs and to implement

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Apply switching theory to the design logic theory problems.
- **CO2:** Design and simulate basic CMOS circuits like inverter, common source amplifier and differential amplifiers.
- CO3: Design and simulate combinational and sequential digital circuits.
- CO4: Design of various MOS differential amplifier
- CO5: Design and analysis of Common drain amplifier and Perform DC and AC analysis
- CO6: Design of NAND/NOR Layout and Extract parasitic R and C in layout

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0442P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PCC
			Syllabus		
LIST OF EXPE	RIMENTS: (C	Conduct all exp	periments).		
•		-	to be conducted.		
1. Generate the	Ū.		U U		
-	-	· •	Exponential v) Sa		
		•	-	ncy response (magni	-
-	•			en two given signals	8.
4. Study the g	eneration of up	p- Sampling &	& Down sampling.		
5. Implement a	and verify auto	correlation for	or the given seque	nce and cross correla	ation between
twogiven sig	gnals.				
6. Compute an	nd implement th	he N-point DF	T of a given sequ	ence and compute the	he power densit
spectrum of	the sequence.				
7. Implement	and verify N-p	oint DIT-FFT	of a given seque	nce and find the fre	quency respons
(magnitude	and phase).				
8. Implement a	and verify N-po	oint IFFT of a g	given sequence.		
9. Design IIR	Butterworth fil	lter and compa	are their performan	nces with different of	orders (Low Pas
Filter /High	Pass Filter)				
10. Design IIR	Chebyshev filt	er and compa	re their performan	ces with different of	orders (Low Pas
Filter /High	Pass Filter).				
11. Design FIR	filter (Low Pa	ss Filter /High	Pass Filter) using	different window te	echniques
(rectangular	, hamming and	Kaiser)			
12. Design and	verify Filter (I	IR and FIR) fi	requency response	by using Filter des	ign and Analysi
Tool.					
13. Compute the	e Decimation a	nd Interpolatio	on for the given sig	mal.	
14. Real time in	nplementation	of an audio sig	nal using a digital	signal processor.	
15. Compute th	e correlation of	coefficient for	the two given au	idio signals of sam	e length using
digital signa	l processor.				
References:					1 0010
1. Stephen J. Ch			ming tor Engineer	s'' L'engage Novem	nber 2012

Course Outcomes:			
After the completion of the course students will be abl	e to:		
CO1: Implement various DSP Algorithms using MAT	LAB.		
CO2: Implement DSP algorithms with Digital Signal	Processor.		
CO3: Analyze and observe magnitude and phase	characteristics	(Frequency	response
Characteristics) of digital IIR-Butterworth filters			
CO4: Analyze and observe magnitude and phase	characteristics	(Frequency	response
Characteristics) of digital IIR- Chebyshev filters			
CO5: Analyze and observe magnitude and phase	characteristics	(Frequency	response
Characteristics) of digital FIR filters using windo	ow techniques.		
CO6: Analyze and implement various digital filters.			

			VA PROGRAMMI on to EEE,ME and		
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type
22A0539	1:0:2:0	2	CIE: 30 SEE:70	3 Hours	SC
Course Objec	tives:		·		
This course will • To introduc			s of object-oriented	programming to desig	gn & implement

- object oriented programming concepts in Java. • To obtain knowledge about the principles of inheritance and polymorphism
- Learn the usage of Control structures in java
- To implement the concept of Array, interfaces, exception handling
- To understand the usage of Threads in java

<i>C j</i>	
Syllabus	Total Hours:48

Module : 1

Fundamentals of Object Oriented Programming: Introduction, Object Oriented Paradigm, Basic concepts of OOP: Class, Object, Inheritance, Polymorphism, Abstraction, Encapsulation..

Task: introduction to Object Oriented Programming and its basic concepts.

Module : 2

Overview of Java Language: Introduction, Java features, Java program structure, parts of Java, Java Virtual Machine-Java versus C++, How to Compile & Executing a basic java program.

Task: Differences between Java and C++, Execute "Hello welcome to java" program

Module : 3

Variables-Identifiers-Literals- Data types: Integer literals-character literals-Floating point literals- String Literals, Variables, Keywords, Data types.

Task: implementing data types with variables, find valid/invalid variables, Identifiers

Module: 4

Operators: Arithmetic operators, Relational operators, Assignment operators, Conditional operators, Type casting/Type Conversion in java.

Task: Perform all arithmetic operators using a single program, program using typecast/type conversion

Module : 5

Java Statements: Input and Output Statements, Accepting Input from the Keyboard, Displaying output with System.out.printf(), Displaying Formatted output with String.format() **Task:** Write a program using I/O statements in java.

Module : 6

Control Structures: Conditional control statements :- if ...statement, if ... else statement- if-else-if ladder, Switch statement

Task: Write a program to find a person is eligible for vote >18?, Largest number among 3 numbers?

Module:7

Looping/Repetitive/Iterative statements: While statement- Do ...While statement-For Statement, Continue statement-Break statement.

Task: print N natural numbers, sum of N natural numbers, Armstrong number, Strong number using for statement.

Module:8

Arrays: Arrays, One-dimensional arrays, Creating an array, Find The Length Of An Array, Types of Arrays:-Two-dimensional arrays, Creating a two-dimensional array.

Task: Find the Nth Largest value in an array, Insert and Addition of values using array

Module : 9

Strings: Introduction to strings, Built in strings, Creating Strings, String reverse, String Concatenation, String comparison, Immutability of Strings

Task: write a program to Perform all string operations as single output

Module: 10

Classes , Objects& Methods: Introduction, Defining a class, Adding Variables, Object Creation, Initializing the Instance variables, Access Specifiers, Methods, Constructors, Method Overloading

Task: To implement Class and Object concept, Method Overloading program

Module :11

Interfaces: Interface, Multiple Inheritance using Interfaces.

Exception Handling: Errors in Java Program, Exceptions, throws clause, throw clause, Types of Exceptions,

Task: Implement a program using exception handling, write a program Multiple Inheritance using Interfaces.

Module: 12

Threads: Introduction, Creating Threads, Extending the Threads, Stopping and Blocking a Thread, Life Cycle of a Thread. single Tasking Using a Thread, Multi tasking Using ThreadsTask: Implement a program using Threads.

Reference Books:

- 1. Programming with Java by E.Balagurusamy.
- 2. Programming in Java by Sachin Malhotra, OXFORD University Press.
- 3. Java Complete Reference by Herbert Schildt.
- 4. John R.Hubbard, Programming with Java, Second Edition, Schaum's outline series, TATA McGraw-Hill Company.

Web References:

- 1. https://www.javatpoint.com/java-tutorial
- 2. https://www.learnjavaonline.org/
- 3. https://www.tutorialspoint.com/java/index.htm
- 4. https://www.w3schools.com/java/
- 5. https://www.geeksforgeeks.org/java/

Course Outcomes (CO):

On completion of this course, student will be able to

CO1: Understand the basic concepts of OOP

CO2: Compare & Contrast basic constructs of C++ & Java

CO3: Develop a program on operators in Java

CO4: Apply Control statements to solve real time problems

CO5: Analyze the concepts of constructers, overloading, Inheritance and Interfaces in java

CO6: Implementing different types of Threads to solve real time problems

Course Code	L:T:P:S	Credits	Exam marks	Exam Dura	tion	Course Type
22A0032M	3-0-0	0				MC
Course Object		U				Me
0		concepts of	research and rese	arch problem		
		1	rious types of data	1	d samplin	ng design
			of statistical eval		F	-88
			rious testing tools			
			rite a research rep			
	awareness on		-			
		Syllabu	IS		Total H	Iours: 30
Unit -I		. Found	ations of Researc	h		6 Hrs
-		•	••			rch Approaches – Concepts related to
	U	0	xperimental Desig		Design –	Concepts related to
Unit -II		Ĩ	npling Design	,		7 Hrs
			F88			
Sampling Des	ign –steps in	Sampling F	Jacian Character	istics of a Goo	nd Samn	la Davian Dandan
	0 1	1 0	e		-	e
Sampling Des	0 1	1 0	e		-	ent –Tests of Sound
	ign. Measure	ement and S	caling Technique	s-Errors in Me	easureme	ent –Tests of Sound
Measurement	ign. Measure –Scaling and	ement and S I Scale Cons	caling Technique struction Techniq	s-Errors in Me ues –Time Ser	easureme ries Anal	ent –Tests of Sound lysis –Interpolation
Measurement and Extrapolat	ign. Measure –Scaling and ion. Data Co	ement and S I Scale Cons	caling Technique struction Techniq	s-Errors in Me ues –Time Ser	easureme ries Anal	ent –Tests of Sound
Measurement and Extrapolat	ign. Measure –Scaling and ion. Data Co	ement and S I Scale Cons	caling Technique struction Techniq	s-Errors in Me ues –Time Ser	easureme ries Anal	ent –Tests of Sound lysis –Interpolation
Measurement	ign. Measure –Scaling and ion. Data Co	ement and S I Scale Cons Illection Met	caling Technique struction Techniq	s-Errors in Me ues –Time Ser	easureme ries Anal	ent –Tests of Sound lysis –Interpolation
Measurement and Extrapolat and Interviews Unit -III	ign. Measure –Scaling and ion. Data Co	ement and S d Scale Cons ollection Met	caling Techniques struction Techniq hods –Primary Da ata Analysis	s-Errors in Me ues –Time Sen ata –Secondary	easureme ries Anal data –Q	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs
Measurement and Extrapolat and Interviews Unit -III Correlation an	ign. Measure –Scaling and ion. Data Co d Regression	ement and S d Scale Cons ollection Met D Analysis –N	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S	s-Errors in Me ues –Time Sen ata –Secondary	easureme ries Anal v data –Q	ent –Tests of Sound lysis –Interpolation Questionnaire Survey 6 Hrs
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs	ign. Measure –Scaling and ion. Data Co d Regression	ement and S d Scale Cons illection Met D Analysis –N on –Types of	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and	s-Errors in Me ues –Time Sen ata –Secondary	easureme ries Anal v data –Q	ent –Tests of Sound lysis –Interpolation guestionnaire Survey 6 Hrs Correlation –
Measurement and Extrapolat and Interviews Unit -III Correlation an	ign. Measure –Scaling and ion. Data Co d Regression	ement and S d Scale Cons illection Met D Analysis –N on –Types of	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S	s-Errors in Me ues –Time Sen ata –Secondary	easureme ries Anal v data –Q	ent –Tests of Sound lysis –Interpolation Questionnaire Survey 6 Hrs
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV	ign. Measure –Scaling and ion. Data Co d Regression Determinatio	ement and S d Scale Cons ollection Met D A Analysis – D On –Types of Interp	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data	s-Errors in Me ues –Time Sen ata –Secondary Gquares –Regre Their Applicat	easureme ries Anal data –Q ession vs tions	ent –Tests of Sound lysis –Interpolation guestionnaire Survey 6 Hrs Correlation –
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe	ign. Measure –Scaling and ion. Data Co d Regression Determination rence: Tests	ement and S d Scale Cons illection Met D Analysis – D on –Types of Interp of Hypothes	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs	s-Errors in Me ues –Time Ser ata –Secondary Squares –Regre Their Applicat	easureme ries Anal data –Q ession vs tions	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs Correlation – 6 Hrs
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe	ign. Measure –Scaling and ion. Data Co d Regression Determination rence: Tests ampling Theo	ement and S d Scale Cons ollection Met D A Analysis – D on –Types of Interp of Hypothes ory –Samplir	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs	s-Errors in Me ues –Time Ser ata –Secondary Squares –Regre Their Applicat	easureme ries Anal data –Q ession vs tions	ent –Tests of Sound lysis –Interpolation Questionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa	ign. Measure –Scaling and ion. Data Co d Regression Determination rence: Tests ampling Theo Multivariate	ement and S d Scale Cons illection Met D Analysis –N on –Types of Interp of Hypothes ory –Samplir Analysis	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs	s-Errors in Me ues –Time Sen ata –Secondary Squares –Regre Their Applicat Non-parametri Chi-square Tes	easureme ries Anal data –Q ession vs tions	ent –Tests of Sound lysis –Interpolation Questionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa Co-variance – Unit -V	ign. Measure -Scaling and ion. Data Co d Regression Determination rence: Tests umpling Theo Multivariate A	ement and S d Scale Cons ollection Met D A Analysis – D on –Types of Interp of Hypothes ory –Samplir Analysis port Writing	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs ng Distribution –C g and Professiona	s-Errors in Me ues –Time Sen ata –Secondary Squares –Regre Their Applicat Non-parametri Chi-square Tes	easureme ries Anal data –Q ession vs cions ic Tests - st –Analy	ent –Tests of Sound lysis –Interpolation guestionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing ysis of variance and
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa Co-variance – Unit -V Report Writing	ign. Measure -Scaling and ion. Data Co d Regression Determination rence: Tests impling Theo Multivariate Re g and Profest	ement and S d Scale Consol illection Met D Analysis –N on –Types of Interp of Hypothest ory –Samplir Analysis port Writing	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs ng Distribution –G g and Professiona es: Interpretation	s-Errors in Me ues –Time Ser ata –Secondary Gquares –Regre Their Applicat Non-parametri Chi-square Tes al Ethics of Data –Rej	easureme ries Anal v data –Q ession vs tions tions tic Tests - st –Analy	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs Correlation – 6 Hrs -Hypothesis Testing ysis of variance and 5 Hrs
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa Co-variance – Unit -V Report Writing Research Pape	ign. Measure -Scaling and ion. Data Co ion. Data Co d Regression Determination rence: Tests impling Theo Multivariate g and Profest er –Techniqu	ement and S d Scale Cons ollection Met D A Analysis – D on –Types of Interp of Hypothest ory –Samplir Analysis port Writing ssional Ethic es of Interpr	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs ng Distribution –C g and Professiona es: Interpretation retation-Making S	s-Errors in Me ues –Time Ser ata –Secondary Gquares –Regre Their Applicat Non-parametri Chi-square Tes al Ethics of Data –Rej	easureme ries Anal v data –Q ession vs tions tions tic Tests - st –Analy	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing ysis of variance and 5 Hrs ting –Layout of a
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa Co-variance – Unit -V Report Writing	ign. Measure -Scaling and ion. Data Co ion. Data Co d Regression Determination rence: Tests impling Theo Multivariate g and Profest er –Techniqu	ement and S d Scale Cons ollection Met D A Analysis – D on –Types of Interp of Hypothest ory –Samplir Analysis port Writing ssional Ethic es of Interpr	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs ng Distribution –C g and Professiona es: Interpretation retation-Making S	s-Errors in Me ues –Time Ser ata –Secondary Gquares –Regre Their Applicat Non-parametri Chi-square Tes al Ethics of Data –Rej	easureme ries Anal v data –Q ession vs tions tions tic Tests - st –Analy	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing ysis of variance and 5 Hrs ting –Layout of a
Measurement and Extrapolat and Interviews Unit -III Correlation an Correlation vs Unit -IV Statistical Infe Procedure –Sa Co-variance – Unit -V Report Writing Research Pape Seminars –Pro	ign. Measure -Scaling and ion. Data Co d Regression Determination rence: Tests impling Theo Multivariate g and Profest er –Techniqu fessional Eth	ement and S d Scale Consol illection Met D Analysis –N on –Types of Interp of Hypothesion of Hypothesion Analysis port Writing ssional Ethic es of Interprision Resear	caling Techniques struction Techniq hods –Primary Da ata Analysis Method of Least S Correlations and oretation of Data is –Parametric vs ng Distribution –C g and Professiona es: Interpretation retation-Making S	s-Errors in Me ues –Time Ser ata –Secondary Squares –Regre Their Applicat Non-parametri Chi-square Tes al Ethics of Data –Rej cientific Prese	easureme ries Anal v data –Q ession vs tions tions tic Tests – st –Analy port Wri ntations	ent –Tests of Sound lysis –Interpolation puestionnaire Survey 6 Hrs Correlation – 6 Hrs –Hypothesis Testing ysis of variance and 5 Hrs ting –Layout of a in Conferences and
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- 1. P.Narayana Reddy and G.V.R.K.Acharyulu, "Research Methodology and Statistical Tools", 1stEdition,Excel Books,New Delhi.
- 2. Donald R. "Business Research Methods", Cooper & Pamela S Schindler, 9thedition.
- 3. S C Gupta, "Fundamentals of Statistics",7thedition Himalaya Publications

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand basic concepts of research and research problem **CO2:** Demonstrate the knowledge of research processes

CO3: Read, comprehend and explain research articles in their academic discipline

CO4: Analyze various types of testing tools used in research

CO5: Understand the method of writing a research report **CO6:** Design a research paper without any ethical issues

No.LTP1PECProfessional Elective-III3002PECProfessional Elective-IV3003PECProfessional Elective-V3004OECOpen Electives-III3005OECOpen Electives-IV3006HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	Sl.	Category	CourseCode	Course Title	Course Title Hours per week			Credit
2PECProfessional Elective-IV3003PECProfessional Elective-V3004OECOpen Electives-III3005OECOpen Electives-IV3006HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	No.				L	Т	P	С
3PECProfessional Elective-V3004OECOpen Electives-III3005OECOpen Electives-IV3006HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	1	PEC		Professional Elective-III	3	0	0	3
4OECOpen Electives-III3005OECOpen Electives-IV3006HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	2	PEC		Professional Elective-IV	3	0	0	3
5OECOpen Electives-IV3006HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	3	PEC		Professional Elective-V	3	0	0	3
6HSCOpen Elective-V:3007SC22A0458PSkill Advanced Course: Mobile Application Development102	4	OEC		Open Electives-III	3	0	0	3
7SCSkill Advanced Course: Mobile Application Development102	5	OEC		Open Electives-IV	3	0	0	3
22A0458P Mobile Application Development	6	HSC		Open Elective-V:	3	0	0	3
I	7	SC			1	0	2	2
8 22A0460 Evaluation of Industry Internship 0 0	8			Evaluation of Industry Internship	0	0		3

S. No.	Course Code	Name of the Professional Electives
1	22A0449T	Mobile Communications
2	22A0450T	Low Power VLSI Design
3	22A0451T	Embedded Real Time Systems
4	22A0452T	Fuzzy sets, logic systems and Applications
5	22A0453T	Advanced Digital Signal Processing
6	22A0454T	Internet of Things
7	22A0455T	CPLD & FPGA Architectures and Applications
8	22A0456T	Digital Image Processing
9	22A0457T	Digital TV Engineering

S. No.	Course Code	Name of the Open Electives
1	22A0529T	Cloud Computing
2	22A0241Ta	Smart Grid
3	22A0330Ta	Measurements and Mechatronics
4	22A0151T	Disaster Management
5	22A0534b	Cyber Security
6	22A0327Ta	Renewable Energy Sources
7	22A0152T	Construction Management
8	22A0232Ta	Electric Vehicles
9	22A3301T	Artificial Intelligence
10	22A0024T	Entrepreneurship & Innovation
11	22A0023T	Management Science
12	22A0026T	Business Environment
13	22A0033T	Human Resource Management

Category	Credits
Professional Elective Courses (PEC)	9
Humanities and Social Science Course (HSC)	3
Open Elective Courses (OEC)	6
Skill Advanced Course (SC)	2
Industrial/Research Internship	3
Total	23

		MOBILE CO	OMMUNICATIO	NS	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0449T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objecti	ves:		SEE.70		
Ŭ		ifferent wireless	s standards and the	ir technical specific	cations.
-	ifferent propagat			Ĩ	
• To present	concepts of 3G/	4G Wireless C	ommunication syst	ems to solve the re	levant
Problems.					
			-	MA, MIMO, and	OFDM through
performance	e metrics to find	d the merits and	d demerits.		
		Syllabus			Total hours: 48
		Unit –I			10 Hrs
				ations - Introduction	on, 2G, 3G, and
			ervice Progression,	-	
	ry: Introduction	to teletraffic t	heory, Cellular tra	ffic modelling and	blocking
probability.		1	1		а
			ysis, Log normal sl	models, Ground re	flection model,
Okumura moder	, Hata model, Ll	Unit –II	ysis, Log normai s	nadowing.	10 Hrs
Small Scale Fa	ding and Mult		in wireless channe	el, Rayleigh fading	
	ung and mun	ipath. I admg	III whereas channe	, Rayleigh faulig	, DLK III WIICU
	annels Wireles	ss channel and	t delay spread (oherence handwid	
and wireless ch				Coherence bandwid nd Jake's model.	
and wireless ch channel, ISI and	Doppler in wire	eless channel, D	Ooppler spectrum a	nd Jake's model.	lth of wireless
and wireless ch channel, ISI and	Doppler in wire niques: Introduc	eless channel, D ction to diversi	Ooppler spectrum a ty techniques, MR		lth of wireless
and wireless ch channel, ISI and Diversity Tech	Doppler in wire niques: Introduc	eless channel, D ction to diversi	Ooppler spectrum a ty techniques, MR	nd Jake's model.	lth of wireless
and wireless ch channel, ISI and Diversity Tech with diversity, S	Doppler in wire niques: Introduc patial diversity a	eless channel, D ction to diversi and diversity or Unit –III	Doppler spectrum a ty techniques, MR der.	nd Jake's model.	lth of wireless na system, BER 9 Hrs
and wireless ch channel, ISI and Diversity Tech with diversity, S Basics of Chan	Doppler in wire niques: Introduc patial diversity a nel Modeling:	eless channel, D ction to diversi and diversity or Unit –III Maximum Del	Doppler spectrum a ty techniques, MR der. ay Spread, RMS o	nd Jake's model. C for multi-antenr	lth of wireless na system, BER 9 Hrs er delay profile,
and wireless ch channel, ISI and Diversity Techn with diversity, S Basics of Chan Coherence Band	Doppler in wire niques: Introduce patial diversity a nel Modeling: width, Doppler	eless channel, D ction to diversi and diversity or Unit –III Maximum Del Spread, Impac	Doppler spectrum a ty techniques, MR rder. ay Spread, RMS of t of Doppler spread	nd Jake's model. C for multi-antenr delay Spread, Powe	lth of wireless na system, BER 9 Hrs er delay profile, nnel, Coherence
and wireless ch channel, ISI and Diversity Techn with diversity, S Basics of Chan Coherence Band Time, Clarke's Channels.	Doppler in wire niques: Introduce patial diversity a nel Modeling: width, Doppler Model, Simula	eless channel, D ction to diversi and diversity or <u>Unit –III</u> Maximum Del Spread, Impac tion Procedure	Doppler spectrum a ty techniques, MR rder. ay Spread, RMS of t of Doppler spread e for flat fading	nd Jake's model. C for multi-antenr lelay Spread, Powe d on Wireless Char and Frequency So	Ith of wireless a system, BER 9 Hrs er delay profile, nnel, Coherence elective Fading
and wireless ch channel, ISI and Diversity Techn with diversity, S Basics of Chan Coherence Band Time, Clarke's Channels. Code Division	Doppler in wire niques: Introduce patial diversity a nel Modeling: width, Doppler Model, Simula Multiple Acces	eless channel, D ction to diversi and diversity or <u>Unit –III</u> Maximum Del Spread, Impaction tion Procedure s: Introduction	Doppler spectrum a ty techniques, MR der. ay Spread, RMS of t of Doppler spread e for flat fading to CDMA, spread	nd Jake's model. C for multi-antenr delay Spread, Powe d on Wireless Char and Frequency Se d spectrum and LF	Ith of wireless na system, BER 9 Hrs er delay profile, nnel, Coherence elective Fading SR. Generation
and wireless ch channel, ISI and Diversity Techn with diversity, S Basics of Chan Coherence Band Time, Clarke's Channels. Code Division and properties	Doppler in wire niques: Introduce patial diversity a nel Modeling: width, Doppler Model, Simula Multiple Access of PN sequence	eless channel, D ction to diversi and diversity or Unit –III Maximum Del Spread, Impaction tion Procedure s: Introduction ces, Correlation	Doppler spectrum a ty techniques, MR rder. ay Spread, RMS of t of Doppler spread e for flat fading to CDMA, spread n of PN sequence	nd Jake's model. C for multi-antenr lelay Spread, Powe d on Wireless Char and Frequency Se d spectrum and LF	Ith of wireless a system, BER 9 Hrs er delay profile, anel, Coherence elective Fading 7SR. Generation margin, CDMA
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PAPR in OFDM systems, Introduction to SC-FDMA.

4G & Beyond: Introduction – 4G vision – 4G features and challenges - Applications of 4G – 4G Technologies: Multicarrier Modulation, Smart antenna techniques, IMS Architecture, LTE, Advanced Broadband Wireless Access and Services, MVNO.

Text Books:

- 1. Aditya K Jagannatham, "Principles of Modern Communication Systems Theory and Practice," McGraw Hill Education, 2016.
- 2. T. S. Rappaport, "Wireless Communications Principles and Practice," Second Edition, Pearson, 2010.
- 3. Jochen Schiller, "Mobile Communications", Second Edition, Pearson Education 2012.
- 4. Vijay Garg, "Wireless Communications and networking", First Edition, Elsevier 2007

References:

- 1. David Tse and PramodViswanath, "Fundamentals of Wireless Communications", Cambridge University Press.
- 2. Andrea Goldsmith, "Wireless Communications", Cambridge University Press.
- 3. EzioBiglieri, "MIMO Wireless Communications", Cambridge University Press.
- 4. Erik Dahlman, Stefan Parkvall, Johan Skold and Per Beming, "3G Evolution HSPA and LTE
- 5. for Mobile Broadband", Second Edition, Academic Press, 2008.
- 6. Anurag Kumar, D.Manjunath, Joy kuri, "Wireless Networking", First Edition, Elsevier 2011.
- 7. Simon Haykin, Michael Moher, David Koilpillai, "Modern Wireless Communications", First Edition, Pearson Education 2013

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** Understand various Wireless standards and their technical specifications.
- **CO2:** Compare different propagation models.
- **CO3:** Apply concepts of 3G/4G wireless communication systems to solve problems.
- CO4: Analyze performance of various 3G/4G wireless communication systems under AWGN.
- **CO5:** Analyze performance of various 3G/4G wireless communication systems under small-scale Fading channel conditions.

CO6: Compare different wireless technologies through performance metrics

Course Code		-	VER VLSI DESIC		
	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0450T	3:1:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objective	es:		·		
• To impart kn	owledge on d	ifferent abstra	action levels in VL	SI Design and the	impact of power
reduction me	thods at higher	r levels			
• To describe	leakage contro	ol mechanism	ns to reduce static	power consumptio	n in DSMVLS
regime					
• To explain te	echnology inde	ependent and	technology-dependent	dent techniques for	Dynamic power
reduction in C	CMOS circuits				
• To introduce	varioussoftwa	re power estin	mation and optimiz	ation techniques for	low power
VLSI system	design				
To demonstra	ate low power	circuit and ar	chitectural techniq	ues for reducing pov	ver consumption
in SRAM des	igns				
		Syllabus	5		Total Hours: 4
		Unit –I			10 Hrs
Introduction to l	Low Power de	esign: Why w	vorry about power	– at global and SOC	C levels,
Emerging zero	-power app	lications (V	WSN), 20 nm	a scenario, Des	sign-productivity
challenge,Impact	of implementa	tion Choices	,Motivation for LP	D, Basic VLSI Desi	gn
Flow, Optimization	n examples at	various level	s (System, Sub-sys	stem, RTL, Gate, Ci	rcuit and
Device levels)Lay	out Design fo	r various Trar	nsistors, Sources of	fpower dissipation,	MOS transistor
leakage component	nts, Static Pov	ver dissipatio	n, Dynamic Power	rdissipation, Circuit	Techniques
for Low Power	Design–Standl	by leakage co	ontrol using transis	stor	
stacks, Multiple V	TH and dynar	nic VTH tech			
			iniques, Supply vol	tage scaling techniq	ue.
	*	Unit –II		tage scaling techniq	ue. 10 Hrs
Power Optimiz		Unit –II			10 Hrs
-	ation Tech	Unit –II niques–I: I	I Dynamic Power		10 Hrs Daches, Circui
Parallelization, Vo	vation Tech oltage Scaling	Unit –II niques–I: I Based Circuit	I Dynamic Power t Techniques, Circu	Reduction Appro	10 Hrs Daches, Circui lependent Powe
Parallelization, Vo Reduction, Circui	vation Tech oltage Scaling t Technology	Unit – II niques–I: I Based Circuit Dependent F	I Dynamic Power t Techniques, Circu Power Reduction;	Reduction Appro	10 Hrs baches, Circui lependent Powe luction–Leakag
Parallelization, Vo Reduction, Circui Components, Des	zation Tech oltage Scaling t Technology ign Time Red	Unit –II niques–I: I Based Circuit Dependent F uction Techni	I Dynamic Power t Techniques, Circu Power Reduction; 2 iques, Run-time St	Reduction Appro ait Technology – Ind Leakage Power Red	10 Hrs Daches, Circui lependent Powe luction–Leakag fechniques, Run
Parallelization, Vo Reduction, Circui Components, Des	Eation Tech oltage Scaling t Technology ign Time Red action Technic	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio	Dynamic Power t Techniques, Circu Power Reduction; D iques, Run-time St on in Cache Memo	Reduction Appro ait Technology – Ind Leakage Power Red and-by Reduction T	10 Hrs Daches, Circui lependent Powe luction–Leakag fechniques, Run
Parallelization, Vo Reduction, Circui Components, Des time Active Redu	Eation Tech oltage Scaling t Technology ign Time Red action Technic	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio	Dynamic Power t Techniques, Circu Power Reduction; Di iques, Run-time St on in Cache Memo ogic.	Reduction Appro ait Technology – Ind Leakage Power Red and-by Reduction T	10 Hrs Daches, Circui lependent Powe luction–Leakag fechniques, Run
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Ado	vation Tech oltage Scaling t Technology ign Time Red oction Technic lers using mult	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio tiple-valued la Unit –II	Dynamic Power t Techniques, Circu Power Reduction; iques, Run-time St on in Cache Memo ogic. I	Reduction Appro ait Technology – Ind Leakage Power Red and-by Reduction T	10 Hrs baches, Circui dependent Powe duction–Leakag dechniques, Run Styles, Current 10 Hrs
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add	tion Techniqu	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reduction tiple-valued la Unit –II tes – II: Low	Dynamic Power t Techniques, Circu Power Reduction; Di iques, Run-time St on in Cache Memo ogic. I Power Very Fast I	Reduction Appro ait Technology – Inc Leakage Power Rec and-by Reduction T pries, LVLP Logic	10 Hrs baches, Circuit lependent Powe luction–Leakag dechniques, Run Styles, Current 10 Hrs uits, Low Powe
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera	t Technology ign Time Red iction Technic lers using mult tion Technique tors, Energy	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reduction tiple-valued la Unit –II tes – II: Low	Dynamic Power t Techniques, Circu Power Reduction; Di iques, Run-time St on in Cache Memo ogic. I Power Very Fast I	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic	10 Hrs baches, Circuit lependent Powe luction–Leakag dechniques, Run Styles, Current 10 Hrs uits, Low Powe
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Ado Power Optimizat Arithmetic Opera implementation is	tation Technology ign Time Reduction Technology ign Time Reduction Technology lers using multi tion Technology tion Technology sues (Ref-2).	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cir	Dynamic Power t Techniques, Circu Power Reduction; Di iques, Run-time St on in Cache Memo ogic. I Power Very Fast I rcuit Design, Adia	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic	10 Hrs Daches, Circuit lependent Powe luction–Leakag Techniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design	t Technology ign Time Red action Technic lers using mult tion Technique tors, Energy sues (Ref-2).	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio tiple-valued la Unit –II tes – II: Low Recovery Cir	Dynamic Power t Techniques, Circu Power Reduction; iques, Run-time St on in Cache Memo ogic. I Power Very Fast I rcuit Design, Adia	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ Ibatic – Charging H	10 Hrs Daches, Circuit lependent Powe luction–Leakag fechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw	t Technology ign Time Red action Technic lers using mult tion Technique tors, Energy sues (Ref-2).	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio tiple-valued la Unit –II tes – II: Low Recovery Cir	Dynamic Power t Techniques, Circu Power Reduction; iques, Run-time St on in Cache Memo ogic. I Power Very Fast I rcuit Design, Adia	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T ories, LVLP Logic Dynamic Logic Circ batic – Charging H	10 Hrs Daches, Circuit lependent Powe luction–Leakag fechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe
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Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power.	Exation Techn oltage Scaling it Technology ign Time Red action Technic lers using mult tion Technique tors, Energy sues (Ref-2). a for Low P vare Power Op	Unit –II niques–I: I Based Circuit Dependent F uction Techni ques Reductio tiple-valued la Unit –II tes – II: Low Recovery Cir ower: Source timizations, A Unit –IV tic Random	I Dynamic Power t Techniques, Circulation; Techniques, Run-time Strends Power Reduction; Techniques, Run-time Strends iques, Run-time Strends Strends in Cache Memory Strends in Cache Memory	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ batic – Charging F ower Dissipation, 5 wer Code Generatio	10 Hrs Daches, Circuit lependent Powe luction–Leakag Techniques, Rum Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design fo 9 Hrs veen 6T and 47
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power.	cationTechnologyoltageScalingtTechnologyignTimeignTimeactionTechnicdersusingdersusingdersusingtorsEnergysues(Ref-2).aforLowParePowerwPowerStanLPSRAMCe	Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cir ower: Source timizations, A Unit –IV tic Random	I Dynamic Power t Techniques, Circu Power Reduction; T iques, Run-time St St on in Cache Memo Dogic. I Power Very Fast I rcuit Design, Adia es of Software P Access memories nared bit-line SRAI	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T bries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, f wer Code Generatio : Basics, Race betw M cell configuration	10 Hrs baches, Circuit lependent Powe duction–Leakag fechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design fo 9 Hrs veen 6T and 47 , Power efficien
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power. Low Voltage Lo memory cells, LV 7T SRAM cell wi	tation Technology ign Time Reduction Technology ign Time Reduction Technology iders using multiplets using multiplets tion Technique tors, Energy sues (Ref-2). a for Low P are Power Op w Power Sta LP SRAM Centhology	Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cir ower: Source timizations, A Unit –IV tic Random ell designs- Sh de read and v	I Dynamic Power t Techniques, Circulation; Techniques, Run-time Stronger Power Reduction; Techniques, Run-time Stronger iques, Run-time Stronger Stronger Power Very Fast I rcuit Design, Adia es of Software P Automated Low-Po V Access mared bit-line write, Load less V Stronger	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, 3 wer Code Generatio : Basics, Race betw M cell configuration IOS 4T SRAM cell	10 Hrs Daches, Circuit lependent Powe luction–Leakag Techniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design fo 9 Hrs veen 6T and 47 , Power efficient , The 1T SRAM
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power. Low Voltage Lo memory cells, LV 7T SRAM cell wi cell, Pre-charge a	tation Technology ign Time Reduction Technology ign Time Reduction Technology iders using multiplets using multiplets tion Technique tors, Energy sues (Ref-2). a for Low P are Power Op w Power Sta LP SRAM Centhology	Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cir ower: Source timizations, A Unit –IV tic Random ell designs- Sh de read and v	I Dynamic Power t Techniques, Circulation; Techniques, Run-time Stronger Power Reduction; Techniques, Run-time Stronger iques, Run-time Stronger Stronger Power Very Fast I rcuit Design, Adia es of Software P Automated Low-Po V Access mared bit-line write, Load less V Stronger	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T bries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, f wer Code Generatio : Basics, Race betw M cell configuration	10 Hrs Daches, Circuit lependent Powe luction–Leakag Techniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design fo 9 Hrs veen 6T and 47 , Power efficient , The 1T SRAM
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power. Low Voltage Lo memory cells, LV 7T SRAM cell wi cell, Pre-charge a Output Latch,	tation Technology ign Time Reduction Technology ign Time Reduction Technology ign Time Reduction Technology iters using multi- tion Technology tion Technology tion Technology sues (Ref-2). a for Low P are Power Op w Power Sta LP SRAM Centhology ith current mo- and Equalization	Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cir ower: Source timizations, A Unit –IV tic Random ell designs- Sh de read and v on Circuit, D	I Dynamic Power Techniques, Circu Power Reduction; T iques, Run-time St Don in Cache Memory Dogic. I Power Very Fast I recuit Design, Adia es of Software P Automated Low-Po V Access memories nared bit-line SRAI vrite, Load less CN ynamic and static	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, 5 wer Code Generatio : Basics, Race betw M cell configuration IOS 4T SRAM cell decoders, Voltage	10 Hrs Daches, Circui lependent Powe luction–Leakag Pechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design for 9 Hrs veen 6T and 47 , Power efficien , The 1T SRAN Sense amplifier
Parallelization, Vo Reduction, Circui Components, Des time Active Redu Mode CMOS Add Power Optimizat Arithmetic Opera implementation is Software Design Estimation, Softw Low Power. Low Voltage Lo memory cells, LV 7T SRAM cell wi cell, Pre-charge a Output Latch, Low Power SRA	cationTechnologyoltage Scalingttt <t< td=""><td>Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cin ower: Source timizations, A Unit –IV tic Random ell designs- Sh de read and v on Circuit, D</td><td>I Dynamic Power At Techniques, Circular Power Reduction; Transference Power Reduction; Transference iques, Run-time Stron Interference point Cache Memory Design Memory Design Atian es of Software Atcess memories hared bit-line Virite, Load less Vynamic and static To SRAM Power, Load Lower, Load</td><td>Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, 3 wer Code Generatio : Basics, Race betw M cell configuration IOS 4T SRAM cell</td><td>10 Hrs Daches, Circui lependent Powe luction–Leakag Pechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design for 9 Hrs veen 6T and 47 , Power efficien , The 1T SRAN Sense amplifier</td></t<>	Unit –II niques–I: I Based Circuit Dependent F uction Technic ques Reduction tiple-valued la Unit –II tes – II: Low Recovery Cin ower: Source timizations, A Unit –IV tic Random ell designs- Sh de read and v on Circuit, D	I Dynamic Power At Techniques, Circular Power Reduction; Transference Power Reduction; Transference iques, Run-time Stron Interference point Cache Memory Design Memory Design Atian es of Software Atcess memories hared bit-line Virite, Load less Vynamic and static To SRAM Power, Load Lower, Load	Reduction Appro- nit Technology – Ind Leakage Power Red and-by Reduction T pries, LVLP Logic Dynamic Logic Circ batic – Charging H ower Dissipation, 3 wer Code Generatio : Basics, Race betw M cell configuration IOS 4T SRAM cell	10 Hrs Daches, Circui lependent Powe luction–Leakag Pechniques, Run Styles, Current 10 Hrs uits, Low Powe Principle and it Software Powe n, Co-design for 9 Hrs veen 6T and 47 , Power efficien , The 1T SRAN Sense amplifier
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Large LPVLSI System design and Applications: Architecture driven Voltage Scaling, Power optimization using operation reduction and operation substitution, Pre-computation based optimization, Multiple and Dynamic supplyvoltage design, Choice of supply voltages, Varying the clock speed, varying the VDD of RAM structures, Gated Clocking. Leakage current reduction in medical devices.

Text Books:

- 1. Kiat- Seng Yeo and Kaushik Roy, "Low-Voltage, Low-Power VLSI Subsystems, Tata Mc Graw hill Edition, 2005.
- 2. Christian Piguet, "Low Power CMOS Circuits Technology, Logic Design and CAD Tools", 1stIndian Reprint, CRC Press, 2010.

References:

- 1. Kaushik Royand Sharat Prasad, "Low-Power CMOS VLSI Circuit Design", Wiley Pub., 2000.
- 2. Dimitrios Soudris, Christian Piguetand Coastas Goutis, "Designing CMOS Circuits for Low Power", Kluwer Academic Pub, 2002
- 3. J.Rabaey, LowPowerDesignEssentials, 1stEdition, SpringerPublications, 2010.

Course Outcomes:

After the completion of the course students will able to:

CO1: Explain technology independent and technology dependent techniques for CMOS circuits.

CO2: Distinguish impact of various power reduction techniques at different levels of VLSI Design.

- **CO3:** Identify sources of power dissipation and apply leakage reduction techniques to reduce static power consumption in CMOS circuits.
- **CO4:** Analyze different power reduction techniques for VLSI systems at Design time, Run-time and Stand-by modes.
- **CO5:** Apply simple software power estimation and optimization techniques for low power VLSI system design.
- **CO6:** Apply low power circuit and architectural techniques such as capacitance reduction, gatedclocking, VDD and Vth scaling, DVS etc in digital systems and SRAM designs.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0451T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objective	es:		1		
• Develop an u	inderstanding of	f the technolog	gies behind the er	nbedded computing	g systems,
capabilities a	nd limitations of	f the hardware	e, software compo	nents.	
• Methods to e	valuate design t	radeoffs betwe	een different techn	ology choices.	
• design metho	dologies				
		Syllabus			Total Hours: 48
		Unit –I			10 Hrs
Introduction to l	Embedded syst	ems: What is	an embedded syst	em Vs. General co	mputing system,
history, classifica	ation, major ap	oplication are	as, and purpose	of embedded sys	stems. Core of
=	=			ion interface, emb	edded firmware,
other system com	ponents, PCB ai		nponents.		10 11
Miaro controllo	rs arabitaatura	Unit –II	iag quality attrik	outes application s	10 Hrs
				ng a controller, Al	-
				Instruction set, Th	
• •	•	· •	0	evelopment, desigi	
	-				
		Unit –III			9 Hrs
		ing system ba	• •	TOS, tasks, proce	ss and threads,
		ing system ba , types of mult	• •	TOS, tasks, proce emptive, pre-empti	ss and threads, we scheduling.
multiprocessing a	nd multitasking,	ing system ba , types of mult Unit –IV	itasking, non-pre-	emptive, pre-empti	ss and threads, we scheduling. 10 Hrs
multiprocessing a Task communica	nd multitasking	ing system ba types of mult Unit –IV Shared memo	itasking, non-pre- ory, pipes, memor	emptive, pre-empti	ss and threads, ive scheduling. 10 Hrs message queue,
multiprocessing a Task communica mailbox, signallin	nd multitasking, ation of RTOS: ng, RPC and soc	ing system ba types of mult Unit –IV Shared memorikets, task com	itasking, non-pre- ory, pipes, memon nmunication/synch	emptive, pre-empti	ss and threads, ive scheduling. 10 Hrs message queue, racing, deadlock.
multiprocessing a Task communica mailbox, signallin Priority Inversion	nd multitasking, ation of RTOS: ag, RPC and soc semaphore, mu	ing system ba types of mult Unit –IV Shared memo kets, task com itex, critical so	itasking, non-pre- ory, pipes, memor nunication/synch ection objects, eve	emptive, pre-empti ry mapped objects, ronization issues, r ents, device, device	ss and threads, ive scheduling. 10 Hrs message queue, racing, deadlock.
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multiprocessing a Task communica mailbox, signallin Priority Inversion clause an RTOS, Simulators and Development life	nd multitasking, ation of RTOS: ag, RPC and soc semaphore, mu Integration and a emulators:	ing system ba types of mult Unit –IV Shared memorikets, task com tex, critical so testing of emb Unit –V Simulators	itasking, non-pre- ory, pipes, memor nmunication/synch ection objects, eve edded hardware a and emulators,	emptive, pre-empti ry mapped objects, ronization issues, r ents, device, device nd firm ware.	ss and threads, ive scheduling. 10 Hrs message queue, racing, deadlock. e drivers, how to 9 Hrs pedded Product
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multiprocessing a Task communica mailbox, signallin Priority Inversion clause an RTOS, Simulators and Development life	nd multitasking, ation of RTOS: ag, RPC and soc semaphore, mu Integration and emulators: cycle (EDLC),	ing system ba types of mult Unit –IV Shared memorikets, task comutex, critical set testing of emb Unit –V Simulators Trends in emb	itasking, non-pre- ory, pipes, memor nmunication/synch ection objects, eve edded hardware a and emulators, edded Industry, ir	emptive, pre-empti ry mapped objects, ronization issues, r ents, device, device nd firm ware.	ss and threads, ive scheduling. 10 Hrs message queue, racing, deadlock. e drivers, how to 9 Hrs pedded Product
multiprocessing a Task communica mailbox, signallin Priority Inversion clause an RTOS, I Simulators and Development life Textbooks: 1. Introduction to	nd multitasking, ation of RTOS: ag, RPC and soc semaphore, mu Integration and emulators: cycle (EDLC), ' o embedded syst	ing system ba types of mult Unit –IV Shared memorikets, task comutex, critical set testing of emb Unit –V Simulators Trends in emb	itasking, non-pre- ory, pipes, memor nmunication/synch ection objects, eve edded hardware a and emulators, bedded Industry, ir .V, TMH, 2009.	emptive, pre-empti ry mapped objects, ronization issues, r ents, device, device nd firm ware.	ss and threads, ive scheduling. 10 Hrs message queue, cacing, deadlock. e drivers, how to 9 Hrs pedded Product (ICE).
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After the completion of the course students will able to:

CO1: Understand the basics of an embedded system and RTOS

CO2: Understand the architecture of Microcontroller and quality attributes.

CO3: Analyze the various types of Scheduling algorithms in Embedded systems RTOS.

CO4: Analyze the different types of task communication protocol to design the RTOS based embedded systems.

CO5: Describe the problems related to the RTOS for design of embedded systems.

CO6: Analyze the various tools to available to test the designed embedded system.

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0452T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objecti	ves:		I	1	
• To provide	the student	with the bas	sic understanding of	of fuzzy sets and log	gic system
fundamenta	ls.				
• To understa	nd the feature	es of Membe	ership functions.		
• To develop	the fundamen	tal concepts	such as fuzzy sets,	operations and relation	ons.
-		-	n crisp and fuzzy se	-	
	e fuzzy arithn		1		
	uzzy inferenc	-			
					T-4-1 II 40
		Syllab Unit ·			Total Hours: 48 10 Hrs
Introduction: Fu	zzv sets, logi			introduction to real 1	
	•	•		n MATLAB, Memb	
	=	=	-	zy sets- Membership	-
Nomenclature us	se in Fuzzy s	ets theory. T	beoretic operation	used in Euzzy sets	
	-	ets theory, 1		used III Fuzzy sets.	
	-	Unit -	-II	-	10 Hrs
	peration in F	Unit - Fuzzy sets, l	-II Properties of Fuzz	y sets- Law of Cont	radiction, Law of
Excluded mide	peration in F lle, Idempo	Unit - Fuzzy sets, l tency, Inv	- II Properties of Fuzzy olution, Commut	y sets- Law of Cont ativity, Associativit	radiction, Law of y, Distributivity
Excluded mide Absorption, Ab	peration in F lle, Idempo sorption of	Unit - Fuzzy sets, l tency, Inve complement	-II Properties of Fuzzy olution, Commuta and Demorgan's	y sets- Law of Cont ativity, Associativit laws. Distance bet	radiction, Law of y, Distributivity ween Fuzzy sets
Excluded mide Absorption, Ab Arithmetic oper	peration in F lle, Idempo sorption of ation on Fuzz	Unit - Fuzzy sets, l tency, Inve complement zy numbers-	- II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a	radiction, Law of y, Distributivity, ween Fuzzy sets, nd Division,
Excluded mide Absorption, Ab Arithmetic oper	peration in F lle, Idempo sorption of ation on Fuzz	Unit - Fuzzy sets, l tency, Inve complement zy numbers-	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op	y sets- Law of Cont ativity, Associativit laws. Distance bet	radiction, Law of y, Distributivity, ween Fuzzy sets, nd Division,
Excluded mide Absorption, Ab Arithmetic oper complement of H	peration in F Ile, Idempo sorption of ation on Fuzz Fuzzy sets, T-	Unit - Fuzzy sets, l tency, Invo complement zy numbers- Norm operat Unit –	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a	radiction, Law of y, Distributivity ween Fuzzy sets nd Division, s. 10 Hrs
Excluded mide Absorption, Ab Arithmetic oper complement of F Parameterized T and Fuzzy relat	peration in F Ile, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project	Unit - Fuzzy sets, l tency, Invo complement zy numbers- Norm operat Unit – norm operat ion of Fuzz	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op -III tions, Crisp Relation zy relation set, cyl	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set	radiction, Law of y, Distributivity, ween Fuzzy sets, and Division, s. 10 Hrs perations on Crisp
Excluded mide Absorption, Ab Arithmetic oper complement of F Parameterized T and Fuzzy relat	peration in F Ile, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project	Unit - Fuzzy sets, l tency, Inve complement zy numbers- Norm operat Onrm operat ion of Fuzz relation, Ex	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op -III tions, Crisp Relatio zy relation set, cyl tension Principle.	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O	radiction, Law of y, Distributivity, ween Fuzzy sets, nd Division, s. 10 Hrs perations on Crisp of Fuzzy sets and
Excluded mide Absorption, Ab Arithmetic oper- complement of H Parameterized T and Fuzzy relat properties of Cri	peration in F lle, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy	Unit - Fuzzy sets, l tency, Invo complement zy numbers- Norm operat Onrm operat ion of Fuzz relation, Ex Unit –	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op -III tions, Crisp Relatio zy relation set, cyl tension Principle. -IV	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension o	radiction, Law of y, Distributivity, ween Fuzzy sets, and Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs
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Excluded mide Absorption, Ab Arithmetic oper- complement of H Parameterized T and Fuzzy relat properties of Cri Composition of Linguistic, hedg	peration in F lle, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy Fuzzy relation	Unit - Fuzzy sets, l tency, Inve complement zy numbers- Norm operation ion of Fuzz relation, Ex Unit - ons and its complement	-II Properties of Fuzzy olution, Commuta and Demorgan's Addition, Subtract tion and S-Norm op -III tions, Crisp Relatio zy relation set, cyl tension Principle. -IV properties, Fuzzy	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension o	radiction, Law of y, Distributivity ween Fuzzy sets nd Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs ce relations,
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Excluded mide Absorption, Ab Arithmetic oper complement of H Parameterized T and Fuzzy relat properties of Cri Composition of Linguistic, hedg on composite lin Contrast intensif	peration in F lle, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy Fuzzy relation es, negation/o guistic terms.	Unit - Fuzzy sets, I tency, Invo complement zy numbers- Norm operat on of Fuzz relation, Ex Unit - ons and its complement - Zzy set Orth	-II Properties of Fuzzy olution, Commutation and Demorgan's Addition, Subtractive tion and S-Norm op -III tions, Crisp Relation zy relation set, cyling tension Principle. -IV properties, Fuzzy conventions, concer- -V mogonality of Fuzzy	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension of tolerances equivalence entration, dilation, an	radiction, Law of y, Distributivity ween Fuzzy sets and Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs ce relations, and some examples 9 Hrs zzy Reasoning and
Excluded mide Absorption, Ab Arithmetic oper- complement of F Parameterized T and Fuzzy relat properties of Cri Composition of Linguistic, hedg on composite lin Contrast intensif Fuzzy inference Antecedent with	peration in F lle, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy Fuzzy relation guistic terms fication of Fu systems, Ma three rules a	Unit - Fuzzy sets, I tency, Inve complement zy numbers- Norm operat on of Fuzz relation, Ex Unit - ons and its complement zzy set Orth amdani Fuzz nd for Two	-II Properties of Fuzzy olution, Commutation and Demorgan's Addition, Subtractive tion and S-Norm op -III tions, Crisp Relation zy relation set, cyling tension Principle. -IV properties, Fuzzy conventions, concerned -V mogonality of Fuzzy zy model, Example Antecedents with fuzzy	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension of tolerances equivalence entration, dilation, an	radiction, Law of y, Distributivity, ween Fuzzy sets and Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs ce relations, and some examples 9 Hrs zzy Reasoning and model for Single
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Excluded mide Absorption, Ab Arithmetic oper- complement of H Parameterized T and Fuzzy relat properties of Cri Composition of Linguistic, hedg on composite lin Contrast intensif Fuzzy inference Antecedent with Tsukamoto Fuzz Textbooks:	peration in F ile, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy Fuzzy relation guistic terms fication of Fu systems, Ma three rules a sy model, TSH	Unit - Fuzzy sets, I tency, Invo complement zy numbers- Norm operat onorm operat ion of Fuzz relation, Ex Unit - complement Unit - zzy set Orth amdani Fuzz nd for Two K Fuzzy mod	-II Properties of Fuzzy olution, Commutation and Demorgan's Addition, Subtractive tion and S-Norm op -III tions, Crisp Relation zy relation set, cyling tension Principle. -IV properties, Fuzzy conventions, concerner -V mogonality of Fuzzy zy model, Example Antecedents with fedel	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension of tolerances equivalent entration, dilation, an	radiction, Law of y, Distributivity, ween Fuzzy sets, and Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs ce relations, and some examples 9 Hrs zzy Reasoning and model for Single zzy model,
Excluded mide Absorption, Ab Arithmetic oper- complement of H Parameterized T and Fuzzy relat properties of Cri Composition of Linguistic, hedg on composite lin Contrast intensif Fuzzy inference Antecedent with Tsukamoto Fuzz Textbooks: 1. Ross, T. J. (peration in F ile, Idempo sorption of ation on Fuzz Fuzzy sets, T- -norm and S- ions, Project sp and Fuzzy Fuzzy relation guistic terms fication of Fu systems, Ma three rules a sy model, TSH 2005), "Fuzz	Unit - Fuzzy sets, I tency, Invo complement zy numbers- Norm operat ion of Fuzz relation, Ex Unit - ons and its complement Zzy set Orth amdani Fuzz nd for Two X Fuzzy mod	-II Properties of Fuzzy olution, Commutation and Demorgan's Addition, Subtractive tion and S-Norm op -III tions, Crisp Relation zy relation set, cyling tension Principle. -IV properties, Fuzzy conventions, concerner -V mogonality of Fuzzy zy model, Example Antecedents with fedel	y sets- Law of Cont ativity, Associativit laws. Distance bet tion, Multiplication a peration for Fuzzy set n, Fuzzy Relation, O indrical Extension o tolerances equivalence entration, dilation, an	radiction, Law of y, Distributivity, ween Fuzzy sets, and Division, s. 10 Hrs perations on Crisp of Fuzzy sets and 9 Hrs ce relations, and some examples 9 Hrs zzy Reasoning and model for Single zzy model,

- A First Course in Fuzzy Logic, Fourth Edition, by Hung T. Nguyen, Carol Walker, Elbert A. Walker, CRC press.
- 2. Fuzzy Logic, Systems and Engineering Applications by Hubert Parks , Murphy & Moore Publishing March 8, 2022.

Course Outcomes:

After the completion of the course students will be able to:

CO1: Understand the fundamentals of fuzzy sets and logic systems.

CO2: Understand the features of Membership functions.

CO3: Analyze the fundamental concepts such as fuzzy sets, operations and relations.

CO4: Understand the differences between crisp and fuzzy set relations.

CO5: Understand the Arithmetic operations on Fuzzy numbers.

CO6: Analyze different fuzzy inference applications.

	ADVAN	CED DIGIT	AL SIGNAL PR	ROCESSING	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0453T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objective	s:		5LL./V		
• To understand	the sampling r	ate conversio	n and summarize	multirate DSP.	
• To describe the	various linear	filtering tech	nniques and its ap	plications to DSP.	
• To apply and each	stimate parame	etric and non-	parametric power	r spectrum estimatio	n.
• To acquire the	knowledge on	applications	of multi rate digit	al signal processing	
		Syllabus			Total Hours:48
		Unit –I			10 Hrs
Variant Filter Stru Conversion of B Modulation-Free M Arbitrary Factor, F Linear Prediction Random Process, Forward Linear Pr the Lattice Forwar The Levinson-Du	ctures, Multist and pass Sig Aethod for Dec Tirst-Order App n and Optim Relationships rediction, Back d and Backwa rbin Algorithr	tage Impleme nals, Decim cimation and proximation, a Unit –II um Linear Between the cward Linear ard Predictors n, AR Lattic	entation of Sampl ation and Interp Interpolation, San Second-Order Ap Filters: Innovati Filter Parameter Prediction, The G, Relationship of ce Structure, AR	s, Polyphase Filter S ling-Rate Conversion polation by Freque mpling-Rate Conver proximation (Linear ions Representation is and the Autocorre Optimum Reflection an AR Process to I RMA Processes and Filter, IIR Wiener	n, Sampling-Rate ncy Conversion sion by an Interpolation). 10 Hrs of a Stationary elation Sequence a Coefficients for Linear Prediction
		Unit –III			9 Hrs
Nonparametric N	Iethods for P		rum Estimation:	: Estimation of Spe	
-		-		correlation and Pov	
Random Signals, U	Use of the DF	T in Power S	pectrum Estimati	ion, Bartlett Method	, Welch Method
Blackman and Tuk	ey Method, Pe	erformance C	haracteristics of I	Nonparametric Powe	er Spectrum
Estimators.					
		Unit –IV			10 Hrs
Autocorrelation an The Burg Method Model Parameters, Model Order, MA Estimation.	d the Model P for the AR M , Sequential Es Model for F igital Signal I pidal Signals,	arameters, Th lodel Paramet stimation Me Power Spectr Unit –V Processing: I Spectral Ana	ters, Unconstraine thods for the AR rum Estimation, A Dual Tone Multi- llysis of Non stat	Method for the AR M ed Least-Squares M Model Parameters, ARMA Model for Frequency Signal D tionary Signals, Spe	Iodel Parameters ethod for the AF Selection of AF Power Spectrum 9 Hrs etection, Spectra

Text Books:

- 1. J G Proakis, D G Manolokis, "Digital Signal Processing Principles, Algorithms and Applications" 3rd Edition, Prentice Hall.
- 2. Sanjit K Mitra, "Digital Signal Processing A Computer Based Approach", 2nd Edition, Tata Mc graw Hill Publications.

References:

- 1. A V Oppenhiem, R W Schafer, "Discrete-Time Signal Processing", Pearson Education.
- 2. S. M. Kay, "Modern spectral Estimation Techniques" PHI, 1997.

Course Outcomes:

After the completion of the course students will able to:

CO1: Understand the sampling rate conversion, interpolation and decimation for signal processing applications also need of optimum linear filtering and its applications.

CO2: Apply and explore the real-time applications to multirate DSP systems.

CO3: Analyze the parametric and non-parametric methods for power spectrum estimation.

CO4: Describe the applications of DSP to real-time requirements.

CO5: Solve the linear equations and analyze the optimum filters to estimate the signals corrupted by noise.

CO6: Differentiate parametric and non-parametric methods for power spectrum estimation.

		INTERN	ET OF THINGS		
Course Code	L:T:P	Credits	Exam. Marks	Exam Duratio	on Course Type
22A04054T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objectiv	es:			I	
• To understan	d Smart Object	ts and IoT Arc	hitectures.		
• To learn about	ut various IOT-	related protoc	ols.		
• To build sim	ple IoT System	s using Arduir	o and Raspberry	Pi	
		C	the context of IoT		
• To develop I	oT infrastructur	re for popular	applications		
		Syllabus	11		Total hours:48
		Unit –I			10 Hrs
Fundamentals o	f IoT: Definit		teristics of IoT	Evolution of In	ternet of Things
					VF) and Alternativ
-	-				Edge and Cloud i
	-			-	cts and Connecting
		-	inctional Blocks, S		ets and Connecting
Smart Objects Lo	gicai Desigii oi	$\frac{101 - 101, 10}{\text{Unit} - \text{II}}$	inctional Diocks,	Security.	10 Hrs
Communication	Drotocola for				
Communication	Frotocols 10		ing principles of	t concorr $I(Y)$	L' doployment to
Doomborry Di /Ar			ing principles o		
	duino/Equivale	ent platform –	Reading from Se	ensors, Communi	cation: Connectin
microcontroller w	duino/Equivale /ith mobile dev	ent platform – vices – commu	Reading from Senication through	ensors, Communi Bluetooth, WIFI	cation: Connectin and USB - Contik
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References:

- 1. Vermesan, Ovidiu, and Peter Friess, eds. Internet of things-from research and innovation to market deployment, 1st edition, Aalborg: River publishers, 2014.
- 2. Rajesh Singh, Anita Gehlot, Lovi Raj Gupta, Bhupendra Singh, Mahendra Swain, Internet of Things with Raspberry Pi and Arduino, CRC Press, 2019.
- 3. Olivier Hersent, David Boswarthick, Omar Elloumi, —The Internet of Things Key applications and Protocols, Wiley, 2012 (for Unit 2).

E-learning resources:

- 1. https://www.guru99.com/iot-tutorial.html
- 2. https://developer.ibm.com/technologies/iot/tutorials/

Course Outcomes:

After the completion of the course students will able to:

CO1: Explain the concept of IoT.

CO2: Analyze various protocols for IoT.

CO3: Design a PoC of an IoT system using Rasperry Pi/Arduino

CO4: Apply data acquisition and use cloud offerings related to IoT.

CO5: Analyze applications of IoT in real time scenario.

CO6: Apply the knowledge of IOT in various areas of engineering field.

CPLD & FPGA ARCHITECTURE AND APPLICATIONS

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A0455T	3:0:0	3	CIE:30	3 Hours	PEC
			SEE:70		

Course Objectives:

- To understand the concepts of Programmable Logic Devices & Complex Programmable Logic Devices
- To give exposure to understand the concept of Field Programmable Gate Arrays design.
- To give exposure to understand the concept of Field Programmable Gate Arrays Case Studies.
- The Students aims to practical experience by designing of Finite State Machines
- To provide students with the understanding of the different FSM Architecture & System level Design.

Syllabus	Total Hours: 48
Unit –I:: Introduction to Complex Programmable Logic Devices	10 Hrs
Programmable Logic: ROM, PLA, PAL, PLD, FPGA – Features	
Complex Programmable Logic Devices: ALTERA CPLDs and ALTERA FLI	EX 10k Series
CPLD, Speed Performance.	
Unit –II:: Field Programmable Gate Arrays	10 Hrs
Xilinx logic Cell array, CLB, I/O Block Programmable interconnect, Techno	ology Mapping for
FPGA: Library based, LUT based, Multiplexer based Technology Mapping.	
Unit –III:: FPGA Case Studies	10 Hrs
Case Studies: programming Technologies, Xilinx XC3000, XC4000, Actel F	PGAs, Alteras
FPGAs, Plus Logic FPGA, AMD FPGA, Quick Logic FPGA, Algotronix F	FPGA, Cross point
solutions FPGA, FPGA Design Flow.	
Unit –IV:: Finite State Machines (FSM)	9 Hrs
Finite State Machines (FSM): Finite State Machine- State Transition Table	e, State Assignments
for FPGAs. Problem of the Initial State Assignment for One Hot Encoding.	
Realization of State Machine: Derivation of SM Charts. Realization of St	tate Machine Chart,
Alternative Dealistica of State Machine Chartersine Missersensers Link	
Alternative Realization of State Machine Chart using Microprogramming. Link	ked State Machines.
One–Hot State Machine, Petri nets for State Machines – Basic Concepts, Pr	
One-Hot State Machine, Petri nets for State Machines - Basic Concepts, Pr	
One-Hot State Machine, Petri nets for State Machines – Basic Concepts, Pr Petri nets for Parallel Controllers.	roperties. Extended 9 Hrs
One–Hot State Machine, Petri nets for State Machines – Basic Concepts, Pr Petri nets for Parallel Controllers. Unit –V:: FSM Architectures & Systems Level Design	roperties. Extended 9 Hrs
One–Hot State Machine, Petri nets for State Machines – Basic Concepts, Pr Petri nets for Parallel Controllers. Unit –V:: FSM Architectures & Systems Level Design FSM Architectures: Architectures Centered Around Non- Registered PLDs.	roperties. Extended 9 Hrs State Machine
One-Hot State Machine, Petri nets for State Machines – Basic Concepts, Pretri nets for Parallel Controllers. Unit –V:: FSM Architectures & Systems Level Design FSM Architectures: Architectures Centered Around Non- Registered PLDs. Designs Centered Around A Shift Register.	operties. Extended 9 Hrs State Machine Design. Application
 One-Hot State Machine, Petri nets for State Machines – Basic Concepts, Pretri nets for Parallel Controllers. Unit –V:: FSM Architectures & Systems Level Design FSM Architectures: Architectures Centered Around Non- Registered PLDs. Designs Centered Around A Shift Register. Systems Level Design: One-Hot Design Method. Use of ASMs in One-Hot 2010 	operties. Extended 9 Hrs State Machine Design. Application
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Course Outcomes:

After the completion of the course students will able to:

CO1: Acquire qualitative knowledge about the PLD's & CPLD's.

CO2: Understand the concept of Field Programmable Gate Arrays design.

CO3: Apply the basic FPGA Case Studies in different Module design.

CO4: Understand the different Modules of Finite State Machine.

CO5: Understand the Architecture of Finite State Machine.

CO6: Acquire qualitative knowledge about realization of Finite State Machine.

		(Common	to ECE and CSE)		
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	n Course Type
22A0456T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objective	es:		I	I	
This course is	designed to e	nable the stude	ents to familiarize t	hemselves with b	basic concepts of
	U		transforms and lear		1
	-	-			
techniques like in	lage enhancen		n, segmentation and		
		Syllabus			Total Hours: 48
Unit –I			o Image Processing		10 Hrs
	-	-	al steps in digital in	• • •	-
image processing	system, imag	ge sensing and	acquisition, image	sampling and qu	antization, some
basic relationship	s between pix	els, an introdu	ction to the mather	natical tools used	in digital image
processing.					
· ·	ns: Need for	image transform	ns, Discrete Fourier	r transform (DFT)) of one variable
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LATCHSION to Tune					
	Nora Walch 7				
Importance of Ph					
Importance of Ph Discrete Cosine t	ransform, KL		VD and Radon Tr		
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Unit-V

Image segmentation

Image segmentation: Fundamentals, point, line, edge detection, thresholding, and region –based segmentation.

Morphological Image Processing: Preliminaries, Erosion and dilation, opening and closing, basic morphological algorithms for boundary extraction, thinning, gray-scale morphology, Segmentation using morphological watersheds.

Textbooks:

- 1. R. C. Gonzalez and R. E. Woods, Digital Image Processing, 3rd edition, Prentice Hall, 2008.
- 2. Jayaraman, S. Esakkirajan, and T. Veerakumar," Digital Image Processing", Tata McGraw-Hill Education, 2011.

Reference Books:

- 1. Anil K.Jain, "Fundamentals of Digital Image Processing", Prentice Hall of India, 9th Edition, Indian Reprint, 2002.
- 2. B.Chanda, D.Dutta Majumder, "Digital Image Processing and Analysis", PHI, 2009Hwei Hsu, "Schaum's Outline of Signals and Systems", 4thEdition, TMH, 2019.

Course Outcomes (CO):

After the completion of the course students will able to:

CO1: Understand various image transform techniques.

CO2: Understand image manipulations and different digital image processing techniques.

CO3: Understand basic operations like – Enhancement, segmentation, compression, Image transforms.

CO4: Classify Image transforms and restoration techniques on image.

CO5: Analyze pseudo and full color image processing techniques.

CO6: Apply various morphological operators on images.

Course Code	L:T:P	Credits	Exam. Marks	Exam Durati	on Course Type
22A0457T	3:0:0	3	CIE:30 SEE:70	3 Hours	PEC
Course Objecti	ves:	I		I	
To teach know	edge on Digit	al television sta	indards		
To impart infor		-			
			evision& its contro		
To provide the	awareness of		n lines, testing & m	easurement of po	ower for Digital TV
		Syllabus Unit –I			Total Hours: 48 10 Hrs
Digital Televisi	on Transmis		S: ATSC terrestrial	transmission sta	
-			standard, ISDB-		-
			EG-2 Performance		
	-	-	smission errors, er	•	-
interference, co-	channel inter	ference, adjacer	t channel interferen	nce, analog to dig	gital TV, transmitte
requirements					
		Unit –II			10 Hrs
	-	•	al Television: Da	•	
-			eaving, inner code	-	isertion, quadratur
modulation, 8 v S	B, bandwidth	Unit –III	FDM, flexibility, b	andwidth.	9 Hrs
Transmittars f	or Digital 7	Colovision Pro	-correction and e	uualization un	conversion precis
	-		-correction and ed e transmitters, RF		-
frequency contr	ol, RF ampli	fiers, solid-state	e transmitters, RF	amplifier modul	es, power supplies
frequency contr cooling, automa	ol, RF ampli tic gain or lev	fiers, solid-state		amplifier modul	es, power supplies
frequency contr cooling, automa	ol, RF ampli tic gain or lev	fiers, solid-state	e transmitters, RF	amplifier modul	es, power supplies
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frequency contr cooling, automa performance equ Transmission I system AERP, r order modes, per wind load, wav trade-offs, wave Test and Me measurement, ca testing digital te Text Books: 1. Gerald w. C	ol, RF ampli tic gain or lev ality. Line for Digi igid coaxial tr eak power rate guide, bandy guide or coar easurement alorimetry, po levision trans	fiers, solid-state vel control, ac d Unit –IV tal Television: ransmission line ting, frequency width, waveguid x Pressurization Unit –V for Digital ower meters, per mitters.	e transmitters, RF istribution, transmi Fundamental para es, dissipation, atter response, standard de attenuation, pow Television: Powe ak power measurer	amplifier modul tter control, tube meters, efficienc nuation, and pow lengths, corrug wer rating, frequ er measurement nent, measurement smission, JohnW	es, power supplies transmitters, 10 Hrs y, effect of VSWF er handling, higher ated coaxial cables ency response, siz 9 Hrs s, average powe ent uncertainty, Viley, 2001.
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e-resources:

- 1. https://www.youtube.com/watch?v=_nGnRvyHMEI HYPERLINK
- $\label{eq:list_relation} 2. ``https://www.youtube.com/watch?v=_nGnRvyHMEI&list=RDCMUCdlnqMpRrMcClK2fT6z8EEw&index=2''& HYPERLINK \\$
- 3. "https://www.youtube.com/watch?v=_nGnRvyHMEI&list=RDCMUCdlnqMpRrMcClK2fT6z8EEw&inde x=2"list=RDCMUCdlnqMpRrMcClK2fT HYPERLINK
- 4. "https://www.youtube.com/watch?v=_nGnRvyHMEI&list=RDCMUCdlnqMpRrMcClK2fT6z8EEw&in dex=2"6z8EEw HYPERLINK
- 5. "https://www.youtube.com/watch?v=_nGnRvyHMEI&list=RDCMUCdlnqMpRrMcClK2fT6z8EEw&ind ex=2"& HYPERLINK
- 6. "https://www.youtube.com/watch?v=_nGnRvyHMEI&list=RDCMUCdlnqMpRrMcClK2fT6z8EEw&ind ex=2"index=2
- 7. https://www.rfwireless-world.com/Tutorials/digital-television-DTV-basics.html

Course Outcomes:

After the completion of the course students will able to:

CO1: Compare Digital TV transmission standards and performance parameters

CO2: Analyze channel coding, errors, interferences

CO3: Analyze various modulation techniques for Digital TV

- CO4: Make use of RF amplifiers, modules and systems for Digital TV
- CO5: Apply Transmission line principles for Digital TV

CO6: Understand the measurement parameters for a Digital TV Transmitter

			OUD COMPUTING			
~ ~ ~ ~ 1			to CE,EEE,ME and			
Course Code	L:T:P:S	Credits	Exam Marks		m Duration	Course Typ
22A0529T	3:0:0:0	3	CIE: 30 SEE:70	•	3 Hours	OEC
Course Objecti This course will		to to:				
To introduceTo understarTo understar	the broad per- d the concept d the features	ceptive of clo of Virtualiza of cloud sim	oud architecture and r tion and familiar with ulator and apply diffe e the trusted cloud Co	n the le erent cl	oud programm	
• To design of		Syllabus		mputi		Hours:48
Unit -I		v	d Computing			Hrs
Characteristics a Virtualization :	nd Benefits, C Introduction	Challenges Al	to Cloud, Cloud nead, Elasticity in Clo istics of Virtualize and Cloud computing.	oud, Oi ed En	n-demand Prov	
Unit -II	Cloud Ar	chitecture, I	Models and Security	7	9	Hrs
Clouds. Cloud Deployn	ent Model: I		Platform as a Service s, Private Clouds, H			
Clouds. Cloud Deployn Economics of th Unit -III Apache Hadoop	ent Model: F e Cloud. Cloud T , Map Reduce,	Public Cloud F echnologies , Hadoop Clu	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo	ybrid (Clouds, Comm	unity Clouds, DHrs
Clouds. Cloud Deployn Economics of th Unit -III Apache Hadoop Programming Ei	ent Model: F e Cloud. Cloud T , Map Reduce,	Public Cloud echnologies , Hadoop Clu r Google App	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo b Engine – Open Stac	ybrid (Clouds, Comm 10 ogle App Engin	unity Clouds, DHrs ne,
Clouds. Cloud Deployn Economics of th Unit -III Apache Hadoop	ent Model: F e Cloud. Cloud T , Map Reduce,	Public Cloud F echnologies , Hadoop Clu	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo b Engine – Open Stac	ybrid (Clouds, Comm 10 ogle App Engin	unity Clouds, DHrs
Clouds. Cloud Deploym Economics of th Unit -III Apache Hadoop Programming En Unit -IV VM Ware: Bast machine on loca	ent Model: H e Cloud. Cloud T , Map Reduce, avironment for ics of VM War l host, cloning	Public Cloud echnologies , Hadoop Clu r Google App VM ware S re, Advantag	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo b Engine – Open Stac	ybrid C ox, Goo k lizatior	Clouds, Comm 10 ogle App Engin 9 n, create a new	nunity Clouds, DHrs ne, Hrs virtual
Clouds. Cloud Deploym Economics of th Unit -III Apache Hadoop Programming En Unit -IV VM Ware: Bast machine on loca	ent Model: H e Cloud. Cloud T , Map Reduce, avironment for ics of VM War l host, cloning	Public Cloud echnologies , Hadoop Clu r Google App VM ware S re, Advantag	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo b Engine – Open Stac Simulator es of VMware virtual nines, virtualize a phy	ybrid C ox, Goo k lizatior	Clouds, Comm 10 ogle App Engin 9 n, create a new nachine, startin	nunity Clouds, DHrs ne, Hrs virtual
Clouds. Cloud Deploym Economics of th Unit -III Apache Hadoop Programming En Unit -IV VM Ware: Basi machine on loca stopping a virtua Unit -V Cloud Applicat	ent Model: H e Cloud. Cloud T , Map Reduce, nvironment for ics of VM War l host, cloning l machine. ions: Scientifi Consumer Ap	Public Cloud echnologies Hadoop Clu r Google App VM ware S re, Advantage virtual mach Cloud App c Application plications -	s, Private Clouds, Hy and Advancements ster setup, Virtual Bo b Engine – Open Stac Simulator es of VMware virtual nines, virtualize a phy	ybrid C ox, Goo k lization sical n	Clouds, Comm 10 ogle App Engin 9 n, create a new nachine, startin 10 e.	unity Clouds, DHrs ne, Hrs virtual ng and DHrs

- 1. Cloud computing for dummies- Judith Hurwitz , Robin Bloor , Marcia Kaufman ,Fern Halper, Wiley Publishing, Inc, 2010
- 2. Cloud Computing (Principles and Paradigms), Edited by Rajkumar Buyya, James Broberg, Andrzej Goscinski, John Wiley & Sons, Inc. 2011
- 3. Enterprise Cloud Computing, Gautam Shroff, Cambridge University Press, 2010.
- 4. Cloud Application Architectures: Building Applications and Infrastructure in the Cloud, George Reese, O 'Reilly, SPD, rp2011.
- 5. Essentials of Cloud Computing by K. Chandrasekaran. CRC Press. Cloud computing A Hands-On Approach by ArshdeepBahga and Vijay Madisetti.

Web Resources:

- 1. https://nptel.ac.in/courses
- 2. https://freevideolectures.com/university/iitm

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand the basic concepts about cloud computing vision and its developments and gain the Knowledge of virtualization technology.

CO2: Analyze the concepts of cloud services and the deployment models.

CO3: Choose among various cloud technologies for implementing applications (GAE, Open stack, etc)

CO4: Construct the virtual machines by using VMware simulator.

CO5: Build scientific applications by using Cloud environment.

CO6: Develop Business and Consumer Applications.

			AART GRID	-		
<u> </u>	I T D C		n to all Except EE			a m
Course Code	L:T:P:S	Credits	Exam marks	Exam Durat	ion	Course Type
22A0241Ta	3:0:0:0	3	CIE:30 SEE:70	3 Hours		OEC
Course Objecti	ves:		SEL. / V			
*		ies required fo	r the smart grid			
	-	-	s for data communi	cation		
• Standards for	or information	exchange and s	smart metering			
• Methods us	ed for informat	tion security on	n smart grid			
• Smart mete	ring and protoc	cols for smart n	netering			
• Power qual	ity managemen	t with upgrade	d technologies.			
		Syllabus	5		To	tal Hours: 48
Unit-I		Introduc	tion to Smart Gri	d		10 Hrs
Evolution of F	Electric Grid	Concept Defi	nitions and Need	for Smart Grid	Sm	art grid driver
		-	nefits, Difference l			-
· 11		e	Present developme			
-		-	global Smart Grid i		··· ·	
Unit-II		-	Grid Technologies			8 Hrs
Automation ,Ti	ansmission sys	stems: EMS, F	es, Smart substation FACTS and HVDO	C, Wide area mo	onitoı	ring, Protection
Automation ,Tr and control, Di	ansmission systems stribution system stage manager	stems: EMS, F ems: DMS, Vo nent, High E	FACTS and HVD0 olt/VAR control, F Efficiency Distribu	C, Wide area mo ault Detection, I	onitoi Isolati	ring, Protection
Automation ,Tr and control, Di restoration, Ou	ansmission systems stribution system stage manager	stems: EMS, F ems: DMS, Vo nent, High E Electric Vehicl	FACTS and HVD0 olt/VAR control, F Efficiency Distribu	C, Wide area mo ault Detection, I	onitoi Isolati	ring, Protection
Automation ,Tr and control, Di restoration, Ou Transformers, H Unit –III	ansmission systems stribution system stage manager Plug in Hybrid	stems: EMS, F ems: DMS, Vo nent, High E Electric Vehicl	FACTS and HVDO olt/VAR control, F Efficiency Distribu les (PHEV).	C, Wide area me ault Detection, I tion Transform	onitoi Isolati ers,	ring, Protection ion and service Phase Shifting 10 Hrs
Automation ,Tr and control, Di restoration, Ou Transformers, F Unit –III Introduction to	Smart Meters,	stems: EMS, F ems: DMS, Vo nent, High E Electric Vehicl St Advanced Me	FACTS and HVDO olt/VAR control, F Efficiency Distribu les (PHEV). mart Meters	C, Wide area me ault Detection, I tion Transforme re (AMI) drivers	onitor Isolati ers,	ring, Protection ion and service Phase Shifting 10 Hrs benefits, AMI
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- 1. The Smart Grid Enabling Energy efficiency and demand response, Clark W. Gellings, P.E., CRC Press, Taylor & Francis group, First Indian Reprint. 2015.
- 2. Smart Grid Applications, Communications, and Security Edited by Lars Torsten Berger, Krzysztof Iniewski, WILEY, 2012, Reprint 2015.
- Practical Electrical Network Automation and Communication Systems, Cobus Strauss, ELSVIER, 2003

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand the concepts and design of Smart grid.

CO2: Understand the various communication technologies in smart grid.

CO3: Understand the various measurement technologies in smart grid.

CO4: Understand the analysis and stability of smart grid.

CO5: Learn the renewable energy resources and storages integrated with smart grid.

CO6: Familiarize the high performance computing for Smart Grid applications

			TS AND MECHA		
Course Code	L:T:P:S	Credits	Exam marks	Exam Duratio	on Course Type
22А0330Та	2: 1:0 :3	3	CIE:30 SEE:70	3 Hours	OEC
Course Objectiv	ves:				
• To instruct t	he principles o	f interchangeal	ble manufacture.		
• To introduce	e basic principl	es of mechanic	cal measurements.		
	nowledge on m				
		Syllabus		r	Fotal Hours: 48
		•			
UNIT-I			mits & Fits		0 Hrs
Introduction, ter	rminology perta	aining to limits	s and fits – unilatera	al and bilateral tol	erance system, hole
and shaft basis s	systems – Inter	changeability,	deterministic & sta	tistical tolerance,	selective assembly
International Sta	andard system	of limits and fi	its		
Limit Gauges:	Taylor's princi	ple – Classific	ation and design of	limit gauges.	
UNIT-II]	Linear and A	ngular Measureme	ents 1	0 Hrs
Line and end st	tandards, slip g	gauges and ler	ngth bars. bevel pro	otractor – angle s	slip gauges – spirit
levels and auto	collimator.				
Interferometry	Applied to	Measuremen	nt: NPL flatness int	erferometer and N	NPL gauge
-	Applied to	Measuremen	nt: NPL flatness int	erferometer and N	VPL gauge
interferometer.					
interferometer. Surface Rougl	hness Measure	ement: Differe	ences between surfa	ce roughness and	l surface waviness-
interferometer. Surface Rougl Numerical asse	hness Measure ssment of surf	e ment: Differe face finish – (ce roughness and	l surface waviness-
interferometer. Surface Rougl Numerical asse surface finish –	hness Measure ssment of surf	e ment: Differe Face finish – (Falysurf	ences between surfa CLA, R.M.S, Rz v	ace roughness and alues, Methods of	l surface waviness-
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- 1. 1. IC Guptha,"Engineering Metrology ",Danpath Rai Publications.
- 2. Doeblin Earnest. O. Adaptation by Manik and Dhanesh,"Measurement Systems: Application and Design", Tata Mc Graw Hill Publications.

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Design the limit gauges for interchangeable manufacture.

CO2: Apply the basic principles of mechanical measurements for engineering practice.

CO3: Illustrate the role of mechatronics systems in manufacturing.

CO4: Explain principles of mechanical, hydraulic, pneumatic and electrical actuating systems.

CO5: Understand the components of a typical mechatronic system.

CO6: Understand the Design Aspects of a Mechatronic system.

			ER MANGEMEN		
Course Code	(Comm L:T:P:S	on to ME, CS Credits	E,AI&ML, CS, D Exam marks	S, ECE,EEE) Exam Durat	ion Course Type
22A0151T	3:1:0:0	3	CIE:30	3 Hours	ion Course Type OEC
22A01311	5.1.0.0	5	SEE:70	5 110015	OLC
Course Objecti	ves:		5		
-		of why and h	ow the modern dis	saster manager i	s involved with pre-
1	post-disaster a	2		U	1
	-		al phases of natura	l disaster respon	se and refugee relief
operations.		_	-	_	-
• Describe th	e three planning	g strategies use	ful in mitigation.		
• Describe pu	blic awareness	and economic	incentive possibilit	ties.	
• Understand	the tools of pos	st-disaster man	agement		
		Syllabus	3		Total Hours:48
Unit-I	Natu	ıral Hazards a	and Disaster Mana	agement	9 Hrs
Introduction of	DM – Inter di	sciplinary -nat	ure of the subject-	- Disaster Mana	gement cycle – Five
priorities for ac	ction. Case stud	ly methods of	the following: floo	ods, draughts – l	Earthquakes – global
warming, cyclo	nes & Tsunami	s – Post Tsuna	imi hazards along th	he Indian coast -	- landslides
Unit-II		Man	Made Disaster		9 Hrs
Fire hazards - t	ransport hazard	l dynamics – s	olid waste manager	ment – post disas	ster – bio terrotirism
threat in mega	cities, rail and a	air craft's accid	lents, and Emerging	g infectious dise	ases & Aids and thei
management.					
Unit -III		Risk a	nd Vulnerability		10 Hrs
Building code	s and land us	e planning –	social vulnerabili	ity – environm	ental vulnerability
Macroeconomi	c management	and sustainable	e development, clir	nate change risk	rendition – financia
management of	disaster – relat	ed losses.			
Unit -IV	Role of	Technology in	n Disaster Manage	ements	10 Hrs
Disaster manag	ement for infra	structures, tax	conomy of infra stru	ucture – treatme	nt plants and process
facilities-electr	ical substation	s roads and	bridges- mitigatio	n programme	for earth quakes –
flowchart, geo	spatial informa	ation in agric	ulture drought as	sessment-multin	nedia technology in
disaster risk ma	inagement and t	training- transf	ormable indigenou	s knowledge in o	lisaster reduction.
Unit -V	Edu	ucation and C	ommunity Prepar	edness	10 Hrs
					munity capacity and
Education in di			<u> </u>	inity based disas	ter management and
Education in di disaster resilier	ce-Community	based disaster	recovery -Commu	inity based disas	ster management and
disaster resilier	•		community capacit	•	der management and
disaster resilier social capital-D	•		•	•	der management and
disaster resilier social capital-D Fextbooks:	esigning resilie	ence- building	•	y for action.	
disaster resilier social capital-D Fextbooks:	esigning resilie & R R Krishnar	ence- building	community capacit	y for action.	
disaster resilier social capital-D Textbooks: 1. Rajib shah Local Solut	esigning resilie & R R Krishnar ions' Univer	ence- building on murthy "Disast rsities press. (2	community capacit	y for action. Global Challen	ges and
disaster resilier social capital-D Fextbooks: 1. Rajib shah Local Solut	esigning resilie & R R Krishnan ions' Univen ttacharya, "Dis	ence- building on murthy "Disast rsities press. (2	community capacity eer Management" – 009),	y for action. Global Challen	ges and

1. Harsh. K. Gupta "Disaster Management edited", Universities press, 2003. E-resources:

1. https://www.youtube.com/watch?v=DExlZTfKZAM&list=PLC4PaTsQiLcbejXqJR7S59Ohk2O K1rgEG

Course Outcomes(CO):

On completion of this course, student will be able to:

- CO1: Know about the natural hazards and its management
- CO2: Know about the fire hazards and solid waste management
- CO3: Understand about the emerging infectious diseases and aids their management

CO4: Know about the regulations of building codes and land use planning related to risk and vulnerability.

CO5: Impart the education related to risk reduction in schools and communities.

CO6: Describe public awareness and economic incentive possibilities.

		-	BER SECURITY	1 FOF		
Course Code	L:T:P:S	Credits	to CE,EEE,ME an Exam Marks		n Duration	Course Tur
22A0534b	3:0:0:0	3	CIE: 30 SEE:70		B Hours	Course Typ OEC
Course Objec	tives:		SEE.70			
This course will		nts to:				
Security arc.Students will Security pro	hitecture, risk I gain insight fessionals.	management, into the impo	the students with fo , attacks, incidents, a rtance of Cyber Sec Il determine the futu	and emen urity and	rging IT and I I the integral r	S technologies cole of Cyber
	1	Syllabus			•	Hours:48
Unit -I]	 Introduction	to Cybercrime		9	Hrs
Security, Who Perspectives, (are Cyberc Cybercrimes:	riminals, Cla An Indian P	and Origins of the assifications of Cyl erspective, Cyberch rcrime Era: Surviva	bercrime rime and	es, Cybercrim d the Indian	ne: The Legal ITA 2000, A
Unit -II		Cyber	Offenses		10	Hrs
Backdoors-Ste		- 0				
	Cyberc	rime Mobile	and Wireless Devic	ces	9	Hrs
Introduction, I Frauds in Mob Registry Settin	Proliferation bile and Wire lgs for Mobil e Devices: S	of Mobile an less Computin e Devices, A	and Wireless Devices d Wireless Devices ng Era, Security Ch uthentication Servic eations for Organiza	s, Trend hallenges he Secur	s in Mobility Posed by M ity, Attacks o	y, Credit Card obile Devices, on Mobile/Cell
Introduction, I Frauds in Mot Registry Settin Phones, Mobil	Proliferation pile and Wire ags for Mobil e Devices: S ile.	of Mobile an less Computin e Devices, Ar ecurity Implic	d Wireless Devices ng Era, Security Ch uthentication Servic	s, Trend nallenges xe Secur nations, C	s in Mobility Posed by M ity, Attacks o Organizational	y, Credit Card obile Devices, on Mobile/Cell
Introduction, H Frauds in Mob Registry Settin Phones, Mobil Handling Mobi Unit -IV Introduction, H Spywares, Vir	Proliferation oile and Wire ogs for Mobil e Devices: S ile. Tools a Proxy Servers us and Worr acks on Wire	of Mobile an less Computin e Devices, An ecurity Implic and Methods and Anonyn ns, Trojan Ho	d Wireless Devices ng Era, Security Ch uthentication Servic cations for Organiza	s, Trend nallenges ce Secur ations, C ne assword rs, DoS	s in Mobility Posed by M ity, Attacks o Organizational 10 Cracking, Ke and DDoS A	y, Credit Card obile Devices, on Mobile/Cell Measures for OHrs ey loggers and attacks, Buffer
Introduction, H Frauds in Mob Registry Settin Phones, Mobil Handling Mobi Unit -IV Introduction, H Spywares, Vir Overflow, Atta	Proliferation oile and Wire ags for Mobil e Devices: S ile. Tools a Proxy Servers us and Worr acks on Wire ID Theft).	of Mobile an less Computin e Devices, An ecurity Implic and Methods and Anonyn ns, Trojan Ho less Network	d Wireless Devices ng Era, Security Ch uthentication Servic cations for Organiza Used in Cybercrin nizers, Phishing, Pa orses and Backdoor	s, Trend nallenges ce Secur ations, C ne assword rs, DoS	s in Mobility Posed by M ity, Attacks o Organizational (Cracking, Ke and DDoS A heft: Introduct	y, Credit Card obile Devices, on Mobile/Cell Measures for OHrs ey loggers and attacks, Buffer
Introduction, H Frauds in Mob Registry Settin Phones, Mobil Handling Mobi Unit -IV Introduction, H Spywares, Vir Overflow, Atta Identity Theft (<u>Unit -V</u> Cyber Security organizations:	Proliferation oile and Wire ogs for Mobil e Devices: S ile. Tools a Proxy Servers us and Worr acks on Wire ID Theft).	of Mobile an less Computin e Devices, An ecurity Implic and Methods and Anonyn ns, Trojan Ho less Network Cyber Crime onal implicatio f Perils-Socia	d Wireless Devices ng Era, Security Ch uthentication Servic cations for Organiza Used in Cybercrin nizers, Phishing, Pa orses and Backdoor s, Phishing and Ide	s, Trend aallenges e Secur ations, C ne assword rs, DoS entity Th mes and Security	s in Mobility Posed by M ity, Attacks o Organizational (Cracking, Ke and DDoS A neft: Introduct (IPR issues V and privacy	 A, Credit Card Cobile Devices, on Mobile/Cell Measures for DHrs And Attacks, Buffer tion, Phishing, DHrs Attacks for Measures for Mishing, DHrs

Reference Books:

1. Information Security, Mark Rhodes, Ousley, MGH.

E-resources:

- 1. https://www.tutorialspoint.com/fundamentals_of_science_and_technology/cyber_crime_and_c yber_security.htm
- 2. https://www.javatpoint.com/cyber-security-tutorial
- 3. https://www.youtube.com/watch?v=lpa8uy4DyMo&list=PL9ooVrP1hQOGPQVeapGsJCktzIO 4DtI4_

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand Cyber Security architecture principles

CO2: Identifying System and application security threats and vulnerabilities

CO3: Identifying different classes of attacks

CO4: Cyber Security incidents to apply appropriate response

CO5: Describing risk management processes and practices

CO6: Demonstrate the role security management in cyber security defense

Course Code	L:T:P:S	Credits	Exam Marks	Exan	n Duration	Course Type
22A0327Ta	2: 1:0 :3	3	CIE: 30 SEE:70		Hours	OEC
Course Objecti	ves:					
This course will		ents to:				
• To impart kn	owledge on n	on-conventio	nal sources of energy	and tec	hniques used	in exploiting
			s of energy and Bior			
• To introduce	direct energy		ystems such as therm	no electr		
		Syllabus				Hours:47
UNIT-I			nd Their Availabilit	•		0Hrs
			Conventional and no			
			sification of RES, rol	-		
Solar Radiation	a: Structure of	of the sun, sola	ar constant, environn	nental in	npact of solar	radiation,
			on measuring instrur			•
			n, spectral distribution			adiation, solar
	ed surfaces ar	nd empirical e	quations for estimati	ng solar	radiation.	
UNIT-II			Collectors			OHrs
Solar Collector	s: Principles	of the conve	rsion of solar radiati	ion into	heat, classific	cations of solar
collectors- flat	plate collec	tors and con	centrating collector	s, collec	ctor materials	s, performance
analysis of a fla	t plate collect	tor.				
Solar Energy S	torage and	applications:	Different storage me	ethods-s	ensible and la	tent heat, solar
-			cooling, solar electri	ic conve	rsion, solar di	istillation, solar
pumping, solar	furnace, solar	cooking and	solar green house.			
UNIT-III			Energy			0Hrs
	-		conversion, site selec			-
			nd vertical axis, app			
-	-	-	iomass conversion te	-		-
-	-	-	classification of biog	gas plan	ts, advantages	s and
disadvantages, l	0					
Geothermal Th	ermal Energ	gy: Resources	, types of wells, meth	hods of I	harnessing the	e energy.
UNIT-IV		Ocean The	ermal Energy		(Hrs
	l Energy• M		an thermal electric p	ower ge		
Ucean Inerma			an mermarelectric p	ower ge	neration open	cycle systems,
	tems					
closed cycle sys		ing principle	components of tidal	nower n	lant single ha	sin and double
closed cycle sys Tidal Power Sy	v stem: Worki		components of tidal	power p	lant, single ba	asin and double
closed cycle sys Tidal Power Sy basin tidal energ	y stem: Worki gy system adv	vantages and l	imitations.		-	
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy:	v stem: Worki gy system adv Wave energy	vantages and 1 conversion E	imitations. Devices-wave energy	convers	ion by floats,	high level
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy: reservoir wave 1	v stem: Worki gy system adv Wave energy	vantages and 1 conversion E dolphin type v	imitations. Devices-wave energy wave power machine	convers	ion by floats, tages and disa	high level advantages.
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy: reservoir wave f UNIT-V	v stem: Worki gy system adv Wave energy machine and o	vantages and l conversion I dolphin type v Direct Ener	imitations. Devices-wave energy wave power machine gy Conversion	convers . Advan	ion by floats, tages and disa	high level advantages. DHrs
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy: reservoir wave 1 UNIT-V Direct Energy	ystem: Worki gy system adv Wave energy machine and o Conversion:	vantages and l conversion E dolphin type v Direct Ener Need for DE	imitations. Devices-wave energy wave power machine gy Conversion C, limitations, princip	convers . Advan ples of I	ion by floats, tages and disa DEC. thermoe	high level advantages. DHrs
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy: reservoir wave f UNIT-V Direct Energy See-beck, Peltie	vstem: Worki gy system adv Wave energy machine and o Conversion: or, Joule -Tho	vantages and l v conversion E dolphin type v Direct Ener Need for DE mson effects,	imitations. Devices-wave energy wave power machine gy Conversion C, limitations, princip Thermo-electric Pow	convers . Advan ples of I wer gene	ion by floats, tages and disa <u>9</u> DEC. thermoe rators	high level advantages. PHrs lectric Power –
closed cycle sys Tidal Power Sy basin tidal energ Wave Energy: reservoir wave f UNIT-V Direct Energy See-beck, Peltie MHD Power G	vstem: Worki gy system adv Wave energy machine and o Conversion: er, Joule -Tho eneration: P	vantages and l conversion E dolphin type v Direct Ener Need for DE mson effects, principles, diss	imitations. Devices-wave energy wave power machine gy Conversion C, limitations, princip	convers . Advan ples of I ver gene on, Hall	ion by floats, tages and disa DEC. thermoe rators effect, magn	high level advantages. Hrs lectric Power – etic flux, MHD

Text Books:

- 1. SP Sukhatme, "Solar Energy: Principles of thermal collection and storage" Tata McGraw Hill
- 2. Tiwari and Ghosal, "Renewable Energy Resources: Basic Principles and Applications", narosa
- 3. G.D. Rai, "Non-Conventional Energy Sources", Dhanpat Rai and Sons

Reference Books:

- 1. B.H.Khan, "Non conventional Energy Resources", Tata McGraw Hill education Pvt. Ltd.
- 2. 2. Twidell& Weir, "Renewable Energy Sources". Routledge (Taylor & Francis Group)

Course Outcomes(CO):

Upon successful completion of the course, the students will be able to:

- **CO1:** Classify various types of renewable sources of energy and illustrate the principles of solar radiation.
- **CO2:** Evaluate solar flat plate collector efficiency and illustrate various solar energy storage methods and applications.
- **CO3:** Describe the techniques of exploiting wind, biomass and geothermal energies in power generation.
- CO4: Illustrate the methods of tapping ocean thermal, tidal and wave energies in power generation.
- **CO5:** Describe the working of various direct energy conversion systems and their applications. Cyber Security incidents to apply appropriate response

CO6: Describing risk management processes and practices

		CONSTRUC	TION MANAGEM	IENT	
	(Comm	ion to ME, CS	SE,AI&ML, CS, D	S, ECE,EEE)	
Course Code	L:T:P:S	Credits	Exam marks	Exam Durat	tion Course Ty
22A0152T	3:1:0:0	3	CIE:30 SEE:70	3 Hours	OEC
Course Objecti	ves:	I	L		
 schedule an To teach the activities To make the milestone c To teach the schedule and the	d maintaining c e students abou e students fami harts	locuments and t various terms liar with conce concepts of ti	the stimates involved in pro-	tivities nvolved in earth oject management	work of constructint like bar charts a
sidek, entre		Syllabus	5		Total Hours:4
In:4 I	Enne	lamontala of (Construction Tech	nology	0.11mg
Unit-I	Func	iamentals of C	Construction Tech	nology	9 Hrs
Unit-II		I	Earth Work		9 Hrs
C1 'C' '			1		
			evelopment – Settin		
Groundwater C	ontrol – Trenc	hless (No-dig)	Technology – Gra	ding – Dredgin	g.Rock Excavatior
Groundwater C Basic Mechani	ontrol – Trenci cs of Breakage	hless (No-dig) e – Blasting	Technology – Gra Theory – Drillabili	ding – Dredgin ty of Rocks –	g.Rock Excavatior Kinds of Drilling
Groundwater C Basic Mechani Selection of th	ontrol – Trenci cs of Breakage ne Drilling Me	hless (No-dig) e – Blasting 7 ethod and Equ	Technology – Gra	ding – Dredgin ty of Rocks – ves – Blasting	g.Rock Excavatior Kinds of Drilling
Groundwater C Basic Mechani Selection of th Sequence – Sm	ontrol – Trenci cs of Breakage ne Drilling Me	hless (No-dig) e – Blasting 7 ethod and Equ	Technology – Gra Theory – Drillabili aipment – Explosi	ding – Dredgin ty of Rocks – ves – Blasting	g.Rock Excavation Kinds of Drilling Patterns and Firi
Groundwater C Basic Mechani Selection of th	ontrol – Trenci cs of Breakage the Drilling Me ooth Blasting –	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta	Technology – Gra Theory – Drillabili aipment – Explosi- al Effect of Blasting nt , Bar Charts an	ding – Dredgin ty of Rocks – ves – Blasting	g.Rock Excavatior Kinds of Drilling
Groundwater C Basic Mechani Selection of th Sequence – Sm	ontrol – Trenci cs of Breakage the Drilling Me ooth Blasting –	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta	Technology – Gra Theory – Drillabili upment – Explosit al Effect of Blasting	ding – Dredgin ty of Rocks – ves – Blasting	g.Rock Excavation Kinds of Drilling Patterns and Firi
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III	ontrol – Trenci cs of Breakagu ne Drilling Me ooth Blasting – Proje	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme	Technology – Gra Theory – Drillabili upment – Explosit al Effect of Blasting nt, Bar Charts and Charts	ding – Dredging ty of Rocks – ves – Blasting d Milestone	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin	ontrol – Trenci cs of Breakage he Drilling Me ooth Blasting – Proje g – Scheduling	hless (No-dig) e – Blasting f ethod and Equ Environmenta ct Manageme – Controlling	Technology – Gra Theory – Drillabili aipment – Explosi- al Effect of Blasting nt , Bar Charts an	ding – Dredging ty of Rocks – ves – Blasting d Milestone	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a	ontrol – Trenci cs of Breakage he Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration researcl	Technology – Gra Theory – Drillabili aipment – Explosi- al Effect of Blasting nt , Bar Charts an Charts – Role of decision	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o	ontrol – Trenci cs of Breakage he Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam	Technology – Gra Theory – Drillabili aipment – Explosi- al Effect of Blasting nt , Bar Charts and Charts – Role of decision = h – Methods of pla aples – Shortcoming	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a	ontrol – Trenci cs of Breakage he Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam	Technology – Gra Theory – Drillabili aipment – Explosival Effect of Blasting nt, Bar Charts and Charts – Role of decision the – Methods of pla	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction –	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts Elemen Event – Activi	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam nts of Networl	Technology – Gra Theory – Drillabili aipment – Explosit al Effect of Blasting nt , Bar Charts an Charts – Role of decision th h – Methods of pla aples – Shortcoming k and Developmen – Network rules –	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networ
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction –	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts Elemen Event – Activi	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam nts of Networl	 Technology – Gra Theory – Drillabili aipment – Explosival al Effect of Blasting nt , Bar Charts and Charts – Role of decision and the methods of plating and Developmen 	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networ
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction –	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts Elemen Event – Activi	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative examination nts of Networl ity – Dummy network – Num	Technology – Gra Theory – Drillabili aipment – Explosit al Effect of Blasting nt , Bar Charts an Charts – Role of decision th h – Methods of pla aples – Shortcoming k and Developmen – Network rules –	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networ
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction – Common partia	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling Iternatives Ope f bar chart – Ill estone charts Elemen Event – Activi l situations in r	hless (No-dig) e – Blasting f ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam hts of Network ity – Dummy hetwork – Num	 Technology – Gra Theory – Drillabili aipment – Explosival al Effect of Blasting nt , Bar Charts and Charts – Role of decision to the – Methods of plating and Development – Network rules – abering the events – 	ding – Dredging ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid Cycles Problen	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networns. 10 Hrs
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction – Common partia Unit -V Time estimates Problems -Ear	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling lternatives Ope f bar chart – Ill estone charts Elemen Event – Activi l situations in r	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam hts of Networl ity – Dummy hetwork – Num PE distribution – time – Formu	 Technology – Gra Theory – Drillabili aipment – Explosival Effect of Blasting nt , Bar Charts an Charts – Role of decision is h – Methods of pla aples – Shortcoming k and Development – Network rules – abering the events – RT and CPM Mean, variance an allation for TE - I 	ding – Dredgin ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid Cycles Problen d standard dev Latest allowable	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networns. 10 Hrs iation-Expected time e occurrence time
Groundwater C Basic Mechani Selection of th Sequence – Sm Unit -III Project plannin for analyzing a Development o measures – Mil Unit -IV Introduction – Common partia Unit -V Time estimates Problems -Ear	ontrol – Trenci cs of Breakage ne Drilling Me ooth Blasting – Proje g – Scheduling Iternatives Ope f bar chart – Ill estone charts Elemen Event – Activit l situations in re – Frequency liest expected r TL - Combine	hless (No-dig) e – Blasting 7 ethod and Equ Environmenta ct Manageme – Controlling eration research ustrative exam hts of Network hts of Network etwork – Num PE distribution – time – Formu ed tabular com	 Technology – Gra Theory – Drillabili aipment – Explosival Effect of Blasting nt, Bar Charts and Charts – Role of decision the – Methods of plate aples – Shortcoming k and Development – Network rules – and the events – Bering the events – RT and CPM Mean, variance and allation for TE - I putations for TE and the putations for the putations f	ding – Dredgin ty of Rocks – ves – Blasting d Milestone in project manag nning and prog gs of bar charts t of Network Graphical guid Cycles Problen d standard dev Latest allowable	g.Rock Excavation Kinds of Drilling Patterns and Firi 10 Hrs gement – Techniqu ramming problems and remedial 10 Hrs delines for networns. 10 Hrs iation-Expected time e occurrence time

Textbooks:
1. Construction project management by Jha ,Pearsonpublications, New Delhi 2nd Edition 2015
2. Construction Technology by SubirK.Sarkar and SubhajitSaraswati – Oxford Higher
EducationUniv.Press, Delhi 2008 edition
3. 3. Project Planning and Control with PERT and CPM by Dr.B.C.Punmia, K.K.Khandelwal,
Lakshmi Publications New Delhi 2022 editionDelhi
Reference Books:
1. Optimal design of water distribution networks P.R.Bhave, Narosa Publishing house 2003.
2. Total Project management, the Indian context- by: P.K.JOY- Mac Millan Publishers India
Limited.
E-resources:
1. https://nptel.ac.in/courses/105104161
Course Outcomes(CO):
On completion of this course, student will be able to:
CO1: Identify the various construction activities like preparing construction schedule an maintaining
documents and records of those activities
CO2: Understand the concepts and techniques involved in earthwork activities
CO3: Understand about the emerging infectious diseases and aids their management
CO4: Understand the steps involved in developing a project scheduling and management and the
application of bar charts and milestone charts.
CO5: Understand the various elements of a network diagram like event, activity and dummy.
CO6: Understand the concepts of calculation of time estimates of CPM and PERT

			TRIC VEHICLES		
			n to all Except EE	1	
Course Code	L:T:P:S	Credits	Exam marks	Exam Durati	J
22A0232Ta	3:0:0:0	3	CIE:30 SEE:70	3 Hours	OEC
Course Objectiv	/es:				
Understand hybrid andFamiliarize	To address the electrical vehic energy storage	e underlying co eles e systems for e	on hybrid and elect oncepts and method electrical and hybrid ectric vehicles and l	ls behind power t l transportation	
		Syllabus	5	-	Total Hours: 50
Unit-I	Electi	ric Vehicle Pr	opulsion and Ener	rgy Sources	10 Hrs
energy, specific	e power, Ragor management sy	ne plot. batter ystem- soc me	attery capacity, sta ry modeling - run easurement, battery her battery.	time battery me	odel, first principl
Unit-II	E	lectric Vehicle	e Power Plant And	l Drives	10 Hrs
reluctance mach DC/DC convert	ines. Power ele er. Two quadr	ectronic conve ant chopper a	rters-DC/DC conve	erters - buck boos es. AC drives PV	net machines, switcl st converter, isolated WM, current contro
Unit -III			Electric Drive Tr		9 Hrs
energy supplies. Power flow con	Hybrid tractio trol and energy otor drives, per	n and electric efficiency and	and social importan traction. Hybrid an alysis, configuration et motor drives, sw	d electric drive tr n and control of I	DC motor drives
Unit -IV	Ele	ctric and Hył	orid Vehicles - Cas	se Studies	11 Hrs
Toyota Prius, hybridized vehi	Honda Insight cles and low v	, Chevrolet V oltage system	Volt. 42 V system	n for traction a case study - GM	ehicle case study pplications. Lightl I EV1, Nissan Leat es.
Unit -V		Electric and	Hybrid Vehicle D	esign	10 Hrs
engine. Sizing	of propulsion	motor, power	electronics, drive	system. Selection	internal combustion n of energy storag egies in hybrid and

Textbooks:

- 1. Iqbal Hussein, "Electric and Hybrid Vehicles: Design Fundamentals", 2nd edition, CRC Press, 2003.
- 2. Amir Khajepour, M. Saber Fallah, Avesta Goodarzi, "Electric and Hybrid Vehicles: Technologies, Modeling and Control - A Mechatronic Approach", illustrated edition, John Wiley & Sons, 2014.
- 3. Mehrdad Ehsani, YimiGao, Sebastian E. Gay, Ali Emadi, "Modern Electric, Hybrid Electric and Fuel Cell Vehicles: Fundamentals, Theory and Design", CRC Press, 2004.

Reference Books:

- 1. James Larminie, John Lowry, "Electric Vehicle Technology", Explained, Wiley, 2003.
- 2. John G. Hayes, G. Abas Goodarzi, "Electric Powertrain: Energy Systems, Power Electronics and Drives for Hybrid, Electric and Fuel Cell Vehicles", 1st edition, WileyBlackwell, 2018.

Course Outcomes(CO):

On completion of this course, student will be able to:

- CO1: Understand the working of hybrid and electric vehicles
- **CO2:** Apply a suitable drive scheme for developing an hybrid and electric vehicles depending on resources
- **CO3:** Develop the electric propulsion unit and its control for application of electric vehicles.
- CO4: Understand the proper energy storage systems for vehicle applications
- CO5: Design and develop basic schemes of electric vehicles

CO6: Design and develop basic schemes of Hybrid electric vehicles

		ARTIFICI	AL INTELLIGEN	CE		
Course Code	L:T:P:S	Credits	Exam marks	Exam Durat	ion Cour	se Type
22A3301T	3:0:0:0	3	CIE:30 SEE:70	3 Hours	0	DEC
Course Objectiv	es:	1	•	•		
This course will	enable studer	nts to:				
• To understand	d the importan	ce of the task e	environment in dete	rmining the app	ropriate agen	t design
• To teach the	concepts of s	tate space rep	resentation, heurist	ic search togeth	er with the	time an
Space comple	exities.					
		-	nethods and natural		-	
-	-		nguage for commun	-	-	
• To understand	d the basic kno	owledge on rob	otics and philosoph	tical foundations	s of AI.	
		Syllabus	5		Total Ho	urs: 45
Unit-I		Introduction	to Artificial Intelli	gence	9 Hi	rs
	AI Definition	n. Foundation	s of Artificial I	ntelligence. Hi	story of A	Artificia
			Environments, Goo	-	•	
-		-	gents. Problem-Solv		-	-
		-	search, Uniform-co	• •	-	
Search strategies	-			st search, DIS.	intornica (ri	curistic
Unit-II	-		nd classical search	and Learning	9 Hi	PC
			problems: Hill-cli	-		
	-	-	rith Non-Determinis	-	-	
			nown Environment		arching with	i partia
Unit -III		0	arning and Natura		9 Hı	
0111 1 - 111	Kein		Processing	I Language	9 П	18
Introduction Pa	ssive Reinford		g, Active reinforcer	nent Learning (Generalizatio	n in
			lications of Reinforce	0		
	-		formation Extraction	-	, Language I	vioueis,
Unit -IV	-				9 Hi	a G
		8 8	communication a	-		
	-	• •	sis, Augmented gra		-	
	-	-	Image formation, H	• •	• •	
	• • • •	nce, Reconstru	icting the 5D work	i, Object recogn	illion from st	ructura
Object recogniti	na Vision					
information, Usi	-	Dehoting and I		Jotiona	0.11.	
information, Usi Unit -V	Ī		Philosophical found		9 Hi	
information, Usi Unit -V ntroduction, Re	botic Hardw	are, Robotic	Perception, Plann	ning to move,	Planning	uncerta
information, Usi Unit -V ntroduction, Ro novements, Mov	botic Hardw	are, Robotic software archi	Perception, Planr itectures, and applic	ning to move, cation domains.	Planning Week AI, St	uncerta rong A
information, Usi Unit -V ntroduction, Ro novements, Mov Ethics and Risks	botic Hardw ving, Robotic s of AI, Agen	are, Robotic software archi nt Component	Perception, Plann	ning to move, cation domains.	Planning Week AI, St	uncerta rong A
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Reference Books:

- 1. Patrick Henny Winston, Artificial Intelligence, 3rdEdition, Pearson Education.
- 2. Patterson, Introduction to Artificial Intelligence and Expert Systems, 1st Edition Pearson India.
- 3. George F Lugar, Artificial intelligence, structures and Strategies for Complex problem solving,6thed, PEA, 2008 .
- 4. Poole, D. and Mackworth, Artificial Intelligence: Foundations of Computational Agents, Cambridge University Press. 2010
- 5. Padhy, N.P , Artificial Intelligence and Intelligent Systems, 2009, Oxford University Press.

E-resources:

- 1. https://www.tutorialspoint.com/artificial_intelligence/index.htm
- 2. https://www.javatpoint.com/artificial-intelligence-ai
- 3. https://www.youtube.com/watch?v=JMUxmLyrhSk

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand the role of agents, environments and relationship among them.

CO2: Examine various problem-solving approaches in searching and learning.

CO3: Demonstrate the use of Reinforcement learning and natural language processing.

CO4: Understand the natural language for communication and object perception.

CO5: Demonstrate the role of Robot in various applications.

CO6: List out philosophical issues in AI.

	I.T.D.C	Cara ditta	r	INNOVATION	German Terra
Course Code	L:T:P:S 3:1:0:0	Credits 3	Exam marks	Exam Durati 3 Hours	ion Course Type HSC
22A0024T	5:1:0:0	3	CIE:30 SEE:70	5 Hours	HSC
			SEE:70		
Course Object					
			Entrepreneurship		
• To enable th enterprise	e student in k	cnowing vario	ous sources of gen	ierating new ide	eas in setting up of New
• To facilitate	the student in	n knowing va	rious sources of f	inance in startin	ng up of a business
• To impart ki	nowledge abo	out various go	overnment sources	s which provide	financial assistance to
	rs/women ent	1			
 To encourage 	ge the student	in creating an	nd designing busing	ness plans	
		Syllabu	IS		Total Hours:48
Unit -I		Introduction	to Entronyonou	rahin	10Hrs
Unit -I		Introduction	n to Entrepreneu	rsmp	IUTITS
Differences be mindset and p	etween Entre	epreneur and		nderstanding in	ence of entrepreneurship dividual entrepreneurial
		G 4 4			1011
ideas- Opportu Financial feas	unity recogni	Generating b tion- Feasibil	y Up New Ventur Dusiness idea – So ity study-Market	urces of new id feasibility, tech	10Hrs eas & methods of generatin nical/operational feasibility - Presenting business plan t
Starting the No ideas- Opportu Financial feas investors.	unity recogni	Generating b tion- Feasibil	y Up New Ventur Dusiness idea – So ity study-Market	urces of new id feasibility, tech	eas & methods of generatin nical/operational feasibility - Presenting business plan t
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Starting the No ideas- Opportu Financial feas investors. Unit -III Sources of fin Institutional F in India for su entrepreneuria Unit -IV Women Entr Government a incentives, sul Women entre Issues & Chal Unit -V Fundamentals	unity recognit ibility - Draw ance - Variou inance – Cor mall and med l journey- Ins epreneurship nd State Gov bsidies and g preneurship lenges-Entrep Intro of Business I	Generating b tion- Feasibil ving business Sources as sources of nmercial Ban dium business stitutions in a Women - Entreprene vernment in p grants – Expo - Role and in preneurial mo oduction to In	y Up New Ventur ousiness idea – So ity study-Market plan - Preparing ces of Finanace Finance available ks, SFC's in India s -Entrepreneurshi d of entrepreneurshi eurship Developer romoting women ort- oriented Units mportance - Gro otivations.	- Long term so - Long term so - Long term so - NBFC's in In- nip development - ship development - sh	eas & methods of generatin nical/operational feasibility - Presenting business plan t 9 Hrs - Operational feasibility - Presenting business plan t 9 Hrs - The - T
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Text books:

- D F Kurat koand TV Rao, "Entrepreneurship"- A South- Asian Perspective Cengage Learning, 2012. (For PPT, Case Solutions Faculty may visit:login.cengage.com)
- 2. Nandan H, "Fundamentals of Entrepreneurship", PHI, 2013

Reference Books:

- 1. Vasant Desai, "Small Scale Industries and Entrepreneurship", HimalayaPublishing2012.
- 2. RajeevRoy"Entrepreneurship", 2nd Edition, Oxford, 2012.
- 3. B.JanakiramandM.Rizwana"EntrepreneurshipDevelopment: Text&Cases", ExcelBooks, 2011.
- 4. Stuart Read, Effectual "Entrepreneurship", Routledge, 2013.

Course Outcomes(CO):

On completion of this course, student will be able to:

CO1: Understand the concept of Entrepreneurship and challenges in the world of competition.

CO2: Apply the Knowledge in generating ideas for New Ventures.

CO3: Analyze various sources of finance and subsidies to entrepreneur/ women Entrepreneurs.

CO4: Evaluate the role of central government and state government in promoting entrepreneurship.

CO5: Analyze the process of business incubation/incubators.

CO6: Create and design business plan structure through incubations.

		MAN	NAGEMENT SC	IENCE		
Course Code	L:T:P:S	Credits	Exam marks	Exam Du	ration	Course Type
22A0023T	3:1:0:0	3	CIE:30	3 Hou	rs	HSC
			SEE:70			
Course Object						
• To provide concepts.	e fundamenta	al knowledge	on Management	, Administrati	on, Orga	nization & its
-	ne students u	nderstand the	role of managem	ent in Product	ion	
			-			election, Training
-	_		erit rating concept		linent, b	
•			0 1		PERT/CP	M for better Project
Manageme		lucinity stru				
-		ware of the co	ontemporary issue	s in managem	ent	
		Syllabu	1 1	s in managem		otal Hours:48
Unit -I		Introduct	ion to Managem	ent		10Hrs
-		-	anization-MatrixC	-	-	Line organization anization-
Committeeform Unit -II	nofOrganiza	tion-Socialres Operatio	sponsibilitiesofMa ons Management	anagement.	rojectorga	-
Committeeform Unit -II Principles and Production),W	nofOrganiza d Types of ork Study-	tion-Socialres Operatio f Plant Lay Statistical Q	sponsibilitiesofMa ons Management out - Methods puality Control-D	of Producti eming's contr	on (Job,	anization- 10Hrs , batch and Ma to Quality. Mater
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Committeeform Unit -II Principles and Production),W Management Analysis - Pu Meaning-Natu Advertisement Unit -III HRM - Definit - Job Analysis Employee Sele On-the-job&O Appraisal – Pla Unit -IV Definition & Environmental ProjectManage Path Method (M	nofOrganiza d Types of ork Study- - Objectives rchase Proc re-Functions andSalesPro ion and Mea - Human Re ection -Proce ff-the-jobtrat acement- Em Meaning-Set Scanning - ement-Netwo CPM)Identif	tion-Socialres Operation f Plant Lay Statistical Q - Inventory edure and S ofMarketing- motion-Mark Human Rese uning – Natur esource Plant esource Plant esource Plant stand Tests iningmethods ployee Induc Strategic & I cting of V Steps in Stra orkAnalysis-P ying Critical	sponsibilitiesofMa ons Management vout - Methods vality Control-D -Functions - Typ tores Manageme MarketingMix-Cl etingStrategiesbas ources Managem e - Managerial an hing(HRP)- Emploi in Employee Sele -PerformanceApp tion –Wage and S Project Managen ision -Mission ategy Formulation ProgrammeEvalua	of Producti eming's contr bes, T Invento nt - Marketir hannelsofDistr sedonProductI eent d Operative fu oyee Recruitm ction -Employ oraisal Concep Salary Admini nent -Goals –Co n and Implement tionandReview	on (Job, ribution to ory Tech og Manag ribution- LifeCycle. Inctions - ment-Sour- veeTrainin ot- Methor stration.	anization- 10Hrs batch and Ma to Quality. Materniques - EOQ-Al gement - Concep 10Hrs Evolution of HRN ces of Recruitmenn ngandDevelopmenn ods of Performance 10Hrs Planning Proces - SWOT Analysis

	Contemporary Issues in Management	8Hrs
The concept	of ManagementInformationSystem(MIS)-Materials	sRequirementPlanning(MRP)
Customer Relat	ions Management(CRM)-Total Quality Management	(TQM)-Six Sigma Concept
Supply Chain M	lanagement (SCM)-Enterprise Resource Planning (ERF	P)- Performance Management
	s Outsourcing (BPO) -Business Process Re-engineering	ng and Bench Marking-
	Card-Knowledge Management.	
Textbooks:		
1. A.RAryasri,	'ManagementScience",TMH,2013	
2. Stoner, Free	man, Gilbert, Management, Pearson Education, NewDell	hi,2012.
Reference Bool		
1. Koontz&We	ihrich, "EssentialsofManagement", 6th edition, TMH, 2005	j.
2. ThomasN.D	uening&JohnM.Ivancevich,"ManagementPrinciplesand	Guidelines",Biztantra.
3. KanishkaBe	di, "ProductionandOperationsManagement", OxfordUniv	versityPress,2004.
4. SamuelC.Ce	rto, "ModernManagement", 9th edition, PHI, 2005	
Course Outcon	nes(CO):	
On completion of	f this course, student will be able to:	
CO1: Understan practical w	nd the concepts & principles of management and design or ld	ns of organization in a
CO2: Apply the	knowledge of Work -study principles& Quality Control	ol techniques in industry
CO3: Analyze t	he concepts of HRM in Recruitment, Selection and Trai	ning&Development
CO4: Evaluate project	PERT/CPM Techniques for projects of an enterprise	and estimate time& cost of
CO5: Analyze t	he business through SWOT	
	odern technology in management science.	

		BUS	INESS ENVIRO	NVIENI	
Course Code	L:T:P:S	Credits	Exam marks	Exam Duration	on Course Type
22A0026T	3:1:0:0	3	CIE:30 SEE:70	3 Hours	HSC
Course Object	tives:		I	1	
• To make	the student u	nderstand abo	out the business e	nvironment.	
• To enable	e them in kno	wing the imp	ortance of fiscal a	and monitory pol	icy.
• To facilit	tate them in u	nderstanding	the export policy	of the country.	
• Impart k	nowledge abc	out the function	oning and role of '	WTO.	
-	-		the structure of sto		
		Syllabu			Total Hours:48
		•			
Unit -I	A	n Overview o	of Business Envir	onment	10Hrs
Scopeofbusine		-	ess-Process&limit		onmental analysis nentalanalysis.
by public expe Budget - N	enditure - Eva MONETARY	evenues-Publi aluation of re POLICY	cent fiscal policy - Demand ar	blicdebtDevelop: of Government ad Supply of	10 Hrs mentactivities financec of India - Highlights of Money – RBI
FISCALPOLI by public expo Budget - M Objectivesofm Unit -III INDIA'S TRA and Multilater OFPAYMEN'	enditure - Eva MONETARY nonetaryandce India ADE POLICY cal Trade Agr TS–Structure	evenues-Publicaluation of re POLICY reditpolicy-R a's Trade Pol Y - Magnitud eements - EX &Majorcomp	icExpenditure-Pul cent fiscal policy - Demand ar ecenttrends-Rolec licy & Balance of le and direction of XIM policy and ro ponents-Causesfor	blicdebtDevelop: of Government of Supply of ofFinanceCommi f payments f Indian Internat ole of EXIM ban	mentactivities financec of India - Highlights of Money – RBI ssion. 10Hrs ional Trade – Bilateral c - BALANCE nBalanceofPayments-
FISCALPOLI by public expo Budget - M Objectivesofm Unit -III INDIA'S TRA and Multilater OFPAYMEN'	enditure - Eva MONETARY nonetaryandce India ADE POLICY cal Trade Agr TS–Structure asures–WTO	evenues-Publicaluation of re POLICY reditpolicy-R a's Trade Pol Y - Magnitud eements - EX &Majorcomp - Nature and	icExpenditure-Pul cent fiscal policy - Demand ar ecenttrends-Rolec licy & Balance of le and direction of XIM policy and ro ponents-Causesfor	blicdebtDevelop: of Government of Supply of ofFinanceCommi f payments f Indian Internat ole of EXIM ban	mentactivities financed of India - Highlights of Money – RBI ssion. 10Hrs ional Trade – Bilateral c - BALANCE
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FISCALPOLI by public expo Budget - M Objectivesofm Unit -III INDIA'S TRA and Multilater OFPAYMEN' Correctionmea of WTO in pro Unit -IV Features and money market - Investor prot Unit -V	enditure - Eva MONETARY nonetaryander India ADE POLICY cal Trade Agr TS–Structure asures–WTO omoting worl components ts and capital tection and ro	evenues-Public aluation of re POLICY reditpolicy-R a's Trade Pol a's Trade 	icExpenditure-Pul cent fiscal policy - Demand ar ecenttrends-Rolec licy & Balance of le and direction of XIM policy and ro ponents-Causesfor Scope - Organiza ets and capital me nancial systems - forms and recent	blicdebtDevelop of Government of Supply of ofFinanceCommi f payments f Indian Internat ole of EXIM ban Disequilibriumin tion and Structur arkets • Objectives, fea development– Si n	mentactivities financed of India - Highlights o Money – RBI ssion. 10Hrs ional Trade – Bilatera ional Trade – Bi

Textbooks:

- 1. Francis Cherunilam (2009), "International Business": Text and Cases, Prentice Hall of India.
- 2. K. Aswathappa, "Essentials of Business Environment": Texts and Cases & Exercises 13th Revised Edition. HPH2016.

Reference Books:

- K.V. Sivayya, V.B.M Das (2009), Indian Industrial Economy, Sultan Chand Publishers, NewDelhi, India.
- Sundaram, Black (2009), International Business Environment Text and Cases, Prentice Hall of India, New Delhi, India.
- 3. Chari .S.N (2009), International Business, Wiley India.
- 4. E. Bhattacharya(2009), International Business, Excel Publications, New Delhi.

Course Outcomes(CO):

On completion of this course, student will be able to:

- **CO1:** Understand various types of business environment.
- CO2: Evaluate fiscal and monitory policy
- CO3: Analyze India's Trade Policy
- **CO4:** Understand the role of WTO

CO5: Apply the knowledge of Money markets in future investment

CO6: Develop a personal synthesis and approach for identifying business opportunities

		HUMAN	RESOURCE MA	ANAGEMENT	
Course Code	L:T:P:S	Credits	Exam marks	Exam Durati	on Course Type
22A0033T	3:0:0:0	3	CIE:30	3 Hours	HSC
			SEE:70		
Course Object	tives:				
• To make t	he student un	derstand abo	ut human resource	e management.	
• To enable	the students	about job ana	lysis, job specific	ation and job en	richment.
• To enable	the students	knowing abo	ut HR planning a	nd retention.	
• To impact	knowledge a	bout recruitn	nent, selection and	l performance a	ppraisal.
• To create	knowledge of	n training and	l development, co	mpensation man	<u> </u>
		Syllabu	IS		Total Hours:48
Unit - I	Hum	an Resource	Management-In	troduction	9 Hrs
Introduction-	Obiectives –	Scope & Fea	tures of HRM –	Importance & -	Functions of HRM-
	5	-			manager - Strategic Human
Resource Mar		C			0 0
Unit - II		Job Anal	ysis and Job Desi	gn	9 Hrs
<u> </u>		1			
-		-			b Description & Job
Specification ·	- Job design -	- Factors affect	cting Job design -	Job enrichment	Vs Job enlargement.
Unit - III	Hu	man Resourc	e Planning and I	Imployee	10 Hrs
	110		Retention	Employee	
•				-	rs affect the HR Planning -HF
Information S	ystem - Empl	loyee retentio	n - Importance of	retention - strat	egies of retention.
TT •4 TT7		• • • • • • • • • • • • • • • • • • • •			10 11
Unit - IV	HR	-	and Managing F erformance	Imployee	10 Hrs
		r	eriormance		
Recruitment -	Objectives a	and Sources of	of recruitment - S	Selection - Obje	ctives - Selection Procedure
Placement - 1	Performance	Appraisal –	Objectives & Imp	portance, perfor	rmance Appraisal Methods -
Constraints.					
Unit - V	HR De	evelopment a	nd Compensatio	n Management	9 Hrs
		_		_	
	Development	t– Objectives	, Need and Meth	ods of Training	g -career planning and caree
Training and	-		ant Job avaluat	ion – welfare p	covisions and fringe benefits
-	-	ion Managem	ient - Job evaluat	1	
-	- Compensati	•		Ĩ	
development - Quality Circle	- Compensati	•			
development - Quality Circle	- Compensati	Quality Manag	gement.		son 2017.
development - Quality Circle Textbooks: 1. Gary Des	- Compensati s and Total Q sler, Biju Var	Quality Manag rkkey, Humar	gement. n Resource Manag	gement, 4e, Pear	
development Quality Circle Fextbooks: 1. Gary Des 2. Robert L	- Compensati s and Total Q sler, Biju Var	Quality Manager Reference of the second rkkey, Human n H. Jackson,	gement. n Resource Manag	gement, 4e, Pear	son 2017. ResourceManagement,

Reference Books:

- 1. Aswathappa, Human Resource Management, 4th Edition, TMH 2006.
- 2. Subbarao, Personnel and Human Resource Management -Text and cases, Himalaya, 2009
- 3. R.Wayne Mondy, Robert M.Noe, Human Resource Management, Pearson
- 4. Noea.Raymond, John Hollenbeck, Barry Gerhart and Patrick Wright, HumanResource Management, Tata McGraw Hill.
- 5. Muller, Human Resource Management a case study approach, Jaico Publishers, 2008
- 6. VSP Rao, Human Resource Management, Text and Cases, Excel Books 2006.

Course Outcomes (CO):

On completion of this course, student will be able to:

CO1: Understand the basic concept of Human Resource Management

CO2: Explain the job analysis and job design methods

CO3: Understand the demand and supply of HR & concept of employee retention

CO4: Understand the sources of Recruitment, Selection process and Performance appraisal methods

CO5: Examine the Training and Development methods and compensation managementprocess.

CO6: Familiarize the students with the contemporary issues in Management

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A04058P	1:0:0	2	CIE:30	3 Hours	SC
			SEE:70		
Course Objecti	ves:				
• To facilitate	students to un	derstand and	oid SDK.		
• To help stud	ents to gain a	basic understa	nding of Android a	application developm	ient.
-	-		roid Studio develoj		
		Syllabus]	Fotal Hours: 48
		Unit –I			10 Hrs
Application, An				nding Anatomy of A	10 Hrs
Android Appli	cation Desig	gn Essentials:	: Anatomy of	an Android applic	cations, Andro
	-	•	•	nts, Receiving and H	Broadcasting
terminologies, A	II ·····				
-				Intent Filter, Permiss	sions.
Intents, Android	Manifest File	e and its comm Unit –III	on settings, Using		10 Hrs
Intents, Android	Manifest File	e and its comm Unit –III gn Essentials:	on settings, Using User Interface Sc	Intent Filter, Permiss	10 Hrs
Intents, Android Android User In	Manifest File	e and its comm Unit –III gn Essentials:	on settings, Using User Interface Sc vith Animation.		10 Hrs
Intents, Android Android User In faces with Layou Testing Androi	Manifest File nterface Designuts, Drawing a	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing	User Interface Sc vith Animation.	ereen elements, Desi ation, Using Andro	10 Hrsgning User Inte9 Hrsoid preferences
Intents, Android Android User In faces with Layou Testing Androi	Manifest File nterface Designuts, Drawing a	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc	User Interface Sc vith Animation.	creen elements, Desi	10 Hrs gning User Inte 9 Hrs oid preferences ources.
Intents, Android Android User In faces with Layou Testing Androi Managing Appli	Manifest File nterface Designts, Drawing a d application cation resource	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc Unit –V	on settings, Using User Interface Sc with Animation.	ereen elements, Desi ation, Using Andro different types of reso	10 Hrs gning User Inte 9 Hrs Did preferences Durces. 9 Hrs
Intents, Android Android User In faces with Layou Testing Androi Managing Appli Using Common Sharing Data b	Manifest File nterface Designts, Drawing a id application cation resource Android API etween Appli	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc Unit –V s: Using Andr cations with 0	User Interface Sc vith Animation. Android applica thy, working with c oid Data and Stora Content Providers.	ereen elements, Desi ation, Using Andro	10 Hrs gning User Inte 9 Hrs oid preferences ources. 9 Hrs data using Sqlit etworking API
Intents, Android Android User In faces with Layou Testing Androi Managing Appli Using Common Sharing Data b	Manifest File nterface Designts, Drawing a id application cation resource Android API etween Appli	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc Unit –V s: Using Andr cations with 0	User Interface Sc vith Animation. Android applica thy, working with c oid Data and Stora Content Providers.	ereen elements, Desi ation, Using Andro different types of reso age APIs, Managing , Using Android N	10 Hrs gning User Inte 9 Hrs oid preferences ources. 9 Hrs data using Sqlit etworking API
Intents, Android Android User In faces with Layou Testing Androi Managing Appli Using Common Sharing Data b Using Android	Manifest File nterface Designts, Drawing a id application cation resource Android API etween Appli	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc Unit –V s: Using Andr cations with 0	User Interface Sc vith Animation. Android applica thy, working with c oid Data and Stora Content Providers.	ereen elements, Desi ation, Using Andro different types of reso age APIs, Managing , Using Android N	10 Hrs gning User Inte 9 Hrs oid preferences ources. 9 Hrs data using Sqlit etworking API
Intents, Android Android User In faces with Layou Testing Androi Managing Appli Using Common Sharing Data b Using Android V World. Text Books:	Manifest File nterface Designts, Drawing a d application cation resource Android API etween Appli Web APIs, U	e and its comm Unit –III gn Essentials: and Working v Unit –IV ns, Publishing ces in a hierarc Unit –V s: Using Andr cations with o sing Android 7	User Interface Sc vith Animation.	ereen elements, Desi ation, Using Andro different types of reso age APIs, Managing , Using Android N	10 Hrs gning User Inte 9 Hrs oid preferences ources. 9 Hrs data using Sqlit etworking API Application to th
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After the completion of the course students will able to:

CO1: Identify various concepts of mobile programming that make it unique from programming for other platforms.

CO2: Create and Run Android project using SDK.

CO3: Develop first level Android applications that can accept information from the users.

CO4: Design Android application screen with various elements for improving users experience.

CO5: Utilize various Android API's for improving users experience.

CO6: Understand simple GUI applications, use built-in widgets and components, work with the database to store data locally.

COURSES OFFERED FOR HONOR DEGREE BY ECE

1. The Honor subjects are having a total of 20 additional credits.

2. Students should acquire 4 credits through MOOCs compulsorily to award the Honor Degree.

Sl. No.	Course	Name of the Honor Course	Ho	urs per	week	Credits
	Code		L	Т	Р	С
1	22A04H01	Low Power VLSI Circuits and Systems	3	1	0	4
2	22A04H02	Pattern Recognition	3	1	0	4
3	22A04H03	Software Defined Radio	3	1	0	4
4	22A04H04	Micro Electro Mechanical Systems	3	1	0	4
5	22A04H05	Wireless Communications	3	1	0	4
6	22A04H06	VLSI Testing and Testability	3	1	0	4
7	22A04H07	ARM based Embedded System Design	3	1	0	4
8	22A04H08	Semiconductor Device Modelling	3	1	0	4
9	22A04109	Modern Digital Communication Techniques	3	1	0	4
10	22A04110	VLSI Interconnects	3	1	0	4

22A04H01 3:0:0 4 CIE:30 3 Hours HONOR Course Objectives: • Understand the concepts of Low power VLSI circuits and systems and Electrical characteristics of MOS Transistors • Understand the characteristics MOS Inverters and MOS Combinational Circuits. • Understand the characteristics MOS Inverters and MOS Combinational Circuits. • Students can learn the various sources and voltage scaling techniques to design the low powe VLSI circuits. • To understand the leakage power minimization techniques. • Total Hours:48 Unit -1 10 Hrs 10 Hrs Introduction, Historical background, why low power, sources of power dissipations, low-power design methodologies. • 10 Hrs MOS Transistors: introduction, the structure of MOS Transistor, MOS Transistors are switch. • 10 Hrs MOS Combinational Circuits: introduction, short-circuit power dissipation, inverter ratio in different situations, switching characteristics, delay parameters, driving large capacitive loads. MOS Combinational Circuits: introduction, short-circuit power dissipation, switching power dissipation, leakage power dissipation. Supply voltage scaling for low power: introduction, device features size scaling, architecture level approaches. Voltage Scaling Unit –IU 10 Hrs Sources of Power Dissipation: introduction, sort-circuit power dissipation, switching power diss	Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
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1. Kaushik Roy and Sharat C. Prasad, Low-Power CMOS VLSI Design, Wiley-Interscience, 2000.

Course Outcomes:

After the completion of the course students will able to:

CO1: Explain the structure, fluid model and Electrical characteristics of MOS transistors.

CO2: Explain the concepts of MOS Inverters and MOS Combinational Circuits.

CO3: Summarize the power Dissipation and voltage scaling techniques in digital circuits.

CO4: Analyze the system level and circuit level approaches for low power VLSI.

CO5: Describe the approaches to minimize the leakage power for VLSI system.

CO6: Explain the software tools for low power VLSI circuit design.

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Posteriori estimation. B Criterion functions for methods. Cluster valid parameter estimation. Markov Models (HMM density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	ayesian estima clustering. A ation. Gaussia Maximum en Is). Discrete I en-window me Unit	ation: Gaussian case lgorithms for clust an mixture models, tropy estimation. S HMMs. Continuous ethod. K-Nearest Ne –III	e. Unsupervised lea ering: K-Means, H , Expectation-Maxi Sequential Pattern s HMMs. Nonparan ighbour method.	rning and clustering - lierarchical and other imization method for Recognition. Hidden metric techniques for 10 Hrs
Criterion functions for methods. Cluster valid parameter estimation. Markov Models (HMM density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictional Linear discriminate f machines - a brief introd	clustering. A ation. Gaussia Maximum en Is). Discrete I en-window me Unit	lgorithms for clust an mixture models, tropy estimation. S HMMs. Continuous ethod. K-Nearest Ne –III	ering: K-Means, H , Expectation-Maxi Sequential Pattern 5 HMMs. Nonparan ighbour method.	lierarchical and other imization method for Recognition. Hidden metric techniques for 10 Hrs
methods. Cluster valid parameter estimation. Markov Models (HMM density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	ation. Gaussia Maximum en Is). Discrete I en-window me Unit	an mixture models, tropy estimation. S HMMs. Continuous ethod. K-Nearest Ne –III	, Expectation-Maxi Sequential Pattern 8 HMMs. Nonparan ighbour method.	imization method for Recognition. Hidden metric techniques for 10 Hrs
parameter estimation. Markov Models (HMM density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	Maximum en Is). Discrete I en-window me Unit	tropy estimation. S HMMs. Continuous ethod. K-Nearest Ne –III	Sequential Pattern 5 HMMs. Nonparat 9 HMMs. Nonparat 9 HMMs. Nonparat	Recognition. Hidden metric techniques for 10 Hrs
Markov Models (HMN density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	Is). Discrete I en-window me Unit	HMMs. Continuous ethod. K-Nearest Ne –III	HMMs. Nonparan	metric techniques for 10 Hrs
density estimation. Parz Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	en-window me Unit	ethod. K-Nearest Ne –III	ighbour method.	10 Hrs
Dimensionality reduct discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	Unit	-III		
discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd			it relationship to	
discriminant analysis - Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd	on: Principal	component analysis		Eigen analysis. Fisher
Factor Analysis, Total factorization - a dictiona Linear discriminate f machines - a brief introd		icon analysis Eicon		vactore as distinguisa
factorization - a dictiona Linear discriminate f machines - a brief introd			-	
Linear discriminate f machines - a brief intro			learning methods.	non negative matrix
machines - a brief introd	Unit			9 Hrs
machines - a brief introd			dures Percentron	
		dient deseent proce		Support vector
Агнистат пентат петм		ver perceptron – f	eed forward neura	l network. A brief
introduction to deep neu				
F		t –V	,,	9 Hrs
Non-metric methods			umeric data or not	
trees: Classification and	-			
Application(s): Face	-		ce detection algoi	rithms, selection of
representative patterns,	-		•	
Text Books:				
1. O.Duda, P.E.Hart a	nd D.G.Stork,	Pattern Classificati	on, John Wiley, 200)1
2. S.Theodoridis and				nic Press 2009

References:

- 1. C.M.Bishop, Pattern Recognition and Machine Learning, Springer, 2006
- P.A Devijver and J. Kittler, Pattern Recognition: A Statistical Approach, Prentice-Hall International, Englewood Cliffs, NJ, 1980.
- K. Fukunaga, Introduction to Statistical Pattern Recognition, 2nd Ed. Academic Press, New York, 1990.

Course Outcomes:

After the completion of the course students will able to:

- **CO1:** A good knowledge of Bayesian decision theory and Bayesian learning.
- **CO2:** Fundamental understanding of classifiers such as linear discriminate function, quadratic discriminate function, nearest neighbor rule, neural network and SVM.

CO3: A good understanding of feature selection algorithms.

CO4: Ability to evaluate the performance of various classifiers on real-world datasets.

CO5: To design and develop machine learning systems.

CO6: Ability to evaluate the performance of various classifiers on real world data sets.

		SOFT	WARE DEFINED	RADIO	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A04H03	3:0:0	4	CIE:30	3 Hours	HONOR
			SEE:70		
Course Objecti	ves:				
• Learn the	e design of th	he wireless	networks based on t	the cognitive radio	
• Understa	nd the conce	epts of wire	less networks and n	ext generation networ	ks
		•	Syllabus		
			Unit –I		
				and potential benefit	s, software radio
architecture evol	ution, techn	ology trade	offs and architecture Unit –II	e implications.	
SDR Architectu	re: Essentia	l functions		adio, basic SDR, har	dware architecture
				top level component	
topologies amon	g plug and p	olay module			
Introduction to 1	Comitivo D	adios. Marl	Unit –III	re, cognitive techniqu	es position
				ptimization of radio r	
Intelligence Tecl					
-	-		Unit –IV		
-		-		components and desi	
		-	ases, Inference Hie are defined Radio An	erarchy, Architecture	maps, Building th
	7 Heinteetui	e on boitwa	Unit –V		
Next Generation	Wireless I	Networks: 7	The XG Network a	architecture, spectrum	sensing, spectru
	ectrum mob	ility, spectru	um sharing, upper la	ayer issues, cross – lay	ver design.
Text Books:					
1			5	-Oriented Approaches	to Wireless
System Eng	ineering, Jo	hn Wiley &	Sons Ltd., 2000.		
2. Thomas W.	Rondeau, C	Charles W. E	Bostain, Artificial In	telligence in Wireless	communication,
ARTECH h	ouse, 2009.				
References:		·		2000	
	-		echnology", Elsevie		
2 Ian F Akvi	diz, Won –	Yeol Lee, N	Aehmet C. Vuran, S	Shantidev Mohanty, "Y	Next generation /
2. Iuli I . / Iky I		ss / cognitiv	e radio wireless net	tworks: A Survey" El	sevier Computer
•	ectrum acce	e Biiii			1
•		ee, eegenee			1
dynamic sp Networks, N	May 2006.		bling Location and	Environment Awaren	-
dynamic sp Networks, N 3. Hasari Cele	May 2006. bi, Huseyin	Arslan, Ena	bling Location and nications, Jan 2008		-

After the completion of the course students will able to

- Describe basics of the software defined radios.
- Understand the architectures of SDR.
- Understand the concept of Cognitive Radio Architecture.
- Understand various functions, components and design rules regarding Cognitive Radio Architecture.
- Design the wireless networks based on the cognitive radios.
- Explain the concepts behind the wireless networks and next generation networks.

MICRO ELECTRO MECHANICAL SYSTEMS

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A04H04	3:0:0	4	CIE:30	3 Hours	HONOR
			SEE:70		

Course Objectives:

- To impart knowledge of semiconductors and solid mechanics to fabricate MEMS devices.
- To understand the fundamentals of Micro fabrication techniques.
- To learn various sensors and actuators and different materials used for MEMS
- To outline the applications of MEMS to disciplines beyond Electrical and Mechanical engineering.

Syllabus	Total Hours: 48
Unit –I	10 Hrs
Introduction: Intrinsic Characteristics of MEMS - Energy Domains and	d Transducers- Sensors
and Actuators - Introduction to Micro fabrication - Silicon based ME	EMS processes – New
Materials - Review of Electrical and Mechanical concepts in MEMS - See	emiconductor devices –
Stress and strain analysis – Flexural beam bending- Torsional deflection.	
Unit –II	10 Hrs
Sensors and Actuators-I:Electrostatic sensors Electrostatic sensors E	electrostatic sensors -
Parallel plate capacitors - Applications - Inter digitated Finger capacitor -	- Comb drive devices –
Micro Grippers – Micro Motors - Thermal Sensing and Actuation.	
Unit –III	10 Hrs
Sensors and Actuators-II: Piezo resistive sensors – Piezo resistive sensors	nsor materials - Stress
analysis of mechanical elements - Applications to Inertia, Pressure, Tact	ile and Flow sensors -
Piezoelectric sensors and actuators - piezoelectric effects - piezoelectric m	naterials – Applications
to Inertia, Acoustic, Tactile and Flow sensors.	
Unit –IV	9 Hrs
Anisotrophic Wet Etching – Dry Etching of Silicon – Plasma Etching Etching (DRIE) – Isotropic Wet Etching – Gas Phase Etchants – Case micro machining processes – Structural and Sacrificial Materials – Accelera – Striction and Antistriction methods – LIGA Process - Assembly of 3 process.	studies - Basic surface ation of sacrificial Etch
Unit –V	9 Hrs
Polymer and Optical Mems: Polymers in MEMS– Polimide - SU-8 - I (LCP) – PDMS – PMMA – Parylene – Fluorocarbon - Application to Accel and Tactile sensors- Optical MEMS – Lenses and Mirrors – Actuators for A Textbooks:	eration, Pressure, Flow
1. Chang Liu, "Foundations of MEMS", Pearson Education Inc., 2006.	
2. Stephen D Senturia, "Microsystem Design", Springer Publication, 2000).
 Tai Ran Hsu, "MEMS & Micro systems Design and Manufacture" Tata Delhi, 2002. 	a McGraw Hill, New

References:

- 1. James J.Allen, "Micro Electro Mechanical System Design", CRC Press Publisher, 2010
- Julian w. Gardner, Vijay K. Varadan, Osama O. Awadelkarim, "Micro Sensors MEMS and Smart Devices", John Wiley & Son LTD,2002
- 3. Mohamed Gad-el-Hak, editor, "The MEMS Handbook", CRC press Baco Raton, 2000
- Nadim Maluf," An Introduction to Micro Electro Mechanical System Design", Artech House, 2000.
- 5. Thomas M.Adams and Richard A.Layton, "Introduction MEMS, Fabrication and Application," Springer 2012.

Course Outcomes:

After the completion of the course students will able to:

- CO1: Understand the operation of micro devices, micro systems and their applications
- CO2: Understand the concept of Electrostatic sensors
- CO3: Understand the operation of Piezo resistive sensors
- **CO4:** Choose a micromachining technique, such as bulk micromachining and surface micromachining for a specific MEMS fabrication process

CO5: Simplify the design of micro devices, micro systems using the MEMS fabrication process.

CO6: Understand the concept of polymer and optical MEMS

		WIRELESS	COMMUNICATI	ONS	
Course Code	L:T:P	Credits	Exam. Marks	Exam Duratio	on Course Type
22A04H05	3:0:0	4	CIE:30 SEE:70	3 Hours	HONOR
Course Objectiv	/es:				
• To study the c	haracteristic o	of wireless cl	nannel		
• To understand	the design of	a cellular sy	vstem		
• To study the v	various digital	signaling tec	chniques and multip	ath mitigation tec	chniques
• To understand	l the concepts	of multiple a	antenna techniques		
		Syllabus			Total Hours: 48
		(Wireless (10 Hrs
• •			Free Space and Two	•	• •
	-		nultipath channels -	-	-
		-	& Coherence time,	-	-
-	ing – frequen	cy selective	fading – Fading du	ie to Doppler spi	read – fast fading
slow fading.	Unit _II	(Cellular Ai	rchitecture)		10 Hrs
Multiple Access		`	MA, CDMA – Capa	city calculations	
-	-		d off- interference &	-	_
of service – Cove		-		5 1 .	
	<u> </u>		or Fading Channel	s)	10 Hrs
Structure of a w	ireless comm	unication lin	k, Principles of Off	set-QPSK, p/4-D	OQPSK, Minimum
Shift Keying, G	aussian Minir	num Shift K	leying, Error perfor	mance in fading	channels, OFDM
principle - Cycli	c prefix, Wind	lowing PAP	D		
	nit –IV (Mult	ipath Mitig	ation Techniques)		9 Hrs
Equalisation – A	nit –IV (Mult daptive equali	ipath Mitig zation, Line	ation Techniques) ar and Non-Linear e		o forcing and LMS
Equalisation – A Algorithms. Dive	nit –IV (Mult daptive equali ersity – Micro	ipath Mitig zation, Line and Macro	ation Techniques) ar and Non-Linear e diversity, Diversity	combining techn	o forcing and LMS
Equalisation – A Algorithms. Dive	nit –IV (Mult daptive equali ersity – Micro ling channels	ipath Mitig zation, Line and Macro with diversit	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re	combining techn	o forcing and LMS hiques, Error
Equalisation – A Algorithms. Dive probability in fac	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu	ipath Mitigazation, Linea and Macro with diversity Itiple Anten	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques)	combining techr ceiver.	o forcing and LMS hiques, Error 9 Hrs
Equalisation – A Algorithms. Dive probability in fac MIMO systems	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques) rstem model -Pre-co	combining techr ceiver. oding - Beam for	o forcing and LMS hiques, Error 9 Hrs ming - transmitter
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques)	combining techr ceiver. oding - Beam for	o forcing and LMS hiques, Error 9 Hrs ming - transmitter
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels.	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques) rstem model -Pre-co	combining techr ceiver. oding - Beam for	o forcing and LMS hiques, Error 9 Hrs ming - transmitter
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books:	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C	ipath Mitig zation, Line and Macro with diversity Itiple Anten iplexing -Sy Channel state	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques) rstem model -Pre-co	combining techr ceiver. oding - Beam for ity in fading and	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books: 1. Rappaport,T (UNIT I, II,	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C .S., —Wireles	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy Channel state s communica	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re na Techniques) rstem model -Pre-co e information-capac	combining techr ceiver. oding - Beam for ity in fading and cation, Second Ed	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading dition, 2010.
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books: 1. Rappaport,T (UNIT I, II, 2. Andreas.F. I References:	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C .S., —Wireles IV) Molisch, —W	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy Channel state s communica	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re ma Techniques) rstem model -Pre-co e information-capac ations, Pearson Edue	combining techr ceiver. oding - Beam for ity in fading and cation, Second Ed Viley – India, 200	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading dition, 2010. 6. (UNIT III,V)
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Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books: 1. Rappaport,T (UNIT I, II, 2. Andreas.F. I References: 1. Wireless Co	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C .S., —Wireles IV) Molisch, —W	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy Channel state s communica ireless Comm	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re ma Techniques) rstem model -Pre-co e information-capac ations, Pearson Edue	combining techr ceiver. oding - Beam for ity in fading and cation, Second Ed Viley – India, 200 University Press	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading dition, 2010. 6. (UNIT III,V)
Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books: 1. Rappaport,T (UNIT I, II, 2. Andreas.F. I References: 1. Wireless Co	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C .S., —Wireles IV) Molisch, —W mmunication and Ramji Pr	ipath Mitig zation, Line and Macro with diversit ltiple Anten iplexing -Sy Channel state s communica ireless Comm	ation Techniques) ar and Non-Linear e diversity, Diversity y reception, Rake re ma Techniques) rstem model -Pre-co e information-capac ations, Pearson Edue nunications, John W	combining techr ceiver. oding - Beam for ity in fading and cation, Second Ed Viley – India, 200 University Press	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading dition, 2010. 6. (UNIT III,V)
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Equalisation – A Algorithms. Dive probability in fac MIMO systems diversity, receive channels. Text Books: 1. Rappaport,T (UNIT I, II, 2. Andreas.F. I References: 1. Wireless Co 2. Van Nee, R. House, 2000	nit –IV (Mult daptive equali ersity – Micro ling channels Unit –V (Mu – spatial mult er diversity- C .S., —Wireles IV) Molisch, —W mmunication and Ramji Pr) nd PramodVis	ipath Mitig zation, Line and Macro with diversity ltiple Anten iplexing -Sy Channel state s communica ireless Comm -Andrea Go asad, —OFD	ation Techniques) ar and Non-Linear of diversity, Diversity y reception, Rake re ma Techniques) rstem model -Pre-co e information-capac ations, Pearson Educ nunications, John W ldsmith, Cambridge DM for wireless mult	combining techr ceiver. oding - Beam for ity in fading and cation, Second Ed <u>'iley – India, 200</u> University Press timedia communi	o forcing and LMS hiques, Error 9 Hrs ming - transmitter 1 Non-fading dition, 2010. 6. (UNIT III,V) , 2011 ications, Artech

After the completion of the course students will able to:

CO1: Understand the concepts of wireless communications and standards

CO2: Characterize a wireless channel and evolve the system design specifications.

CO3: Analyze working of wireless technologies

CO4: Design a cellular system based on resource availability and traffic demands

CO5: Identify suitable signaling and multipath mitigation techniques for the wireless channel and system under consideration.

CO6: Plan a wireless system for deployment

	1		NG & TESTABI			
Course Code	L:T:P	Credits	Exam. Marks	Exam Du		Course Type
22A04H06	3:0:0	4	CIE:30 SEE:70	3 Ho u	irs	HONOR
Course Objecti	ves:					•
•		the basic faults	s that occur in digit	al systems		
• To describe f	ault detection	on techniques in	n combinational ci	cuits.		
• To outline p	rocedures t	o generate test	t patterns for dete	cting single	stuck f	aults in
		ntial circuits.	•	0 0		
• To explain d	esign for tes	tability techniq	ues with improved	fault cover	age.	
• To introduce	BIST conce	epts and specifi	c architectures.			
• To give exp	osure to ap	proaches for i	introducing BIST	into logic o	circuits,	memories and
embedded co	ores.					
		Syllabus			Tota	l Hours: 48
			esting & Testabilit	-		10 Hrs
		0	ability (DFT) Fun	· · · · · · · · · · · · · · · · · · ·		0 0
			l and structural m			
			nodels, Element e	valuation, I	Hazard o	letection, Gate
level event drive						10.11
		-II::Fault Mod	0	1 1	F 1/	10 Hrs
			ult detection and a			
General techniqu			stuck – Fault mod	els. Fault s	mulatio	ii applications,
General techniqu		III::Fault Sim				10 Hrs
Testing for sing			mated test pattern	generation	(ATPG/	
			Functional testing			
	-		paction and compre	-		
		::Design for te		,	8	9 Hrs
Design for testa		-	ffs, techniques. Sca	an architectu	ires and	testing –
			boundary scan, ful			
scan design. Bo	ard level an	nd system leve	el DFT approaches	. Boundary	scan st	andards,
Compression tec			ues, syndrome test	and signatu	ire analy	sis.
	Unit –V::	Built-in self-te	est (BIST)			9 Hrs
Built-in self-tes	t (BIST): E	BIST Concepts	and test pattern	generation.	Specific	BIST
Architectures -	CSBL, BE	ST, RTS, LOO	CST, STUMPS, C	BIST, CEB	S, RTD	, SST, CATS,
CSTP, BILBO.	Brief ideas	on some advar	nced BIST concept	ts and desig	n for se	lf-test at board
level.						
					ntroduct	•
Memory BIST	(MBIST):]	Memory test ar	chitectures and tec	hniques – I	mouuci	ion to memory
•	, ,	•	chitectures and tec mbedded memory	-		•
test, Types of m	nemories and	dintegration, E	mbedded memory	testing mod		•
test, Types of m requirements for	nemories and	dintegration, E		testing mod		•
test, Types of m requirements for Text Books:	memories and MBIST. Bi	dintegration, E rief ideas on em	mbedded memory ibedded core testin	testing moo g.	del. Mer	nory test
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After the completion of the course students will able to:

- CO1: Understand the Need and Necessity of Testing & Testability of VLSI Circuits.
- **CO2:** Model digital circuits at logic and RTL levels.
- **CO3:** Simulate digital ICs in the presence of faults and evaluate the given test set for fault coverage.
- **CO4:** Generate test patterns for detecting single stuck faults in combinational and sequential circuits.
- **CO5:** Identify schemes for introducing testability into digital circuits with improved fault coverage.
- **CO6:** Compare different approaches for introducing BIST into logic circuits, memories & embedded cores.

ARM BASED EMBEDDED SYSTEM DESIGN

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A040H07	3:0:0	4	CIE:30	3 Hours	HONOR
			SEE:70		

Course Objectives:

- To get knowledge in system design using Micro controllers.
- To Study the architectural features and programming aspects of ARM controllers/processors.
- To learn about memory management in the system design applications.
- To develop software and program for an embedded system.
- To analyze operating systems concepts, types and choosing RTOS.
- To Design, implement and test an embedded system.

Syllabus	Total Hours: 48
Unit –I	10 Hrs
ARM Embedded Systems: An Embedded System-Definition, Embedded	led System Design and
Development, Life Cycle, Embedded system Architecture, Embedded	Systems classification,
The RISC Design Philosophy, The ARM Design Philosophy, Embed	•
Embedded System Software, ARM processor Families, Core extensions,	
Unit –II	10 Hrs
ARM Programming Model-I Instruction Set: Data Processing Instr	uctions, Branch, Load,
Store Instructions, PSR Instructions, Conditional Instructions.	0.11
Unit –III	9 Hrs
ARM Programming Model-II Thumb Instruction Set: Register Usa	•
Instructions, Data Processing Instructions, Single Register and Multi Re-	egister Load-Store
Instructions, Stack, Software Interrupt Instructions Unit –IV	10 Hrs
ARM Programming: Simple C Programs using Function Calls, Point	
and Floating Point Arithmetic, Assembly Code using Instruction Sch	-
Allocation, Conditional Execution and Loops.	leduning, Register
Unit –V	9 Hrs
Memory Management: Cache Architecture, Polices, Flushing and Cach	
Translation, Access Permissions, Content Switch.	., ., .,
Text Books:	
1. Andrew N. Sloss, Dominic Symes, Chris Wright, "ARM Systems De-	veloper's Guide-
Designing & Optimizing System Software", 2008, Elsevier.	
2. 2. Jonathan W. Valvano - Brookes / Cole, 1999, "Embedded Microco	mputer Systems, Real
2. 2. Johannan V. Valvano Brookes/Cole, 1999, Enlocaded Microe	
Time Interfacing", Thomas Learning.	
Time Interfacing", Thomas Learning.	
Time Interfacing", Thomas Learning. References:	2005.
Time Interfacing", Thomas Learning. References: 1. Intel and ARM Data Books on Microcontrollers.	

E-learning resources:

- 1. nptel.ac.in/courses/ARM embedded systems design
- 2. https://www.ARMembedded.com
- 3. An embedded software premier/http://books.google.co.in

Course Outcomes:

After the completion of the course students will able to:

CO1: Gets complete knowledge about the system design concepts using Micro controllers.

CO2: Understand thoroughly the architectural and programming concepts of ARM controllers.

CO3: Know about the memory management concepts in system design.

CO4: Identify the significance of Real Time Operating Systems.

CO5: Analyze the types of memory and interfacing to external hardware

CO6: Describe embedded firmware design approaches

SEMICONDUCTOR DEVICE MODELING

Course Code	L:T:P	Credits	Exam. Marks	Exam Duration	Course Type
22A04H08	3:0:0	4	CIE:30	3 Hours	HONOR
			SEE:70		

Course Objectives:

- This course provides a solid foundation in the physics of semiconductors so that students will be able to not only understand current devices and exploit the novel applications.
- It also appreciates the workings of new semiconductor devices as they materialize and evolve in future years.

Syllabus	Total Hours: 48				
Unit –I: Semiconductor Physics	10 Hrs				
Metals, insulator, semiconductors, intrinsic and extrinsic sem	iconductors, direct and				
indirect band gap, free carrier densities, Fermi distribution, density of states, Boltzmann					
statistics, thermal equilibrium, current flow mechanisms, drift c	current, diffusion current,				
mobility, band gap narrowing, resistance, generation and recomb	bination, lifetime, internal				
electro-static fields and potentials, Poisson's equation, continuity	equations, drift-diffusion				
equations					
Unit –II: PN-Junction Diodes	10 Hrs				
Thermal equilibrium physics, energy band diagrams, space charge	layers, internal electro-				
static fields and potentials, reverse biased diode physics, junction c	capacitance, wide and				
narrow diodes, transient behavior, transition, diffusion capacitance	e, small signal model.				
Unit –III: Bipolar Transistors	10 Hrs				
Basic theory and operation, heavy doping effects, double diffused transistors, Eber's-					
Moll model, low forward bias, junction and diffusion capacitance, transit times, parasitic,					
small-signal models, Early effect, saturation and inverse operation, breakdown					
mechanisms, punch-through.					
Unit –IV: MOS Transistors	9 Hrs				
MOS capacitor, accumulation, depletion, strong inversion, the	reshold voltage, contact				
potential, oxide and interface charges, body effect, drain current	, saturation voltage, gate				
work function, channel mobility, sub-threshold conduction,	short channel effects,				

Compact models for MOSFET and their implementation in SPICE. Level 1, 2 and 3, MOS model parameters in SPICE.

Unit –V: UDSM Transistor Design Issues

9 Hrs

Short channel and ultra short channel effects; Effect to_X, effect of high k and low k dielectrics on the gate leakage and Source –drain leakage; tunneling effects; different gate structures in UDSM-impact and reliability challenges in UDSM.

effective channel length, effects of channel length and width on threshold voltage,

Text Books:

- 1. Y.P. Triviids, The MOS Transistor, Mc Graw-Hill, international editioned, 1988.
- 2. Nandita Das Gupta, Amitava Das Gupta, Semi conductor Devices: Modeling and Technology, PHI
- 3. S. M. Sze, Semiconductor Devices Physics and Technology, John Wiley & Sons Inc, (2/e).

References:

- 1. Getreu, Modeling the bipolar transistor, New York, NY: Elsevier, 1978.
- 2. D. Roulston, Bipolar Semi conductor Devices, Mc GrawHill, 1990.
- 3. N.Arora, MOSFET Models for VLSI Circuit Simulation, Springer-Verlag, 1993.

Course Outcomes:

After the completion of the course students will able to:

CO1: Apply their knowledge in analyzing Semiconductor devices.

CO2: Understand fundamentals of energy band theory in semiconducting materials

CO3: Understand the characteristics of diodes and transistors

CO4: Classify and analyze the various circuit configurations of Bipolar and MOS Transistors

CO5: Demonstrate the knowledge of MOS Transistors and their characteristics.

CO6: Analyze the concepts of UDSM and observe its characteristics.